

SINGLE MOLECULE OPTICAL ABSORPTION BY STM AND A NEW ALGORITHM FOR
SOLVING DYNAMICS ON A FREE ENERGY SURFACE

BY

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DISSERTATION

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Abstract

The combination of the high spatial resolution of the scanning tunneling microscope (STM) and the spectral resolution of a laser provides a powerful tool for probing the local optical and electronic properties of materials. Optical absorption detected by STM offers direct imaging of molecular absorption well below the diffraction limit that hampers traditional spectroscopic methods. This technique is used to optically differentiate carbon nanotubes within nanometers of each other and, further, to resolve local variations in absorption within a single carbon nanotube. Provided from this is direct imaging of the spatial distribution of exciton generation from an optical absorption event. The interactions between light and single molecules are shown to be highly wavelength dependent and are very sensitive to the local electronic environment.

Relating experimental thermodynamic and kinetic data to the dynamics on free energy surfaces can be cumbersome for all but the most trivial of cases. Many models have been developed to explain a variety of phenomena, but few methods are appropriate for cases with low kinetic barriers. Those methods that do fit free energy surfaces with low barriers are typically computationally expensive in multiple dimensions. A new method is presented for solving dynamics on free energy surfaces based on the Smoluchowski diffusion equation. Computational cost is saved by reducing the complexity of the surface through the use of a singular value decomposition basis set. Fitting is performed with a parallelized genetic algorithm. Free energy surfaces are fitted in up to 2-dimensions for the α 3D and PTB1:4W proteins. The algorithm is further used to create test data for a new method for finding thermodynamic data from kinetic experiments when thermodynamic experiments are insufficient for probing the stability of proteins.

Acknowledgements

While most of the experimental work described in this dissertation was performed under vacuum conditions, my work has not been done in vacuum in the literary sense of the word. I owe a great deal of thanks to a number of individuals who have cultivated my development as a scientist and educator, many of whom do not appear on this short page of tribute.

I am extremely grateful for the opportunity to work under the guidance of Professor Martin Gruebele throughout my time as a graduate student. I could not have asked for a better advisor under which to grow professionally and personally. Martin is both an excellent researcher and a dedicated educator and I only hope that I can emulate his leadership style as I begin my career in academia. I have also had the great fortune to learn from Professor Joseph Lyding. Joe's expertise in STM and his willingness to help adapt our system for specialized needs have been invaluable. Joe operates with a generosity of spirit and I have been fortunate to have the opportunity to share in such an agreeable collaboration.

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My pathway through graduate school and continuing into the future has been shaped in large part by the opportunity to work with an inspiring group of students in a classroom in Brownsville, TX during my tenure as a Teach For America corps member. I am thankful that Martin has supported my involvement in a number of educational venues in addition to my work in the lab.

I cannot even begin to express my gratitude to my family to whom I owe a great deal, particularly my parents. They have been unfailingly supportive of me through every stage of my development. I am acutely aware of my good fortune to be born into such a caring and giving family. I do not have the literary capacity to fully express my appreciation to my family, and I am in great debt to them.

While this dissertation marks the end of my graduate studies, it also marks the beginning of my opportunity to put what I gained in graduate school to work. It is my hope that I can show my true appreciation to all those who have helped me along the way by being a good steward of the knowledge and skills they have helped me to obtain and to use it for the benefit of others.

To my students in Brownsville, TX

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Part I : Single molecule optical absorption by STM

Chapter 1: Introduction and Background

1.1 Methods for single-molecule optical detection

The vast majority of single-molecule experiments do not directly measure absorption, but rather infer absorption from a secondary process such as fluorescence. This is because single absorbers usually have an absorption cross-section which is very small relative to the experimental noise or the background absorption. A large number of these types of studies have been performed on single carbon nanotubes (CNTs) to gain information about their optical properties. With just a few exceptions, the vast majority of these experiments has not directly measured optical absorption, but has instead relied on a secondary process, namely fluorescence. While these experiments have provided much useful knowledge, they have provided only indirect information about absorption. Moreover, while some molecules fluoresce strongly, the techniques developed or used for these systems are not universally applicable since not all molecules fluoresce.

Direct measurements of absorption of single CNTs have not been ignored because they are not interesting, but because they have proved to be difficult experiments because the absorption cross-section for a single-molecule is very small and because background absorption is relatively large, leading to a major signal-to-noise problem. In 1989, the first single-molecule absorption experiment was done at cryogenic temperatures with strong molecular absorbers¹ and advances in the field have been relatively slow. Room temperature single-molecule experiments have recently become plausible and there have been a slowly growing number of techniques that examine systems on these scales.

Our lab reported the first example of room-temperature single-molecule optical absorption in 2006.² Single-molecule absorption detected by scanning tunneling microscopy (SMA-STM) introduced a technique that provided direct imaging of optical absorption of single molecules by monitoring laser-induced changes in local electronic structure with a scanning tunneling microscope. This study employed carbon nanotubes as the molecular absorbers and has served as the foundation for the work presented in the following chapters. Shortly after this initial room-temperature demonstration, our lab presented a frequency-modulation scheme that further cut-down on the background.³ In the few years since our lab first demonstrated room-temperature single-molecule optical absorption, a handful of other single-molecule techniques have emerged.

One method of room-temperature single-molecule absorption with low background relies on a photothermal contrast mechanism.⁴ In this scheme, a modulated heating beam hits a sample causing local thermal inhomogeneities where molecules are absorbing and leads to changes in the local refractive index. A probe beam is then rastered over the surface and dips in transmission are monitored which result from scattering at the locally heated regions. Another method has achieved single-molecule detection of absorption using ground-state depletion microscopy.⁵ Here, two lasers at different wavelengths both within a molecular absorption band are collinearly focused on a sample. One of the lasers is modulated and if an absorption event occurs, the ground state of the molecule becomes depleted, which leads to a modulation in transmission of the second laser. Finally, direct transmission measurements from a single laser have also reached the single-molecule detection level. In this method, absorption images of single molecules are taken by spatially dispersing the molecules in a sample and monitoring transmission losses while rastering the sample through a tightly focused laser beam.^{6,7} Laser intensity fluctuations, which can plague single molecule experiments, are accounted for by the use of a balanced photodetector with a reference beam.

There have also been a few other studies in the past few years that have utilized carbon nanotubes as their absorbers in single-molecule experiments. One technique required the growth of CNTs across a slit cut into a silicon wafer. A laser was shined down the length of the slit and the sample was oscillated such that the CNT translated into and out of the laser beam. The very small changes in transmission were monitored by lock-in-detection at the oscillation frequency.⁸ In another technique, a photothermal heterodyne imaging technique was used to excite CNTs with one laser and probe the induced local heating field with another.⁹ Recently, this photothermal technique has been extended to single dye-molecules as well, as discussed above.⁴

Despite having achieved room-temperature single-molecule detection, these methods still have some limitations. All of these methods are still essentially diffraction-limited. As a consequence, they require that molecules are still spatially distributed on their samples at a concentration low enough that guarantees mono-dispersion. Even still, verification that an absorption measurement is a single-molecule largely requires observation of phenomena such as blinking or one-step bleaching.

These articles which discuss single-molecule absorption point to each other, but not to our technique described in the following chapters. Our technique, SMA-STM, offers several unique or complementary advantages to other techniques. The primary advantage is the unparalleled spatial-resolution of optical absorption, which can be directly imaged below the nanometer level. The method relies on measuring absorption by monitoring changes in the local density of states and allows the simultaneous collection of

electronic and topographic information in addition to the optical signal. We can resolve optical absorption well below the diffraction limit on a sub-nanometer scale. This, along with a demonstration of our ability to differentiate absorption between two nanotubes that are directly adjacent to each other, are detailed in Chapter 3.

1.2 Background on Optical STM Methods

The coupling of optical techniques with STM is not a new idea, though its evolution into mature technologies has been more recent. Most of the research that couples STM with optical techniques have utilized the introduction of laser excitation at the tunneling junction between the STM tip and sample in order to examine a variety of phenomena. Much of the existing work is detailed at length in a review by Grafström.¹⁰ Some of the highlights of that review as well as some additional more recent work is briefly summarized here.

Under laser-illumination of the tunneling gap, a temperature difference can exist between the tip and the sample, which leads to a thermovoltage across the gap.¹¹ It is possible to leverage this to indirectly examine differences in the local density of states on a sample due to differences in heating and therefore the thermovoltage.¹² Images can also be taken of difference mixing of multiple laser fields in a tunneling junction.¹³

Surface states on semiconductors lead to a charge buildup. Optical excitation above the band gap of the semiconductor creates carriers which disrupt the equilibrium, causing a potential referred to as the surface photovoltage (SPV). The spatial variance of the SPV has been mapped in a number of studies on different substrates, the first of which was on Si(111)-(7x7).¹⁴ The variation in local work function on a surface can be monitored as well.¹⁵

Local photoelectron spectroscopy can be examined by collecting photoemitted electrons with an STM tip.¹⁶ Recent work has shown that the light-induced tunneling current can be dissected into components arising from excitation of carriers into the conduction band of materials as well as the SPV.¹⁷ Not only can electrons excited by photons be monitored, but others have collected photons emitted by tunneling electrons, which has recently been done on the submolecular level.¹⁸ Our technique, described in Chapter 2, is complementary to many of the techniques described above, but achieves optical absorption measurements with superior spatial resolution.

1.3 The optical properties of carbon nanotubes

While carbon nanotubes (CNTs) were likely identified earlier,¹⁹ interest in them has grown substantially over the past two decades since Iijima's well-recognized papers were published.^{20,21} Research on these

nano-materials has continued unabated because of their unique optical, electronic, mechanical, and thermal properties. The work described in the following chapters examines some of the electrical and optical properties, so they will be briefly reviewed here. There are a large number of different carbon nanotubes, though the discussion here will be limited to the sub-class identified as single-walled carbon nanotubes.

A CNT is an allotrope of carbon which is often described as a rolled up sheet of graphene, a monatomic layer of graphite. Because of the hexagonal arrangement of atoms in graphene, there are a number of geometric arrangements in which a seamless cylinder can be formed, each with varying diameters and angles—known as the chiral angle—and of indefinite length. The electronic and optical properties are directly related to the specific structure of the nanotube, specifically the diameter and the chiral angle.

The diameter and chiral angle for each possible CNT can be uniquely described by two indices n , and m , where the vector around the circumference of the nanotube along the chiral vector is given by²²

$$\vec{A} = n\vec{a}_1 + m\vec{a}_2 \quad (1)$$

where \mathbf{a}_1 and \mathbf{a}_2 are the basis vectors in the real-space graphene lattice. From these two indices, simple geometric relationships allow the diameter and chiral angle to be determined. Furthermore, the electronic structure—and therefore the optical properties—of the CNTs are directly related to this information.

When the (n,m) indices satisfy the requirement that ' $(n-m) / 3 = \text{integer}$ ' the CNTs behave as metals whereas those that do not satisfy this requirement are semiconducting. The implication here is that in a random distribution of CNTs, one third will be metallic while the remaining two thirds will be semiconducting. This effect arises because the discrete linear wavevectors for CNTs allowed along the axis of the nanotube on the first Brillouin zone overlap the K symmetry points of the 2D hexagonal Brillouin zone of graphene. This model, which further allows for the prediction of electronic properties, is known as the zone-folding method.²²

In general, there is an inverse relationship between the diameter of CNTs and their bandgap and therefore their optical transition energies. This has been shown both theoretically and experimentally.^{23,24} The electronic structure that was predicted predominantly by tight-binding calculations indicated that all CNTs had sharp spikes in their local density of states at particular energies related to their geometries. These asymmetric areas of high state density, known as Van Hove singularities (VHS) were long considered to be the source of electronic and optical transitions, an idea that was supported by some early high-resolution STM electronic measurements.²⁵ Semiconducting tubes were considered to have no state density between the highest occupied VHS in the valence band and the lowest unoccupied VHS in the

conduction band. Until recently, it was thought that optical transitions in semiconducting carbon nanotubes were band-to-band transitions between the VHSs, yet some convincing photoluminescence experiments proved that there must be optically accessible states within the conventional band gap predicted by these calculations.

The work that changed the interpretation of optical transitions were two-photon photoluminescence experiments wherein CNTs were excited by a two-photon absorption process, after which photon emission occurred at a substantially lower energy.²⁶ The interpretation was that excitonic states existed within the band gap of the CNTs. These excitons—Coulomb-bound electron-hole pairs—had binding energies that made up a substantial fraction of the bandgap and were responsible for observed optical resonances. 1-dimensional materials have excitons with even symmetry (*s* symmetry) with respect to reflection along the nanotube axis, and odd symmetry (*p* symmetry). Owing to symmetry-based selection rules, the *s*-states are one-photon allowed and the *p*-states are two-photon allowed. In a single-particle model that does not account for excitons, both one and two-photon processes are allowed in the optical transition to the continuum. In the picture presented by these experiments, two-photon absorption excited electrons only to the higher-lying *p*-states or the band edge, after which the electrons relaxed to the lowest-lying *s*-state where emission occurred.

While the realization that excitons, rather than band-to-band Van Hove transitions, were responsible for optical processes in CNTs did not invalidate the body of work that led to the development of many trends relevant to the photophysics of CNTs, it did open up new avenues for interpretation and exploration. Subsequent calculations, utilizing the Bethe-Salpeter equation²⁷ to account for the bound states, showed that the exciton states had a finite confinement area and an expected symmetric absorption lineshape.²⁸

The nature of optical transitions in CNTs arising from excitons had a number of implications guiding the work presented here. Considering the difference in the predicted lineshape for exciton absorption and the asymmetry present in VHS's, single-molecule absorption offers an opportunity to examine this discrepancy. Because excitons have a confined local wave function, high-resolution experiments allow for direct visualization of these states when pinned at defects. Because this work is all done under high-electric fields, the presence of excitons introduces additional variables which must be considered including field-induced binding-energy shifts and potential exciton dissociation. Not only would it be difficult to ferret out some of this information from bulk experiments—particularly since the preparation or purification of specific CNT chiralities has proved extremely difficult despite vast efforts—but much of this requires experiments sensitive to a level below that of single structures.

The ability to resolve optical transitions on a scale smaller than a single CNT is also relevant because carbon nanotubes are prone to structural defects. These defects can lead to the opening or closing of the band gap locally, or result in a change in the density of states.^{29,30}

Chapter 2: Optically-Assisted STM Instrumentation and Experimental Design

The combination of STM with optical excitation provides an opportunity to leverage both the high spatial resolution inherent to STM with the spectral resolution of laser spectroscopy. Moreover, the STM provides highly localized electronic measurements. This combination of tools yields a surface sensitive technique that offers direct real-space imaging of absorption events with simultaneous temporal resolution of correlated spatial, electronic, and optical properties on a sub-nanometer scale. Because of the high resolution of this setup, we denote this optically-assisted STM technique Single-Molecule-Absorption detected by Scanning Tunneling Microscopy (SMA-STM).

Optically-assisted STM experiments combine a conventional STM with laser sources. Only minor physical modifications of an STM are required to allow the implementation of this technique. One or more lasers are then coupled with the STM, which excite resonant features on the surface and the resulting modification of the density of states is monitored via lock-in detection.

2.1 Basic STM Theory

In an STM, a sharp metallic tip is brought to within ~ 1 nm of a conductive or semiconducting substrate and a bias is applied to the sample. Electrons tunnel quantum mechanically across the vacuum barrier at a rate proportional to the local density of states and which depends exponentially on the size of the tunneling gap. The tunneling current for a one-dimensional system at low voltage is given as

$$I_t \propto e^{-2\kappa d} \quad (2)$$

where I_t is the tunneling current, d is the distance between the tip and the sample, and κ is given by

$$\kappa = \frac{\sqrt{2m_e\phi}}{\hbar} \quad (3)$$

where m_e is the electron mass and ϕ is the local effective work function, which is the average work function for the tip and sample. This simple relationship was what allowed for the first experimental STM imaging and was used in its interpretation.³¹ The practical application of Equation (2) for typical values of ϕ is that a vertical change of tip position by 1 Å yields a change of an order of magnitude in the tunneling current.³²

Tersoff and Hamann established a theory based on the transfer Hamiltonian approach of Bardeen³³, wherein they determined the tunneling conductance for an STM system in 3-dimensions. Considering that real STM tips are not infinitely sharp, this formalism has important relevance to modern STM applications. They showed that the tunneling current is also linearly proportional to the local density of states of the sample.³⁴ This proportionality can be exploited to gather information about the local

electronic structure of surfaces and molecules, which will be described more in depth in the section on Scanning Tunneling Spectroscopy.

We operate our STM at a constant tunneling current. The STM tip, rastered over the sample by four quadrants of a piezoelectric cylinder, adjusts the tunneling distance when changes in the tunneling current are induced by topographic or electronic variations in the sample. The sensitive z-adjustment from this feedback loop is used to build the topographic image.

Scanning Tunneling Spectroscopy

Because the tunneling current in an STM is proportional to the local density of states, the STM can be used to collect surface-sensitive local electronic information. The primary technique used for this is known as Scanning Tunneling Spectroscopy (STS). In STS, the tip is positioned over a chosen spot on the sample and the current feedback loop is then turned off. The voltage is then swept across a range while the current is collected, which generates a current vs. voltage (I-V) curve.

The most fundamental piece of information that can be gained from the I-V curve is the band gap. For a semiconductor at low sample bias, there may be no states from which or to which electrons can tunnel. At these energies, the tunneling current will fall to zero and the width of that region in the I-V curve corresponds to the band gap. Because this can be difficult to observe by eye, a plot of the logarithm of the current makes the band edges readily identifiable and easy to measure.

Inaccuracies in the band gap measurement provided by STS can present themselves. The band gap can often be overestimated by the procedure described above because at low bias the tunneling current will drop off to a value below the sensitivity of the instrument despite the fact that states exist at that energy. This can be corrected for by implementing a variable spacing method, wherein the tip steadily approaches the surface as the bias approaches zero and retracts again as the bias increases with the opposite magnitude. In this way, the tunneling current does not reach a negligible value until there are truly no states into which to tunnel.

Less systematic, the band gap can often be inaccurate due to irregularities with the tip, most notably due to an insulating oxide on the tip apex.^{35,36} When working on the Si(100) surface, we have a known band gap of 1.1 eV, which acts as a standard to determine when the STS is producing accurate results for the band gap. Moreover, we are often more interested in the relative difference in band gaps within a single image, as we can compare this to the differential absorption that we observe.

STS has been used to probe the electronic properties of carbon nanotubes in a variety of studies. Of note, recent STS measurements of CNT bundles were interpreted as showing the excitonic gap rather than the

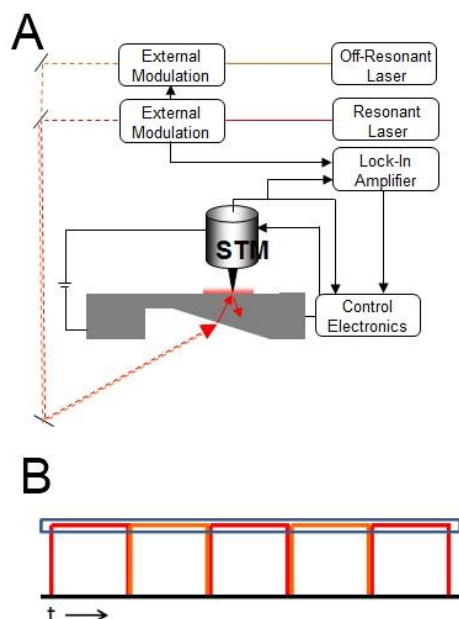


Figure 1. Schematic of optical STM setup. (A) A laser resonant with a molecular transition is modulated and directed into the rear of a silicon sample through a machine wedged in the back of the sample (alternatively, prisms can be attached to the rear of the sample). The light undergoes a total internal reflection at the sample face and the evanescent wave excites molecules on the surface of the sample. The modulation frequency and phase are fed to a lock-in amplifier, which is compared to fluctuations in the tunneling current. The output of the phase-sensitive detection of the lock-in-amplifier are sent to the STM control electronics to spatially correlate the lock-in absorption signal with the topographic image. In the frequency-modulation scheme, a second, non-resonant laser is collinearly added to the resonant laser 180° out of phase. (B) shows that the total power incident on the sample is held largely constant as the two lasers are modulated, though the molecular species will only respond to the laser with which they are resonant.

non-interacting band gap.³⁷ Previous measurements with chiral resolution of single CNTs had shown van Hove singularities as expected for the non-interacting band gap.²⁵ It is still not completely clear whether STS should measure the same excitonic gap as optical transitions or whether it will measure the non-interacting gap, though experiments with our method should provide the tool to elucidate this seeming contradiction of results.

2.2 Optical STM Setup

We use a home-built ultra-high vacuum (UHV) STM similar to previously described systems³⁸ that operates at pressures below 10^{-10} torr. For the STM probes, we use electrochemically etched tungsten tips. All samples and tips are loaded into the UHV system through a small load lock, which can be pumped to 10^{-8} torr before samples are transferred to the UHV preparation chamber with a magnetically coupled linear translation device. Everything introduced to the system is degassed in the preparation chamber by resistive heating, either by passing current directly through it or by heating a nearby tungsten filament that is in thermal contact through a copper block. The preparation chamber is also where silicon samples are hydrogen-passivated.

The primary impediment to coupling laser excitation with an STM is the introduction of thermal perturbations at the tunneling junction. Introduction of a laser directly at the tip-sample junction leads to significant photocurrents and thermal expansion of the tip, which substantially reduces the imaging quality of the STM. This heating problem can be somewhat mitigated by using light in the ultraviolet region³⁹, but cannot be easily overcome with front illumination at many wavelengths of interest, particularly in the infrared. We circumvent the majority of the heating problem by introducing our laser light from behind the sample. The light undergoes a total internal reflection at the sample face and an evanescent wave excites molecules on the surface. The evanescent wave decays exponentially into the vacuum over a distance of $\sim \lambda/2$, which is more than sufficient for covering the region containing

molecules on the surface. One major disadvantage of this approach is that the substrate must be transparent to the wavelength of illumination, though there are opportunities to expand this application to a variety of wavelengths (see Chapter 4).

Silicon was the substrate used for the majority of the experiments shown here. We machined a 15° wedge in the back of a boron-doped p-type Si(100) wafer by successive staircase cutting with a diamond dicing saw. Subsequently, the wedge was polished with a Dremel and fine-grit alumina paste to create an optical entryway for laser light that would then undergo total internal reflection at the front-face of the sample. This wafer was then diced into appropriately sized-pieces for use in our sample holders. The clamps in the sample holders have large slits cut in them to allow optical access to the wedge in the rear of the sample. In the lab frame, the z (tip)-axis is horizontal, which allows the use of a normal optical table with all laser beams operating at the same height. The angle at which the light strikes the silicon wedge is near the Brewster angle, so p-polarized (parallel to the plane of incidence) light is preferentially transmitted. The Fresnel equations written in terms of transmission for incident angles are

$$T_p = 1 - \left[\frac{n_1 \sqrt{1 - \left(\frac{n_1}{n_2} \sin \theta_i\right)^2} - n_2 \cos \theta_i}{n_1 \sqrt{1 - \left(\frac{n_1}{n_2} \sin \theta_i\right)^2} + n_2 \cos \theta_i} \right]^2 \quad (4)$$

$$T_s = 1 - \left[\frac{n_1 \cos \theta_i - n_2 \sqrt{1 - \left(\frac{n_1}{n_2} \sin \theta_i\right)^2}}{n_1 \cos \theta_i + n_2 \sqrt{1 - \left(\frac{n_1}{n_2} \sin \theta_i\right)^2}} \right]^2 \quad (5)$$

where T_p and T_s are the transmitted p and s light, n_i and n_2 are the indices of refraction for the initial and final media, and θ_i is the incident angle of the light⁴⁰. These relationships indicate that 91% of p-polarized light and 44% of s-polarized light are transmitted into the silicon sample with our experimental geometry. Figure 1 illustrates the geometry of the introduction of laser light through the rear of the sample.

A tunable diode laser is used to excite molecules on the surface. It is overlapped with a helium neon (HeNe) laser that provides visible guidance during the rough alignment process. Optionally, a second diode laser of fixed wavelength can be used to further minimize differential heating (see 2.3 Signal Detection).

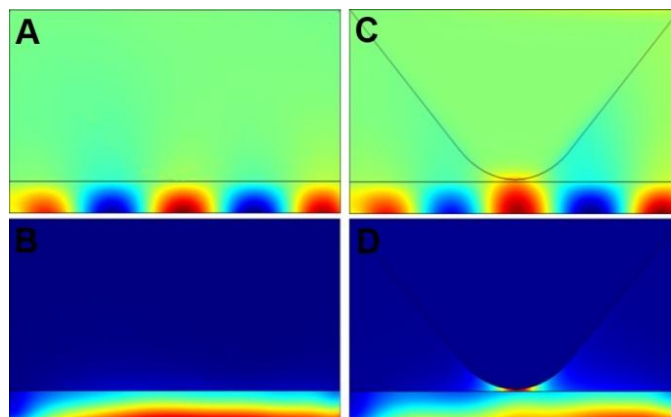


Figure 2. Calculations of field enhancement for a silicon surface with infrared light undergoing total internal reflection. The upper panels (A and C) show the field distribution and the lower panels show the energy density distribution (B and D). The left side (A and B) is without the presence of a metal tip and the right side (C and D) is with a metal tip a few nm from the surface. The local field enhancement in the tunneling junction is clearly visible.

Field Enhancement

A major advantage of the geometry of optically-assisted STM is that the tip acts to substantially enhance the laser's electric field, allowing the use of modest laser powers.

Dr. Dong Xiao from the group of Professor Harley Johnson performed finite element calculations with the COMSOL software package using parameters very similar to our experimental design. Infrared light underwent total internal reflection in a medium with a dielectric constant of 12 to simulate a value close to that of silicon⁴¹ both without and with a metal tip a few nm from the surface. Figure 2 illustrates the results of the simulation. The leftmost panels show that the majority of the electric field and the energy density do not penetrate beyond the surface. In the presence of a sharp metal tip, however, the evanescent field is substantially enhanced within the tunneling region of the tip-sample gap. Other, more rigorous calculations have shown that this field enhancement is on the order of 500-1000.⁴²

The strength of the field enhancement depends strongly on the shape of the tip as well as the distance of the tip from the surface. The distance-dependence of the field enhancement was directly visualized by a group who used an STM in a front-illumination geometry to enhance the field of a UV laser to depassivate hydrogen from a Si(100) surface.⁴³ The size of their depassivated spot correlated with the enhanced field and was strongly dependent on the tip-sample distance and also on the radius of curvature, with sharper tips producing better results. Our electrochemical etching procedure produces a large variety of tip shapes and sizes that may account in part for variations in the ability of the technique to detect absorption.

2.3 Signal Detection

In conventional absorption spectroscopy, absorption is determined from a loss in transmission through a sample. In SMA-STM, changes in the local electronic structure, and therefore the tunneling current, are used to identify and spatially resolve absorption events. We modulate our lasers and monitor fluctuations in the tunneling current at the modulation frequency with a lock-in amplifier while scanning to generate an absorption image. We operate the lasers in either an amplitude modulation or frequency modulation scheme. Full details of the laser alignment are given in Appendix A.

In the amplitude modulation scheme, the resonant laser is modulated between zero power and some chosen power as a square wave. When using the tunable diode laser, we mechanically chop the laser because the external cavity diode laser has a nonlinear response to an input signal, making the use of electro-optic modulation cumbersome. In frequency-modulation, we introduce a second collinear laser that is close in energy to the first, but non-resonant with the molecular transition. It is 180° out of phase with the resonant laser and acts to keep the heating constant, but should play no role—or at least a lesser role—in the modulation of the electronic density of states of the molecule on the surface. Figure 1B shows how the total incident power is maintained at a constant level in this scheme.

The topographic image is given by the average tunneling current and the absorption image is given by the lock-in detected modulation of the tunneling current that occurs faster than the STM feedback low-pass cutoff. Regardless of whether an amplitude modulation or frequency modulation scheme is used, only the laser resonant with the molecular transition should result in appreciable fluctuations in the tunneling current at the modulation frequency. While some thermal fluctuations will result, the difference between molecule and substrate in the lock-in image will be small. When the molecule is absorbing, however, there will be relatively large current fluctuations when the tip is positioned over the molecule compared to when the tip is over the substrate.

Chapter 3: Sub-nanometer Resolution of Optical Absorption in Individual CNTs

Portions of this chapter were previously published in:

Scott, G.; Ashtekar, S.; Lyding, J.; Gruebele, M. Direct Imaging of Room Temperature Optical Absorption with Subnanometer Spatial Resolution. *Nano Letters*. 2010:10, 4897-4900. <http://dx.doi.org/10.1021/nl102854s>

3.1 Introduction

We demonstrate here the ability to resolve optical absorption at the sub-nanometer level. To exploit the high spatial resolution of the SMA-STM technique, we imaged two kinds of carbon nanotube (CNT) systems. The first involves two CNTs in contact with one another, verifying that we can spectroscopically distinguish adjacent nanotubes based on their electronic structure. To test the limits of our ability to localize an optical signal, we then looked for carbon nanotubes containing a structural defect clearly imaged by conventional STM. Defects in carbon nanotubes can significantly alter the local electronic structure²⁹. We correlated the optical response with electrical (I-V) measurements, and showed how direct visualization of excitonic absorption by the CNT can be used to measure penetration of the exciton into the defect.

3.2 Results and Discussion

The experimental setup has been described in Chapter 2 and in refs ^{2,3}. The specifics for the sub-nm resolution experiment are summarized here (additional details are given in 3.3). Experiments were performed with a home-built ultrahigh-vacuum (UHV) STM similar to ones previously reported⁴⁴, using electrochemically etched tungsten tips. P-type (boron-doped) Si(100) samples with a 15° polished wedge in the back side were hydrogen-passivated *in situ* to produce a 2x1 reconstructed surface. HiPCO produced carbon nanotubes were applied to the samples *in situ* using the dry contact transfer technique with a fiberglass applicator.⁴⁵ STM images were collected at a tunneling current of 50 pA and a sample bias of -2 V.

To detect the λ_{11} absorption transition of a CNT, amplitude-modulated or frequency-modulated near-infrared laser light was introduced through the wedge in the rear of the silicon wafer. Rear illumination and wavelength modulation (by 50 nm) of the laser maximally suppressed thermal modulation of the STM tip-sample junction.³ The light undergoes a total internal reflection (TIR) at the sample surface and creates an evanescent wave that excites any resonant CNTs stamped onto the surface. A few mW of laser power was sufficient to saturate the molecular transition because the sharp tip locally enhances the electric field of the laser by a factor of 500-1000.⁴² The bulk of the tip is not illuminated by the TIR geometry. The average tunneling current produces a conventional STM image. Simultaneously, a lock-in

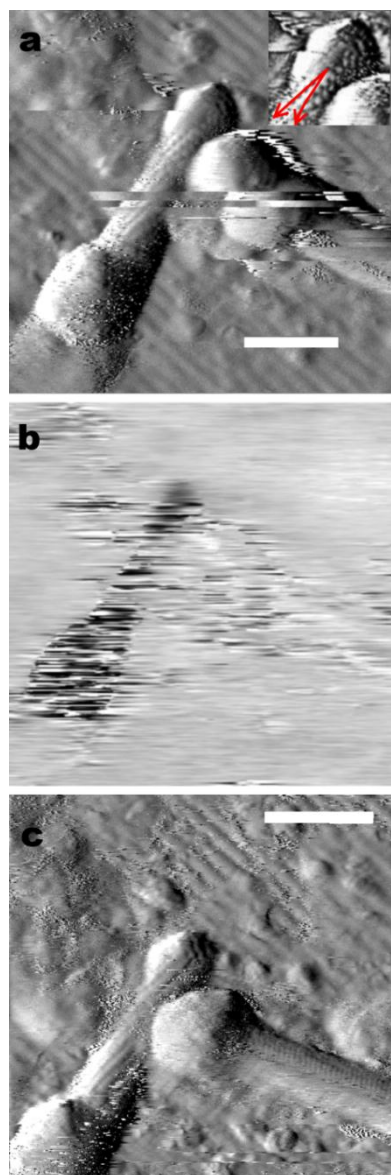


Figure 3. Differentiation of molecules separated by a few nm by optical absorption. (a) Topographic derivative image of two carbon nanotubes in close proximity. Inset: enhanced image showing the carbon lattice of the nanotube on the left. The red vectors show the chiral angle of 13° . Scale bar is 5 nm. (b) Simultaneously collected lock-in absorption image under 1200 nm laser excitation showing absorption by the left nanotube and no absorption by the right nanotube. (c) Subsequent topographic image showing the two carbon nanotubes in contact after the right tube was lifted by the tip.

amplifier (time constant 10 ms) demodulates the tunneling current at the modulation frequency of the laser (1.2 kHz), thus detecting changes in the local electronic structure due to resonant laser excitation. STM and absorption images with sub-nm resolution are thus obtained concurrently. The lateral resolution was measured to be 0.40 ± 0.05 nm (see Figure 7).

Figure 3 illustrates differentiation of two directly adjacent nanotubes by room temperature optical absorption. The laser energy (1.03 eV) is in the range of the λ_{11} lowest energy absorption band of 1 nm diameter carbon nanotubes. The entire image shown is approximately 500 times smaller than the focused size of the diffraction-limited near-IR spot. Figure 3a shows a derivative of the conventional STM topographic image of two semiconducting carbon nanotubes nearly in contact on a hydrogen-passivated Si(100)-2x1 reconstructed surface. Figure 3b shows the SMA-STM absorption image, collected at the same time. Only the carbon nanotube on the left absorbs at 1200 nm. The horizontal streaks in the middle of the topographic image are a result of the CNT on the right moving ~ 1 nm towards the left CNT in the middle of the scan. Thus the right nanotube is strongly interacting with the tip, but not with the laser. Figure 3c shows the two CNTs after the right tube has moved.

Based on its chirality, its diameter, and the absorption wavelength of 1200 nm, the carbon nanotube on the left can be identified as one of two types. The spatial derivative of the STM topography image in the inset of panel 1a reveals a chiral angle of $13 \pm 1^\circ$. The measured topographic height was 0.9 ± 0.1 nm. Based on data from an empirical Kataura plot,²⁴ we can assign the absorbing CNT to either a (10,3) tube (12.73° chiral angle, 0.936 nm, $\lambda_{11}=1249$ nm) or less likely a (11,3) tube (11.74° chiral angle, 1.01 nm, 1197 nm). All other identities can be confidently excluded.

Although optical discrimination without photoswitching between

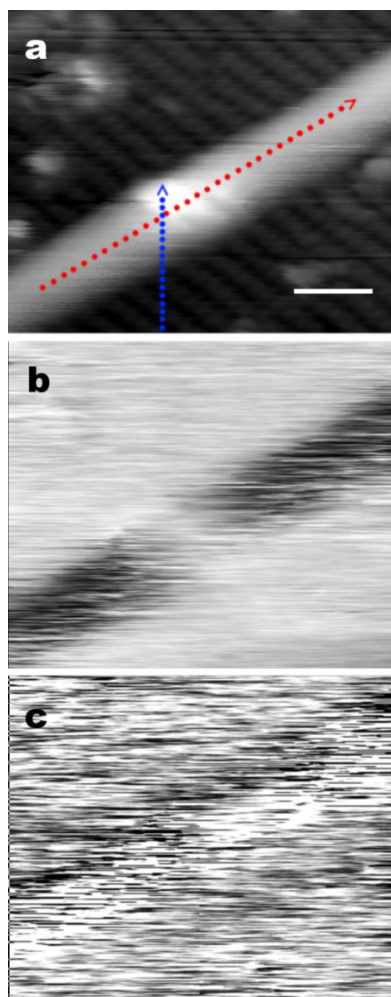


Figure 4. Sub-nm absorption image of a defected single-walled carbon nanotube. (a) Topographic image of a carbon nanotube showing a defect along its axis. The blue and red circles correspond to points at which scanning tunneling spectroscopy was performed (see Figure 5). Scale bar is 2 nm. (b) Absorption image taken under 1200/1300 nm excitation by frequency-modulated laser excitation. The defect from (a) shows up as a decrease of the absorption signal over a 2 nm length of the CNT. In (c), the lock-in amplifier phase was rotated 90 degrees from that in (b). No significant absorption relative to the silicon background is observed even though the vertical scale of the image is expanded to highlight the noise floor. The phase of (b) and (c) was adjusted by 180° to yield a similar gray-scale as in Figure 3b for comparison.

similar molecules separated by a few nm is a novel capability, Figure 4 illustrates that we can identify variations in absorption even within a single nanotube, and correlate these variations with electrical and excitonic properties. The topograph in Figure 4a and the lock-in absorption image excited at 1200 nm in Figure 4b were collected simultaneously. The topograph shows individual dimers on the Si(100)-2x1 hydrogen passivated surface, as well as some dangling bonds near the CNT. Near the central part of the CNT, a structural defect causes the apparent height of the nanotube to increase. The absorption image shows no differential absorption signal relative to the substrate at the defect location, while the rest of the CNT strongly absorbs at 1200 nm. Thus the local bandgap of the CNT has shifted below the 1.03 eV laser energy at the defect site. Figure 4c shows the lock-in amplifier signal 90° out of phase with the laser modulation. Aside from a small amount of noise induced as the tip undergoes feedback to move over the edge of the CNT⁴⁶, there is no net signal observed relative to the substrate. This observation verifies that the detected absorption image is phase-sensitive relative to the laser modulation, and that thermal effects are minimal: thermal modulation would show up with a phase lag (residual signal at 90°), while the absorption signal is modulated essentially instantaneously on the ms time scale of the modulation ($\tau_{\text{relax}} \ll 1$ ms for CNTs⁴⁷).

We can directly compare the optical absorption with the electrically measured bandgap. Scanning tunneling spectroscopy (STS) was used to measure I-V curves from -2 to +2 V at each red and blue point in Figure 4a between two of the laser absorption scans. Figure 5 shows the resulting bandgaps as a function of distance along the trace. Moving from substrate to CNT along the blue trace, the bandgap narrows suddenly, defining our lateral resolution of ± 0.1 nm. The red trace shows the bandgap narrowing more gradually along the tube. The defect bandgap shrinks by about 40% compared to rest of the molecule, pushing the optical

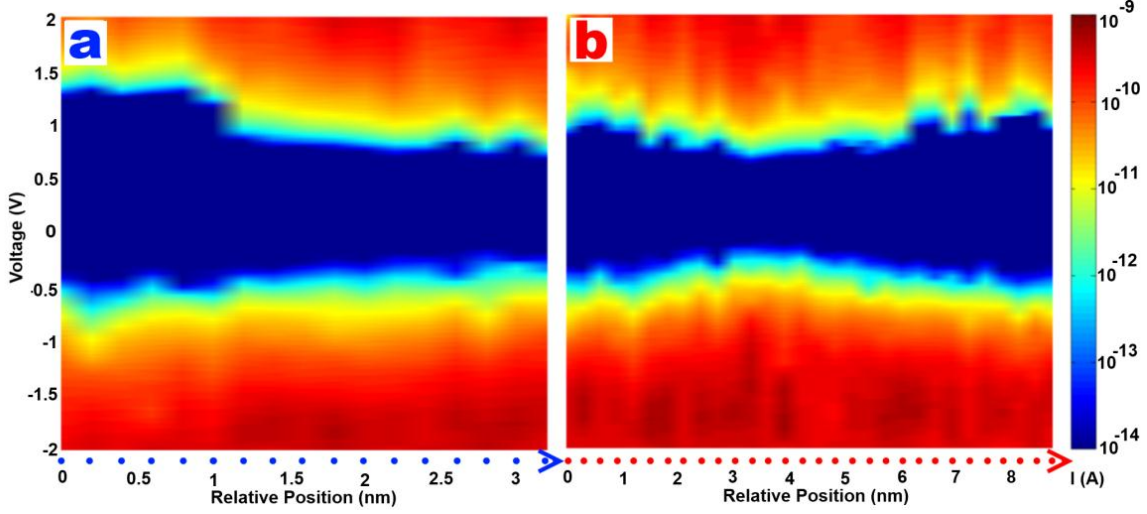


Figure 5. Scanning tunneling spectroscopy traces. Spatially-resolved maps of current-voltage scans that correspond to the blue (a) and red (b) dots in Figure 4. The band gap (dark blue) narrows from silicon substrate to nanotube (a), and at the defect site on the nanotube (b).

transition out of resonance with the 1200 nm excitation laser. The bandgaps measured by STS are overestimated here, likely due to an insulating oxide on the apex of the STM tip. Using the silicon bandgap as a reference and rescaling it to 1.1 eV, the CNT bandgap away from the defect scales to ~ 1.0 eV, commensurate with the excitation laser energy. Unlike an I-V curve, the optical absorption signal can be collected simultaneously with a conventional STM scan to spatially resolve such defects and characterize their bandgap in high throughput.

We used the result in Figure 4 to visualize directly exciton penetration into the defect. Optical absorption in the λ_{11} band yields a bright excitonic state with a probability envelope $\exp[-x^2/\sigma^2]$,^{26,48,49} with σ proportional to the diameter of the CNT. The 1200 nm laser generates excitons at all points along the CNT except in the non-resonant defect. Excitons generated adjacent to the defect delocalize into the smaller bandgap region. Figure 6 shows a fit of the normalized absorption signal along the tube axis to

$$A(x) = e^{-\frac{x^2}{\sigma'^2}} \quad (x < 0) \\ = 1 \quad (x \geq 0) \quad (6)$$

where x is the distance along the carbon nanotube axis illustrated by the red line in the inset of Figure 6. We measure $\sigma' = 0.9 \pm 0.3$ nm (accounting for the lateral resolution), which defines the penetration depth of the exciton into the defect region. The off-resonant bandgap in the defect reduces the penetration depth of the edge exciton compared to the width of a free exciton (assuming the defect does not substantially alter the dielectric constant). By solving the non-linear Schrödinger equation for a room temperature exciton propagating into the low-bandgap region of the defect, we find $\sigma/\sigma' = 2.0$ for the exciton size-to-

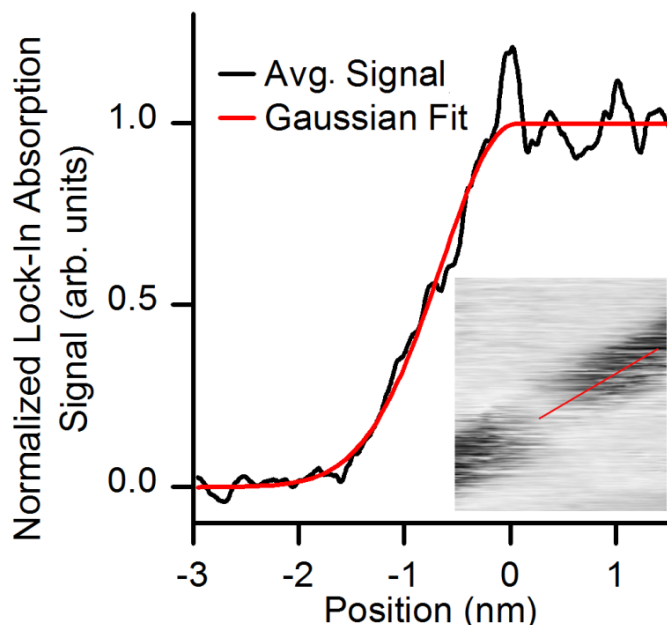


Figure 6. Exciton penetration into the defect. The normalized (0 to 1) lock-in absorption signal is shown in black, progressing from the defect region on the left to the absorbing region on the right. The Gaussian decay fit of the exciton penetration is shown as a red solid line, yielding $\sigma=1.0\pm0.3$ nm in eq. (1). The range of the x-axis is illustrated as a red 4.5 nm scale bar in the inset, which reproduces a detail from Figure 4b.

The onset of absorption can be imaged within a single nanotube, quantifying exciton spatial penetration into a CNT defect and allowing exciton size to be evaluated.

3.3 Experimental Conditions

For the data presented in Figure 3, one laser was used and amplitude-modulated at a laser power between 0 and 3.9 W/cm^2 . The modulation and lock-in frequency was set to 1.2 kHz with the laser operating at 1200 nm. The lock-in amplifier time constant was 10 ms and the STM tip velocity was 20.1 nm/s. This time constant/scan rate combination minimized any ‘smear’ of the absorption image. Our resolution analysis (see Figure 7) shows that the optical resolution is similar to the current image resolution, limited by the tip.

For the data presented in Figure 4 and Figure 5, two lasers were used to allow frequency-modulation of the incident laser light over a wide frequency range. The resonant laser was operated at 1200-1240 nm and modulated from 0 to 1.5 W/cm^2 at 1.9 kHz. The off-resonant laser was operated at 1300 nm and modulated exactly 180° out of phase from 0 to 10.7 W/cm^2 . The lock-in amplifier time constant was 3 ms and the tip velocity was 14.8 nm/s. The resonant laser was unpolarized, with residual polarization at the

penetration ratio and therefore $\sigma = 1.8\pm0.6$ nm for the exciton size. For a 1 nm diameter CNT, theoretical predictions put the size of an exciton close to $\sigma = 1.5 \text{ nm}$ ⁴⁹⁻⁵¹. Our result agrees within uncertainty with this prediction. Previous experimental work, which extracted the exciton size from a reduction in oscillator strength using pump-probe spectroscopy, found a value of 2 nm for the size of excitons in a (6,5) nanotube, considerably larger than the theoretical prediction of 1.1 nm⁵².

In summary, optical absorption can now be imaged at room temperature with sub-nm resolution. It can distinguish similar molecules in direct contact. The signal depends on laser excitation, not on which molecule more strongly couples with the tip.

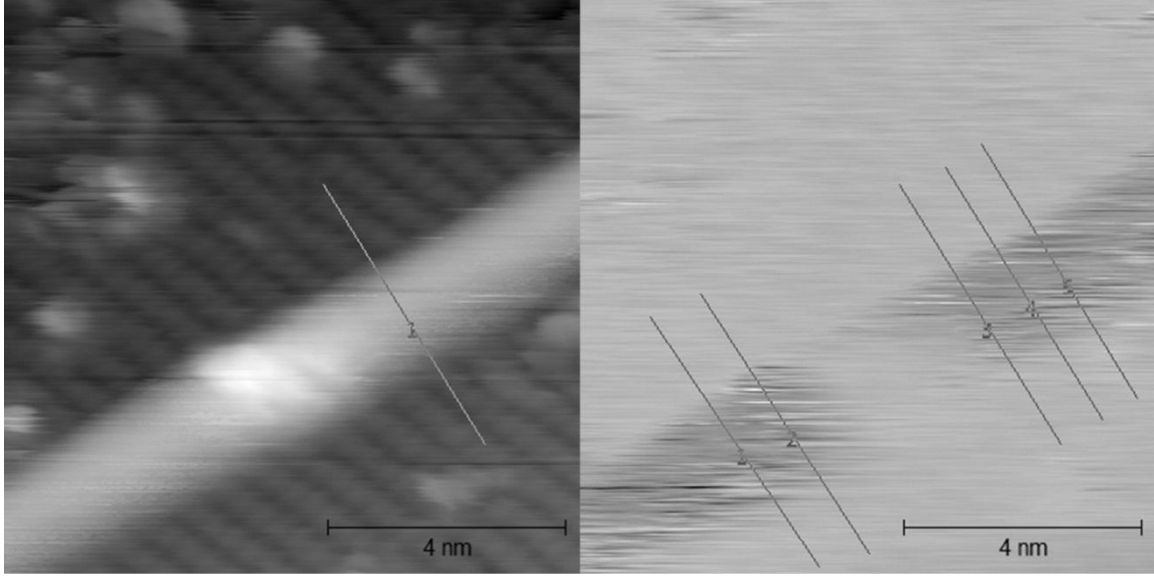


Figure 7. Minimum resolution was estimated by measuring profiles of the topographic and absorption image perpendicular to the carbon nanotube axis away from the defect. The estimated σ value (using the same units as for exciton width) is 0.40 ± 0.05 nm, less than 1 nm. This broadens a 1 nm measured width by $< 10\%$.

sample due to the internal reflection process. The off-resonant laser was polarized in the s-plane with respect to the wedge. The maximum powers of 1.5 and 10.7 W/cm² (different to account for polarization-dependent reflection of both lasers) were chosen to eliminate modulated substrate or tip heating by the two lasers.

The band gap trace was generated by measuring $\log(\text{abs}(I))$ versus V traces obtained at each position (red or blue points in Figure 4a). At each of these positions, 50 I-V traces were averaged with an initial current of 0.3 nA and a variable spacing with the tip approaching the surface by 2 Å as $V \rightarrow 0$ with the STM feedback disabled. When the current flow becomes negligible (below $\sim 10^{-14}$ A), the voltage lies within the band gap and is shown in Figure 5 as dark blue. Relative band gaps were measured at initial set-point currents of 0.3 nA, but absolute gaps in the $I \rightarrow 0$ limit may be slightly lower.

3.4 Exciton Analysis

To measure exciton penetration, six cross-sections averaging 5 pixels wide were taken along the axis of the nanotube for both the forward and reverse scan directions on both sides of the defect, resulting in 24 traces showing signal decays into the defect region. A Gaussian decay (6) was fitted to each of the 24 traces and we discarded 7 low-signal traces whose noise caused the standard deviation of the fit to increase. The trace shown in Figure 6 is an average of the remaining 17 traces weighted by their fitting error and offset horizontally to center the Gaussian peak at zero. The reported uncertainty is one standard deviation of the mean of the 17 fitted values of σ . A Gaussian envelope is strictly only valid for a free

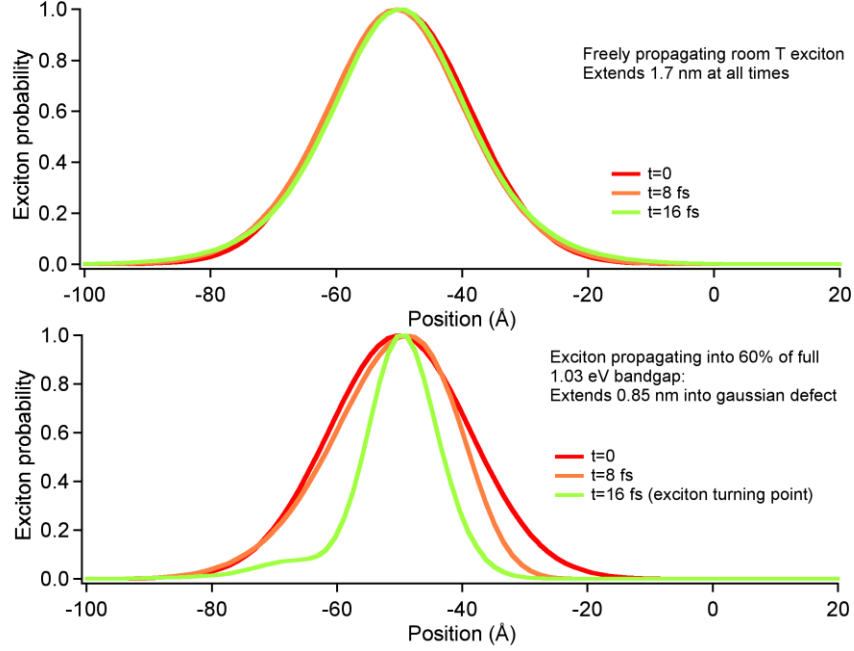


Figure 8. Model exciton propagation with the nonlinear Schrödinger equation. Top: freely propagating exciton at energy $k_B T$ ($T=298$ K) retains constant width (center of wavepacket probability shifted for comparison). Bottom: exciton propagating into a bandgap reduced by 60% has a width reduced by one half (0.85 nm) compared to unperturbed exciton (1.7 nm).

exciton with a quadratic energy-momentum dependence, but a sigmoidal (exponential penetration) fit gave a very similar length scale.

The reduced band gap of the defect provides an effective barrier into which the exciton tunnels, reducing its size and distorting the shape from a Gaussian. To model the exciton, we solved the nonlinear Schrödinger equation describing the propagation of a soliton wave with $\sigma \approx 1.7$ nm into the effective barrier. Propagation along the CNT axis was modeled in one dimension, and the kinetic energy of the soliton was set to the thermal energy ($k_B T$ at 298 K). Figure 8 shows the solution for the free soliton, and the narrowing of the soliton as it penetrates into the band gap. In accordance with Figure 5, the band gap energy along the tube was modeled as a function of position as a 2 nm wide Gaussian dropping by 40% from the value outside the defect. The maximum tunneling depth calculated for the soliton was $\sigma' = 0.85$ nm, yielding the $\sigma/\sigma' = 2$ ratio. Deconvolution of the tip response yields $\sigma' = 0.9$ nm for a measured width of 1 nm (Figure 7), and applying the computed 2:1 ratio, we obtain $\sigma = 1.8$ nm for the width of the unperturbed exciton.

Chapter 4: Broadband Substrates for SMA-STM

The use of silicon as a substrate for SMA-STM is ideal for many cases. Pristine surfaces can be prepared *in situ*, the substrate provides a reliable reference for STS measurements, it is a well-studied system with CNTs, and it is easy to machine a wedge for our rear-illumination scheme. The primary problem with silicon is that its 1.1 eV band gap prevent us from using our rear-illumination geometry with light above that energy. Our experiments are restricted to the infrared, which leaves out the important and interesting spectroscopic regions of the ultraviolet, visible, and very near infrared.

Alternative substrates that provide a broadband platform for SMA-STM must meet several requirements. They must offer optical transparency across a broad wavelength range, be conductive for use in an STM, and must have excellent flatness so that molecules can be readily resolved. We have pursued two primary classes of potential substrates that meet these requirements: ultrathin metal films and graphene on transparent substrates.

4.1 Metals Films on Sapphire

Metal films have long been used as STM substrates because they can be prepared atomically flat and are highly conductive. These single-crystal films that have superior smoothness are typically at least hundreds of nanometers thick,^{53,54} rendering them opaque and therefore useless for rear-illumination optical STM. At thicknesses under ~20 nm, ultrathin metal films still allow substantial light transmission across a broad wavelength range. The difficulty in preparing ultrathin films is in acquiring optimal flatness.

Prior work in our lab established the best parameters for room-temperature growth of ultrathin metal films on sapphire.⁵³ While these films met requirements of flatness, conductivity, and optical transparency for SMA-STM, their flatness was not ideal for most experiments. Our previous work had indicated that the induced temperature profile during deposition was a controlling variable in the film flatness, yet active control of the substrate temperature had not been undertaken. Björn Braunschweig suggested that for ultrathin platinum films, active heating of the substrate could substantially improve the flatness. As a result, we pursued elevated temperature growth of ultrathin platinum and gold films to achieve the optimal balance of flatness, transparency, and conductivity. This work required customizing a UHV heater for installation in an electron-beam evaporator.

Heater Design

The electron-beam evaporation (e-beam) system that we used for thin-film growth was not equipped for thermal control of substrates. It did, however, have a set of electrical feedthroughs that allowed for the easy introduction of a substrate heater. The e-beam was a CHA-SEC 600 in the clean room at the Micro

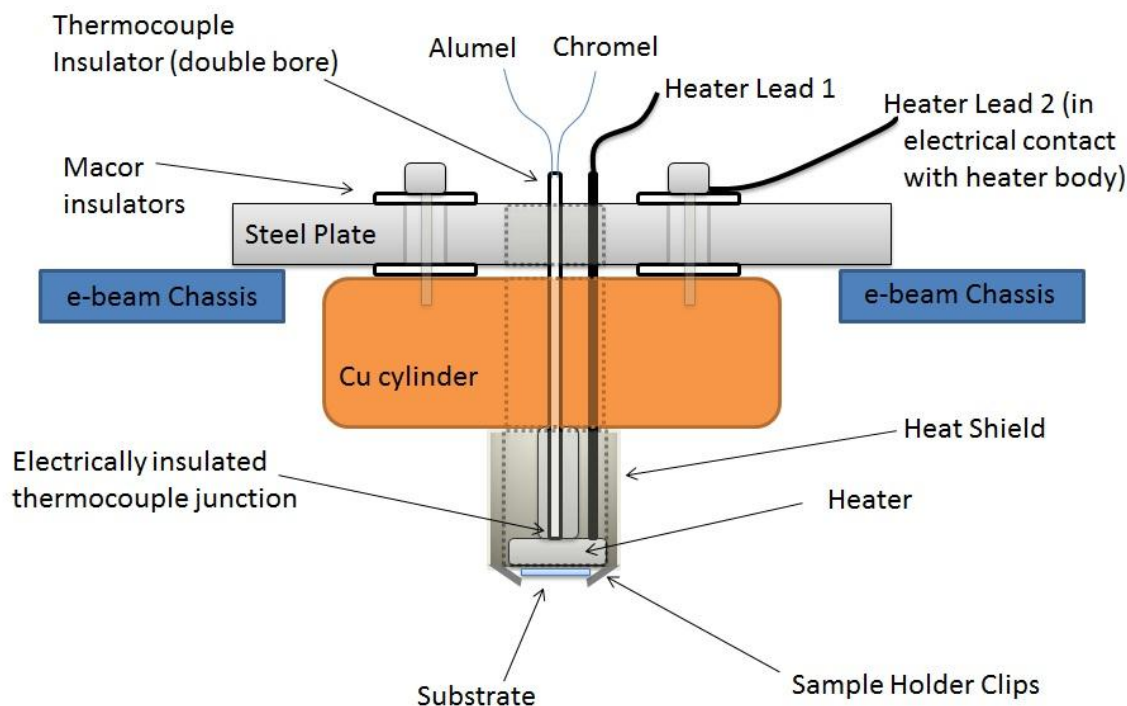


Figure 9. Schematic of the heater apparatus used to control the substrate temperature during e-beam metal film deposition. The heater assembly steel plate rests on the lip of a 4-inch diameter hole in the e-beam chassis which would normally be used to mount substrates on 4-inch wafer plates.

and Nanotechnology Laboratory at the University of Illinois. We combined a commercial substrate heater with a custom mounting and electrical connection apparatus to provide variable temperature heating of substrates during metal film deposition within the e-beam.

We purchased a ½" 1200 °C molybdenum heater from Heatwave Labs with a heat shield assembly and sample clips (part no. 101491-04). We mounted the backside of the heater to a cylindrical copper block, which acted as an additional heat sink to prevent overheating locally within the e-beam instrument. The copper block was then mounted to a 6" long stainless steel plate through a set of MACOR washers and screw insulators. The electrical insulation was required because the body of the heater is one of the heater leads and could not be allowed to short to the body of the e-beam instrument. The steel plate was allowed to rest on top of the 4" hole in the e-beam that is designed for mounting 4" wafers. Figure 9 shows a schematic of the heater apparatus that can be mounted in the e-beam instrument.

The steel plate and the copper plate were machined with holes that allowed the passage of wires for the bias of the heater as well as the application of a thermocouple behind the sample face. The heater wires and thermocouple wires were connected to larger gauge wires for connection to the feedthrough. These larger bare wires were insulated with 1"-long double-bore ceramic tubes. Each set of these was mounted

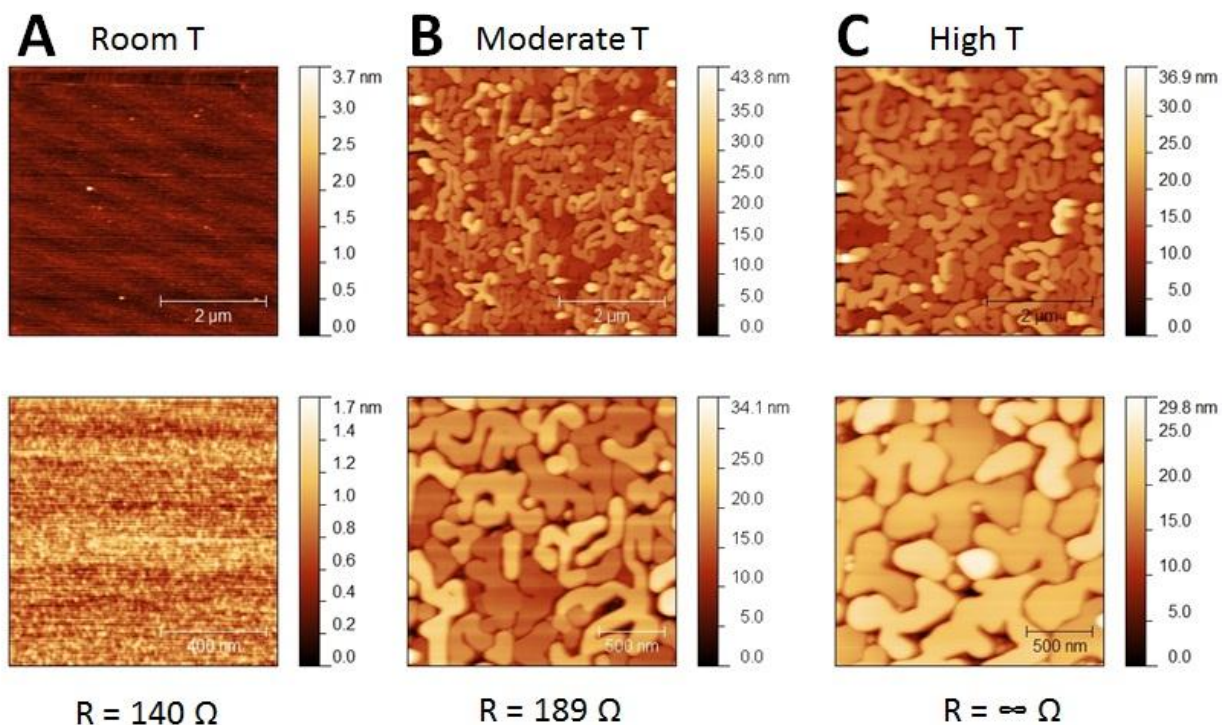


Figure 10. Comparison of platinum films grown at various substrate temperatures. (A) is 10 nm and (B) and (C) are 15 nm, but room temperature films at 15 nm have the same morphology. As the temperature increases, the islands grow larger, but the film resistance increases. “Moderate” temperature here is $\sim 700^\circ\text{C}$. The thermocouple measurement for the “high” temperature film was inaccurate, but it was grown at a higher heater power dissipation than the film in (B). The film in (C) was non-conductive.

with a bracket to the steel plate to minimize strain on the smaller, more fragile wires that connected to the body of the heater. The connection wires were each fitted with alligator clips for easy installation and removal of the heater apparatus to the feedthrough leads.

We originally purchased type-K thermocouples from Heatwave Labs, but they were very fragile and broke easily if they had to be removed from the assembly. For a fraction of the cost, we were able to make our own thermocouples by feeding 0.003” alumel and chromel wires through a double-bore ceramic tube with 0.005” inner-diameter bores. After making the thermocouple junction, we coated the junction with Ceramabond 571 to provide electrical insulation, but thermal conductivity, so that the thermocouple could be inserted directly behind the heater face.

Elevated Temperature Growth of Platinum Films

When the sapphire substrate is actively heated during deposition, atomically smooth islands begin to form. The size of the islands as well as their heights increases with increasing temperature. At the same time that the islands grow larger, the resistances of the films increases until the films become

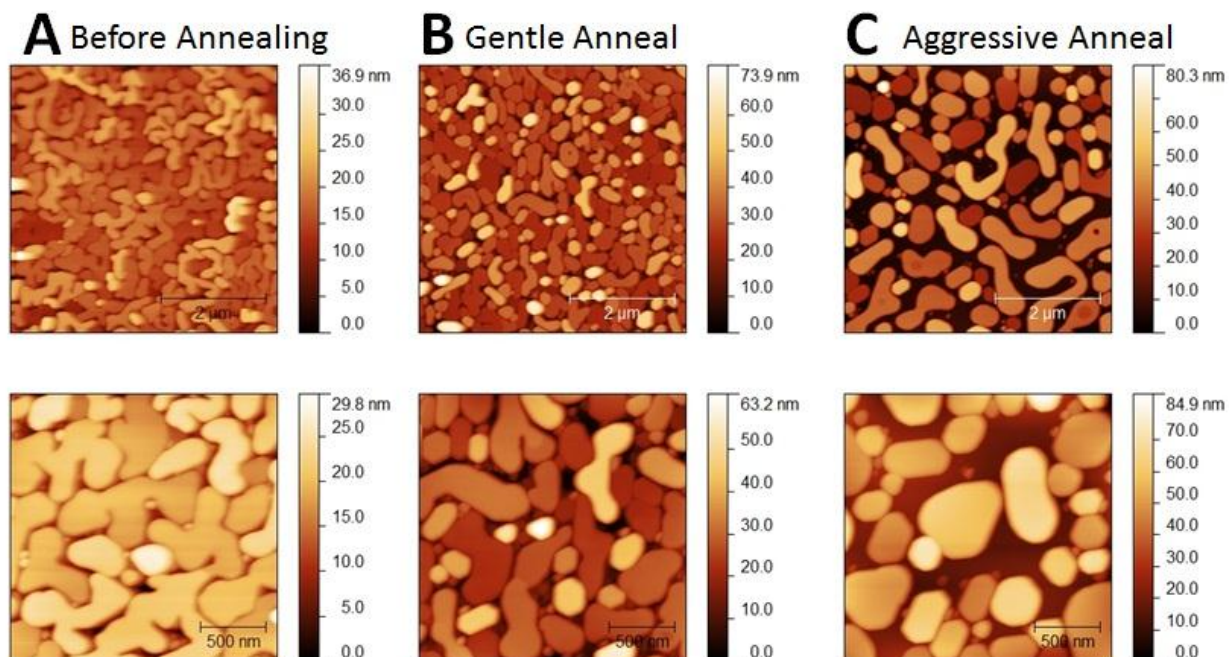


Figure 11. Effects of flame-annealing on ultrathin Pt films. The as-grown film in (A), which corresponds to Figure 10C, was annealed with a hydrogen-oxygen flame. In the “gentle” anneal, the flame was gently brushed over the surface and in the “aggressive” anneal it was more closely swept over the film where a color change was visible to the eye. With the added heat, the islands grew larger and taller.

discontinuous and non-conductive. Figure 10 clearly demonstrates this trend of increasing island surface area and increasing film resistance. The growth mode for these films is a Volmer-Weber growth, as the metal atoms are more attracted to each other than to the substrate.⁵⁵ At room temperature, when the metal atoms lacked sufficient energy to nucleate and aggregate, the growth-mode had appeared to be more layer-by-layer.

This temperature trend can be reproduced to some degree by heating films after deposition. Room temperature films which are flame-annealed do not tend to produce atomically smooth islands, though they do show aggregation. Starting with flat islands, however, and annealing with a hydrogen-oxygen flame produces results like those shown in Figure 11. With additional heating, the islands grow taller and larger, but the areas without metal between the islands also grow larger, leading to disruptions in conductivity.

Figure 12 shows a 15 nm platinum film grown at $\sim 700^\circ\text{C}$. This temperature falls into the range of “intermediate” temperatures for platinum where the size of the flat islands is reasonably large, but for which the film still maintains conductivity. Figure 12A shows an AFM image of the as-grown film. B shows an STM image on which smaller, atomic steps of Pt are visible. C shows how clearly resolved a

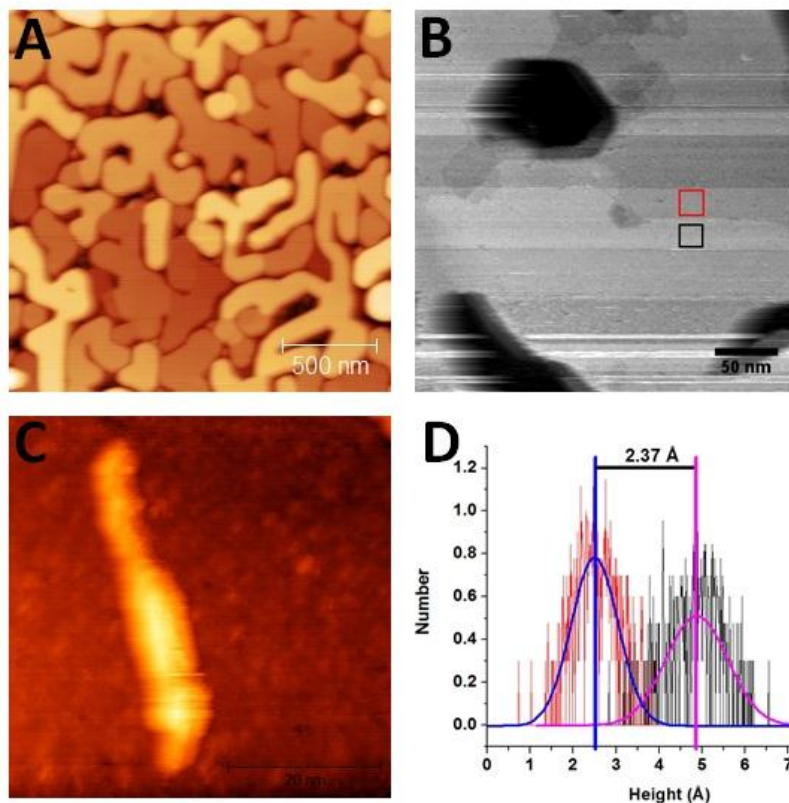


Figure 12. Scanning probe microscopy of flat, conductive Pt film. (A) shows an AFM image of a 15 nm deposition of Pt that corresponds to the film in Figure 10B. (B) shows an STM image of the same film where multiple atomic steps are visible on top of the larger terraces. (C) illustrates a CNT (most likely with a second CNT bound to it at the lower half) on the substrate. (D) shows a normalized histogram of the height values for each pixel in the red and black boxes in (B). The blue and magenta curves are Gaussian fits to the histogram and their peaks are 2.37 Å apart, indicating that the steps are monatomic in height and match the expected step-height for a Pt(111) surface.

CNT is on the flat surface. D shows a normalized histogram of the pixels in the boxes overlaid on panel B. Fitting a Gaussian to each peak in the histogram gives a step height of 2.37 Å. For Pt(111), the step height is 2.3 Å and others have measured an electronic step height of 2.36 Å on a single-crystal Pt substrate.⁵⁶ This is a good indicator that our ultrathin Pt films on sapphire are growing in a (111) orientation.

The STM image shown in Figure 12B was taken within a few days of the film being grown and was degassed in the UHV prep chamber by bringing the sample holder into thermal contact with a copper block at ~100 °C. The image in panel C was taken several months after that in panel B and the sample was hard to scan and appeared dirty after reintroducing it to the UHV-STM after it had been allowed to sit in ambient conditions. The scanning conditions improved drastically by direct resistive heating, passing current through the platinum film itself. AFM performed after removing the sample from the STM showed no noticeable changes to the film morphology due to the resistive degas.

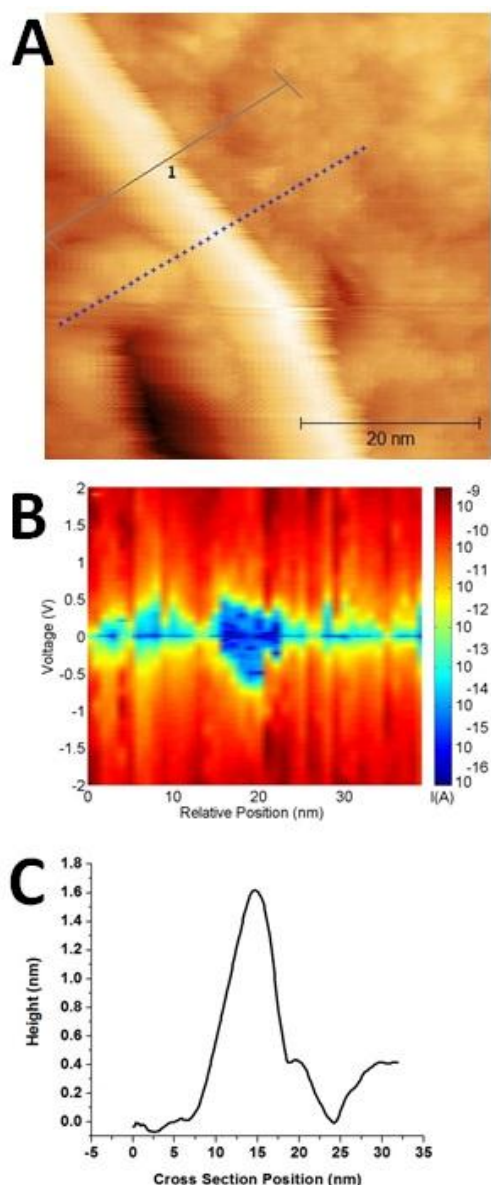


Figure 13. Characteristics of CNT on ultrathin platinum. (A) shows an STM topography of a CNT on a 5 nm Pt film grown at room temperature, then elevated to over 300 °C. The spectra map in (B) corresponds to the blue points in (A) and the height profile in (C) is an average cross section depicted by the line labeled '1' in (A).

We were able to make very thin, conductive platinum films by depositing 5 nm of Pt at room temperature, then immediately heating the sample to over 300 °C. Figure 13A shows an STM topography of such a film with a CNT that was deposited via dry contact transfer. It should be noted that while CNTs can be resolved on this surface, films like those shown in Figure 12 have superior flatness that will be more suitable for smaller molecules. While not universally true, many of the CNTs we have examined on ultrathin metal surfaces tend to have narrower band gaps and a taller apparent height in the STM than we observe on silicon. Figure 13B and C show some representative spectra and height profiles that illustrate this effect. While the data shown in these figures is not extremely far from expected values, we see this trend with large consistency, indicating that the metal surface may be doping the CNTs with additional state density.

Elevated Temperature Growth of Gold Films

Both platinum and gold make an excellent choice for thin films for SMA-STM substrates because they are noble metals and do not oxidize. Gold has a few characteristics which make it more desirable than platinum if it is possible to develop thin films with the same flatness. For comparable thicknesses, gold has slightly better optical transmission than platinum.⁵⁷ Furthermore, gold can act as a support for self-assembled monolayers of alkanethiols or other thiol derivatives which could be functionalized as anchors for

molecules that do not physisorb well to the metal surface.⁵⁸

The previous room-temperature work from our lab all revolved around gold,⁵³ so we set out to develop gold films at elevated temperature in order to create flatter films in the same way that we did with the platinum. The same general trends that we established for elevated temperature deposition of platinum

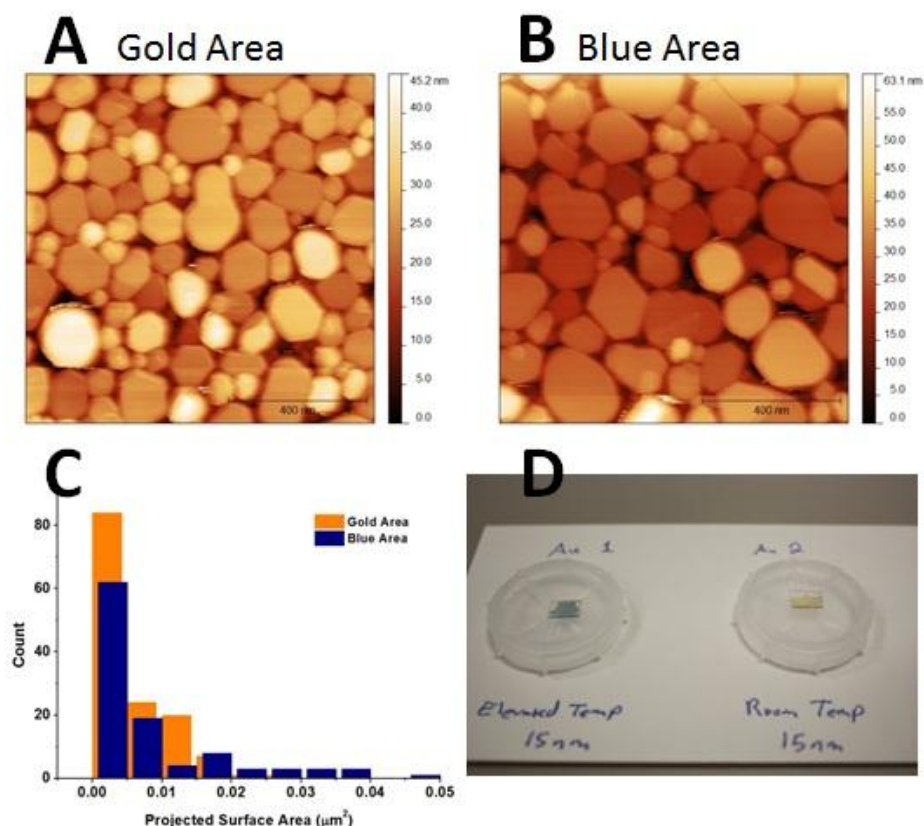


Figure 14. Comparison of gold grain sizes as a function of temperature. (A) and (B) are AFM topographs from the same sample that had variations in the color, likely due to local temperature inhomogeneities across the sample during deposition. (A) shows a region that appeared gold in color to the eye and (B) shows a region that had a bluish tint to it. (C) is a histogram showing the size of the islands in each region. The bars are offset for clarity, but the binning was identical for each data set. (D) is a photograph of two gold samples of the same thickness deposited at different temperatures. The sample on the left demonstrates the blue color that arises from the island formation of the elevated temperature films.

held true for gold as well. At higher temperatures, the islands grew larger, but the conductivity of the films grew smaller. There were some substantial qualitative and quantitative differences between the platinum and gold films, however.

For comparable film thicknesses and deposition temperatures, the gold films produce smaller islands than the platinum films. Morphologically, the gold films tend to aggregate into isolated polygonal structures with straight edges. The platinum films, in contrast, have more rounded edges and the isolated structures merge into extended structures that wrap around each other. Additionally, the gold films become non-conductive at lower temperatures and with smaller islands than the platinum films.

For many of the gold films studied here, their semi-transparent appearance takes on a color other than gold. Our elevated temperature films most often take on a blue hue, though some regions of pink have also appeared. This can be seen in the photograph in Figure 14D. Thin gold films can take on a variety

of colors depending on their morphological structure, a result that arises from the excitation of a plasmon resonance.^{57,59} This aspect of the gold films is undesirable for broadband SMA-STM substrates because the plasmon excitation arises from absorption. For films of a blue color, the plasmon absorption peak is in the red.

Not only can the film colors and morphologies vary from film to film, but in some cases, it will vary within a single film. In one sample, shown in Figure 14A and B, the film appeared gold in some regions and blue in others. As expected, the islands were larger in the region that appeared blue than in the region that appeared gold. Figure 14C shows a histogram comparing the sizes of the islands in the AFM images in panels A and B. The blue area had more larger islands and fewer smaller islands than the region that appeared gold to the eye.

In order to find a compromise between flatness and conductivity, we grew variable temperature gold films. We first deposited a conductive layer of gold at room temperature, then applied a second layer at elevated temperature to provide flat islands for SMA-STM. These films too became discontinuous and control experiments proved that heating a room temperature gold film caused aggregation and island formation—though more rounded than flat on top—that led to a lack of electrical conductivity.

To overcome the problem with the underlayer of metal coalescing, we grew films that were gold on niobium instead of gold on gold. Niobium has a substantially higher melting temperature than gold—2477 °C vs 1064 °C⁶⁰—which should prevent the elevated temperature from leading to substantial diffusion. Additionally, a seed layer of Nb can be used to reduce lattice strain and has been used to make ultrathin gold films before.⁶¹ To date, we have been unable to reproduce the results of ref. ⁶¹. Others have argued that the seed layer does not aid in the production of the films through a decrease in the lattice mismatch, but rather by changing the interaction energy with the substrate.⁶²

Interestingly, for the films that we have grown to date, we have had difficulty producing islands of gold with the flatness we achieved with gold directly on sapphire. These films are, however, more conductive at comparable thickness than the gold on sapphire without the seed layer.

4.2 Graphene on Transparent Substrates

Ultrathin metal films are not the only theoretically feasible avenue for satisfying the criteria of substrates for SMA-STM. Graphene, a single monatomic layer of graphite, has the potential to offer a platform with excellent flatness, high electrical conductivity, and broadband optical transparency. Even with just a monolayer of graphene supported on a transparent substrate, it should be possible to perform optical STM

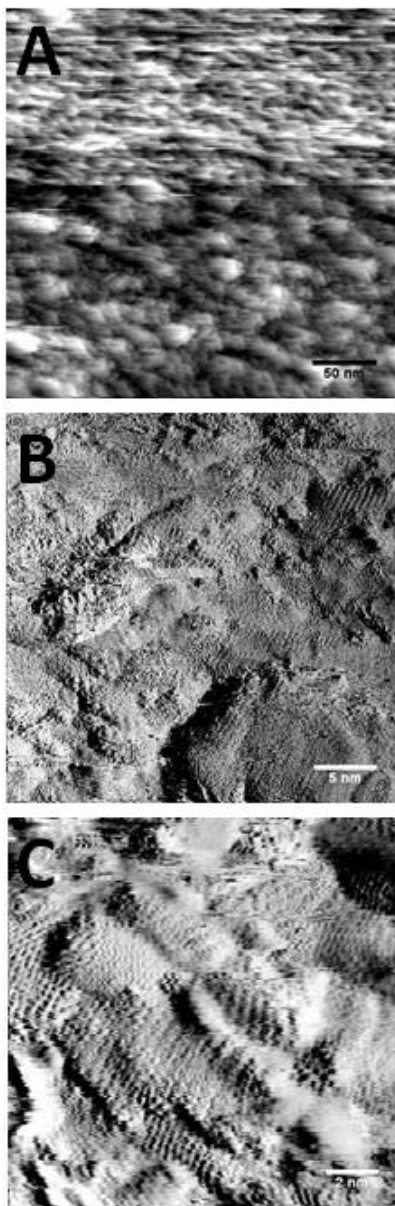


Figure 15. STM images of graphene grown on silicon carbide by molecular beam epitaxy. This sample lost epitaxy during growth. The scale bars are 50 nm in (A), 5 nm in (B), and 2 nm in (C).

experiments. There are a number of ways that such a substrate could be produced and we have explored some of those possibilities.

Since its first isolation⁶³, graphene has garnered substantial research interest due to its unique electrical properties as a 2-dimensional system. Graphene is described as a semi-metal because its valence and conduction bands just touch at the K points in reciprocal space, offering a direct conduction pathway.⁶⁴ The practical result of this electronic structure is that graphene has very high carrier mobilities and a single sheet can have very low resistance.⁶⁵ Moreover, graphene only absorbs 2.3% of light per monolayer⁶⁶, which makes it an ideal candidate for SMA-STM at a variety of wavelengths since single or few layer films are readily possible.

There are many methods for the production of graphene, an area of research which is continuing to grow rapidly. Chandra Mohapatra from the group of Jim Eckstein produced graphene on sapphire and graphene on silicon carbide substrates using molecular beam epitaxy (MBE). In their method, an electron gun vaporizes a solid carbon source in a UHV chamber to produce a molecular beam of carbon, which deposits onto a substrate. During the deposition, the epitaxial growth of the graphene is monitored by reflection high energy electron diffraction (RHEED). The film quality and thickness are later examined using Raman spectroscopy, x-ray photoelectron spectroscopy (XPS), and AFM.

We performed STM on several of these samples, searching for the flatness that would provide an excellent platform for SMA-STM. We were unable to perform STM on the graphene grown on sapphire despite the fact that the samples had resistances on the order of M Ω after growing Ti/Au contacts at the edges. We believe that while there was a percolative pathway for carriers to travel across the sample, the probability of bringing the STM tip onto this pathway rather than an isolated region of graphene islands was small.

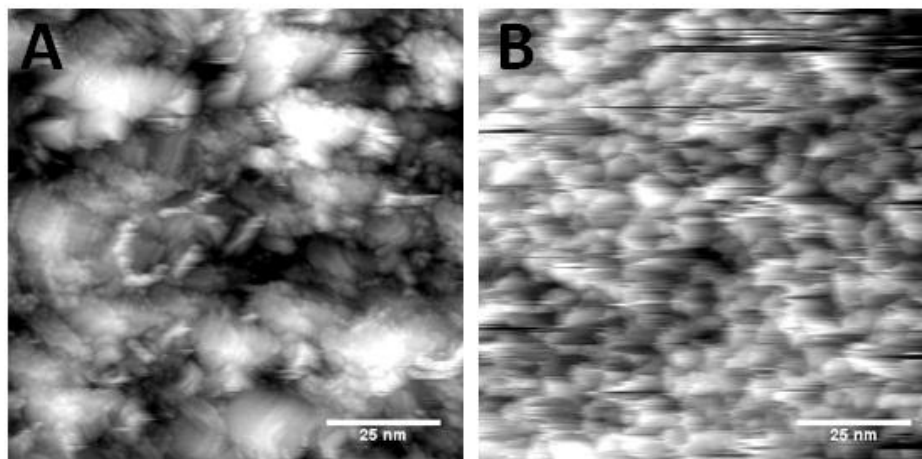


Figure 16. Comparison of two graphene on SiC surfaces by STM. The graphene surface in (A) corresponds to Figure 15 and lost epitaxy during growth. The surface in (B) maintained epitaxy according to RHEED measurements, but maintained an island-like structure.

We were, however, able to perform STM on several samples of graphene grown on silicon carbide. We were able to degas the samples through the silicon carbide to achieve high temperatures and achieved near-atomic level resolution. Figure 15 shows STM images of an ~ 7 monolayer growth of graphene on silicon carbide. According to RHEED measurements, the sample lost epitaxy during the MBE growth. In Figure 15B and C, a mixture of graphene lattice and Moiré patterns can be seen and sheets of graphene appear to curve over the surface which appears to undulate under it.

Figure 16A and B compares the sample from Figure 15 to another sample which was only a few monolayers and maintained epitaxy according to RHEED measurements during the MBE growth. The overall roughness of the sample in B is lower, but it still shows many discrete regions indicating that the growth mode was not layer-by-layer (Frank van de Merwe), but was instead more island-like (Volmer-Weber).⁵⁵

There is a promising alternative to producing graphene on transparent substrates that will be monatomic and more largely continuous that we are pursuing in collaboration with Josh Wood from the groups of Joe Lyding and Eric Pop. This involves growing large sheets of graphene on copper and transferring them via a polymer transfer method onto a transparent substrate such as sapphire. The growth of graphene on copper restricts the formation to almost exclusively monolayer graphene because the chemical vapor deposition (CVD) growth can only catalyze on the copper surface.⁶⁷ Once the surface is saturated, no additional growth can take place. The monolayer graphene can then be transferred to arbitrary substrates.⁶⁸

Chapter 5: Spectral Resolution (Factors affecting absorption)

Single-molecule spectroscopy faces inherent challenges related to signal to noise. Each choice of detection method brings its own complications that must be understood in order to interpret meaningful results from experiments. While SMA-STM is largely straightforward in its implementation, the use of an STM as a detector of optical absorption does introduce its own complexity. This chapter will discuss the collection of single-molecule spectra as well as the factors that may influence the results.

5.1 Collecting Optical Spectra

For single molecules, the observation of optical absorption with high spatial resolution as demonstrated in Chapter 3 becomes much more interesting when we can compare the intensity of absorption across a range of wavelengths. This is the traditional methodology of absorption spectroscopy and its use in single-molecule spectroscopy serves many purposes. Measuring a lineshape for an absorption peak for a single molecule provides a wealth of information. In comparison to bulk experiments, a single-molecule spectrum can elucidate the contributions of homogenous and heterogeneous broadening. It can resolve differences between individual molecules, which is particularly relevant for structures without finite size such as carbon nanotubes. Moreover, it can give information about the influence of the local environment on the optical properties.

For CNTs in specific, there have been many different lineshapes measured or predicted. Van Hove singularities have a very specific asymmetric lineshape,⁶⁹ while Rayleigh scattering experiments have provided a different asymmetric lineshape.⁷⁰ Excitons, however, should have a Gaussian envelope.²⁸ Our method provides a tool that should be able to determine the absorption lineshape for single molecules with high resolution.

Automated spectra collection

The major difficulty in SMA-STM experiments that provide a spectrum arises from the need to have multiple variables functioning together for a long enough period of time to collect an entire spectrum. The lasers must be properly aligned, the CNTs must be absorbing in the laser wavelength range, and the STM tip must maintain high imaging fidelity throughout the collection. For this last reason, it is important to be able to collect spectra quickly to minimize the probability of changes to the tip.

We have set up an automated method for tuning the resonant laser. Our tunable laser from Sacher Lasertechnik can be tuned across a range of 1156-1265 nm. The outputted wavelength is adjusted by a grating which is rotated by an inchworm motor. This motor is controlled via a serial interface through a piece of software written in Labview and provided by the manufacturer. The laser diode current, and thus the laser power, is controlled by the laser power supply, which interfaces with a computer via GPIB.

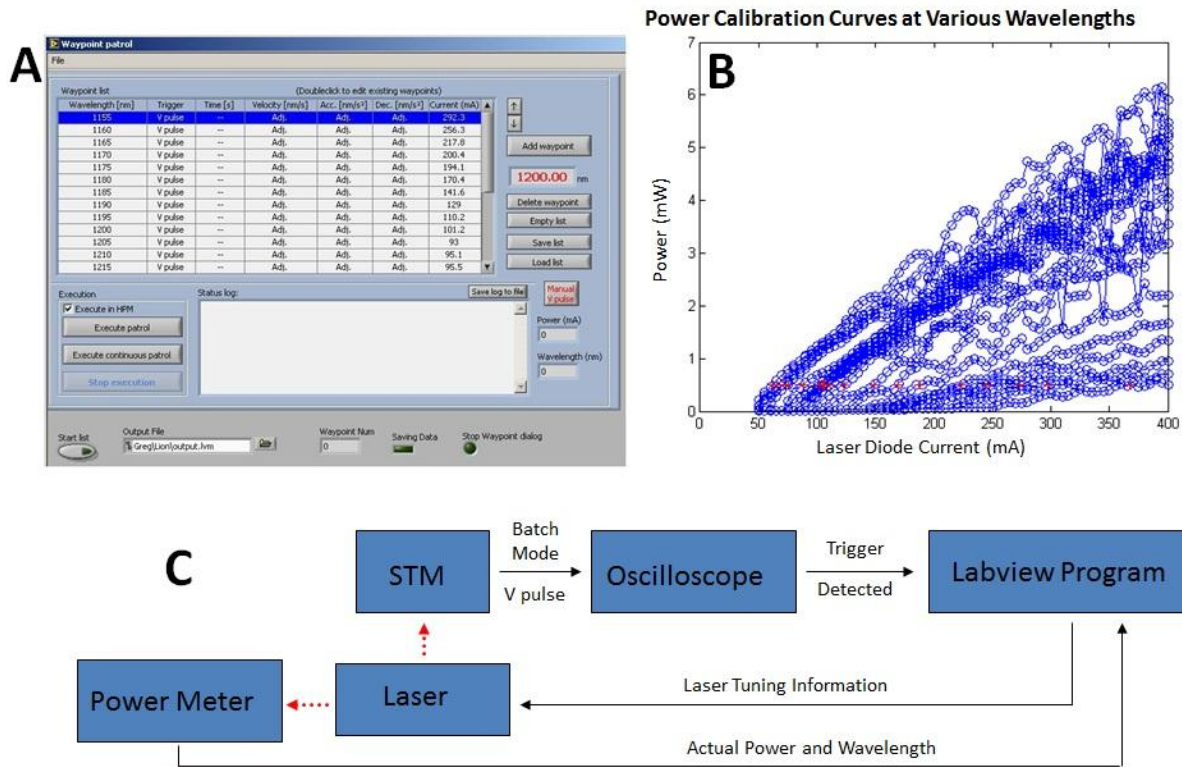


Figure 17. Mechanism of automated spectrum collection in SMA-STM. (A) shows the interface for the laser tuning based on voltage pulses. (B) shows sample laser diode calibration curves for the selection of uniform laser powers at different wavelengths. (C) is a schematic of how the instruments and software communicate with each other for automation.

The software provided by Sacher Lasertechnik does provide a primitive automated tuning capability, which allows the user to tune the wavelength to a list of values either on a regular time schedule or by interacting with the program. This was not sufficient for our needs because we needed to correlate our wavelength changes with the end of an STM scan, which would not always be on regular time intervals and we wanted the data collection to be automated. More importantly, maintaining a constant laser power as the wavelength is changed requires adjusting the laser diode current because the diode output power is not uniform across the tuning range. We modified the program to overcome these shortcomings in the provided design.

Professor Joe Lyding modified the STM software to output a voltage pulse at the end of each scan in a batch mode, which is the mode on our STM which allows the automated collection of images. We modified the Labview program from Sacher to monitor for these voltage pulses through an oscilloscope that communicates via GPIB. When a voltage pulse is detected, a serial command is sent to the laser to tune the wavelength and a GPIB command is sent to adjust the laser diode current. The laser diode current adjustment is determined from a calibration curve of laser powers as a function of current at each of the used wavelengths. We also modified the software to record all of the data and the actual laser

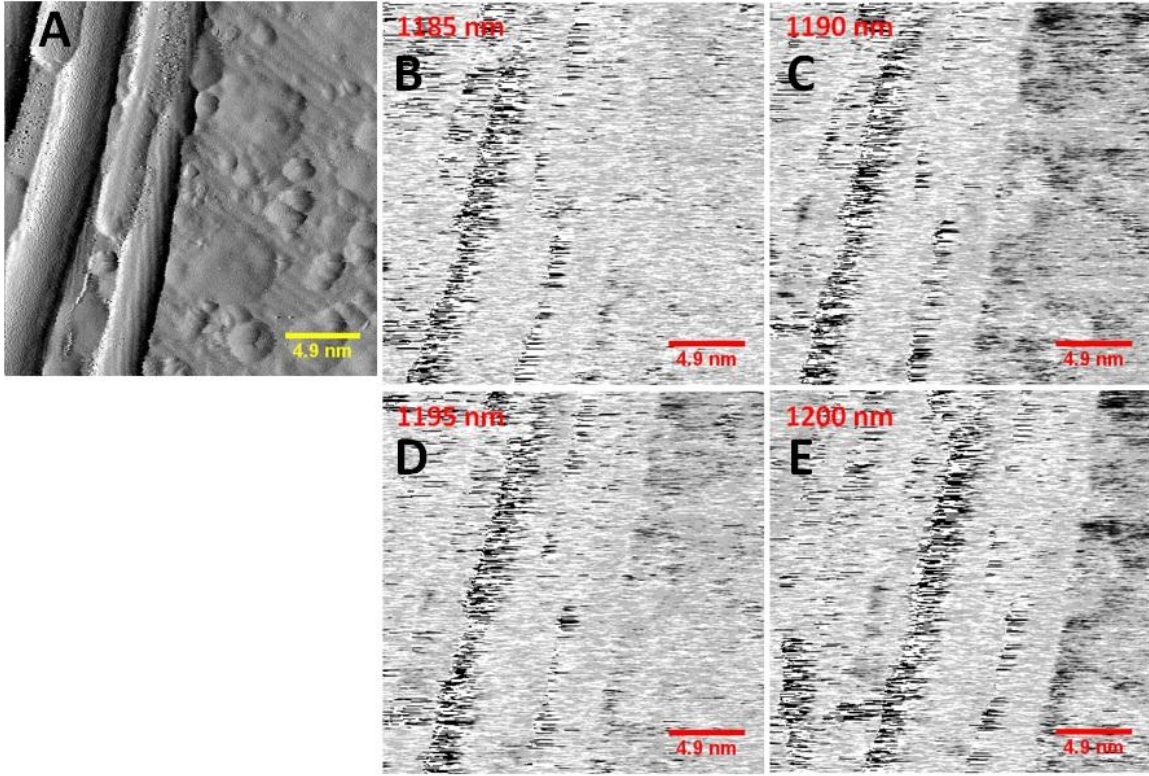


Figure 18. Wavelength dependence of CNTs in SMA-STM. (A) shows a current image of several CNTs on an Si(100)2x1:H surface. (B) – (E) show lock-in absorption images of the same area under different illumination wavelengths. The images were taken with a tunneling current of 1 pA and a sample bias of -2 V.

power of a dumped beam from the beam splitter, so that it can be compared to the STM files saved in the batch mode.

Figure 17 shows how this automation takes place. Panel A shows a screenshot of the software interface and B shows an example of the power vs diode current tuning curves. C shows a schematic of how all of the pieces of equipment and software interact with each other during automated spectra collection. The implementation of this in the Labview code was straightforward, though the details of the code are covered under a non-disclosure agreement with Sacher Lasertechnik.

In many cases, it is not important to collect large square images to get spectral information. In these cases, scans with only a small number of lines in the slow-scan direction can be collected, which speeds up the spectrum collection. To ensure that the lock-in absorption images are properly compared to each other, we implemented a simple cross-correlation algorithm that overlaps the lock-in images based on the topographic images.

We observed several series of wavelength dependencies for carbon nanotube absorption, but later realized that our laser did not have spatial stability during tuning. None of those results are presented here

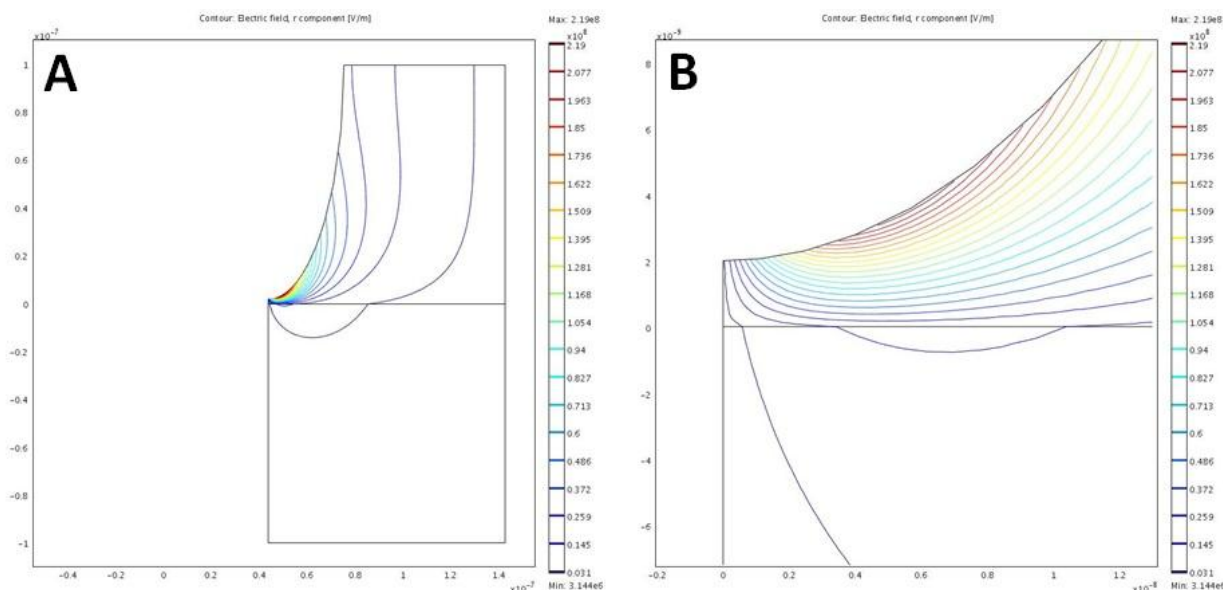


Figure 19. Calculated electric field for a tip with a 10 nm radius of curvature, a 2 nm tip-sample spacing, and 2 V applied to the tip relative to a grounded surface. (A) and (B) show the same calculation on different length scales.

because it was difficult to determine the difference between a dependence on wavelength and on changes in power due to changes in the laser position or spot size. We had the laser provider resolve this problem by coupling the light into a fiber optic cable and propagating it for several feet in the cable before switching back to a freely propagating beam. This produced an unpolarized laser spot that was stable across wavelengths.

Evidence for spectral resolution

With the laser system corrected to avoid power density fluctuations with laser tuning, we have observed differences in absorption as a function of wavelength. Figure 18 shows a clear example of this capability with the laser absorption peaked at 1190 nm. Figure 18A shows an STM current image of several CNTs on a hydrogen-passivated Si(100)2x1 surface. B-E show lock-in absorption images of the same area under various illumination wavelengths. The color scale is the same in each image and the scanning conditions are the same except for the illumination wavelength. The differential absorption largely appears on the substrate in these images, rather than on the CNTs themselves. This phenomenon will be discussed in 5.4 .

5.2 Effects of the STM electric field on the optical properties

The electric field in an STM is of a large magnitude, and its effect on the optical properties of molecules in the scanning region cannot be ignored. At typical scanning voltages on the order of volts and tip-sample separations on the order of nanometers, the electric field in the tunneling junction is on the order of GV/m. This can significantly alter the electrical and optical properties of the materials being studied.

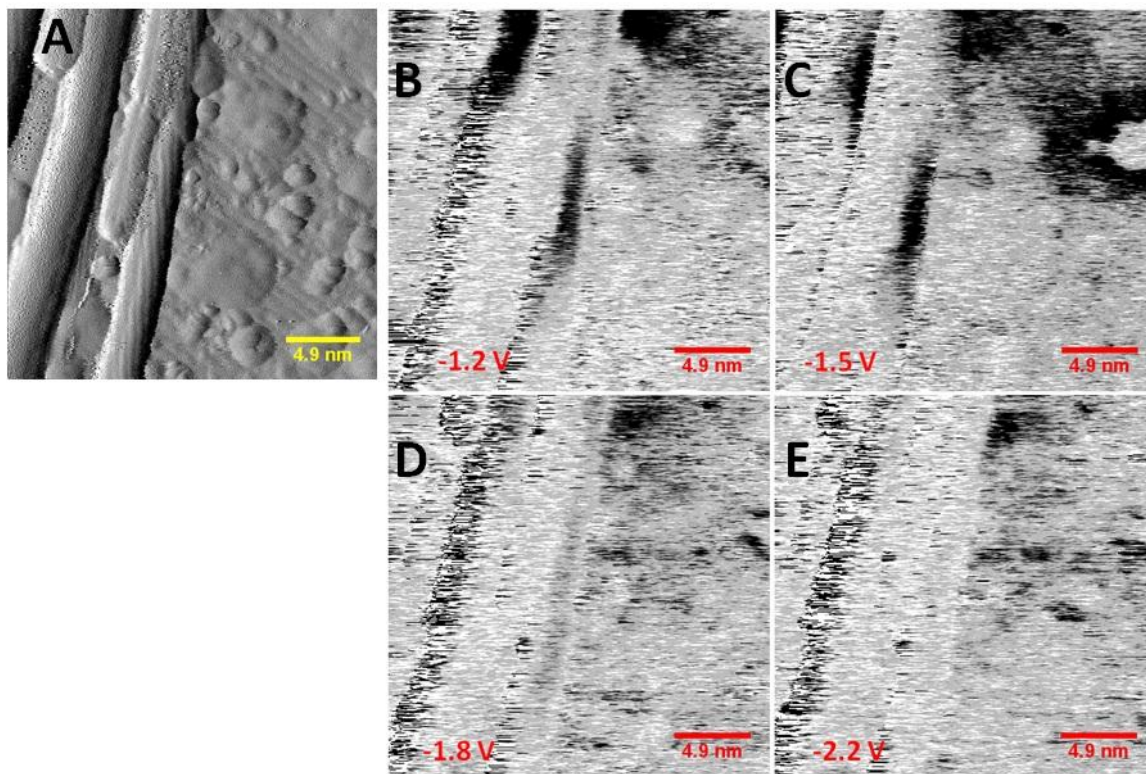


Figure 20. Bias dependence of CNTs in SMA-STM. (A) shows a current image of several CNTs on an Si(100)2x1:H surface. (B) – (E) show lock-in absorption images of the same area under illumination at 1190 nm with varying sample bias. The average tunneling current was 1 pA in all images.

Of primary concern, the molecules in the STM tunneling junction can undergo an optical Stark effect, leading to a shift in their optical transition energies.

The effects of electric fields on CNTs have been examined in a variety of systems and theoretical frameworks. Optical studies have observed both red shifts for CNT absorption in electric fields⁷¹ as well as blue shifts.⁷² Theoretical works have predicted that various electric fields and geometries can lead to band gap modulations^{73,74} and that excitons can have a quadratic stark effect and potentially dissociate.⁷⁵ Exciton dissociation has also been observed experimentally in a setup where red shifts eventually became blue shifts at high electric fields.⁷⁶ Specifically within the STM, a narrowing of the electronic band gap for boron-nitride nanotubes has been attributed to a stark effect from the tip-sample bias.⁷⁷ Conversely, another study attributed band gap opening in CNTs in an STM to the electric field.⁷⁸

Some have examined these fields parallel to the CNT axis, while others have examined the orthogonal field's effects. While most of the electric field component is directed perpendicular to the CNT axis in the STM geometry, there is still an appreciable component along the CNT axis. We performed some calculations using COMSOL in collaboration with William Morgan from the group of Harley Johnson to

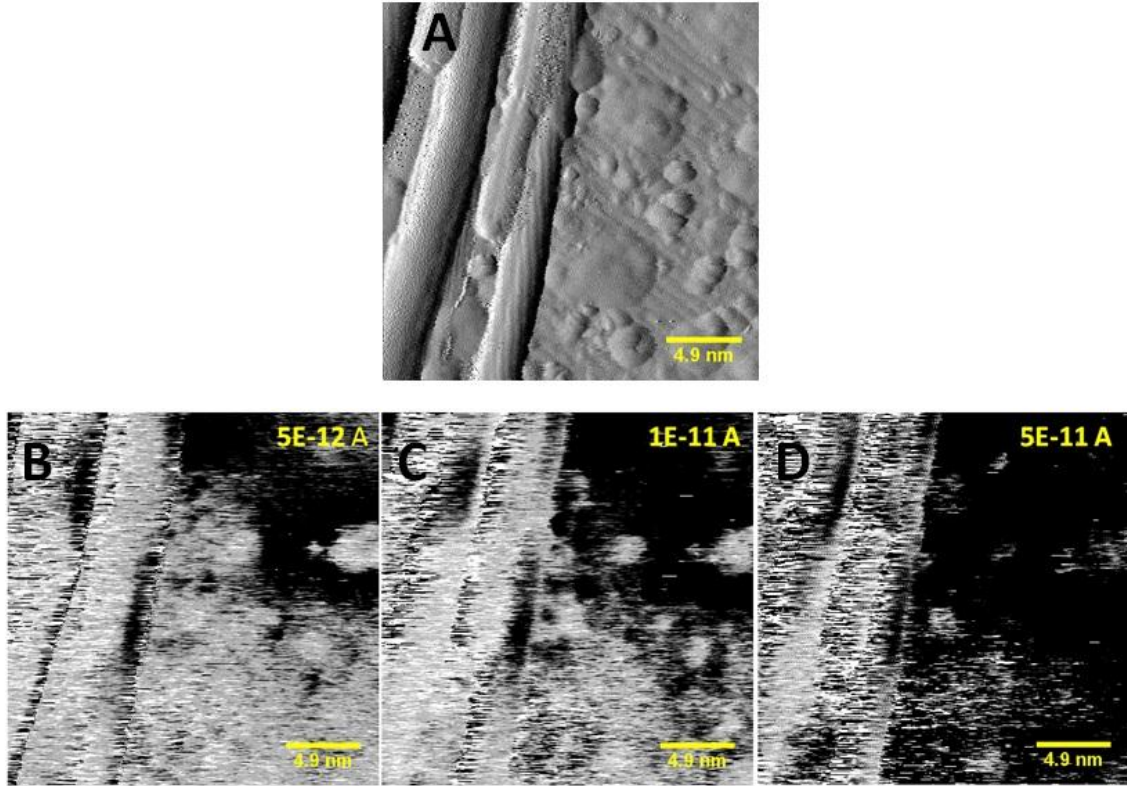


Figure 21. Current dependence of CNTs in SMA-STM. (A) shows a current image of several CNTs on an Si(100)2x1:H surface. (B) – (E) show lock-in absorption images of the same area under illumination at 1190 nm with varying tunneling current setpoints. The sample bias was -1.2 V in all lock-in images.

assess the magnitude of these horizontal components. Figure 19 shows the r-component of the electric field for an STM tip with a 10 nm radius of curvature, a 2 nm tip-sample spacing, and a bias of 2 V relative to a grounded sample. At the sample surface 1 nm off-axis from the center of the tip, the horizontal component of the electric field was $1.8 \times 10^7 \pm 2 \times 10^4$ V/m. This field, off-center and in the horizontal component, is stronger than many of the fields that were discussed in the previous studies.

When we change the sample bias in the STM, the local electric field changes, but the tip-sample separation is also modified, making the different variables difficult to elucidate. Additionally, the current can be changed, which has an even larger effect on the tip-sample separation, but also influences the geometry of the junction, which may affect the local electric field distribution. For the same system studied for its wavelength dependence shown in Figure 18, we studied the effects of the sample bias and the tunneling current setpoint.

We used the maximum signal wavelength of 1190 nm and varied the sample bias. The results are shown in Figure 20. As the sample bias was decreased, the signal intensity became stronger relative to the background and the appearance of the signal began to shift from appearing on the substrate to appearing

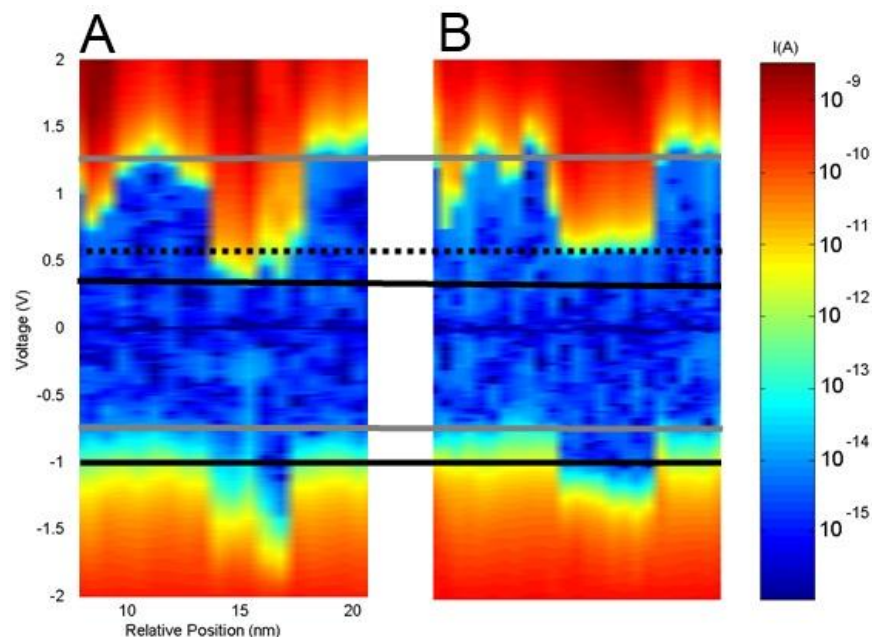


Figure 22. Light-induced shifting of carbon nanotube band edges. (A) shows a spectra map of a CNT on Si(100)2x1:H without laser illumination. The CNT is the central portion just right of center that is shifted toward negative energies relative to the substrate. The solid gray lines are a guide to the eye to represent the silicon band edges and the solid black lines approximate the CNT band edges. (B) shows the CNT under laser illumination with the dotted black line marking the edge of the conduction band. The conduction band is clearly shifted to higher energies. The ambiguity of the band edge in (A) makes it difficult to determine whether the valence band also shifted.

on the nanotubes in certain regions. We then fixed the sample bias at -1.2 V and increased the tunneling current, as shown in Figure 21. At higher tunneling currents the signal began to saturate. It is as of yet unclear whether these changes are simply an improvement in the signal to noise or whether the local electric field modification due to the change in tip position is more largely responsible for these characteristics.

5.3 Effects of the optical field on the electronic properties

Not only have we seen evidence that the STM electric field can influence the optical properties of CNTs, we have also observed changes in the electronic properties of CNTs under laser illumination. We took a line of STS measurements across the axis of a CNT that was absorbing both with the laser off and with the laser on. Figure 22 shows that while the STS spectra on the substrate were not affected by the laser illumination, the CNT showed a narrowing of the band gap. We have not observed this same effect for CNTs that are not absorbing, which indicates that the phenomenon is related to absorption and is not simply a result of a change in the local electric field in the STM tunneling junction.

5.4 Single-molecule optical absorption signatures detected on the substrate

Many of the absorption signals that we have observed with SMA-STM show a clear spatial localization to within the molecular structure itself. This was clearly demonstrated in Chapter 3 among other cases. We

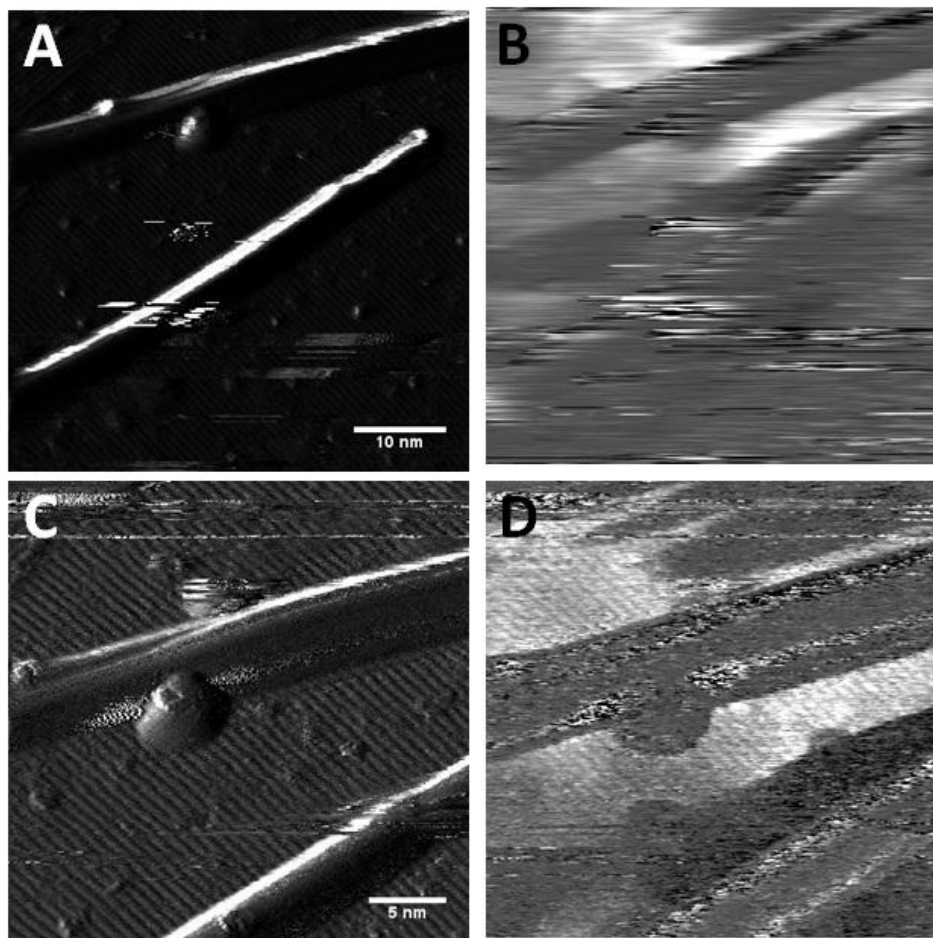


Figure 23. Appearance of signal on substrate. After a tip change, this is the same system as that observed in Figure 4. (A) and (C) show current images while (B) and (D) show the corresponding lock-in absorption images. (C) is a smaller scan of a region in (A). The absorption signal appears on the substrate.

have also observed cases where the signal appears on the substrate rather than on the CNT. We only observe this phenomenon when there is a CNT within close proximity, however, which indicates that the appearance of this signal is related to absorption of light by the CNT. Moreover, after a tip change, we have seen the signal change location from on the CNT to on the substrate.

Figure 23 shows the appearance of the lock-in absorption signal on the substrate where it had previously appeared on the CNT itself as shown in Figure 4. After the tip change, the signal shifted onto the substrate and the apparent height of the CNTs increased by more than a factor of two. The lock-in absorption images in Figure 23 also showed a clear wavelength dependence, though only the 1200 nm images are shown.

The reason for the shift of the signal to the substrate is not yet clear, though we expect that it is related to a change in the local electric field due to a change in the local geometry of the tip. In many cases where

we observe this kind of signal, it is correlated with a multiple tip, where tunneling is occurring from multiple apices. It is possible that the substrate-detected signal results from fast relaxation to the substrate via electron-phonon coupling. This seems unlikely in the case presented in Figure 23 because the lifetime would have had to have changed substantially from the case presented in Figure 4. It seems more likely that tunneling current fluctuations will happen when the tip is off-axis with the CNT because of a complicated tip and electric field geometry. It is not particularly surprising that the tip shape could have a dramatic influence on the detection mechanism, as models have shown that the optical field enhancement is highly dependent upon the tip shape.⁷⁹

Further evidence that the substrate-detected signal is related to CNT absorption can be found in Figure 22. In that case, the absorption signal appeared on the substrate and not on the CNT, yet the STS showed no changes on the substrate. Instead, the electronic structure changes as monitored by STS were only evident on the CNT itself.

Part II : A New Algorithm for Solving Dynamics on Free Energy Surfaces

Chapter 6: Smoluchowski Dynamics with a Singular Value Decomposition Basis Set

Portions of this chapter were previously published in:

Scott G, Gruebele M. Solving the low dimensional Smoluchowski equation with a singular value basis set. *Journal of Computational Chemistry*. 2010;31(13):2428-2433. <http://dx.doi.org/10.1002/jcc.21535>

6.1 Introduction

One of the fundamental principles of physical chemistry is the relationship between a potential energy landscape and the resulting properties of chemical reactions and stability. How to connect the results of experiments of chemical kinetics to the underlying potential surface has long been a complicated problem. Several theoretical frameworks have been developed to understand and predict chemical reaction kinetics. In many cases, simple models provide useful explanations and predictions. In other cases, these models can break down, provide inaccurate or inconsistent results, or are simply too computationally expensive for practical implementation. The following chapters approach some of the theoretical questions related to the chemical kinetics, with a specific focus on the application in experiments related to protein folding. In preparation for that work, this chapter will provide some brief background on the use of probability diffusion equations for chemical kinetics, genetic algorithms, and the relationship between thermodynamic and kinetic properties.

In the master equation description, the kinetics are governed by a first-order differential equation of the form

$$\frac{dP_v}{dt} = \sum_{v'} [-w_{vv'}P_v + w_{v'v}P_{v'}] \quad (7)$$

where P_v is the probability that a trajectory is in state v , and $w_{vv'}$ is the matrix element for the probability that a transition from state v to v' will occur.⁸⁰ It is worth noting that the master equation approach to kinetics requires differentiating the system into discrete states, v . When the barriers become small, on the order of just a few $k_B T$, the probability density on the potential surface cannot be neatly classified into unique states, as there may be non-negligible contributions to the population at or near the barrier.

In transition state theory, first developed by Eyring, the rate coefficient for a reaction $A \rightarrow B$ over a barrier is given by^{81,82}

$$k = \kappa \frac{k_B T}{h} \left(\frac{Q^\ddagger}{Q_A Q_B} \right) e^{-\frac{E^\ddagger}{k_B T}} \quad (8)$$

where κ is the transmission coefficient, k_B is the Boltzmann constant, h is Planck's constant, Q_A and Q_B are the partition coefficients for the reactant and products, Q^\ddagger is the partition coefficient for the transition state, and E^\ddagger is the activation energy. Eyring's formulation assumes that the activated population is small, which breaks down when populations are small. Moreover, when the barrier is small, the effects of the surrounding environment become more important to the rate determination, a factor which is not accounted for in transition state theory.

In the Kramers method, the effect of the surrounding environment is incorporated as a macroscopic friction term.⁸³ One of the fundamental results of Kramers' theory is the simple result that the escape rate over the barrier is given by⁸⁴

$$r_K = \frac{1}{2\pi} \sqrt{G''(x_{min})|G''(x_{max})|} e^{-[G(x_{max})-G(x_{min})]/D} \quad (9)$$

where G'' is the second derivative of the potential, D is the diffusion coefficient, x_{min} and x_{max} are the position of the base of the well and the position of the barrier (transition state) along the reaction coordinate. This method assumes that the barrier is substantially higher than $k_B T$ and that the escape over the barrier is slow such that the perturbation of the population distribution is negligible.⁸⁵

In addition to the problem of partitioning the potential surface into states in the low-barrier regime, transition state theory and the Kramers analytical approach both encounter a time-scale problem. The fluctuation-dissipation theorem⁸⁰ states that the transition toward equilibrium from a non-equilibrium perturbation relaxes in the same way that normal thermal fluctuations at equilibrium relax. Out of this theorem arises the relationship⁸⁶

$$k(t) = k e^{-kt}. \quad (10)$$

In the high-barrier case, k is small and at short times, $k(t)$ will be non-exponential as events occur on the molecular time-scale, and at longer times, will decay exponentially. This division of time scales is always present, but in a typical experiment with large barriers, we observe only the longer time scale, from which the traditional phenomenological kinetic rate laws have been developed.⁸⁰ When the barriers become small, however, most of the interesting parts of the kinetics happen on the molecular time scale. The short-time non-exponential kinetics given by Equation (18) for the high-barrier case are due to barrier-recrossings of activated molecules, but this is short compared to the time-scale of activation in transition state theory. In the low-barrier case, however, the time scale of activation and the molecular time scale become comparable in magnitude, and the assumptions of these models break down. In terms of

experimental observables, the result of this is that different probes may measure different kinetics for large molecules because they measure different molecular actions, which may not share the same time-scale.⁸⁷

The work of Kramers introduced the concept of modeling kinetics as diffusion. His analytical solutions, however, required assumptions based on relatively high barriers ($>k_B T$), as discussed above. When this model fails with low barriers, numerical solutions to the diffusion equation provide a means to model the kinetics.^{88,89} A numerical solution to the diffusion equation can be achieved through Langevin dynamics.

Langevin equations of motion are generally written in the form^{90,91}

$$\frac{dx}{dt} = f(x(t), t) + g(x(t), t)\xi(t) \quad (11)$$

where ξ is a fluctuating force and f and g are some known functions. For the applications of diffusion here, f is a force given in terms of a potential surface

$$f(x, t) = -\frac{\partial G(x, t)}{\partial x} \quad (12)$$

Langevin's work, like much of that surrounding these topics of diffusion, arose out of the study of the Brownian motion of particles. His work formulated the equation of motion for a Brownian particle as^{92,93}

$$m \frac{d^2 x}{dt^2} = -6\pi\mu a \frac{dx}{dt} + \xi \quad (13)$$

where m is the mass, μ is the fluid viscosity, and a is the acceleration. The middle term describes the viscous drag in accordance with Stokes' law. In many applications where the potential is of interest, and in comparison the form given in Equations (11) and (12), the ma term on the left side of Equation (13) is recognized to be the force and can be replaced by

$$F(x) = -\frac{\partial G(x)}{\partial x} \quad (14)$$

In numerical solutions to Langevin dynamics, one can average over trajectories of x , or one can solve the associated Fokker-Planck equation. In general, a Fokker-Planck equation describes the evolution in time of a probability density (population) distribution as a function of position and velocity. For one variable, it takes on the general form⁸⁴

$$\frac{d\rho}{dt} = \left[-\frac{\partial}{\partial x} D^{(1)}(x) + \frac{\partial^2}{\partial x^2} D^{(2)}(x) \right] \quad (15)$$

where $D^{(1)}$ is the drift coefficient and $D^{(2)}$ is the diffusion coefficient.

Langevin dynamics are a useful tool, particularly in low-barrier kinetics simulations and have been used on some of the protein folding kinetics applications discussed in Chapter 7^{88,94}. The search space for the trajectories was too large in some cases⁹⁴, however, so we introduced a new method based on the Smoluchowski equation.

6.2 The Smoluchowski Equation

The Smoluchowski equation is a special form of the Fokker-Planck equation that describes a probability distribution as a function of position and time. The Fokker-Planck equation determines a distribution function of velocity, whereas the Smoluchowski equation determines a distribution in time as a function of position only. The magnitude of experimentally observed variables such as fluorescence or circular dichroism are related to the position on a reaction coordinate, so the spatial distribution function created from the Smoluchowski equation is a useful tool. The use of the Smoluchowski equation for protein folding kinetics is addressed in the following chapters.

The Smoluchowski equation is given by Hummer⁹⁵ in the form

$$\frac{\partial \rho}{\partial t} = \hat{O}(\mathbf{x})\rho = \frac{\partial}{\partial \mathbf{x}} \left\{ D(\mathbf{x}) e^{-\beta G(\mathbf{x})} \frac{\partial}{\partial \mathbf{x}} [e^{+\beta G(\mathbf{x})} \rho] \right\} \quad (16)$$

where $\rho(\mathbf{x}, t)$ is the probability density, $D(\mathbf{x})$ is the diffusion tensor, and $G(\mathbf{x})$ is the free energy, β is $1/k_B T$, and the bold \mathbf{x} indicates the appropriate summation over partial derivatives along N reaction coordinates $\mathbf{x} = \{x_1 \dots x_N\}$. By distributing the inner derivative, this can be expanded to

$$\frac{\partial \rho}{\partial t} = \frac{\partial}{\partial \mathbf{x}} \left\{ D(\mathbf{x}) e^{-\beta G(\mathbf{x})} \left[e^{+\beta G(\mathbf{x})} \frac{\partial}{\partial \mathbf{x}} \rho + \rho e^{+\beta G(\mathbf{x})} \beta \frac{\partial}{\partial \mathbf{x}} G(\mathbf{x}) \right] \right\}. \quad (17)$$

By similarly distributing the leftmost derivative and cancelling terms, this becomes

$$\frac{\partial \rho}{\partial t} = \left[\frac{\partial D}{\partial \mathbf{x}} \frac{\partial \rho}{\partial \mathbf{x}} + D \frac{\partial^2 \rho}{\partial \mathbf{x}^2} \right] + \left[\beta \frac{\partial D}{\partial \mathbf{x}} \frac{\partial G}{\partial \mathbf{x}} \rho + \beta D \frac{\partial^2 G}{\partial \mathbf{x}^2} + \beta D \frac{\partial G}{\partial \mathbf{x}} \frac{\partial \rho}{\partial \mathbf{x}} \right]. \quad (18)$$

These terms can be reduced to

$$\frac{\partial \rho}{\partial t} = \frac{\partial}{\partial \mathbf{x}} \left[D \frac{\partial \rho}{\partial \mathbf{x}} \right] + \frac{\partial}{\partial \mathbf{x}} \left[\beta \frac{\partial G}{\partial \mathbf{x}} D \rho \right]. \quad (19)$$

The diffusion coefficient, D , in the high-friction limit⁸⁴ is

$$D = \frac{k_B T}{m\gamma} \quad (20)$$

where m is the mass of the diffusing particle and γ is the friction coefficient. Substituting (14) and (20) into (19) gives

$$\frac{\partial \rho}{\partial t} = \frac{1}{m\gamma} \left[-\frac{\partial}{\partial \mathbf{x}} F(\mathbf{x}) + k_B T \frac{\partial^2}{d\mathbf{x}^2} \right] \rho. \quad (21)$$

This is the functional form introduced by Smoluchowski⁹⁶ and which is routinely used for the probability distribution as a function of position.⁸⁴

The equilibrium solution can be readily obtained by setting (19) equal to zero, which then becomes

$$\frac{\partial \rho}{\rho} = \frac{\partial \beta G(\mathbf{x})}{d\mathbf{x}} d\mathbf{x}. \quad (22)$$

Integration of both sides followed by applying an exponential to get rid of the logarithms yields the equilibrium condition, which we define for a normalized population density as

$$\rho = \rho_0 e^{-\beta G(\mathbf{x})}, \quad \int_{\text{all space}} d\mathbf{x} \rho = 1 \quad (23)$$

6.3 Singular Value Decomposition

The method of solution to the Smoluchowski equation addressed in the following section relies on the use of singular value decomposition (SVD). SVD is a matrix factorization process that considerably reduces a dataset to its most fundamental components, which allows for the substantial reduction of the size of a dataset without sacrificing meaning. This reduction can be useful for identifying the essential components of a dataset, but in our case was used to improve the computational efficiency of a numerical solution to the Smoluchowski equation that would not be readily feasible in multiple dimensions.

An $m \times n$ matrix M can be singular value decomposed to three new matrices which satisfy the relationship

$$M = B S V^\dagger \quad (24)$$

where B is an $m \times m$ matrix containing the orthonormal basis vectors of M , S is an $m \times n$ diagonal matrix with the singular values on the diagonal, and V^\dagger is the orthonormal basis set expansion in terms of B .⁹⁷ The singular values describe the weight of each basis vector in reconstructing the information in M . By convention, the basis vectors are sorted by order of descending weight and basis functions below a certain threshold are discarded because they are not essential for reconstructing the valuable information in M . In the application described in the following chapter, that cutoff threshold is related to the signal to noise ratio.

Figure 24 illustrates a basic application of SVD. Every matrix has a singular value decomposition, but the example shown here is relevant to the diffusion of a probability distribution on a potential surface that is described in the following chapters. The matrix M contains the data shown in Panel A, which shows

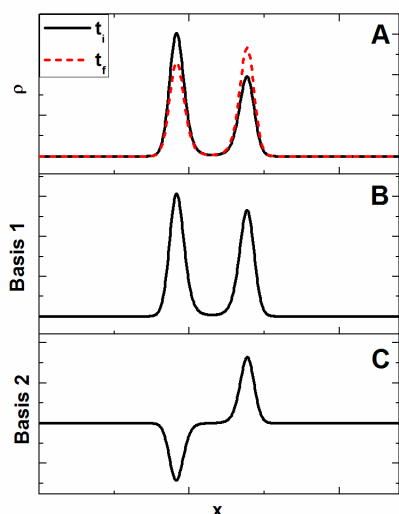


Figure 24. Demonstration of the application of a singular value decomposition (SVD). Panel A shows a probability density at time t_i (black line) that will evolve into the probability density at t_f (red dashed). The minimum SVD basis set required to describe this information is shown in panels B and C. By adding various magnitudes of Basis 2 to Basis 1, the two peaks in Panel A can be shifted up and down with respect to each other. Basis 1 has a larger singular value than Basis 2 because it describes the primary characteristics of the dataset, while Basis 2 describes the change. Any additional basis functions created would have very small singular values because they are not essential to recreating the complete dataset that can be described by the two peaks in Panel A.

the probability distribution for a population at two different times, though one could think of this as a spectrum or any other piece of information. After SVD, the first two basis functions--those with the largest singular values--are shown in Panels B and C. By adding Basis 1 and Basis 2 together in various combinations, any relative distribution of peak heights could be created, including those shown in Panel A. No additional information is needed, so even for a much larger set of data, a small SVD basis set can recreate it. For more complicated data sets, more basis functions may be required, but the magnitude of information required to reconstruct the original data will often be substantially smaller than the complete set of information. Moreover, SVD is an efficient method for isolating the important components of a complicated set of data that evolves with some auxiliary condition that may be hard to pick out by eye. In our method, the SVD decomposes the probability density, ρ , at different temperatures, which then evolves in time in accordance with the Smoluchowski equation.

6.4 Genetic Algorithm

There are a number of ways to optimize a set of parameters to create a best fit to a set of data. When the parameter search space is large and may contain many extrema, however, many of these methods are inefficient or error prone. Genetic algorithms provide one means of efficiently searching a large parameter space while minimizing the risk of convergence on a false maximum that can trouble hill-climbing algorithms when the initial guess is far from optimum. Genetic algorithms are meant to mathematically mimic the biological variability in the genetic code due to mating, crossover, and mutation, which provides a way to search a large parameter space. The ability to sample a large parameter space is essential for the fitting problems of the following chapters, particularly those with multiple experimental probes and multi-dimensional potential surfaces.

The genetic algorithm employed in the Smoluchowski dynamics calculations was based around the open-source software pikaia.⁹⁸ Each of the adjustable parameters in the fitting routine is a number, which we call a gene. All of the parameters together for one guess is called an individual (its genotype is encoded as a chromosome of all the combined genes) and a complete set of individual guesses makes up a

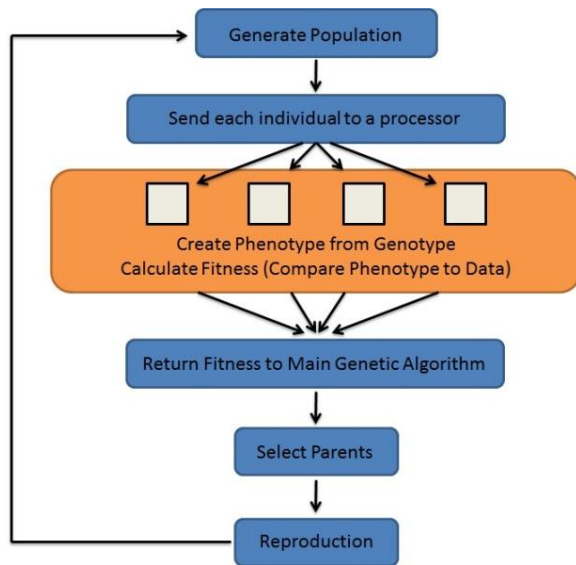


Figure 25. Overview of a parallel genetic algorithm. In a parallelized version (shown in the orange box), each individual's fitness can be evaluated on a separate processor. The fitness of the individual determines its probability to be selected for reproduction.

population for one generation. Each of these genes is initially generated randomly within a given range and with a given distribution around an initial guess. The fitness of each individual is determined by calculating a set of data (the phenotype) based on the dynamics described in the following chapter and comparing that data to experimental data. The more fit that an individual is, the more likely it is that it will be selected for reproduction. When two individual parents are selected to reproduce to create a new generation, their chromosomes are combined by crossover. In crossover, the digits from a parameter are swapped between two parents at some randomly selected point in the number. Additional genetic variability is introduced through mutations, wherein some chromosomes have one digit randomly changed

as a point mutation.

These types of genetic algorithm searches lend themselves to parallel computing, which allows for a substantial improvement in the time required for the best fit to be achieved. Every generation of the algorithm creates a population of parameter guesses, each of which must be computed, the results returned and then compared. Each member of the population can be sent to a separate processor in a cluster to do the computation on the parameters and return the fitness. For a generation of 50 members,

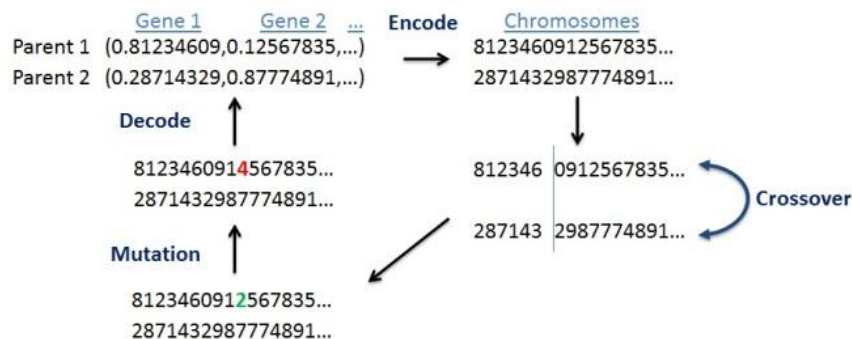


Figure 26. Schematic of the method of reproduction in a genetic algorithm. Two individuals from the population are selected as parents. Their genes, which are the numbers associated with each fitting parameter, are encoded as chromosomes by combining the genes. A crossover point is selected and numbers are swapped between the parent chromosomes. Mutations are allowed to occur with a given probability (which can vary), and the chromosomes are decoded back to the individual genes and the new individuals are inserted into the population for the next generation.

each containing a set of parameters, 50 processors can be employed in parallel to compute the fitness of each parameter set. In this way, all of the fitnesses for the entire generation can be computed in roughly 1/50th the time that a single processor can evaluate the generation in series.

To implement the advantages of parallel processing to the Smoluchowski dynamics fitting, a parallel version of pikaia⁹⁹ was modified. The parallelization was performed with the Message Passing Interface (MPI) and the parameter sets were passed to processors on the Inferno cluster. Figure 25 depicts an overview of the genetic algorithm and Figure 26 illustrates the reproductive mechanisms for the exchange of genetic material and thus the creation of new guesses in the parameter space.

6.5 SVD Smoluchowski Dynamics Model

Based on the principles described above, we present an efficient method that propagates the Smoluchowski equation in a few dimensions. The method is designed to simulate relaxation processes, in which the free energy surface G is suddenly switched, and the probability distribution evolves to a new equilibrium. It relies on singular value decomposition^{100,101} to produce an orthonormal basis set for the probability density ρ . For each propagation in time, the basis set transformation needs to be carried out only once. The time propagation itself occurs with a master equation-like propagator matrix grid typically 100–500 times smaller per dimension than a finite element grid, leading to savings of $>10^4$ in time for two dimensions. The reduction in basis set size makes the method suitable for combination with optimization algorithms that require large numbers of propagations. A genetic algorithm coupled with our singular value Smoluchowski propagation of ρ optimizes free energy surfaces by comparison with thermodynamic and kinetic experimental data.

Consider a free energy $G(\mathbf{x}, d)$ dependent on a perturbation parameter d . d could be the temperature, an applied force, or some other external variable. The perturbation is switched on at time $t=0$, so the surface switches from $G(\mathbf{x}, 0)$ to $G(\mathbf{x}, d)$. The idea is illustrated in Figure 27: the probability density starts out at equilibrium on the surface $G(\mathbf{x}, 0)$, and will evolve after the jump to a new equilibrium on the surface $G(\mathbf{x}, d)$.

To construct a set of basis functions for propagating ρ in time, consider the set of density operators that solve Equation (16) at equilibrium for different values of d ,

$$\rho_{eq}(\mathbf{x}, d) = \rho_0(d) e^{-\beta G(\mathbf{x}, d)} \quad (25)$$

An optimal basis can be constructed by using singular value decomposition of this set. Let $G_i = G(\mathbf{x}, d_i)$ be one of n free energy surfaces where $d_i = d(i-1)/(n-1)$. $i=1$ corresponds to the surface before the perturbation is turned on, $i = n$ corresponds to the free energy surface after the perturbation is fully turned on. To each

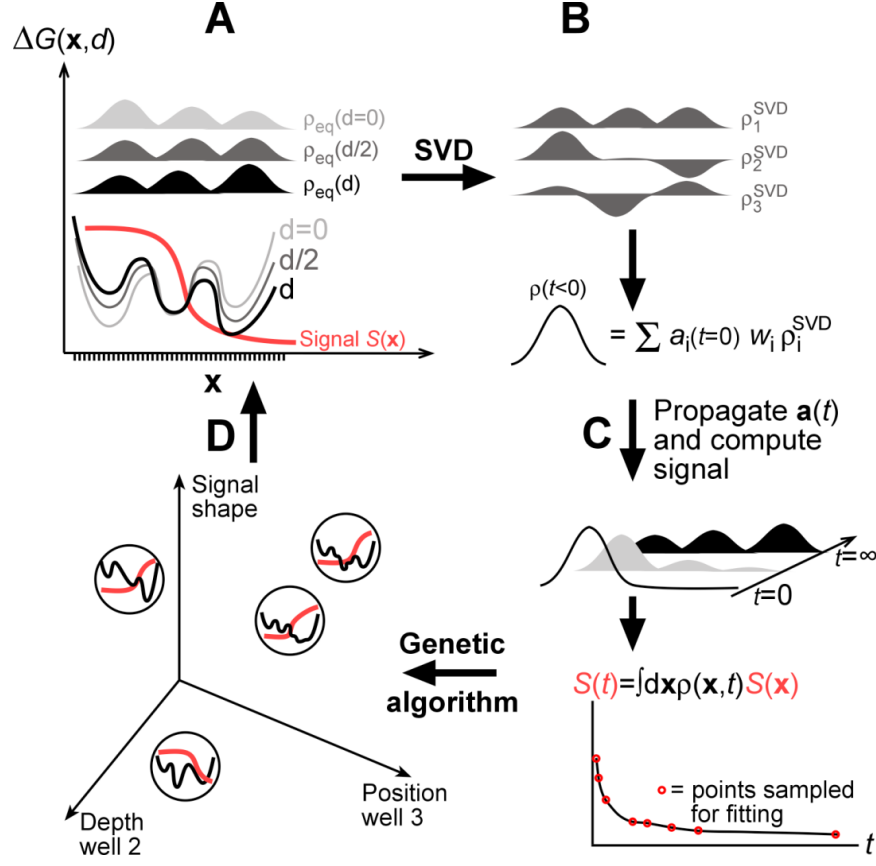


Figure 27. Schematic of the combined Smoluchowski propagation and genetic algorithm optimization. (A) The free energy $G(x, d)$ will be jumped from $d=0$ (light) to d (black); $n = 3$ surfaces and the corresponding ρ_{eq} are calculated on a grid “ x ” Signal functions $S(x)$ are defined. (B) The matrix obtained from ρ_{eq} is singular value decomposed, yielding a small basis with expansion coefficient vector $a(t)$ for $\rho(x, t)$. (C) $a(t)$ is propagated by a master equation; signals are evaluated by integrating $S(t) = \int dx \rho(x, t) S(x)$ only at time points sampled for data fitting. (D) Signals from a family of free energy surfaces/signal functions are compared with data by a genetic algorithm that selects the ‘fittest’ as well as creates new family members for the next generation. The procedure is then repeated until highly ‘fit’ surfaces that match the data well emerge.

G_i belongs to a $\rho_{eq}(\mathbf{x}, d_i)$, as shown in Figure 27. After discretizing the n different $\rho_{eq}(\mathbf{x}, d_i)$ onto a suitable sampled coordinate grid of size m ,[†] we can group the n vectors into a $m \times n$ matrix ρ_{eq} . We then singular value decompose ρ_{eq} as

$$\rho_{eq} = \rho^{SVD} w a^\dagger \quad (26)$$

[†] The simplest grid would just be evenly spaced as shown in Figure 27. Importance-sampled grids or finite element grids are superior. Whichever way the coordinates are sampled and whatever the dimension N of the grid is, all the coordinates can simply be arrayed into a vector of length m into one of the columns of the matrix ρ_{eq} .

The matrix ρ^{SVD} has n orthonormal basis vectors $\rho_{i=1\dots n}^{SVD}(x_{j=1\dots m})$ as columns. The $n \times n$ matrix w contains singular values to judge the importance of the basis vectors in pSVD. The $n \times n$ matrix a^\dagger contains the orthonormal expansion coefficients of ρ_{eq} in terms of the basis vectors ρ^{SVD} .

The key savings is that $n \ll m$ because the density operator tends to be much smoother than the coordinate grid required to converge integration of Equation (16). This is particularly true in relaxation experiments, where the surface $G(\mathbf{x})$ is generally perturbed only by a small amount d . Furthermore, the matrix w provides an objective means for a cutoff to reduce basis set size. As $d \rightarrow 0$, all but the first two singular values w_i rapidly approach zero. When fitting data with a signal-to-noise range SR , one needs to keep only singular values $w_i > w_{max}/SR$.

Expanding the density operator in terms of the singular value basis,

$$\rho(\mathbf{x}, t) = \sum_{i=1}^n a_i(t) w_i \rho_i^{SVD}(\mathbf{x}) \quad (27)$$

and inserting into Equation (16) we obtain

$$w_i \frac{\partial a_i}{\partial t} = \sum_{j=1}^n w_j G_{ij} a_j(t) \quad (28)$$

where the $n \times n$ propagator matrix G_{ij} is given by

$$G_{ij} = \int d\mathbf{x} \rho_i(\mathbf{x}) \hat{O}(\mathbf{x}) \rho_j(\mathbf{x}) \quad (29)$$

and the initial condition is given by

$$a_i(0) = (a^\dagger)_{i1}. \quad (30)$$

The advantage of Equation (28) is that it reduces a large continuum propagation problem back to a very small master equation propagation. Instead of propagating state populations, the master equation propagates expansion coefficients of ρ in a small orthonormal basis. The matrix G_{ij} is expensive to calculate, but only needs to be computed once. The actual propagation over many small time steps is inexpensive, and a back-calculation of $\rho(\mathbf{x}, t)$ is only necessary at those times t where a signal must be evaluated for comparison with data.

Finally, there are practical considerations to optimize performance. To speed up the calculation, Equation (16) should be reduced to a form without exponentials, such as

$$\frac{\partial \rho}{\partial t} = \frac{\partial}{\partial \mathbf{x}} \left\{ \frac{\partial \beta G}{\partial \mathbf{x}} D(\mathbf{x}) \rho + D(\mathbf{x}) \frac{\partial}{\partial \mathbf{x}} \rho \right\} \quad (31)$$

which is the same form as shown in Equation (19).

The derivatives of G can be evaluated analytically if possible, together with the functions $G(\mathbf{x}, d)$ and $D(\mathbf{x}, d)$. In Equation (28), a large dynamic range w_j/w_i can cause stiffness problems for the differential equation solver. For typical $SR \leq 100$ encountered in experimental kinetics data, one should either select only $n' < n$ basis functions with $w_i/w_{max} > 0.01$ for the basis, or redo the singular value decomposition with a smaller n so $w_{min}/w_{max} > 0.01$. With that truncation of basis set size, we found that even a simple Runge-Kutta integrator is adequate. Mapping m^N position data from an evenly spaced grid sequentially into the row dimension of matrix ρ_{eq} performs well for 1-3 dimensions. For higher dimensions, a smarter mapping is needed. For example, the pyramidal algorithm¹⁰² decomposes the free energy surface into wavelets and retains only those high frequency wavelet coefficients where rapid variation $G(\mathbf{x}, d)$ warrants it. Another alternative is to importance-sample the grid using $-\ln G(\mathbf{x})$ because the reduction to a master equation (28) does not rely on any particular grid sampling or spacing.

Equation (28) couples the advantages of simple master equation propagation with the ability to calculate relaxation dynamics after switching an arbitrarily-shaped free energy surface at $t=0$. Low barrier dynamics can be computed exactly for simple diffusion processes, without resorting to transition state models. In effect, the master equation (28) propagates orthogonal components of the density matrix instead of propagating probability density in space directly.

Chapter 7: Applications to Protein Folding

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Some figures were created in part by the cited contributing authors.

7.1 Introduction

While the Singular Value Smoluchowski Dynamics (SVSD) method could be used for a variety of low-barrier kinetic simulations, we developed it for the purpose of examining protein folding kinetics. There has been growing interest in proteins that can fold “downhill” without crossing a significant barrier,¹⁰³⁻¹⁰⁵ yet traditional methods of transition state theory are not practical for these low-barrier kinetic events. To demonstrate the applicability and practicality of the theory described in Chapter 6, we fit free energy surfaces to the experimental data for two fast folders, α_3 D and PTB1:4W.

7.2 α_3 D

α_3 D is a 73-residue *de novo* protein, the structure of which was not designed based on any other protein, which folds into a three helix bundle.^{106,107} It is a very fast (a few μs^{-1}) folder and has been predicted as a likely candidate for downhill folding.^{94,108} The fast folding implies a low folding barrier along the free energy reaction coordinate(s), which makes it a candidate for SVSD, as two-state models are insufficient. Previous attempts to fit all of the thermodynamic and kinetic data were insufficient because the parameter space was large, so we were able to apply our SVSD method through a genetic algorithm search.

We applied SVSD to a biophysical problem that requires calculation of many thermodynamic and kinetic data points to fit experimental data (Figure 28). The Gai and Gruebele labs and recently showed that fluorescence- and infrared-detected folding relaxation kinetics of the three helix bundle protein α_3 D have very different temperature dependences.⁹⁴ In that experiment, the protein solution was subject to a small temperature jump, and the protein population evolved on the free energy landscape towards a new equilibrium. The infrared-detected rate was nearly temperature-independent between 327 and 344 K, whereas the fluorescence-detected rate slowed down by more than a factor of 3 when the temperature was raised over the same range (Figure 28A). When the protein thermally unfolded, infrared and fluorescence

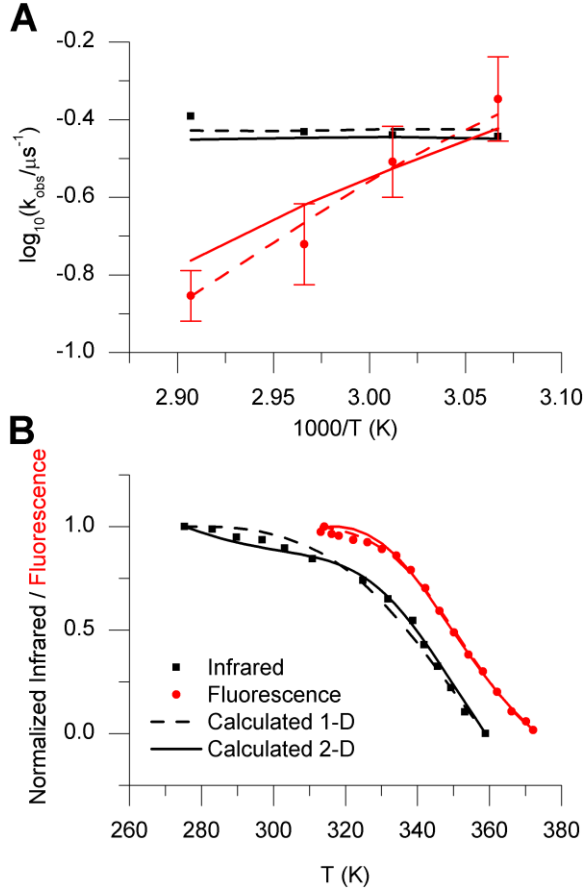


Figure 28. Measured and computed signals for $\alpha_3\text{D}$. (A) Infrared kinetic rates (black points) and fluorescence kinetic rates (red points), compared to a 1-D (dashed) and 2-D (solid) fit. The 2-D fit has a more realistic diffusion coefficient (see text). The actual kinetic data fitted consisted of relaxation decays sampled at many data points, see for example Figure 2 in ref. ⁹⁴. (B) Infrared thermal unfolding data and fluorescence thermal unfolding data and fits using the same labeling.

measurements yielded different unfolding curves in the 275 to 372 K range (Figure 28B). No satisfactory 1-D fit was obtained by trial-and-error with Langevin dynamics and a diffusion coefficient fixed at $0.05 \text{ nm}^2/\text{ns}$,⁹⁴ the value for free diffusion of two small helices in solution.¹⁰⁹ We speculated that at least a 2-D surface would be required to fit the data.

Our goal here was to sample 1-D and 2-D model free energy surfaces and signal functions more exhaustively than was possible by Langevin dynamics. We combined our Smoluchowski propagator with a genetic algorithm that evolved a family of up to 100 free energy surfaces. The genetic algorithm mutated and combined the free energy surface parameters for up to 3000 generations, selecting those surfaces that best reproduced the experimental data summarized in Figure 28. The experimental kinetics data contained 8 traces to be fitted (one for each rate coefficient in Figure 28A). Thus $\sim 10^6$ propagations of the probability function/density matrix in 1-D or 2-D were required during optimization.

Each free energy surface was encoded as a sum of $i=1 \dots k$ Gaussian dimples of variable depth $A_i(d)$, variable anisotropic width $\sigma_i(d)$ and position $\mathbf{x}_i(d)$:

$$G(\mathbf{x}, d) = \sum_{i=1}^k A_i(d) e^{-(\mathbf{x} - \mathbf{x}_i(d))^2 / \sigma_i(d)^2} \quad (32)$$

(The bold vectors in the exponent stand for a sum of squares over N coordinates.) Because only the relative well-depths and the barriers between wells are physically significant, we restricted the Gaussian wells to a minimum depth such that the normalized equilibrium density, given by equation (23), approached zero at the edges of the sampling grid. In this study, we kept the diffusion coefficient coordinate-independent, but allowed its average value to vary.

To compute signals from $\rho(\mathbf{x},t)$ and $\rho_{eq}(\mathbf{x})$, the genetic algorithm also had to adjust signal functions $S_i(\mathbf{x})$ that describe how the infrared, thermal fluorescence, and kinetics fluorescence signals vary along the reaction coordinate. The signal functions $S_i(x)$ were chosen to be baseline sigmoids with height h , width σ , baseline slope m , and switching at position x_o . In 1-D,

$$S_i(x) = \frac{h}{1 + e^{-(x-x_{i0})/\sigma_i}} + m_i x. \quad (33)$$

We chose baseline sigmoids because they can represent both a gradual and a sudden shift in signal along the reaction coordinate. The signals $S_i(t)$ (Figure 28A) or $S_i(T)$ (Figure 28B) were obtained by integrating the time-evolving population distribution $\rho(\mathbf{x},t)$ or equilibrium population $\rho_{eq}(\mathbf{x},T)$ over the signal function as

$$S_i(t) = \int_{x_{min}}^{x_{max}} d\mathbf{x} \rho(\mathbf{x},t) S_i(\mathbf{x}) \text{ or } S_i(T) = \int_{x_{min}}^{x_{max}} d\mathbf{x} \rho_{eq}(\mathbf{x},T) S_i(\mathbf{x}) \quad (34)$$

In two dimensions, the sigmoid was directed along a vector \mathbf{c} defined by $c_1 x_1 + c_2 x_2 = 0$, and a plane $m_1 x_1 + m_2 x_2$ was allowed to tilt with two slopes m_1 and m_2 . The signal functions were truncated to $S \geq 0$ in both 1-D and 2-D simulations.

Within constraints to prevent physically unrealistic functions (e.g. $A_i < 0$), the genetic algorithm *pikaia*⁹⁸ evolved a family of free energy surfaces and signal functions to higher fitness to match the thermodynamic and kinetic signals summarized in Figure 28. In the genetic algorithm, a complete set of parameters such as m_i or A_i describing one free energy surface and its signal functions formed the ‘genes’ of one population member. Genes were subject to random mutation (change of value), or cross-over (exchange among population members). The fitness of population members in the genetic algorithm was determined by a weighted least squares comparison to the experimental data. Specifically, we maximized the fitness function

$$f = \frac{1}{\sum_i [(O_i - S_i)/\sigma_i]^2} \quad (35)$$

where O_i are the experimental data, S_i are the calculated signals, and σ_i are the relative uncertainties in the experimental data. Thermodynamic data points were fitted directly as shown in Figure 28A. Points from raw kinetic data traces such as Figure 2 in ref.⁹⁴ were fitted directly, and Figure 28B shows the resulting rate coefficients.

Figure 28 shows the calculated rates and thermodynamic traces of the fittest free energy surfaces from both the 1-D and 2-D simulations. At a first glance, the 1-D fit (dotted curves) appears to be slightly

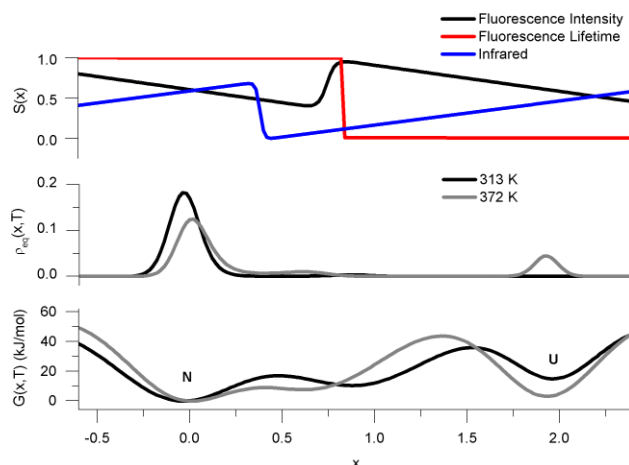


Figure 29. 1-D signal functions (A), equilibrium probability distribution at two temperatures (313 and 372 K) (B), and best free energy surface discovered by the genetic algorithm (C). The native well is labeled ‘N’ and the least folded well ‘U.’ The reaction coordinate corresponds roughly to the change in radius of gyration from the native value in nm.

curvatures change. When we guarded against this solution by constraining the diffusion coefficient to be greater than $0.004 \text{ nm}^2/\text{ns}$, the genetic algorithm could not find a 1-D solution that fit the data in Figure 2. $D \geq 0.004 \text{ nm}^2/\text{ns}$ yields folding speed limits in the $\leq 1 \text{ } \mu\text{s}$ range, the diffusional contact time measured by protein and peptide dynamics experiments.¹⁰⁹⁻¹¹²

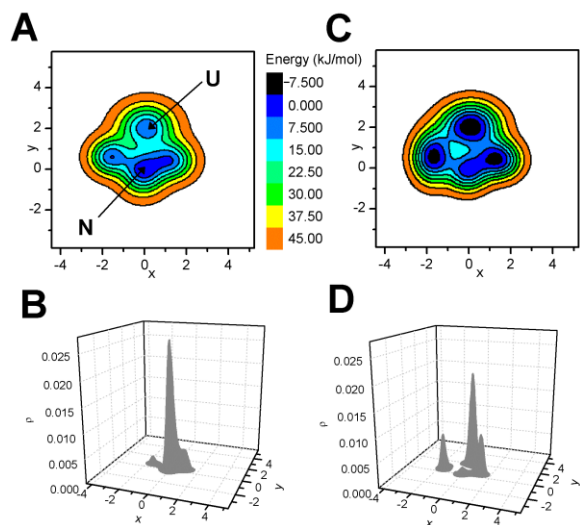


Figure 30. 2-D free energy surface at two different temperatures (313 and 372 K), together with equilibrium populations. The native well is labeled ‘N’ and the least folded well ‘U.’ The temperature range covers the thermal titration detected by fluorescence in Figure 28B.

better than the 2-D fit (solid lines), but the 1-D fit was unsatisfactory from a physical point of view: the 1D fit allows no interconversion of the folded and unfolded populations on the experimentally observed time scale of $< 10 \text{ } \mu\text{s}$.

Figure 29 illustrates the problem with the 1-D surface: the free energy barriers are up to $12 k_B T$ in height, requiring $k \approx (1 \text{ s})^{-1}$ folding times, 10^5 times slower than the experimental rates in Figure 2. The real experiment showed no evidence for a 1 s phase. The fast calculated phase that actually matches the experimental rates in Figure 2 came from diffusion of sub-populations that slightly shift within wells as the well positions and

curvatures change. Our result here confirms the trial-and-error based conclusion in ref.⁹⁴, that physically reasonable diffusion coefficients cannot yield a 1-D solution.

In contrast, we were able to obtain a physically satisfactory 2-D free energy surface. Figure 30 shows the fittest 2-D free energy surface and equilibrium probability density at two temperatures. The fitted signals displayed in Figure 28 (solid lines) reproduce the experimental trends. The 2-D free energy surface supports a large population transfer between the native and unfolded states over low barriers. It has several shallow local minima at low temperature (313 K), through which $\alpha_3\text{D}$ can nearly fold downhill from U to N. The 2-D surface reproduced the experimental trends with a fitted diffusion coefficient of $0.004 \text{ nm}^2/\text{ns}$, 20 times closer

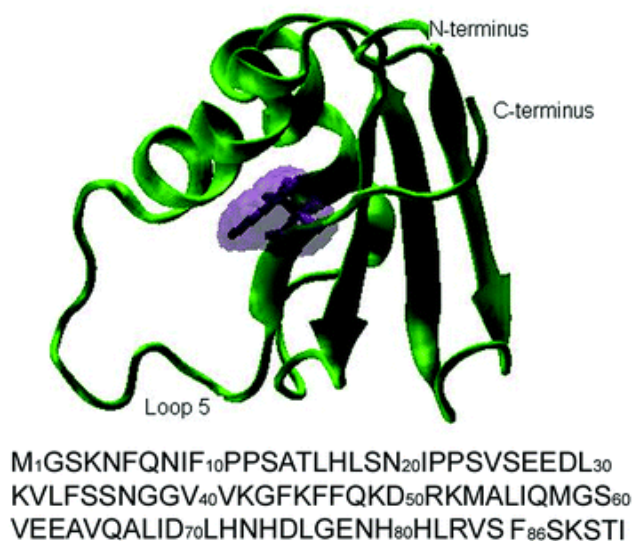


Figure 31. Protein structure and sequence of PTB1:4. The protein structure plot was prepared with VMD.¹¹⁴ Phe86 shown in purple is replaced by Trp in PTB1:4W. Comparison of the ¹H/¹⁵N HSQC NMR spectra (data not shown) of the two proteins show local chemical shift changes, but no indications of significant structural changes.

to the range expected for contact formation in a helix bundle than the 1-D surface. This is still about 10 times less than the 0.05 nm²/ns diffusion coefficient expected for freely diffusing helices. It is possible that a complete description of the $\alpha_3\beta$ folding dynamics will require either a rougher free energy surface (more local minima than shown in Figure 30), or additional reaction coordinates (more than the 2 in Figure 30).

7.3 PTB1:4W

We also utilized our SVSD genetic algorithm method to find a potential energy surface for a protein that falls between the activated folding and downhill folding regimes. This fast (sub-millisecond)

folding protein is ideal for use with the SVSD method due to its low barrier. PTB1:4W is a potential downhill folder with more residues and more complex topology than previously reported fast folders. It is a 91-residue protein with an α/β fold topology (Figure 31), comprising the fourth domain of the polypyrimidine tract binding protein, an RNA binding protein involved in both pre-mRNA splicing and translation initiation.¹¹³ The point mutation F86W was introduced in the wild type sequence so that folding thermodynamics and kinetics can be detected by tryptophan fluorescence. This mutation was conservative and led to high protein expression levels.

A number of different thermodynamic and kinetic probes were used to examine protein stability and folding kinetics. The SVSD genetic algorithm search was useful because the thermal denaturation curves were probe-dependent, which yielded a number of parameters to fit. The experimental results for which SVSD fitting was performed are reported here. The full experimental details as well as additional experimental results related to the addition of the denaturant guanidine hydrochloride (GuHCl), are available in ref ¹¹⁵.

Results

The normalized thermal denaturation curves monitored by circular dichroism (CD) (at 222 nm), integrated fluorescence intensity (excited at 280 nm) and fluorescence peak shift are shown in Figure 32.

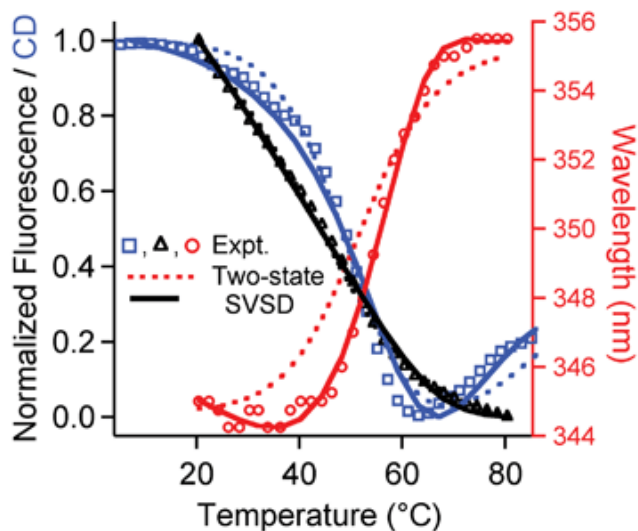


Figure 32. Circular dichroism (open squares, 3 μ M, pH 7) and fluorescence intensity (open triangles, 2 μ M, pH 7) thermal titration curves of PTB1:4W were measured simultaneously and normalized to the 0 to 1 range for comparison. The fluorescence wavelength shift (open circles) was measured separately on a fluorimeter. No satisfactory global two-state fit was achieved (dashed lines). The SVSD model produced a satisfactory fit (solid lines).

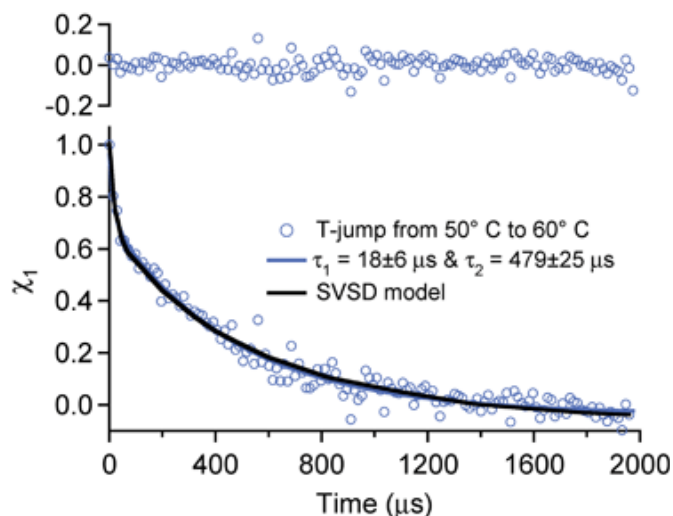


Figure 33. Folding relaxation kinetics of PTB1:4W by a temperature jump from 50 °C to 60 °C detected by normalized fluorescence lifetime change (see Methods in ref. ¹¹⁵). The solid black curve is the SVSD model fit from Smoluchowski dynamics. The top trace shows the residual of a direct double-exponential fit to $\tau_1 = 18 \mu$ s and $\tau_2 = 479 \mu$ s.

The fluorescence intensity curve has a very large negative baseline below 40 °C. Thus Trp 86 fluorescence depends strongly on temperature in the native state. A simultaneous fit of all three experimental traces to a two-state model (dotted curves) with arbitrary linear baselines for each trace does not fit the data well. Instead we used a free energy function model to fit the data (solid curves, see below).

T-jump experiments were carried out at final temperatures from 56 °C to 63 °C, where the largest relaxation signals could be observed. Relaxation kinetics are reported either as the normalized change in tryptophan lifetime (χ_1 , see Methods in ref ¹¹⁵), or as the change in integrated tryptophan fluorescence intensity.

Figure 33 shows the observed relaxation at 60 °C contains a very fast phase of 18 μ s, followed by a still fast phase of <500 μ s. The data in Figure 33 are not compatible with a two-state scenario (single exponential relaxation), but could be fitted by a double-exponential function. The observed slower rate coefficient was temperature-independent within measurement uncertainty over the temperature range we measured.

Figure 34 summarizes the T-jump and stopped flow relaxation kinetics by plotting $\log k = -\log \tau$. Only the slower phase is plotted for the T-jumps. The stopped flow rate at 23 °C does not approach the slower T-jump rates at 0 M

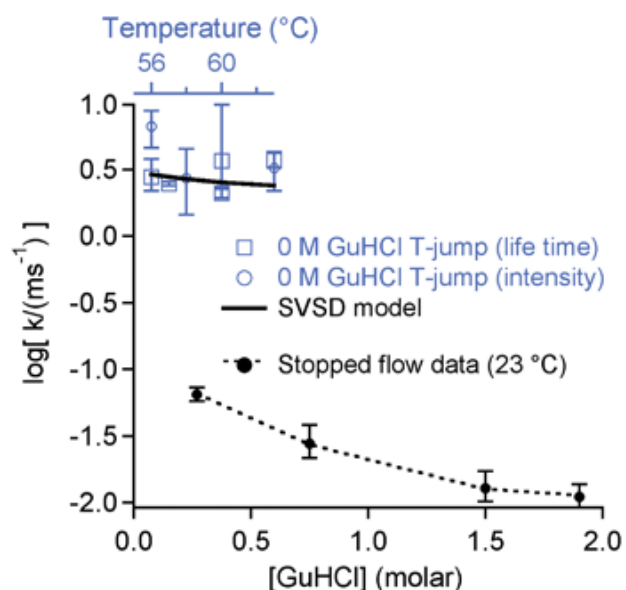


Figure 34. Summary of the kinetic data. The sub-ms phase upon T-jump is shown in open markers at the top with a temperature axis. The ms refolding kinetics from GuHCl stopped flow are shown in black circles at the bottom. The GuHCl chevron is curved throughout, and the 23 °C stopped flow data do not extrapolate to the much faster T-jump data at 35 °C higher temperature.

GuHCl, and the stopped flow data do not resemble a linear chevron plot. Thus the apparent two-state stopped flow kinetics are not supported by a linear chevron plot.

Model Free Energy Function

The multi-probe thermodynamics and T -jump kinetics in Figure 32 and Figure 33 are not fitted well by a two-state model. Our goal was to determine the simplest one-dimensional free energy function and diffusion coefficient compatible with all the thermal titration and T -jump kinetic data.

The singular value Smoluchowski dynamics (SVSD) model summarized in Figure 35 and more thoroughly in Chapter 6 uses a genetic algorithm to search the space of folding free energy functions $G(\mathbf{x}, T)$, diffusion

coefficients $D(\mathbf{x}, T)$ and signal functions $S_i(\mathbf{x})$ for the best fit to the data. The functional forms fitted are described in Appendix D. Our reference coordinate \mathbf{x} was the radius of gyration in nanometers. This choice is arbitrary, but it provides a mapping for the signal functions S onto a reaction coordinate in nm, so one can compare the magnitude of D to known diffusion coefficients. R_g is 1.5 nm for the native state based on the 1QM9 structure in the protein data bank,¹¹⁶ analyzed with VMD.¹¹⁴ For the unfolded state, we used the consensus value $R_g(\text{nm}) = 0.21 N^{0.6}$ from ref.¹¹⁷, which yielded 3.1 nm. The choice of \mathbf{x} is arbitrary in the sense that the experimental reaction coordinates are fluorescence and circular dichroism values, which could be mapped onto any reference coordinate. We chose R_g so the order of magnitude of the diffusion coefficient can be compared with literature values. SVSD calculates the time-evolving protein population $\rho(\mathbf{x}, t)$ after a T -jump, and equilibrium populations $\rho_{\text{eq}}(\mathbf{x}, T)$ at temperature T , without assigning ‘states’ and without making the transition state approximation.

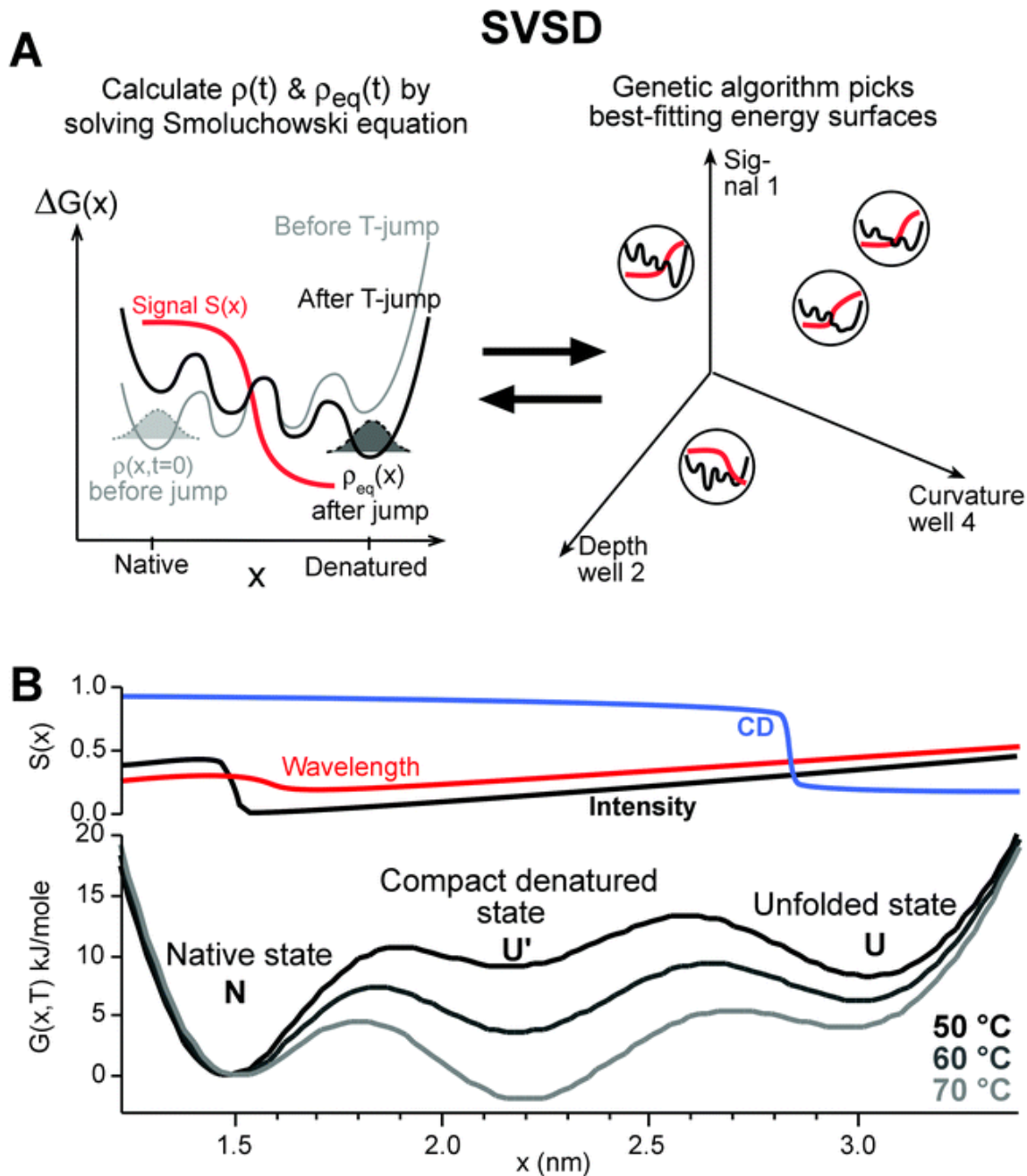


Figure 35. (A) SVSD method. Left: the protein population distribution ρ is calculated at equilibrium or during kinetics on the free energy surface $G(x)$; then $S(x) \cdot \rho(x)$ is integrated to yield the signal $S(T)$ or $S(t)$. Right: A genetic algorithm selects the best members from a population of free energy surfaces and generates the next generation to calculate signals for comparison with experiment. (B) SVSD free energy functions calculated at 50, 60 and 70 °C. Shown are the optimal functions fitted to the temperature jump and titration data in Figure 32 and Figure 33. The normalized signal functions are shown at the top.

We carried out SVSD searches in spaces of 1 and 2 reaction coordinates to globally fit the temperature-dependent data in Figure 32 and Figure 33. A 1-D surface was sufficient to fit the data. The best 1-D fits to the data are shown as solid lines in Figure 32, Figure 33, and Figure 34. Figure 35 shows the

corresponding free energy function at three different temperatures. It has three local minima, which are labelled N, U' and U. The signal functions are also shown in Figure 35. The genetic algorithm does not guarantee that these free energy and signal functions are unique solutions, but they are representative of the type of functions required to explain the experimental data. We fitted only the average diffusion coefficient of $D = 1.5 \times 10^{-5} \text{ nm}^2 \text{ ns}^{-1}$, independent of position. Different fixed values of D did not produce good fits, but the experimental data is not sufficient to determine the position dependence of $G(\mathbf{x})$ and $D(\mathbf{x})$ independently. All fitting parameters for the best fit are listed in Appendix D.

Discussion

PTB1:4W has some characteristics of a two-state folder: single exponential relaxation in GuHCl solution and coincident GuHCl denaturation curves. Other characteristics are more representative of a rough free energy surface: double-exponential T-jump kinetics and non-coincident thermal denaturation curves. This discrepancy can be explained if, in the presence of denaturant, a single large barrier partitions the reaction coordinate into a 'folded' and an 'unfolded' basin, whereas in the absence of denaturant, no single barrier dominates. The latter scenario matches the general situation the SVSD model uncovered *via* the genetic algorithm: without denaturant, a folded state and two unfolded states U and U' with energies within a few RT compete with one another. The barriers are not quite low enough for downhill folding and not quite high enough so that the local minimum U' can be assigned to a separate folding intermediate. Instead, the observed thermodynamics and kinetics correspond to a hybrid mechanism. This observation is in keeping with the observed T-jump relaxation time, which lies between the few millisecond relaxation time of fast apparent two-state folders and the few microsecond relaxation time of downhill folders.

GuHCl denaturation differs from thermal denaturation. As suggested by Tanford, proteins are more completely unfolded when they are denatured by GuHCl, while proteins under thermal denaturation have some persistent structure that may lower the folding barrier.¹¹⁸ As discussed by Naganathan *et al.*,¹¹⁹ denaturant-induced unfolding of small fast-folding proteins at room temperature entails higher activation energies than thermally induced unfolding. Our SVSD surface favors the more structured state U' over U at high temperature (Figure 35). We propose that addition of GuHCl favors the less structured state U by raising the U'-U barrier and decreasing the U free energy. Thermally, the protein denatures to U' rapidly, while in denaturant, it forms U more slowly. Our lab recently observed a candidate for residual structure in U': 'extended structure' in several proteins at high temperature has more ordered side chains than a random coil, and short segments of beta strand-like geometry.¹²⁰

The switch between two-state kinetics and nearly downhill dynamics is plausible according to the model of Wolynes and coworkers.¹⁰³ Naganathan *et al.*¹¹⁹ calculate a denaturant sensitivity of the free energy

such that even the slow rate of 12 s^{-1} we observed in the presence of 1.5 M GuHCl makes PTB1:4W a fast incipient downhill folder (barrier $<3RT$) in the absence GuHCl, in accordance with the data in Figure 34.

In downhill folding, the fastest phase ($\tau_1 = 18\text{ }\mu\text{s}$ in Figure 32) is usually labelled “ τ_m ” for “molecular phase,” indicating that it corresponds to the barrier-free ($\Delta G^\ddagger \leq RT$) diffusion time across the reaction coordinate. Experiments show that τ_m depends on the topology and the size of the protein. Small downhill folders have τ_m in the range of 0.1 to 2 μs near the thermal denaturation transition,¹²¹⁻¹²⁵ and perhaps an order of magnitude slower at room temperature.¹¹⁹ One would expect that downhill folders with more complicated topology have slightly longer τ_m . The 415 residue protein phosphoglycerate kinase has $\tau_m \approx 10\text{ }\mu\text{s}$ under denaturing condition.¹²⁶ It is possible that the 91-residue protein PTB1:4W with its $\alpha + \beta$ topology has a similarly slow molecular time scale. More likely, and supported by the SVSD fit in Figure 35, very small residual barriers remain.

SVSD does not allow the arbitrary baselines frequently used for ‘two-state’ fitting; rather, signal changes arise because the protein distribution shifts along the reaction coordinate, sampling different signals $S(\mathbf{x})$. The large fluorescence intensity baseline below the main unfolding transition (Figure 32) is caused by a switch of the SVSD signal function. Again, we have observed a candidate for such intensity changes: tryptophan sidechain fluctuations in the native state that loosen upon increasing temperature can change the fluorescence quantum yield.¹²⁷ ‘Two-state’ fits that require large baselines should be suspect, as these baselines could signal low barriers or large shifts in free energy minima, and hence a breakdown of the two-state approximation.

The actual diffusion coefficient of the PTB1:4W folding reaction should be coordinate-dependent,¹²⁸⁻¹³⁰ but even so, the average value $1.5 \times 10^{-5}\text{ nm}^2\text{ ns}^{-1}$ we fitted is at the low end of values expected for a polypeptide chain. A larger value could not fit the experimental data with a 1-D free energy function. The small diffusion coefficient can be explained in two ways. It could model additional small traps on the free energy landscape, indicating that the true free energy surface of PTB1:4W is rougher than the 3 well model shown in Figure 35. Alternatively, the collective nature of our single reaction coordinate, which reflects diffusion in a multidimensional coordinate space of protein backbone and sidechains, may result in the smaller effective diffusion coefficient in one dimension.¹³⁰ A similar result was also reported for folding of the lambda repressor fragment, where a 1-D free energy model required a diffusion coefficient much smaller than the free chain diffusion value of $\approx 0.05\text{ nm}^2\text{ ns}^{-1}$.¹⁰⁹

Chapter 8: Deriving Thermodynamics from Kinetics

8.1 Introduction

Protein or nucleic acid denaturation is often approximated by a series of transitions between thermodynamic states.¹³¹⁻¹³³ Each state shifts along the reaction coordinate when the temperature is changed. If a probe (e.g. tryptophan fluorescence lifetime) depends on the reaction coordinate, baselines arise.

These baselines are fitted traditionally by linear functions,¹³⁴⁻¹³⁶ adequate if the signal used to probe folding thermodynamics varies slowly along the reaction coordinate. If not, the baseline can be non-linear, and it can become difficult to separate from the actual folding transition. This is particularly true for small proteins, where the unfolding transition may be broad due to finite-size effects. Schuler and Eaton recently measured the unfolded state baseline under solvent conditions favoring the native state, showing that the baseline is far from linear.¹³⁷ Deviations from a linear baseline lead to inaccurate estimates of protein populations.

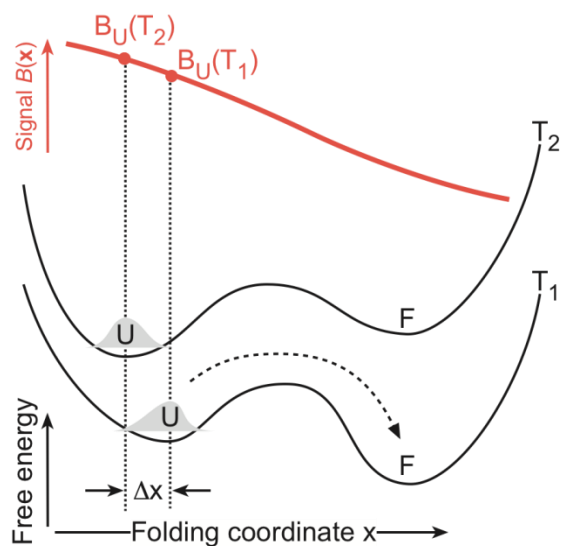


Figure 36. Kinetic separation of time scales. Black free energy curves are shown at two temperatures (T_1 and T_2) as a function of the reaction coordinate x , highlighting the unfolded portion of the thermal population (shaded). The red signal function $B(x)$ shows how the signal varies with x . Upon T-jump, the population instantly relaxes within a well (amount Δx); this fast relaxation does not populate a new thermodynamic state (e.g. F), it merely shifts the thermodynamic state (U). After the T-jump, the population relaxes much more slowly over the barrier (dotted arrow), shifting population between thermodynamic states.

In addition, complete baselines may not always be available experimentally: a protein may have a high melting point, preventing access to the unfolded state baseline;^{138,139} or protein folding is measured in a living cell, where high temperatures or denaturant concentrations cannot be reached without killing the cell,^{140,141} or a protein mutant under study may be destabilized, preventing access to the full native state baseline.^{142,143}

In such cases, kinetics can come to the rescue if all the activated folding/unfolding events can be captured. Kinetics helps because of a separation of time scales. For concreteness we discuss the two-state scenario in Figure 36 where a temperature jump induces folding. Immediately following a jump from T_2 to T_1 , relaxation within a well (the population “U” in Figure 1) is rapid, and creates the unwanted baseline if the detected signal B depends

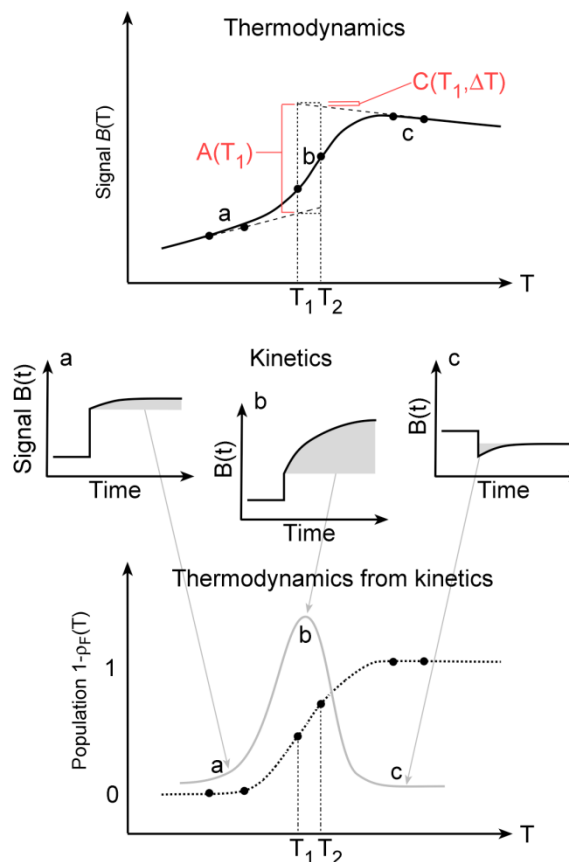


Figure 37. Comparison of traditional heat denaturation and ‘thermodynamics from kinetics.’ Top: thermodynamic folded baseline, transition and unfolded baseline. Red labels are defined by the equations in the text. a, b and c label kinetic T-jumps shown in Middle: at “a,” little population switches states, and the resolved phase is small. The instant phase is proportional to the baseline slope. At “b,” a large population switch between states is resolved. At “c,” the resolved phase is small again. The instant phase has switched sign because the baseline slope has switched sign. Bottom: By plotting only the resolved amplitude (solid curve), the baselines are reduced and only population changes (maximized at b) are selected. Integrating the amplitude curve yields the (unnormalized) population as a function of temperature. The melting point of the protein is easily identified near the maximum at b, even if the baseline at a or c cannot be fully measured.

similar to the schematic in Figure 36. The signal function, $B(x, T)$ was modeled as a straight line with a temperature-dependent y-axis intercept. For the case shown in Figure 38, the temperature-dependence of the signal function was strictly linear, while in Figure 39, a quadratic component was added to generate folded and unfolded baselines with opposite slopes.

on the reaction coordinate x . Relaxation between wells (dotted arrow “U” to “F” in Figure 1) is slow, and corresponds to the desired population transfer among thermodynamic states. If the activation barriers are large enough, kinetics can separate the fast relaxation within thermodynamic states from the slow transitions among thermodynamic states. Thus a small kinetic jump automatically separates baseline from folding amplitude, or, when such a separation ceases to exist, indicates that relaxation in a single well occurs (downhill folding).¹⁴⁴

Here we derive the necessary equations to allow accurate melting temperatures T_m to be extracted when baselines are incomplete, non-linear or noisy. We compare the ‘thermodynamics from kinetics’ approach with conventional thermodynamic fitting, showing that our approach is much more robust when baselines are incomplete. To do so, we first analyze thermodynamic and kinetic simulations obtained from the same microscopic model by solving the Smoluchowski equation.

8.2 Computational Methods

To compare the ‘kinetics from thermodynamics’ with conventional thermodynamic model fits, we simulated thermodynamic and kinetic data for fitting. A one-dimensional two-state free energy surface $G(x, T)$ was modeled as the sum of two Gaussians with the depth of one well allowed to vary linearly with temperature,

The equilibrium populations $\rho(x, T)$ at each temperature were used to determine the thermodynamic titration signal $B(T)$ (see Equations (36) and (37)). For the kinetic data, 4 degree temperature jumps were simulated with a final temperature corresponding to each of the points in the thermodynamic titration. The population change as a function of time was determined from Smoluchowski dynamics using the singular-value basis method of Chapter 6 and ref.¹⁴⁵. An exponential decay function was fitted to determine the resolved amplitude.

To compare the performance of the models with noisy data, equal amounts of Gaussian noise were added to the thermodynamic melts and kinetic traces. At each noise level, this was repeated with 10 different sets of random noise, and the models were fitted using 20 pseudo-random initial guesses for the parameters. The T_m s from the best least-squares fit among these initial conditions were averaged to report the fitted T_m . When fitting the kinetic amplitudes to determine T_m , each point was weighted by the uncertainty of the resolved amplitude from the exponential fit. When the exponential fit did not converge or the fitting error was greater than the amplitude, the resolved amplitude was set to 0 and the uncertainty of the point was set to the RMS noise. An additional point with zero amplitude and low uncertainty was added 90-100 degrees away from the edges of the data at both high and low temperature.

8.3 Model

The fitting procedure discussed here can be used to improve accuracy for any thermodynamic perturbation, such as temperature or denaturant concentration. For concreteness, we will consider temperature as our example. Furthermore, kinetic separation of in-well and barrier-crossing dynamics improves thermodynamic fitting for two-state or multi-state proteins. Again for concreteness, we describe the two-state case.

Consider the model represented in Figure 36 and Figure 37. The free energy along the reaction coordinate (which may also be formulated in more than one dimension¹⁴⁵) leads to a normalized equilibrium population

$$\rho(x, T) = \frac{e^{-\frac{G(x, T)}{RT}}}{\int_{-\infty}^{\infty} dx e^{-G(x, T)/RT}} . \quad (36)$$

The free energy and population depend on temperature (the example discussed here). The signal function $B(x)$ along the reaction coordinate thus yields an observed signal (e.g. tryptophan fluorescence, IR absorption, FRET, etc.) as a function of temperature

$$B(T) = \int_{-\infty}^{\infty} dx B(x) \rho(x, T) . \quad (37)$$

If the two-state (or n-state) approximation is valid, i.e. if the barriers are high enough, we can divide the reaction coordinate into states, such as a “folded” and “unfolded” side in the two-state case. The dividing surface will lie near the barrier.

$$\begin{aligned} B(T) &= \int_{-\infty}^{\infty} dx B(x) \rho(x, T) + \int_0^{\infty} dx B(x) \rho(x, T) \\ &= B_U(T) \rho_U(T) + B_F(T) \rho_F(T) \end{aligned} \quad (38)$$

The second line is obtained by defining $\rho_U(T) = \int_{-\infty}^0 dx \rho(x, T)$ and $\rho_N(T)$ accordingly, and setting $B_U(T) = \int_{-\infty}^0 dx B(x) \rho(x, T) / \rho_U(T)$ and $B_N(T)$ likewise. The observed signal depends on a nonlinear unfolded baseline $B_U(T)$ weighted by the unfolded population, and a folded baseline $B_N(T)$ weighted by a folded population.

The populations are related to the free energy by

$$\rho_i(T) = \frac{e^{-\frac{G_i(T)}{RT}}}{\sum e^{-G_i(T)/RT}} \quad (39)$$

and for the two-state case, a simple and frequently used model for the free energy, equilibrium constant, and population is

$$\Delta G = G_U - G_F = g^{(1)}(T - T_m), \quad K_{eq}(T) = e^{-\frac{\Delta G}{RT}}, \quad \rho_F(T) = \frac{K_{eq}}{1 + K_{eq}}, \quad \rho_U = 1 - \rho_F. \quad (40)$$

The goal is to determine the fitting parameters T_m and $g^{(1)}$ by extracting $\rho_F(T)$ from $B(T)$. In particular, linear baselines with adjustable slopes m have been used in a vast literature to approximate $B_U(T)$ and $B_F(T)$.

$$B(T) \approx (B_{U0} + m_U(T - T_m)) \rho_U + (B_{F0} + m_F(T - T_m)) \rho_F \quad (41)$$

The problem is that if data cannot be collected to map out full baselines, the baseline fitting parameters B_{i0} and m_i cannot be determined accurately. Even if the full baseline is observed, it may be steep or nonlinear in practice, and a linear extrapolation for example of the unfolded baseline into the folded region (low temperature) is inaccurate or inadequate. This has been demonstrated by single molecule experiments. The result is that T_m and other fitting parameters cannot be determined accurately.

Kinetics can help out. If kinetics can be measured that capture all well-to-well relaxation events, easily possible nowadays with nanosecond temperature jumps, the baseline to a significant extent can be separated from the population change. This is illustrated by Figure 37 a-c: at low or high T where only in-well relaxation occurs, kinetics mostly shows a sudden jump, due to the baseline. If kinetics are

measured near T_m , the well-to-well dynamics produce a resolvable amplitude. At T_m , the resolved dynamics has the largest amplitude. Plotting the resolved amplitude thus maps out the thermodynamic transition with a maximum at T_m (Figure 37). This curve can be integrated to yield the population curve. The key is that a straight thermodynamic fit depends on extrapolation of baselines into the region where folded and unfolded populations are comparable, whereas kinetics directly determines the difference of those baselines in that region.

Mathematically, the kinetic signals just before the jump, just after the jump, and at equilibrium, are

$$\begin{aligned} B(t = 0^-) &= B_F(T_1)\rho_F(T_1) + B_U(T_1)\rho_U(T_1) \\ B(t = 0^+) &= B_F(T_2)\rho_F(T_1) + B_U(T_2)\rho_U(T_1) \\ B(t = \infty) &= B_F(T_2)\rho_F(T_2) + B_U(T_2)\rho_U(T_2) \end{aligned} \quad (42)$$

Measuring kinetics independently determines a resolved and an unresolved amplitude

$$\begin{aligned} B(t = \infty) - B(t = 0^+) &= [B_F(T_2) - B_U(T_2)][\rho_F(T_2) - \rho_F(T_1)] \\ B(t = 0^+) - B(t = 0^-) &= [B_F(T_2) - B_U(T_2) + B_U(T_1) - B_F(T_1)]\rho_F(T_1) + [B_U(T_2) - B_U(T_1)] \end{aligned} \quad (43)$$

or

$$\begin{aligned} B_{resolved}(T + \Delta T) &= A(T + \Delta T)[\rho_F(T + \Delta T) - \rho_F(T)] \\ B_{unresolved}(T \rightarrow T + \Delta T) &= [A(T + \Delta T) - A(T)]\rho_F(T) + C(T, \Delta T) \end{aligned} \quad (44)$$

Eqs. (44), together with a model for the population ρ_F such as eq. (40), constitute the kinetic fitting model. The following should be clear from eq.(44). There are still two baseline functions (here A and C), just as in the thermodynamic fit in eq. (38). Unlike eq. (38), now two data points at each temperature constrain the baseline functions and populations, instead of a single data point. Also unlike eq. (38) or eq. (41), the baseline functions A and C in eq. (44) are difference functions (either between different baselines, or between a single baseline at two nearby temperatures). Thus A and C are much more likely than the original baselines to be approximated by linear functions or even constants.

The following are good approximations when a small jump ΔT is applied:

$$\begin{aligned} B_{resolved}(T + \Delta T) &\approx \Delta T A(T + \Delta T) \left. \frac{\partial \rho_F}{\partial T} \right|_{T+\Delta T/2} \\ B_{unresolved}(T \rightarrow \Delta T) &\approx \Delta T \left(\left. \frac{\partial A}{\partial T} \right|_{T+\Delta T/2} \rho_F(T) + \left. \frac{\partial B_U}{\partial T} \right|_{T+\Delta T/2} \right) \end{aligned} \quad (45)$$

In particular, $B_{resolved}$ contains a lot of useful information on its own. It is proportional to the derivative of the thermodynamic population curve. Furthermore, if the folded and unfolded baselines are far apart, or if they are parallel, then $A(T)$ is approximately or exactly constant, and can be expanded accurately as a linear baseline. Using the two-state population model in eq. (40) yields

$$B_{resolved}(T + \Delta T/2) = -\frac{g^{(1)}\Delta T T_m}{RT^2} [A_0 + m_A(T + \Delta T/2 - T_m)] \frac{e^{-g^{(1)}(T-T_m)/RT}}{(1 + e^{-g^{(1)}(T-T_m)/RT})^2} \quad (46)$$

with only four fitting parameters $g^{(1)}$, T_m , A_0 , m_A , including the last two for the baseline. This model requires 2 fewer fitting parameters than eqs. (39) and (40), the standard linear baseline two-state fit, and is expected to yield T_m and $g^{(1)}$ more reliably.

8.4 Results and Discussion

To compare the standard thermodynamic fitting (eq. (41) combined with the two-state model in eq. (40)) with the ‘thermodynamics from kinetics’ fitting (eqs. (45) or (46) combined with the two-state model in eq. (40)), two sets of test data with different baselines were simulated. The model T_m was 323 K in both cases. The results are summarized in Figure 38 and Figure 39. Panels A and B show the thermodynamic titration and the resolved kinetic amplitude $B_{resolved}$. Figure 38 corresponds to a ‘difficult’

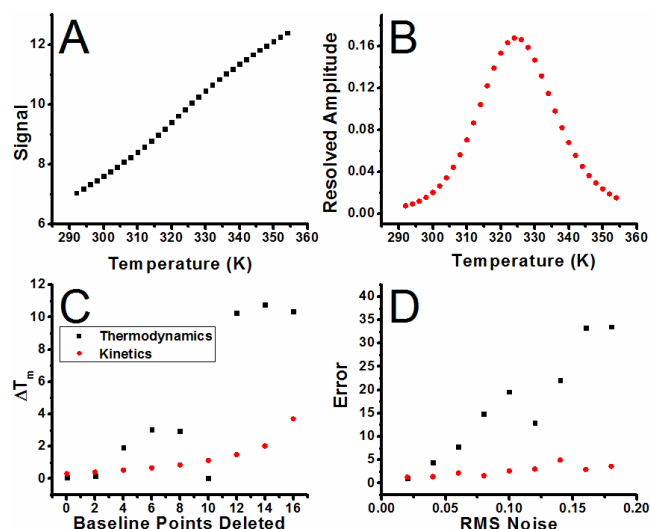


Figure 38. Model data derived by Smoluchowski dynamics from a two state free energy and signal function. The data were chosen to correspond to a ‘difficult’ case, such as FRET with a small protein. (A) Conventional thermodynamic melt. (B) Resolved kinetic amplitude. (C) Error in the fitted melting temperature as function of deleted points in the high temperature baseline. (D) Combined random and systematic error in the melting temperature as a function of noise added to the data in (A) and (B) (same rms noise for both).

case very similar to FRET experiments. In cases like these, a small amount of noise can make it difficult to identify the cooperative region. Figure 39 corresponds to an ‘easy’ case where the folded and unfolded baselines have different slope, so the transition is clearly discernible. Regardless of these differences, we observed similar relative performance between the thermodynamic and kinetic models.

Panel C of Figure 38 and Figure 39 shows the deviation of the melting temperature from the known value as data points were removed from the high-temperature unfolded baseline. This is a common difficulty with *in vivo* or living cell experiments, where high temperature measurements cannot be

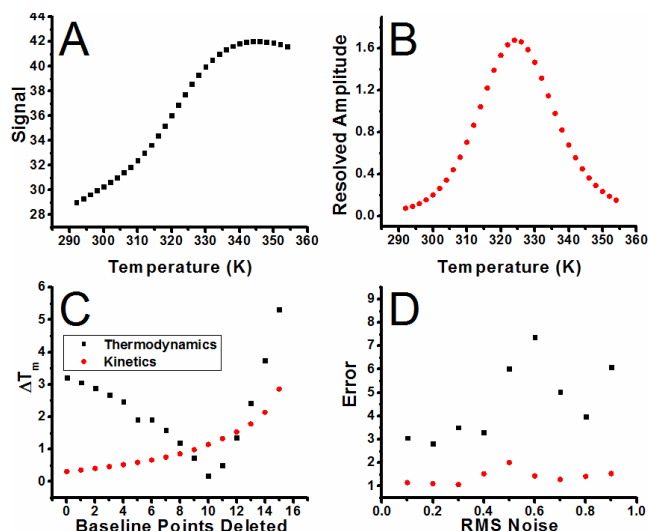


Figure 39. Model data derived by Smoluchowski dynamics from a two state free energy and signal function. The data were chosen to correspond to an ‘easy’ case, with different slopes for the folded and unfolded baselines. (A) Conventional thermodynamic melt. (B) Resolved kinetic amplitude. (C) Error in the fitted melting temperature as function of deleted points in the high temperature baseline. (D) Combined random and systematic error in the melting temperature as a function of noise added to the data in (A) and (B) (same rms noise for both).

made.¹⁴¹ The thermodynamic model became unstable quickly as the baseline was removed. The kinetics were able to fit T_m reliably until the peak of the resolved amplitude was truncated (removal of half of the data points). Similar results for both models were obtained by removing the folded baseline, or by symmetrically removing both baselines progressively.

Because experiments do not produce infinite signal to noise, we tested how the thermodynamic and ‘thermodynamics from kinetics’ fits performed with varying amounts of noise added to the test data. Panel D of Figure 38 and Figure 39 shows the error in T_m as a function of noise level. Two sources of error are included by generating multiple data

sets with different random Gaussian noise. One was the average deviation from the known melting temperature, and the other was the standard deviation of fit. The error is reported as the square root of the sum of squares of these two sources of error and is given in the same arbitrary units as the signal shown in Panels A and B. ‘Thermodynamics from kinetics’ generally makes smaller errors than a conventional thermodynamic fit at the same noise level.

The measurement of protein melting temperatures can be a challenge when the high temperature baseline is missing, or when the baselines are steep. These problems can occur in many situations: Some proteins aggregate at high concentration, and need to be measured at low concentration. Some proteins have melting points to close to the boiling point of the solvent. And with an increasing interest in folding in living cells, or even *in vivo*, the high temperature baseline may be inaccessible without killing the cell or organism under study. In such cases, it would be nice to have a method for measuring protein stability without the need for scanning the whole baseline.

For all of the cases we simulated, we found that the method of fitting ‘thermodynamics from the kinetics’ was more reliable than conventional thermal melts when baseline information is limited. Kinetics eliminates most of the baseline by shifting it into the unresolved phase, whereas the population switch

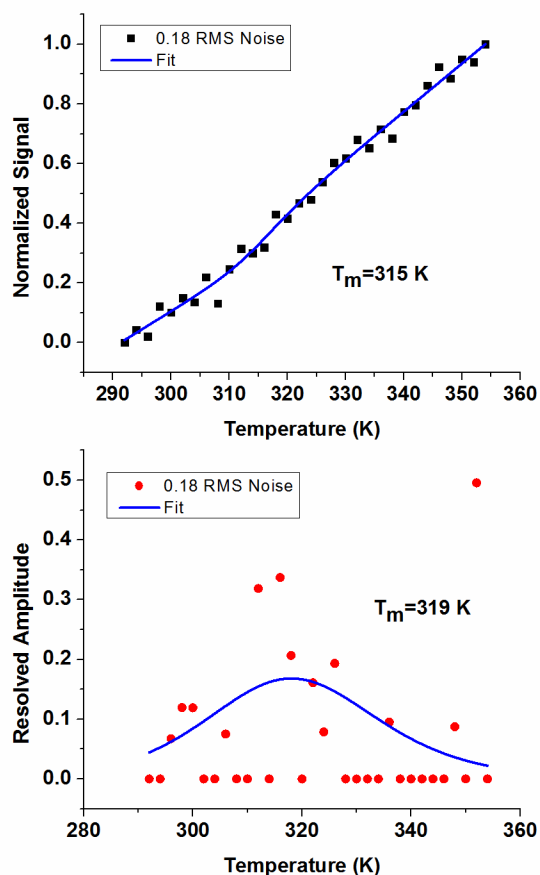


Figure 40. Comparison of noise between thermodynamic and ‘thermodynamics from kinetics’ models. An equal amount of Gaussian noise was added to the thermodynamic titration and to the raw kinetic traces from which the resolved amplitudes were taken. The baselines of the thermodynamics quickly becomes difficult to resolve, but even with large fitting errors in the kinetics, a peak is still resolvable near the melting temperature.

the derivative. Figure 40 demonstrates one point from the selected data in Figure 38. In the thermodynamic case, the upper baseline becomes completely washed out and the model fits it such that the transition region becomes part of the upper baseline. In the kinetic case, however, even when $\sim 1/2$ of the amplitudes have fitting errors larger than the amplitude of the fit and are consequently set to 0, the peak region can still be easily resolved within a few degrees.

Ironically, the experimentally relevant noise is often worse for the thermodynamic signal than for the time-resolved kinetic signal, even though the thermodynamic signal is collected over a longer time period with more signal averaging. In fact, slow data collection amplifies errors such as laser intensity or sample temperature fluctuations during data collection.

among wells falls into the resolved phase. The latter yields a nearly baseline-free signal with a peak near T_m , although large baselines of opposite sign or transitions occurring over a wide temperature range could shift the peak somewhat.

The ‘thermodynamics from kinetics’ model yields a more consistent increase of the error with baseline truncation. In Figure 39C, the nonlinearity of the unfolded baseline leads to a non-monotonic error due to the non-linear high-T baseline truncation. As further data is removed however, the unfolded baseline is lost and the thermodynamic model is unable to fit the melting temperature. The kinetic fit has a predictably increasing error when the baseline is truncated, and generally performs well until the truncation reaches the denaturation midpoint.

We added the same amount of noise mathematically to the thermodynamics and the kinetics test data. We also find that the ‘thermodynamics from kinetics’ method is less susceptible to experimental noise. This is due to the fact that experimental noise is added to a derivative of the thermodynamic signal (T-jump), rather than adding the noise to a smooth function and then taking

The kinetic model can be constrained more easily than the thermodynamic model. For a two-state system, the resolved kinetic amplitudes approach zero away from the melting temperature; for the thermodynamics, the baselines have no similarly consistent constraint. Moreover, the slope of the baseline in the kinetic model can often be constrained to zero, which reduces the fitting parameters to three. Kiran Girdhar in our lab provided experimental data for the PI3K SH3 domain, which was found to have very consistent T_m fits for the kinetics under such a constraint.

The major drawback of ‘thermodynamics from kinetics’ is that all barrier-crossing phases must be resolved. Otherwise, genuine population transfer is lumped together with dynamics within a single state in the instant response right after the T-jump (or other relaxation). Thus methods with good time resolution must be employed for the measurement.

In summary, ‘thermodynamics from kinetics’ provides simple formulas for fitting the resolved kinetics amplitude to obtain thermodynamic parameters such as T_m . The result is more robust to truncation of the baseline and noise than are conventional thermodynamic fits, and the only drawback is that the kinetics must resolve all barrier crossing events so that the instant amplitude contains only the baseline from dynamics within states.

Appendix A: Laser Alignment

The experimental design for optically-assisted STM experiments requires the coupling of one or more lasers into the STM. For experiments taking place in the infrared, a minimum of two lasers must be overlapped for effective laser alignment at the STM. One of these is the laser resonant with the molecular transition of choice, while the second is a visible laser that will aid in alignment within the vacuum system, but which will not be active during experiments. For frequency-modulated experiments a third, non-resonant laser must be overlapped for the minimization of differential heating.

For infrared experiments studying the first electronic transition in single-walled carbon nanotubes, the resonant laser is a tunable external-cavity diode laser (LiON, Sacher Lasertechnik) capable of producing radiation from 1165 nm to 1265 nm. The non-resonant laser is a fixed-wavelength diode at 1300 nm. The visible alignment laser is a helium-neon (HeNe) laser. Figure 41 shows the way in which the optical table is set up.

The resonant laser is first aligned by adjusting the position of the fiber coupler and the positioning of M1 so that the laser spot is centered on both irises, I1 and I2. The infrared spots are centered with the use of an infrared detector card (ThorLabs VC-VIS/IR). The HeNe is then centered through the two irises by adjusting M4 and BS2. With the resonant laser and the HeNe overlapped, the position of the resonant laser inside the STM UHV chamber can be determined by simple visual inspection. The non-resonant laser is then centered on the irises using M2 and M3. This results in three collinear propagating beams. Additionally, the height of the non-resonant laser is chosen such that it passes through the chopper 180° out of phase with the resonant laser.

To ensure optimal overlap of the beams, a kinematic mount with a mirror is mounted at KM and reflected off of M7 through a pinhole positioned at X. X is measured to be the same distance from KM as the STM. The light passes through the pinhole to a power meter and each of the beams is individually adjusted to maximize the power through the pinhole.

The beam spot size and divergence is measured by placing a set of razor blades on a 3-D micrometer mount at X. As the razor blades are moved with the micrometers, the 80% / 20% power positions are monitored with a power meter. L2 is on a translation stage with a micrometer to adjust the focus and therefore the spot size at X, and consequently, at the STM.

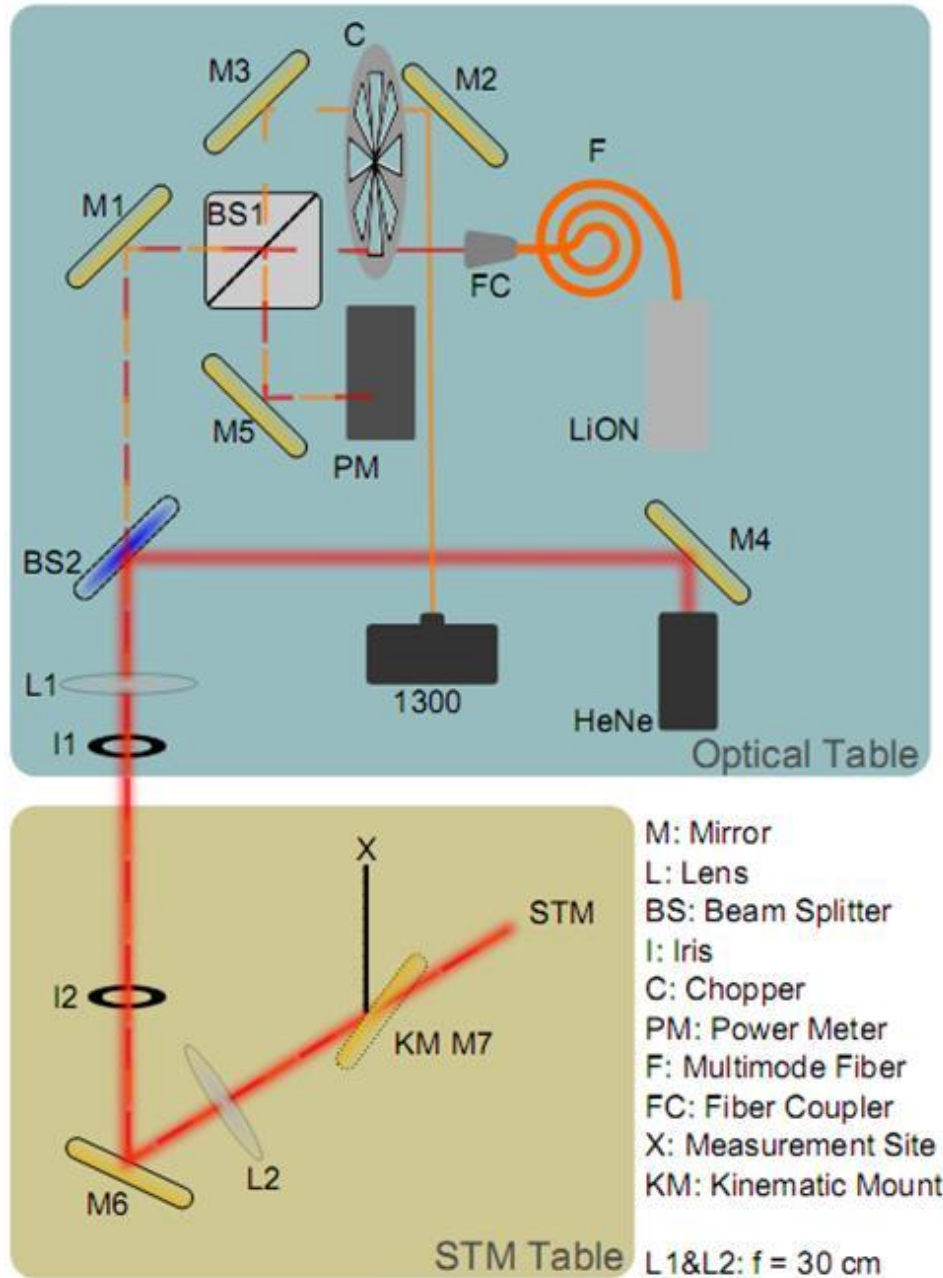


Figure 41. Optical setup for frequency-modulated optically-assisted STM experiments. The lenses are $f=30$ cm UV lenses; for optimal transmission, IR anti-reflection coated lenses could be substituted. BS1 is a broadband, non-polarizing beamsplitter cube anti-reflection coated for 1100-1600 nm (Newport 10BC17MB.3). BS2 is a dichroic mirror/beamsplitter that reflects the HeNe and transmits the IR light efficiently. All of the mirrors are gold-coated. The position X is measured the same distance as the STM at which point various comparative measurements can be made when M7 is inserted on a kinematic mount. The power meter at M5 allows the real-time power to be measured simultaneous with SMA-STM to ensure that power fluctuations do not dominate the signal.

Appendix B: Experimental Procedures

Vacuum System

All of our STM experiments are done under ultrahigh vacuum (UHV). Figure 42 shows a schematic of the vacuum system and the conditions under which valves can be opened during normal system operation. In addition to the pumps shown in Figure 42, both the prep chamber and the STM chamber have titanium sublimation pumps (TSP) contained in a cryoshroud. The TSP pumps should be run regularly to maintain a low background pressure in the chambers and is particularly important in the prep chamber, as it is subjected to the largest pressure fluctuations. The TSP is operated by filling the cryoshroud with liquid nitrogen and sputtering titanium onto the cryoshroud walls by applying 45 A of current to one of the TSP filaments.

Everything loaded into the UHV system must be thoroughly degreased and cleaned and then degassed in the prep chamber before transfer to the STM. For most samples and many other materials, sonication in acetone and isopropyl alcohol is a sufficient cleaning procedure. Ceramic parts should be baked in a furnace after solvent cleaning due to their large surface area and porosity to prevent outgassing. Newly machined parts tend to have embedded oils and should undergo additional degreasing steps before solvent cleaning. Metals can be electro-polished, acid cleaned, and degassed in 409.

Degassing is done by resistive heating on the dipstick. When possible, degassing should take place by resistive heating through the sample or through tip holders in the tip carrier. The dipstick should not exceed 150 °C and can be cooled with nitrogen while the degas is allowed to heat further locally. Materials should be heated slowly enough that the prep pressure does not spike much above 1×10^{-8} torr. This heating is done with a DC power supply by passing current through the two terminals in the rotary stage feedthrough that are opposite each other. For things that cannot be heated directly by resistive heating, the power supply can be switched to the two terminals labeled “F” on the rotary stage feedthrough, which will resistively heat a filament inside the dipstick. Materials in good thermal contact with the dipstick will be heated by indirectly by the filament. Due to the Viton seals in the rotary stage, this method is restricted to heating to 150 °C.

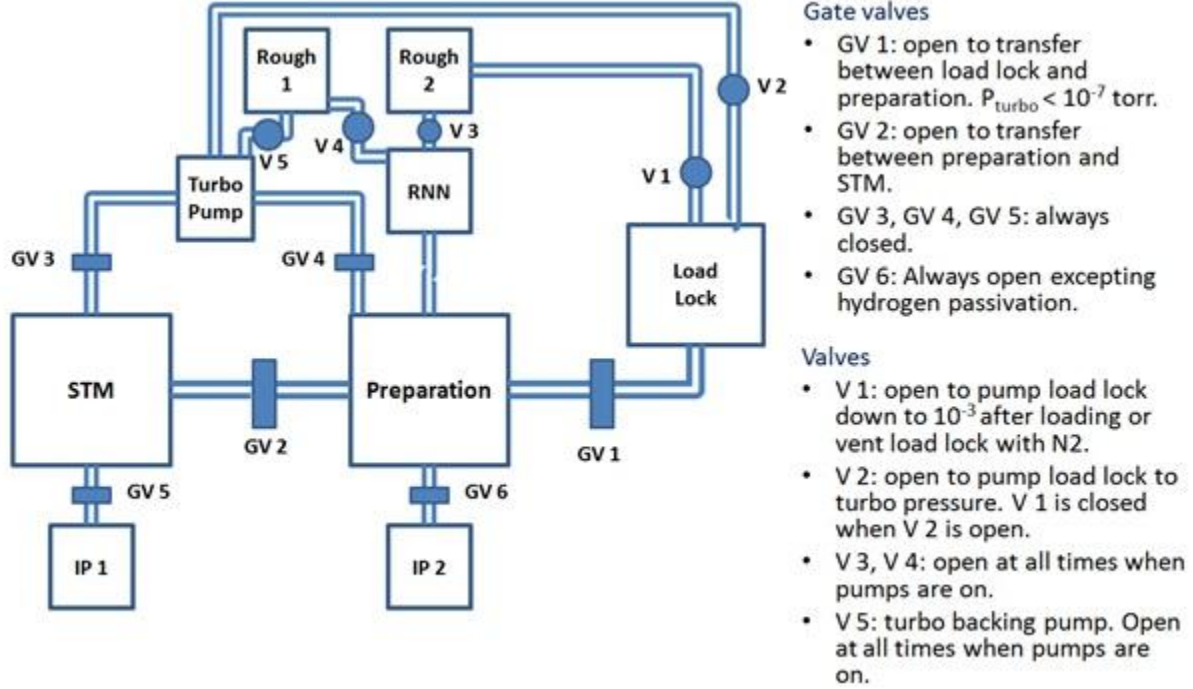


Figure 42. Schematic of the vacuum system and valves of the UHV-STM. The circles represent inline valves and the solid rectangles represent VAT gate valves. The normal operational positions of the valves are listed to the right as well as the parameters under which valves can be opened.

Preparation of wedged Si

Figure 43 shows the geometry of the rear-illumination SMA-STM setup. Total internal reflection at the sample face must be achieved, which happens when the angle D is greater than the critical angle, which is given by

$$\theta_c = \sin^{-1}\left(\frac{n_2}{n_1}\right) \quad (47)$$

where n_2 is the index of refraction for the vacuum, and n_1 is the index of refraction for the silicon. Using values of 1.000 and 3.559, respectively, the critical angle is 16.3° . Based on the experimental angles of A and B, angles C and D be derived from trigonometric relationships and Snell's law as

$$C = 90 - A - B$$

$$D = A + \sin^{-1}\left(\frac{n_2 \sin(90 - C)}{n_1}\right) \quad (48)$$

The other consideration in the choice of angles is the loss of light due to reflection at the wedge itself, which can be determined from the Fresnel equations, given in Equations (4) and (5). For the current

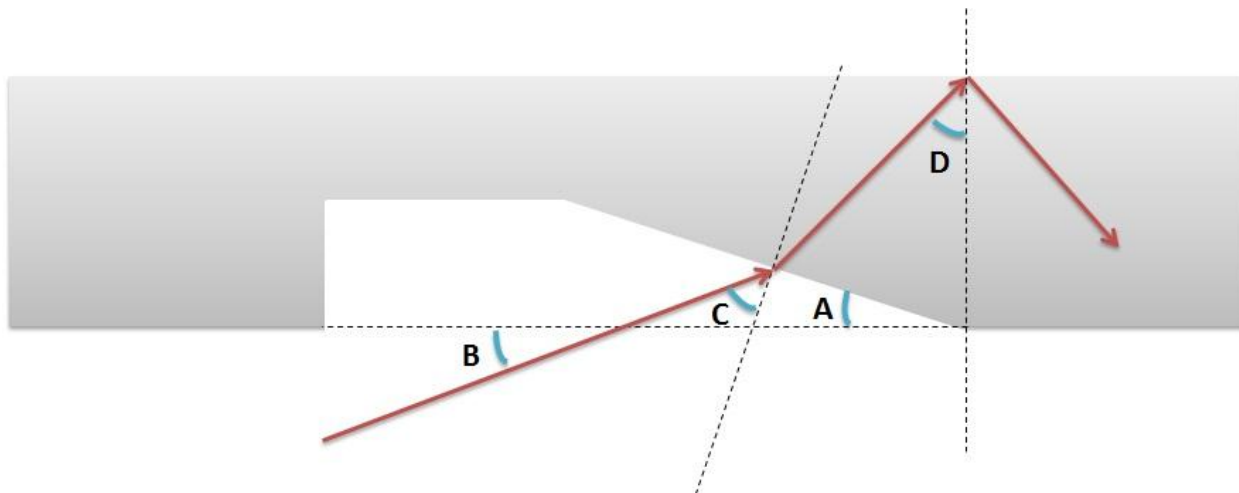


Figure 43. Laser geometry for experiments on silicon. Angle A is the machined wedge angle. B is the angle at which the laser is introduced into the STM. C is the incident angle on the wedge and D is the angle at the face of the silicon which must exceed the critical angle for total internal reflection.

optical setup, the wedge is 15° and angle B is 31° , which gives an angle at D as 26.2° , which exceeds the critical angle for total internal reflection.

We typically machine the wedge at angle A to be $\sim 15^\circ$. The machining process involves bonding a silicon wafer polished side-down onto another sacrificial silicon wafer. Crystalbond 509 (SPI Supplies) is a wax that is readily soluble in acetone and melts at 121°C . The scrap wafer is heated on a hot plate and a stick of Crystalbond is rubbed over the surface to flow on a layer of the wax. The sample wafer of silicon is then placed face-down on the wax and the wafers are removed from the heat. Using the known thicknesses of the wafers and by measuring the thickness of the bonded system, the wedge can be diced on a diamond dicing saw.

Figure 44 demonstrates the way in which the wedge is diced into the wafer. After calibrating the height of the dicing saw chuck in accordance with the saw's operating procedures, the bonded wafers are adhered to the saw chuck with the integrated vacuum. At a feed rate of 0.25 in/sec at a spindle speed of 17 kRPM, 20 cuts are made 0.002" apart to make a clearance area for the laser beam. The wedge is then cut by reducing the y-spacing to 0.001" and creating a staircase pattern at the desired angle. It is possible to machine more than one wedge on a 4" wafer. The sample is then removed and the wedge is thoroughly polished with a Dremel using $1\ \mu\text{m}$ alumina paste and a polishing wheel until the wedge achieves a smooth, mirror-like finish. The wafers are then returned to the dicing saw and diced into $0.3'' \times 0.2''$ samples that will fit into the STM sample holder. To ensure that the cuts are sufficiently deep enough, cuts should be made into the sacrificial silicon wafer underneath. The samples can be removed by heating

the wafers on a hot plate and sliding the samples off. The Crystalbond can be left on the samples until their use at which point the Crystalbond can be removed with acetone.

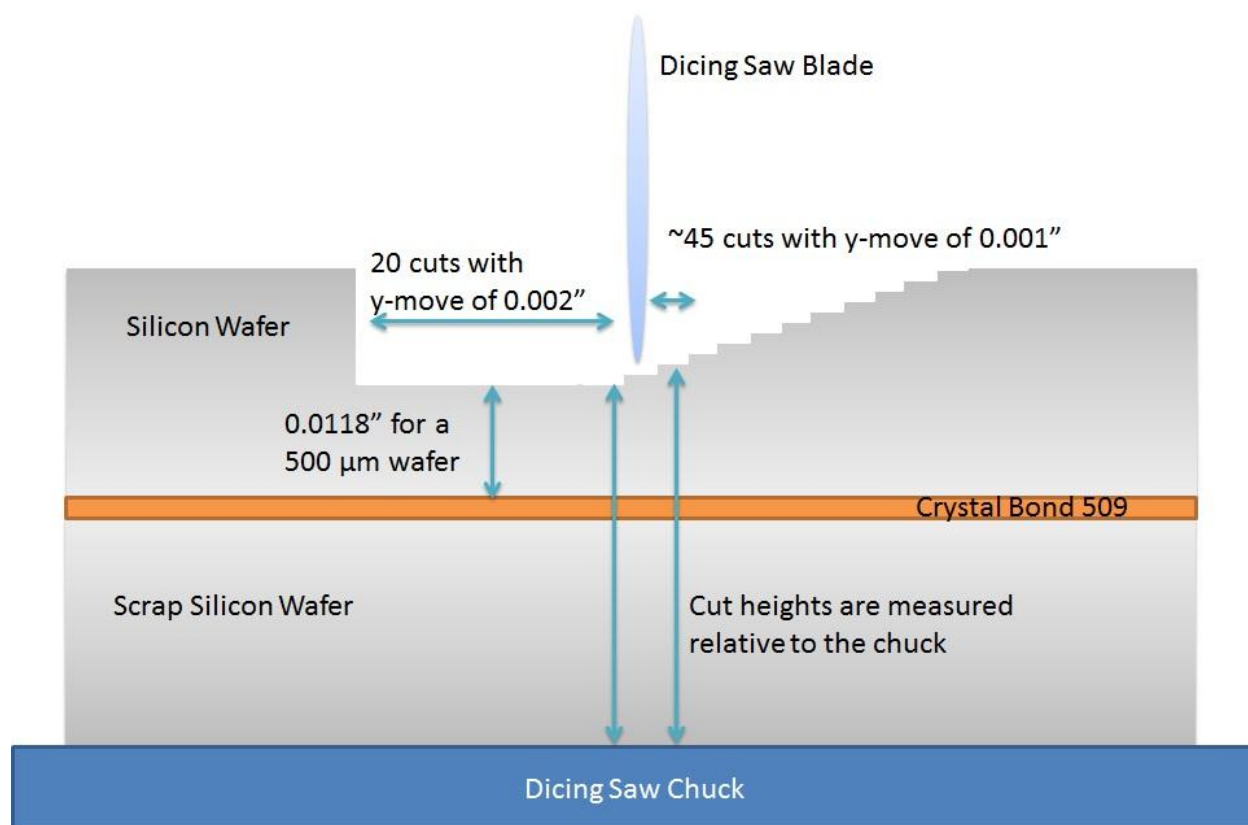


Figure 44. Wedge dicing schematic for silicon. Two silicon wafers are bonded polished sides together with crystal bond 509 wax, then vacuum adhered to a diamond dicing saw chuck and the wedge is machined by dicing stairsteps across the wafer. After polishing the wafer, the wafers are returned to the dicing saw to cut into pieces that will fit into an STM sample holder.

Preparation of Si(100)2x1:H

We passivate our silicon samples with hydrogen *in situ* to create the cleanest possible surface. This involves loading a clean sample, flashing and annealing the sample in vacuum to create the clean reconstructed surface, and chemisorbing a monolayer of atomic hydrogen on the surface. We follow the same passivation procedure described elsewhere,¹⁴⁶ though the details of the procedure are relayed here.

The silicon samples are diced based on the procedure described in the previous section. The samples are thoroughly cleaned of the Crystalbond wax with acetone and then are further cleaned with isopropyl alcohol. For wedged samples, we avoid sonication to prevent the fragile samples from cracking along the machined wedge. The silicon samples are handled with Teflon tweezers at all times to avoid nickel

contamination that might result from the use of stainless steel tweezers. The sample is then put into UV ozone for ~20 minutes for further cleaning and to create a protective oxide layer that will be removed during the sample flash. Two pieces of clean 0.25 mm thick 99.997% Ta foil (Alfa Aesar) are folded and placed over the edges of the sample to improve contact with the sample holder clamps.

The sample holder with the Si sample is loaded into the UHV preparation chamber and degassed on the dipstick at ~600 °C for ~6 hours. The degas takes place by resistive heating through the silicon sample on the dipstick by a DC power supply in constant current mode. The sample temperature is monitored with a pyrometer at an emissivity setting of 0.7. The temperature of the dipstick and the chamber pressure are monitored during the procedure to ensure that neither goes too high. Because of the Viton seals in the dipstick rotary stage, the dipstick temperature should stay below 150 °C. To prevent the base pressure of the prep chamber from rising substantially, the pressure should not readily exceed 1×10^{-8} torr.

During the sample degas, the cracking filament can be briefly degassed for a few seconds at ~18 V from a Variac. When the sample degas is complete, the degas power is turned off and the dipstick is cooled to room temperature with nitrogen gas and the flow of gas should be maintained during the flash. To minimize the background pressure in the prep chamber, the cryoshroud is filled with liquid nitrogen. The sample is flashed by resistive heating with the DC power supply to ~1200 °C as monitored by the pyrometer and then slowly cooled (over ~30 seconds) to achieve a 2x1 surface reconstruction on the (100) surface. If a clean silicon surface is desired, the sample can be moved to the STM chamber at this point.

During passivation, we want to achieve only monohydride formation. At room temperature, only the dihydride forms, which can lead to etching of the surface, but at ~650 K, only the monohydride is formed.¹⁴⁷ During the sample flash, a temperature vs power relationship can be determined using the pyrometer and extrapolated to this temperature. In practicality, setting the current between 0.4 and 1.0 A for wedged silicon samples usually produces excellent surface passivations. The ion pump gate valve is typically closed during the passivations to improve the lifetime of the pump, though the valve can be left open during the passivation if adequately clean samples are not routinely produced. The chamber is backfilled to between 2 and 4×10^{-6} torr with high purity hydrogen from a leak valve on the preparation chamber from a manifold pressurized to 20 psi. The cracking filament is set to ~12 V to achieve a temperature of ~1500 K and the sample is passivated for 10 minutes to achieve monolayer adsorption of hydrogen. After passivation, the leak valve is closed, the gate valve to the ion pump is opened, and the sample is returned to room temperature. When the base pressure of the prep chamber has recovered, the sample can be transferred to the STM for scanning.

Sample Annealing

Sapphire

To achieve optimal flatness, sapphire substrates should be annealed above 1200 °C.¹⁴⁸ We have found, however, that we achieve suitable flatness by annealing in the tube furnace in the Lyding lab at its maximum setpoint of 1000 °C. We score the back of the sample in the corner with a diamond scribe before annealing to make easy the future determination of the sample face. The annealing is performed by loading the samples on a quartz plate and sliding it into the furnace at the location of the thermocouple with the furnace at room temperature. Acceptable parameters include using the normal ramp rate of the furnace, the temperature maintained for several hours at 1000 °C, and passive cooling by allowing the furnace to slowly air cool.

In situ annealing

Some samples that are prepared *ex situ* do not produce good imaging under normal degassing conditions and do not produce high resolution images until after the samples have been annealed in vacuum. One example of this are the graphene films described in 4.2 . These samples can be annealed by resistive heating of the sample to several hundred degrees. For samples that cannot support sufficient current for this type of heating, a silicon backing can be mounted behind the sample and the annealing temperature can be achieved by resistive heating of the backing. In these cases, the temperature can be monitored with a pyrometer.

Prism attachment to sapphire samples

Figure 45 shows a schematic of the attachment of a prism to sapphire with an optical epoxy. A number of different optical epoxies can be used, though these descriptions will involve Epo-Tek 302-3M, which has an index of refraction $n=1.556$, which is nearly index-matched to the $n=1.51$ of the glass prism. For other epoxies, Snell's law can be used to calculate the change through the epoxy. The sapphire has $n=1.76$. Using a similar geometric methodology as that presented for the wedge in the silicon, the relevant angles are given by

$$\begin{aligned} B &= 45 - A \\ C &= \sin^{-1} \left(\frac{n_{vacuum} \sin(B)}{n_{prism}} \right) \\ D &= \sin^{-1} \left(\frac{n_{prism} \sin(45 + C)}{n_{sapphire}} \right) \end{aligned} \tag{49}$$

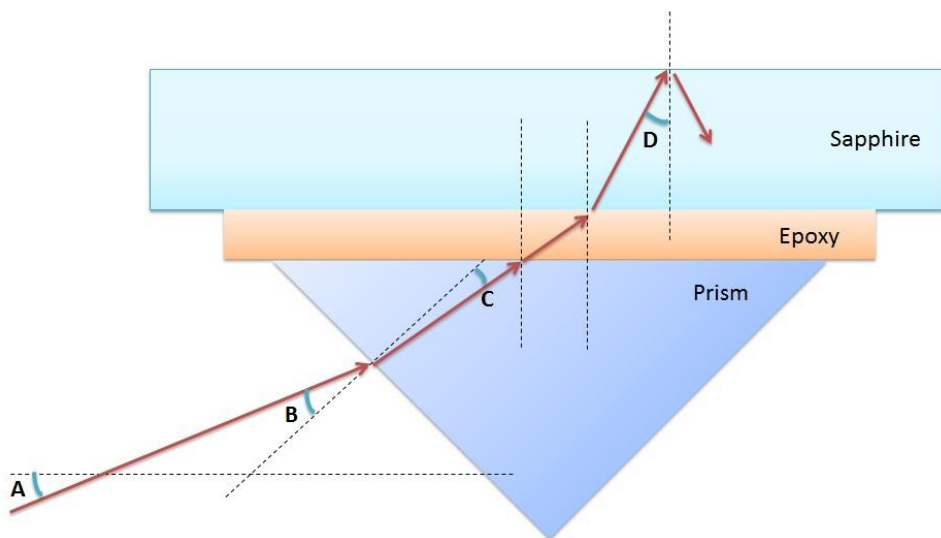


Figure 45. Total internal reflection geometry for a prism on sapphire. The prism is a right-angle prism and the change in angles through the epoxy is negligible for Epo-Tek 302-3M because the prism and the epoxy are nearly index matched.

From Equation (47), the critical angle for total internal reflection is 34.6° . For the current optical setup with angle $A=31^\circ$, B is 14° , C is 9.2° , and D is 44° , which exceeds the critical angle. One notable difference between this experimental design methodology and the silicon platform is that there is substantially less loss at all polarizations when the light is incident on the prism than on the higher dielectric material, silicon, as determined by the Fresnel equations.

The easiest way to attach the prism to the samples is after they are already loaded into the sample holder by applying a bead of the mixed epoxy to the back of the sample while the sample holder is suspended vertically with the sample facing down. The prism can then be dropped in place. While the epoxy should cure quickly, the small surface area exposure to the air slows this process and the prism will slide if it is not properly cured. With the sample holder in the same geometry, it can be placed in a small vacuum chamber or in a warm furnace to speed the curing process. Once the epoxy is properly cured, the prism on the sample can be used in the STM and can be safely heated during degas without the prism sliding.

For removal and re-use of the prism, Epo-Tek 302-3M can be dissolved with vigorous soaking in methylene chloride and this removal process is made easier if the initial bead of epoxy applied is large enough to provide solvent access to the epoxy.

STM Tip Preparation

STM probes can be easily created by electrochemical etching of tungsten wire in a “drop-off” method.¹⁴⁹ Degreased 0.009” diameter tungsten wire (Small Parts, Inc.) is held by a set of alligator clips and suspended vertically through a gold ring held by another set of alligator clips so that the wire drops a few

mm's below the ring. The ring is dipped into a small beaker with 3 M NaOH prepared with ultrapure deionized water (18 M Ω -cm) to create a meniscus of electrolyte. The gold ring is attached to the cathode of a DC power supply and the wire is attached to the anode. A bias is applied to etch the wire to a narrow neck at which point the wire will break and the bottom piece will drop, creating a tip which can be caught in a micropipette tip with a piece of Kimwipe stuffed into it. The tip can then be picked up with tweezers and rinsed in a steady stream of deionized water with the tip facing away from the source of the stream.

We have found that drop-off voltages of 3-3.5 V reproducibly create usable tips. The etching process can be accelerated substantially, however, by using an arbitrarily larger voltage (that will not break the electrolyte meniscus) until the tip neck is narrow. After that point, the voltage can be reduced to the 3 V range. Unless a cutoff circuit is employed, the top piece of wire immersed in the electrolyte cannot be used as a tip because it will be dulled by additional etching after the drop-off.

We have attempted a number of methods for improving the quality of the tips including characterizing them by Transmission Electron Microscopy (TEM). We have been unable to find a correlation between the quality of the tip's sharpness as it appears in TEM and the STM imaging quality or stability. Literature that reports great tip production based on TEM, Auger, or other characterization methods should be viewed with some skepticism unless it provides convincing results that the tips have been used with superior success as STM probes.

Preparation of Dry Contact Transfer Applicators

The method by which we deposit carbon nanotubes, and which can be used for other materials as well, is dry contact transfer (DCT). The applicators are simply frayed pieces of fiberglass wire insulation tied to a tip holder. A piece of fiberglass insulation can be frayed with a razor blade. This piece can then be made into a loop with the frayed area exposed and tied onto a tip holder with a piece of wire. The set screw can be removed from the tip holder and the wire passed through the set screw hole. It is important to ensure that the wire will not impede the ability of the wobble stick fork to pick up the tip holder. After assembly, the applicator can be sonicated in acetone and isopropyl alcohol, then dried with dry nitrogen.

After assembly and cleaning, the DCT applicator can be loaded with carbon nanotubes by rubbing it gently against the inside of the CNT container. Previous protocols in our lab dictated repeatedly loading the applicator and blowing off excess bundles with nitrogen, but this procedure is unnecessary. Some large bundles will transfer off the applicator, but the majority of transfer will be of isolated CNTs. The applicators can be loaded with tips in the tip heater and degassed by the same resistive heating procedure by heating through the tip holders.

Deposition by Matrix-Assisted Sublimation

While DCT is an effective method for the deposition of CNTs and other materials such as exfoliated graphene, it does not work for all nanomaterials. We were unable to deposit PbS quantum dots (QDs) onto the surface of hydrogen passivated silicon by DCT, so we developed a new method for *in situ* deposition of these materials, which we have named Matrix-Assisted Sublimation (MAS).

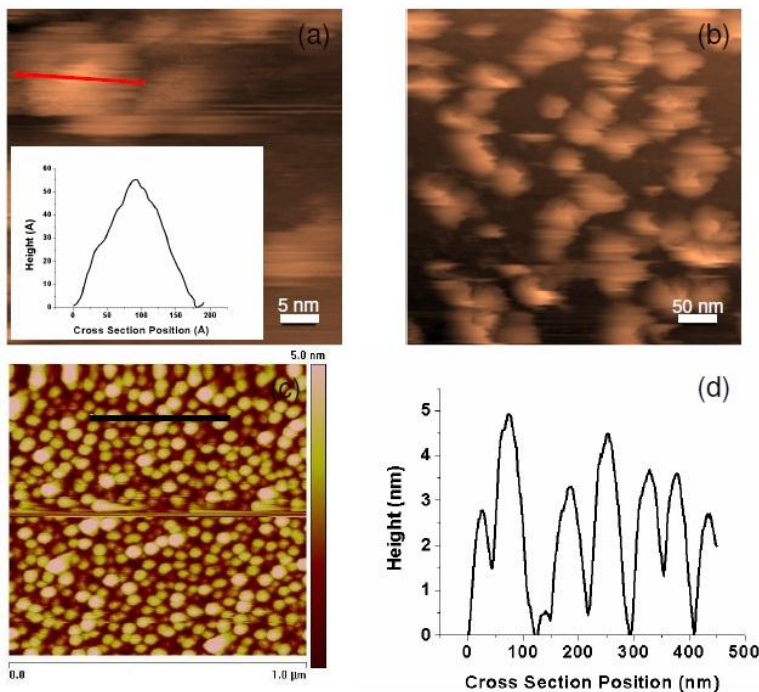


Figure 46. Si:H(2x1) surface after sublimation of 5.3 nm PbS quantum dots in a matrix of C₆₀. STM topographs in (a) and (b). Inset in (a) shows height on the order of that expected for the QDs. AFM topograph in (c) with highlighted cross-section in (d). The surface appears to be completely saturated with quantum dots and no apparent features are small enough to be C₆₀.

Thermal sublimation is a technique commonly used for the deposition of C₆₀ onto unpassivated silicon.¹⁵⁰ The 4-6 nm PbS infrared absorbing quantum dots (Evidots, Evident Technologies) are too large for vacuum sublimation. PbS quantum dots were packed into a matrix of C₆₀ and loaded into an alumina capillary tube which is resistively heated in vacuum and directed toward the sample face on the dipstick. The alumina tube is wrapped with a wire and attached to the two sides of a sample doser. When the matrix reaches the sublimation temperature of the C₆₀ (~250 °C), the QDs will be released into the vacuum. The C₆₀ molecules do not readily physisorb to the H-passivated surface and can only chemisorb to the surface at the reactive dangling bond sites. The more massive QDs will physisorb to the surface leaving isolated nanoparticles on the surface for SMA-STM experiments.

Figure 46(a) and (b) show STM topographs after sublimation deposition. Figure 46(c) shows an AFM image that also shows the surface saturated with spherical particles of the expected diameter of the QDs as indicated by the cross-section in Figure 46(d). This proof-of-concept experiment shows that MAS is a feasible approach to QD deposition

Additional characterization of deposition parameters will be required to ensure that the surface is not over-saturated with QDs. This will likely require a DC power supply that is more precise than our 100 mA precision supply. Because C_{60} sublimates at ~ 250 °C and the PbS QDs decompose at ~ 300 °C, accurate calibration of the molecular doser's resistive heating element will be necessary. While it is possible to deposit isolated QDs on H-passivated Si for STM study using pulse valve injection,¹⁵¹ the matrix-assisted sublimation will be a much cheaper process that requires no modifications to our UHV system. This technique could prove useful not only for depositing quantum dots, but it may also be applicable to other molecules too large for sublimation for which DCT is not effective.

Elevated Temperature Deposition of Metal Films

The heater design for elevated temperature deposition is described in 4.1 . When loading it into the CHA evaporator in the MNTL cleanroom, the rotatable wafer holder must be moved out of the way of the steel plate. This can be achieved by setting the sample rotation switch to fixed and choosing an arbitrary number, then flipping the switch to the “off” position when the sample rotation bar is horizontal. When facing the front of the evaporator, the wires should be run down the right side of the supports inside the vacuum chamber to the feedthrough and the four wires clipped onto the feedthrough connections. If the wires on the ambient side of the feedthrough are not visible, the cabinet cover can be removed to retrieve them. It is important that when the cover is replaced, the interlock switches are properly pressed or the “CAB” interlock will not light when the e-beam power is turned on and the e-beam will not activate. A DC power supply and thermocouple reader can then be attached to the four wires after checking that there are no shorts and that the heater resistance reads $0.8\ \Omega$.

Because the heater resistance is temperature-dependent, we use the DC power supply in constant-current mode. As the heater increases in temperature, the voltage will increase substantially. The applied current should be increased and decreased by slowly turning the power supply knob and not exceeding 3 A of current. Before turning on the mains power to the DC power supply, it is important to check that the current knob is set to zero and did not get rotated during transportation.

Deposition should be performed per the instructions and training provided for the CHA evaporator by the MNTL Cleanroom staff. All films shown in Chapter 4 were deposited between $0.6\ \text{\AA}/\text{sec}$ and $1.0\ \text{\AA}/\text{sec}$. The power should be ramped up carefully when melting any metal, but particularly with Pt and Nb

because they have extremely high melting points. If the power is increased too quickly, the source will spit off chunks of metal or if the e-beam is slightly misaligned, the crucible can be melted. They should also be cooled slowly to avoid cracking the crucible. Also of note, Nb is incompatible with normal graphite crucibles and a Fabmate crucible should be used to avoid melting the crucible when the Nb wets to the crucible.

Appendix C: Matlab Code for STS Spectra Maps

Spectra_Map.m

```
% spectra_map.m
%
% Plots a spectra map from a line of spectroscopy points dumped to a text
% file from STM software. You must delete the top line of the exported
% file that says V I(A) vs V, etc.
%
% Note that the colorbar is really 10^value
%
% Gregory E. Scott
% 10/22/2008

% Input information

pathi=['C:\TEMP\']; %input file path
patho=['c:\temp\']; %output file path

filei=['11_29_10.sts.TXT']; % name of file containing spectroscopy points
fileo=['11_29_10.sts.png']; % name of file for output image

points = 40; % number of spectroscopy points
spacing = 10; % distance between points in Angstroms

% Piece together filenames

namer=[pathi,filei];
nameo=[patho,fileo];

% Map Creation

X=zeros([1 points]); %Create X values for relative spacing between spectroscopy points converted to nm
for n=1:points
    X(1,n)=(n-1)*spacing/10;
end;

fid=fopen(namer, 'r');
YZ = fscanf(fid, '%e', [points+1 1000]); % Import I and V
fclose (fid);

Y=YZ(1,:); % Set voltages as Y values
YZ(1,:) = []; % Discard voltages from matrix
Z=YZ'; % Transpose matrix and set currents as Z values

SMap=surf(X,Y,log10(Z)); % Plot spectra map
view(2); shading interp; colormap(jet);
set(gca,'XLim',[0 (points-1)/10*spacing]);
set(get(gca,'xlabel'),'String','Relative Position (nm)');
set(get(gca,'xlabel'),'FontSize',18);
set(get(gca,'ylabel'),'String','Voltage (V)');
set(get(gca,'ylabel'),'FontSize',18);
set(gca,'FontSize',18);
cb=colorbar;
```

```
set(get(cb,'xlabel'),'String','I(A)');  
set(get(cb,'ylabel'),'String','10','Rotation',0);  
set(get(cb,'xlabel'),'FontSize',18);  
set(get(cb,'ylabel'),'FontSize',18);  
set(cb,'FontSize',18);  
  
saveas(gcf,nameo,'png');
```


Appendix D: Fitting Parameters for PTB1:4W

Potential surfaces were encoded as a sum of Gaussian dimples of variable depth $A_i(T)$, variable anisotropic width $\sigma_i(T)$ and position $x_i(T)$. For the 1-D there-well surface in Figure 35,

$$G(x, T) = - \sum_{i=1}^3 A_i(T) e^{-(x-x_{0i}(T))^2 / \sigma_i(T)^2} \quad (50)$$

The temperature dependence of the parameters P_i in (50) was expanded in a Taylor series to first order, with a reference temperature T_0 of 20 °C:

$$P_i(T) = P_i(T_0) + P_i(T_0)(T - T_0) \quad (51)$$

Because only the relative well-depths and the barriers between wells are physically significant, we restricted the Gaussian wells to a minimum depth such that the normalized probability density approached zero at the edges of the sampling grid. In Figure 35, the depth is offset so that the native well has a minimum at zero energy. We kept the diffusion coefficient coordinate-independent, but allowed its average value to vary.

Signal functions $S_i(x)$ were chosen to be sigmoids with offset S_0 , height h , width σ , slope m , and switching position x_0 .

$$S_i(x) = S_{i0} + m_i x + \frac{h}{1 + e^{-(x-x_{i0})/\sigma_i}} \quad (52)$$

Signal functions shown in Figure 35 were normalized to the range 0 to 1 from the fitted values.

Table 1 gives the minimum and maximum values allowed in the genetic algorithm for the final optimization resulting in the fit presented in 7.3 Initial guesses were determined using larger ranges by optimizing one set of signal data a time with double-well potentials. Parameter ranges were alternately constrained to narrow the parameter space until acceptable optimization was realized.

Table 1.

	Parameter	Minimum	Maximum	Optimized Value
Well 1	A_0	50	50	50
	dA	0	0	0
	σ_0	0.3520	0.4850	0.3921
	$d\sigma$	0	0	0
	x_0	1.4200	1.4200	1.4200
	Dx	0	0	0
Well 2	A_0	27.0000	34.0000	29.8018
	dA	0.5000	0.6500	0.5600
	σ_0	0.5060	0.5650	0.5638
	$d\sigma$	0	0	0
	x_0	1.8900	2.0700	2.0141
	dx	0	0.0026	0.0010
Well 3	A_0	42.0000	46.0000	42.8055
	dA	0.2000	0.6000	0.3119
	σ_0	0.5286	0.6390	0.6153
	$d\sigma$	0	0	0
	x_0	3.0000	3.1700	3.0496
	dx	-0.0044	0	-0.00145
Flourescence Intensity Signal	S_0	15	15	15
	m	0	4.5400	0.6129
	σ	0.00001	0.0440	0.0130
	x_0	1.2330	1.7620	1.3283
	h	-15.0000	0	-12.4829
CD Signal	S_0	25.0000	25.0000	25.0000
	m	-13.6200	0	-6.1562
	σ	0.00001	0.0440	0.0108
	x_0	2.2030	3.0840	2.8193
	h	-25.0000	0	-24.0662
Flourescence Wavelength Signal	S_0	25.0000	25.0000	25.0000
	m	0	22.7000	11.7064
	σ	0.00001	0.0661	0.0141
	x_0	1.1000	1.7621	1.3933
	h	-25.0000	0	-11.0785
Diffusion Coefficient (nm ² /ns)	D	8.8×10^{-6}	1.76×10^{-5}	1.23×10^{-5}

Appendix E: Fortran Code for Singular Value Smoluchowski Dynamics

Compilation Sciprt for Inferno

```
#!/bin/bash

#$ -S /bin/bash

mpif90 pik3.f90 sm21.f90 mpi_pikaia.f90 mpi_fitness.f90 ff_slave.f90
```

Sample Input fort.1 file

```
1,1,240,10000,1,50          Genetics?, Verbose?, Pop Size, Max
Gens, Rep Plan (1), Parents to Keep (deprecated)
123460          Seed for random number generator
3,2             Basis functions, Dimension
250,.3,250,.3   X-points, Step Size
4,1             States in PMF, Num auxiliary
parameters (temperature)
50,50,50,0,0,0          Depth of first well in kJ/mole,
dmin, dmax, temperature dependence, min, max
10.5506,10.5506,10.5506,-.0049,-.0049,-.0049,10.4324,10.4324,10.4324,-.0099,-
.0099,-.0099          Width of first well in nm, temperature
dependence
29,29,29,0,0,0,29,29,29,0,0,0          Location of
first well in nm, T dependence
43.0150,43.0150,43.0150,.3400,.3400,.3400
10.3547,10.3547,10.3547,-.0021,-.0021,-.0021,10.2169,10.2169,10.2169,-.0039,-
.0039,-.0039
27.0030,27.0030,27.0030,-.0055,-.0055,-
.0055,51.7385,51.7385,51.7385,.0151,.0151,.0151
44.6006,43,46,.1568,.1,.2          Well #3 Intermediate
10.3547,9,11,-.0021,-.01,.01,10.2169,9,11,-.0039,-.01,.01
44.6006,42,46,.0110,-.01,.02,35.8675,34,37,-.0061,-.01,.01
8.5090,8.5090,8.5090,.2994,.2994,.2994          Well #4 Dimple
5.0130,5.0130,5.0130,.0199,.0199,.0199,4.6448,4.6448,4.6448,-.0438,-.0438,-
.0438
26.7613,26.7613,26.7613,-.0197,-.0197,-.0197,43.9014,43.9014,43.9014,-.0097,-
.0097,-.0097
.05,.05          Diffusion coefficient in nm^2/us (min,max)
313          Reference temperature (only one aux parameter)
313,372          Display temperatures
3          # of signal baselines
2.7425,0,3.5,0,0,0          Signal #1 at x=0, T dependence of signal at x=0
.1327,-.5,.5,0,0,0          Signal slope dS/dx
0,0,0,0,0,0          Signal slope 2 (after step)
1,1,1,0,0,0          Signal step (a)
38.8591,37,43          Signal step (b)
-7.0426,-10,0          Signal Step magnitude
-1.6978,-2,2,0,0,0          Signal #2 at x=0, T dependence of signal at x=0
-2.0296,-3,1,-.1364,-1,1          signal slope dS/dx
0,0,0,0,0,0          Signal slope 2 (after step)
1,1,1,0,0,0          Signal step (a)
38.2829,30,40          Signal step (b)
```

```

-16.1670,-30,-10          Signal Step Magnitude
2.15,-3.5,3,0,0,0    Signal #3 at x=0, T dependence of signal at x=0
-.5,-1,1,-.0955,-1,1    signal slope dS/dx
0,0,0,0,0,0          Signal slope 2 (after step)
0,0,0,1,1,1          Signal step (a)
38.2,28,47            Signal step (b)
27,0,35              Signal Step Magnitude
0                    # Linked Parameters
6                    # Data Blocks
0,14,3              datatype=0 means thermo, not kinetics, 13 data
points, use signal #3
1,0,1              scale data?, scalemin,scalemax
100              number of time steps (deprecated)
275.3510.001275.35 IR at 1660 cm-1
283.050.987010.001283.05
289.780.948050.001289.78
296.870.935060.001296.87
303.150.89610.001303.15
310.850.844160.001310.85
324.850.740260.001324.85
331.850.649350.001331.85
338.750.545460.001338.75
341.850.428570.001341.85
345.650.324680.001345.65
349.350.220780.001349.35
353.150.10390.001353.15
358.9500.001358.95
1,9,3              IR 325 K datatype=1 means kinetics, # data points,
Signal #
1,0,1              scale data?, scalemin,scalemax
100              number of time steps
0 1      0.001 315
1000 .69837 0.001 325
2000 .48773 0.001 325
3000 .34062 0.001 325
6000 .11602 0.001 325
12000 .01346 0.001 325
30000 .00002 0.001 325
40000 0      0.001 325
50000 0      0.001 325
1,9,3              IR 343 K datatype=1 means kinetics, # data points,
Signal #
1,0,1              scale data?, scalemin,scalemax
100              number of time steps
0 1      0.001 333
1000 .66564 0.001 343
2000 .44308 0.001 343
3000 .29494 0.001 343
6000 .08699 0.001 343
12000 .00757 0.001 343
30000 0      0.001 343
40000 0      0.001 343
50000 0      0.001 343
0,18,1              datatype=0 means thermo, not kinetics, 61 data
points, use signal #1
1,.0178,1          scale data?, scalemin,scalemax

```

```

100                                number of time steps per observed time
interval to converge propagation
313.15 0.974089 0.001 313.15    T (K), 280 nm fluorescence, uncertainty, T is
only aux parameter
314.15 1          0.001 314.15
316.15 0.963765 0.001 316.15
318.15 0.955364 0.001 318.15
322.15 0.936336 0.001 322.15
326.15 0.923684 0.001 326.15
330.15 0.890891 0.001 330.15
334.15 0.860628 0.001 334.15
338.15 0.789372 0.001 338.15
342.15 0.702632 0.001 342.15
346.15 0.593219 0.001 346.15
350.15 0.488158 0.001 350.15
354.15 0.381275 0.001 354.15
358.15 0.299393 0.001 358.15
362.15 0.201619 0.001 362.15
366.15 0.10668 0.001 366.15
370.15 0.0589069 0.001 370.15
372.15 0.0178138 0.001 372.15
1,9,2                                fl 53 oC  datatype=1 means kinetics, # data
points, Signal #
1,0,1                                scale, scalemin,scalemax
100                                number of time steps
0 1          0.001 318
1000 .63474 0.001 326
2000 .40289 0.001 326
3000 .25573 0.001 326
6000 .0654 0.001 326
12000 .00428 0.001 326
30000 0      0.001 326
40000 0      0.001 326
50000 0      0.001 326
1,9,2                                fl 71 oC  datatype=1 means kinetics, # data
points, Signal #
1,0,1                                scale data?, scalemin,scalemax
100                                number of time steps
0 1          0.001 336
1000 .8702 0.001 344
2000 .75723 0.001 344
3000 .65891 0.001 344
6000 .43405 0.001 344
12000 .18809 0.001 344
30000 .01455 0.001 344
40000 .0029 0.001 344
50000 0      0.001 344

```

sm21.f90

```

!      1- or 2-D discrete Smoluchowski solver.  This program
!      propagates a density matrix rho in coordinate space on a
!      potential surface pmf.  PMF can depend on time via a bias(t)
!      parameter.  rho(t=0) can be any function, or can be the
!      stationary state of pmf[bias(t=0)].  The propagation uses
!      singular value decomposition of rho over the range of biases
!      encountered to create an orthogonal basis for rho, then

```

```

! solves the time propagation in this orthogonal basis. For
! small jumps of PMF[bias(t)], even two basis functions are
! sufficient, greatly reducing computational cost for
! calculations of relaxation experiments. To do the SVD,
! subroutine SVDCMP produces a singular value decomposition
! of matrix rho = a * v * w, where v is the basis function
! matrix, w the singular value array, and a the matrix which
! expresses the density in terms of the SVD basis functions.

module set_kinds
  implicit none
  integer, parameter :: ik=4
  integer, parameter :: rk=8
end module set_kinds

module constants
  use set_kinds
  implicit none
  real(rk) :: kb = 0.00831 !! in kJ/mole/K
end module constants

module masterdim
  use set_kinds
  implicit none
  integer(ik), parameter :: rhodim(2)=255,mdim=1000, &
    ndim=10, statedim=10, sigdim=6
  integer(ik), parameter :: dim=rhodim(1)*rhodim(2)
  integer(ik), parameter :: odim=1200, padim=100, &
    blockdim=12, auxdim=4, xdim=2, parmdim=65 !Auxillary (eg T)
parameters, dimensions, adjustable parameters
  integer(ik), parameter ::
refdim=statedim*auxdim*(1+xdim)+sigdim*(1+auxdim+xdim),linkdim=10,&
  numdim=9+xdim*3+auxdim+7*blockdim+2*linkdim
end module masterdim

module obscalc
  use set_kinds
  use masterdim
  implicit none
  real(rk) :: xobs(odim),obs(odim),osig(odim),xaux(odim,auxdim)
  real(rk) :: calc(odim)
  real(rk) :: pa(padim),pasig(padim)
  integer(ik) :: onum, panum, paf(padim),linknum, links(linkdim,linkdim)
! The following are independent variables or other
! information required by cal to evaluate calc():
  integer(ik) :: statenum, contot, datablocks, scaleflag(blockdim),&
    datatype(blockdim), onu(blockdim), datanorm(blockdim), &
    sigtype(blockdim),basenum,popu,dat,auxnum, &
    tstepnum(blockdim), verbflag, maxgens, genflag, replan, nindv,keepnum
  real(rk) ::
datamin(blockdim),datamax(blockdim),scalemin(blockdim),scalemax(blockdim)
end module obscalc

module rhopmfsig
  use set_kinds
  use masterdim

```

```

implicit none
real(rk) :: delx(xdim)
real(rk) :: d0(statedim,0:auxdim), dmin(statedim,0:auxdim), &
dmax(statedim,0:auxdim), w0(statedim,0:auxdim,xdim), &
wmin(statedim,0:auxdim,xdim), wmax(statedim,0:auxdim,xdim), &
x0(statedim,0:auxdim,xdim), xmin(statedim,0:auxdim,xdim), &
xmax(statedim,0:auxdim,xdim), aux0(auxdim)
real(rk) :: s0(sigdim,0:auxdim), s0min(sigdim,0:auxdim), &
s0max(sigdim,0:auxdim), s1(sigdim,0:auxdim), s1min(sigdim,0:auxdim), &
s1max(sigdim,0:auxdim), amin(sigdim,0:auxdim), amax(sigdim,0:auxdim), &
a(sigdim,0:auxdim),
b(sigdim), bmax(sigdim), bmin(sigdim), sigstep(sigdim), &
sigstepmin(sigdim), sigstepmax(sigdim),
s2(sigdim,0:auxdim), s2min(sigdim,0:auxdim), &
s2max(sigdim,0:auxdim)
real(rk) :: dc(xdim), dcmin(xdim), dcmax(xdim)
integer(ik) :: nrho, dimen, mpts(xdim), signum, seedset
real(rk) :: basis(dim, ndim), gs(ndim, ndim), svd(ndim),
t1, t2, nums(numdim), &
parmref(refdim, 2), disptemp(2), penaltyflag,
rhox(0:rhodim(1)+1, 0:rhodim(2)+1)
end module rhopmfsig

```

```

subroutine se

```

```

!-----
! Main program subroutine
! Reads in all input information from file
! Starts genetic algorithm
! Writes all output to files
! Output files:
! pmfrho.out   x,y,z coordinates of pmf, rho, and signal functions at ref.
temp
! pmfrho1.out  pmf, rho at first specified temperature (aux parameter)
! pmfrho2.out  pmf, rho at second specified temperature
! sigs.out     Observed (from input file) vs calculated signals
! parms.out    PMF and signal function parameters for best fit
!-----

```

```

use set_kinds
use masterdim
use obscalc
use rhopmfsig
implicit none
integer(ik) :: i1, i2, i3, i3end, i, j, k, l, maxo
character(3) :: datastring, datastring2
real(rk) :: fit, test, test2
real(rk) :: rho(0:rhodim(1)+1, 0:rhodim(2)+1), &
pmf(0:rhodim(1)+1, 0:rhodim(2)+1), aux(auxdim), &
sigx(0:rhodim(1), 0:rhodim(2)), sigxs(sigdim, 0:rhodim(1), 0:rhodim(2))
! Read spatial grid variables; to allow derivatives to be taken, the
grid
! runs from 0...mpts+1, but only 1...mpts is reported
! nrho          # of rho basis functions to be used (minimum of 2!)
! dimen         either 1 or 2 spatial dimensions
! m             SVD column dimensions (product of mpts in each
dimension)

```



```

!      delx              step size in Angstroms

!-----Read in all input information-----
-
! First line: do genetics?, verbose?, population size, max generations,
replacement plan
! Replacement plan should be 1 (full generational replacement) for parallel
operation
!-----
-
      open(unit=1,file='fort.1')
      read(1,*) genflag,verbflag, nindv,maxgens,replan,keepnum      !keepnum
deprecated
      read(1,*) seedset                                           !Random
number seed
      read(1,*) nrho,dimen                                         !Number
of basis functions, dimension
      read(1,*) (mpts(j), delx(j), j=1,dimen)                     !Number
of points in each dimension
      if (dimen == 1) then
        mpts(2)=0
        delx(2)=0
      else if (dimen == 2) then
        print *, "Dimen=2"
      endif
!      Read PMF Gaussian fitting parameters of each state on the PMF
      read(1,*) statenum,auxnum                                     !Number
of states, number of auxillary parameters
      do k=1,statenum
        read(1,*) (d0(k,i),dmin(k,i),dmax(k,i), i=0,auxnum)
!Well depth
        read(1,*) ((w0(k,i,j),wmin(k,i,j),wmax(k,i,j), i=0,auxnum),
j=1,dimen) !Well width
        read(1,*) ((x0(k,i,j),xmin(k,i,j),xmax(k,i,j), i=0,auxnum),
j=1,dimen) !Well position
      enddo

!      Read diffusion coefficient scaling factor and reference values of
auxiliary parameters
      read(1,*) (dc(j), dcmin(j), dcmx(j),j=1,dimen)
      if (dimen == 1) then
        dc(2)=0
        dcmin(2)=0
        dcmx(2)=0
      endif
      do i=1,auxnum
        read(1,*) aux0(i)
      enddo
      read(1,*) disptemp(1),disptemp(2)      !Temperatures for output of
potentials in pmfrho1.out and pmfrho2.out

!      Read signal parameters
      read(1,*) signum
      do l=1,signum
        read(1,*) (s0(l,i),s0min(l,i),s0max(l,i), i=0,auxnum)
        read(1,*) (s1(l,j),s1min(l,j),s1max(l,j), j=1,dimen)
        read(1,*) (s2(l,j),s2min(l,j),s2max(l,j), j=1,dimen)

```

```

        read(1,*) (a(1,j),amin(1,j),amax(1,j), j=1,dimen)
        read(1,*) b(1),bmin(1),bmax(1)
        read(1,*) sigstep(1),sigstepmin(1),sigstepmax(1)
    enddo

!    Read linked parameters
    read(1,*) linknum
    print *, "linknum:", linknum
    do i1=1,linknum
        read(1,*) links(i1,1),links(i1,2)
        print *, "links:", links(i1,1), links(i1,2)
    enddo

!    Read observable blocks
    read(1,*) datablocks
    onum=1
    do i1=1,datablocks
        read(1,*) datatype(i1),onu(i1),sigtype(i1)
        read(1,*) scaleflag(i1),scalemin(i1),scalemax(i1)
        read(1,*) tstepnum(i1)
        do i2=onum,onum+onu(i1)-1
            read(1,*) xobs(i2),obs(i2),osig(i2), (iaux(i2,i3),i3=1,auxnum)
        enddo
        onum=onum+onu(i1)
    enddo
    onum=onum-1

!-----End Input-----

    !! Start genetic algorithm
    call genetic(fit)

!-----Output all information-----
! Get pmf, rho, and sigx at reference temperature/parameters

    do i=1,auxnum
        aux(i)=aux0(i)
    enddo
    call get_pmf(aux,pmf,0,0)
    call get_rho(pmf,aux,rho)
    do i1=1,signum
        call get_sigx(i1,rho,sigx,aux)
        sigxs(i1,(:,:))=sigx(:,:)
    enddo

    !! Write pmf and rho to file
    open(unit=2,file='pmfrho.out')
    i3end=0
    if(dimen==2) then
        i3end=mpts(2)+1
    endif

    write(datastring,'(i2)') signum
    write(2,*) "xpos ypos pmf rho sig"
    do i2=0,mpts(1)+1

```

```

        do i3=0,i3end
            write(2,'(2(f6.2,1x),f14.10,1x,f14.10
,1x,'//datastring/'(f8.3,1x))') delx(1)*i2, &
            delx(2)*i3, pmf(i2,i3), rho(i2,i3), (sigxs(i1,i2,i3),i1=1,signum)
        enddo
    enddo

!-----Test----- Project 2-D into 1-D
! open(unit=30,file='slice.out')
! if(dimen==2) then
!   test=floor(x0(1,0,1)/delx(1))
!   test=floor(x0(1,0,2)/delx(1))
!   do i2=0,mpts(2)+1
!     write(30,'(f5.2,1x,2(f14.10,1x))', i2*delx(1),pmf(test,i2)
!     write(30,'(f5.2,1x,2(f14.10,1x))', i2*delx(1),pmf(i2,test)
!   enddo
! endif

! do i2=0,mpts(1)+1
!   test=0
!   do i3=0,i3end
!     test=test+rho(i2,i3)*delx(2) !x-slice
!     test2=test2+rho(i3,i2) !y-slice
!   enddo
!   write(30,'(2(f5.2,1x),2(f14.10,1x))') delx(1)*i2,delx(2)*i3,test,test2
! enddo
!----End Test----

!-----Print pmf/rho at display temperatures-----
!!Only works for 1 aux parameter

    aux(1)=disptemp(1)
    call get_pmf(aux,pmf,0,0)
    call get_rho(pmf,aux,rho)

    !! Write pmf and rho to file
    open(unit=20,file='pmfrho1.out')
    i3end=0
    if(dimen==2) then
        i3end=mpts(2)+1
    endif

    write(20,*) "xpos ypos pmf rho"
    do i2=0,mpts(1)+1
        do i3=0,i3end
            write(20,'(2(f6.2,1x),f6.1,1x,f6.4)') delx(1)*i2, &
            delx(2)*i3, pmf(i2,i3), rho(i2,i3)
        enddo
    enddo

    aux(1)=disptemp(2)
    call get_pmf(aux,pmf,0,0)
    call get_rho(pmf,aux,rho)

    !! Write pmf and rho to file
    open(unit=21,file='pmfrho2.out')
    i3end=0

```

```

        if(dimen==2) then
            i3end=mpts(2)+1
        endif

        write(21,*) "xpos ypos pmf rho"
        do i2=0,mpts(1)+1
            do i3=0,i3end
                write(21,'(2(f6.2,1x),f6.1,1x,f6.4)') delx(1)*i2, &
                    delx(2)*i3, pmf(i2,i3), rho(i2,i3)
            enddo
        enddo

!-----

!-----Output parameters of best fit-----
        open(unit=5,file='parms.out')
        write(datastring,'(i3)') auxnum+1
        write(datastring2,'(i3)') auxnum*dimen+1
        write (5,'(A,f7.3,A,f6.3)') "Fitness: ", fit, " Sum of squares:
",1/fit
        do k=1,statenum
            write(5,'(A,i3,A,'//datastring/'(f7.4,1x))') "d0(",k,"):",(d0(k,i),
i=0,auxnum)
            write(5,'(A,i3,A,'//datastring2/'(f7.4,1x))')
"w0(",k,"):",((w0(k,i,j), i=0,auxnum), j=1,dimen)
            write(5,'(A,i3,A,'//datastring2/'(f7.4,1x))')
"x0(",k,"):",((x0(k,i,j), i=0,auxnum), j=1,dimen)
        enddo

        write(datastring2,'(i3)') dimen

        write(5,'(A,i3,A,'//datastring2/'(f10.6,1x))')
"dc(",j,"):",(dc(j),j=1,dimen)

        do l=1,signum
            write(5,'(A,i3,A,'//datastring/'(f7.4,1x))') "s0(",l,"):",(s0(l,i),
i=0,auxnum)
            write(5,'(A,i3,A,'//datastring2/'(f7.4,1x))')
"s1(",l,"):",(s1(l,j), j=1,dimen)
            write(5,'(A,i3,A,'//datastring2/'(f7.4,1x))')
"s2(",l,"):",(s2(l,j), j=1,dimen)
            write(5,'(A,i3,A,'//datastring2/'(f7.4,1x))') "a(",l,"):",(a(l,j),
j=1,dimen)
            write(5,'(A,i3,A,f8.4)') "b(",l,"):",b(l)
            write(5,'(A,i3,A,f8.4)') "sigstep(",l,"):",sigstep(l)
        enddo

        ! Write observed vs calculated data

        open(unit=10,file="sigs.out")
        write(10,*) " Observed | Calculated"
        onum=1
        do il=1,datablocks
            write(10,*) "Data Block #",il
            !
            do i2=1,onu(il)
                do i2=onum,onum+onu(il)-1
                    write(10,'(3(f12.4,1x))') xobs(i2),obs(i2),calc(i2)

```

```

        enddo
        onum=onum+onu(il)
    enddo
    onum=onum-1

end subroutine se

subroutine genetic(fit)
!-----
! Routine to set up and start genetic algorithm
!-----

    use set_kinds
    use masterdim
    use obscalc
    use rhopmfsig
    use Genetic_Algorithm
    implicit none
    integer(ik) :: i,j,k,l,il,seed,status
    integer :: nparms
    real(rk) :: fit
    real(8) :: ctrl(13), parms(parmdim), fness

    INTERFACE
        FUNCTION get_fitness(nparms, parms) RESULT(fn_val)
            IMPLICIT NONE
            INTEGER, INTENT(IN) :: nparms
            real(8), INTENT(IN) :: parms(:)
            real(8) :: fn_val
        END FUNCTION get_fitness
    END INTERFACE

    ! Build linear array of all adjustable parameters in range [0,1]
    call scaledownparms(parms,nparms)

    ! Start the random number generator
    seed=seedset
    call rninit(seed)

    !      Set control variables

    ctrl(1:13) = -1
    ctrl(1)=nindv
    ctrl(2)=maxgens
    ctrl(3)=6
    ctrl(10)=replan
parallel operation)
    ctrl(12)=0
    ctrl(13)=keepnum
    if(verbflag==1) ctrl(12)=2
every generation)

    !Set everything to default values
    !Individuals
    !Generations
    !Number of digits in chromosome
    !Replacement plan (Must be 1 for

    !Turn off verbose output
    !Deprecated
    !maximum verbose (print fitnesses

    ! Start genetic algorithm
    if(genflag==1) then
        call pikaia(get_fitness, nparms, ctrl, parms, fness, status)
    else

```

```

        fness=get_fitness(nparms,parms)
        print *, "No Genetics, Fitness: ",fness
    endif

    fit=fness

    call scaleparms(parms) !Make sure all values are scaled back to
actual ranges
    genflag=0 !Turn off genetics flag so output in final
call to cal will be printed
    call cal !Run through everything with the most fit
individual

    end subroutine genetic

function get_fitness(nparms,parms) RESULT(fn_val)
!-----
! This evaluates the fitness of the individual by comparing all calculated
! signals to the observed values from the input file. It is a weighted
! sum of squares. The reciprocal value is used since pikaia evolves to
! higher fitness values.
!-----

    use set_kinds
    use masterdim
    use obscalc
    use rhopmfsig
    implicit none
    integer(ik) :: i1,i2
    integer, intent(in) :: nparms
    real(8), intent(in) :: parms(:)
    real(8) :: fn_val, fit

    !Rescale from [0,1] to [min,max] for each parameter
    call scaleparms(parms)

    !Turn the parameters into pmf->rho->signal
    call cal

    !! Sum of squares fitness
    fit = 0
    do i2=1,onum
!        fit = fit + (obs(i2)-calc(i2))**2
        fit = fit + ( (obs(i2)-calc(i2))/osig(i2) )**2 !Now weight
depending on significance
    enddo

    if(penaltyflag==1) fit=10000 !Apply penalty function if necessary
(flag turned on if rho does not maintain normalization)

    fn_val=1/fit !Pikaia only finds max values, so
fitness must increase with decreasing error
end function get_fitness

```

```

      subroutine scaledownparms (parms,nparms)
!-----
!Scale values from [min,max] to [0,1] for pikaia input
!Count number of parms and wrap up parameters for parallel sending via MPI
!Parms: Array of only parameters to be evolved by pikaia
!nparms: Length of parms
!Parmref: Array of ranges for all parameters (not just those in parms)
!nums: Constants to be sent via MPI
!
!The way this routine is built is somewhat complicated and makes it very
!difficult to link parameters or figure out which one is out of range.
!This is a great place to clean up the code to make it more user-friendly!
!-----
      use set_kinds
      use masterdim
      use obscalc
      use rhopmfsig
      implicit none
      real(8) :: parms (parmdim)
      integer(ik) :: i,j,k,l,i1,i2,nparms,temp,i3

      nums(1)=nrho
      nums(2)=dimen
      nums(3)=statenum
      nums(4)=auxnum
      nums(5)=signum
      nums(6)=datablocks
      nums(7)=onum
      nums(8)=genflag
      nums(9)=linknum

      i2=9
      do j=1,dimen
         i2=i2+1
         nums(i2)=mpts(j)
         i2=i2+1
         nums(i2)=delx(j)
         i2=i2+1
         nums(i2)=dc(j)
      enddo

      do i=1,auxnum
         i2=i2+1
         nums(i2)=aux0(i)
      enddo

      do i1=1,datablocks
         i2=i2+1
         nums(i2)=datatype(i1)
         i2=i2+1
         nums(i2)=onu(i1)
         i2=i2+1
         nums(i2)=sigtype(i1)
         i2=i2+1
         nums(i2)=scaleflag(i1)
         i2=i2+1

```

```

    nums(i2)=scalemin(i1)
    i2=i2+1
    nums(i2)=scalemax(i1)
    i2=i2+1
    nums(i2)=tstepnum(i1)
enddo

temp=i2

i1=0
i2=0
do k=1,statenum
    do i=0,auxnum
        i1=i1+1
        i2=i2+1
        parms(i1)=(d0(k,i)-dmin(k,i))/(dmax(k,i)-dmin(k,i)) !Re-scale
initial value to fit between [0,1]
        parmref(i2,1)=dmin(k,i) !Wrap up ranges for MPI sending
        parmref(i2,2)=dmax(k,i)
        if(dmax(k,i)==dmin(k,i)) i1=i1-1 !Ignore this parameter for
genetics if range is 0
    enddo
enddo

do k=1,statenum
    do i=0,auxnum
        do j=1,dimen
            i1=i1+1
            i2=i2+1
            parms(i1)=(w0(k,i,j)-wmin(k,i,j))/(wmax(k,i,j)-wmin(k,i,j))
            parmref(i2,1)=wmin(k,i,j)
            parmref(i2,2)=wmax(k,i,j)
            if(wmax(k,i,j)==wmin(k,i,j)) i1=i1-1
            i1=i1+1
            i2=i2+1
            parms(i1)=(x0(k,i,j)-xmin(k,i,j))/(xmax(k,i,j)-xmin(k,i,j))
            parmref(i2,1)=xmin(k,i,j)
            parmref(i2,2)=xmax(k,i,j)
            if(xmax(k,i,j)==xmin(k,i,j)) i1=i1-1
        enddo
    enddo
enddo

do l=1,signum
    do i=0,auxnum
        i1=i1+1
        i2=i2+1
        parms(i1)=(s0(l,i)-s0min(l,i))/(s0max(l,i)-s0min(l,i))
        parmref(i2,1)=s0min(l,i)
        parmref(i2,2)=s0max(l,i)
        if(s0max(l,i)==s0min(l,i)) i1=i1-1
    enddo
enddo

do l=1,signum
    do j=1,dimen
        i1=i1+1

```



```

        i2=i2+1
        parms(i1)=(s1(l,j)-s1min(l,j))/(s1max(l,j)-s1min(l,j))
        parmref(i2,1)=s1min(l,j)
        parmref(i2,2)=s1max(l,j)
        if(s1max(l,j)==s1min(l,j)) i1=i1-1
        i1=i1+1
        i2=i2+1
        parms(i1)=(s2(l,j)-s2min(l,j))/(s2max(l,j)-s2min(l,j))
        parmref(i2,1)=s2min(l,j)
        parmref(i2,2)=s2max(l,j)
        if(s2max(l,j)==s2min(l,j)) i1=i1-1
        i1=i1+1
        i2=i2+1
        parms(i1)=(a(l,j)-amin(l,j))/(amax(l,j)-amin(l,j))
        parmref(i2,1)=amin(l,j)
        parmref(i2,2)=amax(l,j)
        if(amin(l,j)==amax(l,j)) i1=i1-1
    enddo
enddo

do l=1,signum
    i1=i1+1
    i2=i2+1
    parms(i1)=(b(l)-bmin(l))/(bmax(l)-bmin(l))
    parmref(i2,1)=bmin(l)
    parmref(i2,2)=bmax(l)
    if(bmin(l)==bmax(l)) i1=i1-1
    i1=i1+1
    i2=i2+1
    parms(i1)=(sigstep(l)-sigstepmin(l))/(sigstepmax(l)-sigstepmin(l))
    parmref(i2,1)=sigstepmin(l)
    parmref(i2,2)=sigstepmax(l)
    if(sigstepmin(l)==sigstepmax(l)) i1=i1-1
enddo

!If diffusion coefficient in second dimension is set to 0, link it to the
value of the first-dimension's D
!The range of the second D must equal the range of the first D for this to
work properly
do j=1,dimen
    i1=i1+1
    i2=i2+1
    if(dimen==2.and.dc(2)==0.and.j==2) then
        linknum=linknum+1
        nums(9)=linknum
        links(linknum,1)=i1
        links(linknum,2)=i1-1
        dc(2)=dc(1)
        print *, "dc linking:",linknum,i1,i1-1
    endif
    parms(i1)=(dc(j)-dcmin(j))/(dcmax(j)-dcmin(j))
    parmref(i2,1)=dcmin(j)
    parmref(i2,2)=dcmax(j)
    if(dcmin(j)==dcmax(j)) i1=i1-1
enddo

do i3=1,linknum

```

```

        temp=temp+1
        nums(temp)=links(i3,1)
        temp=temp+1
        nums(temp)=links(i3,2)
    enddo

    nparms=i1 !Set number of adjustable parameters

    if(genflag==0) then
        do i1=1,nparms
            print *, "Parms",i1,parms(i1) !Print out parameters for trouble
shooting purposes (particularly when trying to link values)
        enddo
    endif

    do i1=1,nparms
        if(parms(i1)>1.or.parms(i1)<0.and.i1.ne.links(linknum,1)) then
            print *, "Problem with parameter bounds:",i1,parms(i1) !Warn that a
parameter min is larger than its max or that an intial value is not inside
the range
            STOP
        endif
    enddo

end subroutine scaledownparms

```

```

subroutine scaleparms(parms)
!-----
!Re-scale values from pikaia [0,1] to match [min,max] range
!Also unwraps all other parameters that were sent via MPI
!-----
    use set_kinds
    use masterdim
    use obscalc
    use rhopmfsig
    implicit none
    real(8) :: parms(parmdim)
    integer(ik) :: i,j,k,l,i1,i2

    nrho=nums(1)
    dimen=nums(2)
    statenum=nums(3)
    auxnum=nums(4)
    signum=nums(5)
    datablocks=nums(6)
    onum=nums(7)
    genflag=nums(8)
    linknum=nums(9)

    i2=9
    do j=1,dimen
        i2=i2+1
        mpts(j)=nums(i2)
        i2=i2+1
        delx(j)=nums(i2)
    enddo

```

```

        i2=i2+1
        dc(j)=nums(i2)
    enddo

do i=1,auxnum
    i2=i2+1
    aux0(i)=nums(i2)
enddo

do i1=1,datablocks
    i2=i2+1
    datatype(i1)=nums(i2)
    i2=i2+1
    onu(i1)=nums(i2)
    i2=i2+1
    sigtype(i1)=nums(i2)
    i2=i2+1
    scaleflag(i1)=nums(i2)
    i2=i2+1
    scalemin(i1)=nums(i2)
    i2=i2+1
    scalemax(i1)=nums(i2)
    i2=i2+1
    tstepnum(i1)=nums(i2)
enddo

do i1=1,linknum
    i2=i2+1
    links(i1,1)=nums(i2)
    i2=i2+1
    links(i1,2)=nums(i2)
enddo

!-----Link parameters-----
! Parameter to follow should be set to adjust with the same range
do i1=1,linknum
    parms(links(i1,1))=parms(links(i1,2))
!     print *, "Linking:", links(i1,1), links(i1,2), parms(links(i1,2))
enddo
!-----End parameter linking-----

i1=0
i2=1
do k=1,statenum
    do i=0,auxnum
        dmin(k,i)=parmref(i2,1)
        dmax(k,i)=parmref(i2,2)
        i2=i2+1
        if(dmax(k,i).ne.dmin(k,i)) then
            i1=i1+1
            d0(k,i)=parms(i1)*(dmax(k,i)-dmin(k,i))+dmin(k,i)
        else
            d0(k,i)=dmin(k,i)
        endif
    enddo
enddo

```

```

do k=1,statenum
  do i=0,auxnum
    do j=1,dimen
      wmin(k,i,j)=parmref(i2,1)
      wmax(k,i,j)=parmref(i2,2)
      i2=i2+1
      xmin(k,i,j)=parmref(i2,1)
      xmax(k,i,j)=parmref(i2,2)
      i2=i2+1
      if(wmax(k,i,j).ne.wmin(k,i,j)) then
        i1=i1+1
        w0(k,i,j)=parms(i1)*(wmax(k,i,j)-wmin(k,i,j))+wmin(k,i,j)
      else
        w0(k,i,j)=wmin(k,i,j)
      endif
      if(xmax(k,i,j).ne.xmin(k,i,j)) then
        i1=i1+1
        x0(k,i,j)=parms(i1)*(xmax(k,i,j)-xmin(k,i,j))+xmin(k,i,j)
      else
        x0(k,i,j)=xmin(k,i,j)
      endif
    enddo
  enddo
enddo

do l=1,signum
  do i=0,auxnum
    s0min(l,i)=parmref(i2,1)
    s0max(l,i)=parmref(i2,2)
    i2=i2+1
    if(s0max(l,i).ne.s0min(l,i)) then
      i1=i1+1
      s0(l,i)=parms(i1)*(s0max(l,i)-s0min(l,i))+s0min(l,i)
    else
      s0(l,i)=s0min(l,i)
    endif
  enddo
enddo

do l=1,signum
  do j=1,dimen
    s1min(l,j)=parmref(i2,1)
    s1max(l,j)=parmref(i2,2)
    i2=i2+1
    s2min(l,j)=parmref(i2,1)
    s2max(l,j)=parmref(i2,2)
    i2=i2+1
    amin(l,j)=parmref(i2,1)
    amax(l,j)=parmref(i2,2)
    i2=i2+1
    if(s1max(l,j).ne.s1min(l,j)) then
      i1=i1+1
      s1(l,j)=parms(i1)*(s1max(l,j)-s1min(l,j))+s1min(l,j)
    else
      s1(l,j)=s1min(l,j)
    endif
    if(s2max(l,j).ne.s2min(l,j)) then

```

```

        i1=i1+1
        s2(l,j)=parms(i1)*(s2max(l,j)-s2min(l,j))+s2min(l,j)
    else
        s2(l,j)=s2min(l,j)
    endif
    if(amax(l,j).ne.amin(l,j)) then
        i1=i1+1
        a(l,j)=parms(i1)*(amax(l,j)-amin(l,j))+amin(l,j)
    else
        a(l,j)=amin(l,j)
    endif
enddo
enddo

do l=1,signum
    bmin(l)=parmref(i2,1)
    bmax(l)=parmref(i2,2)
    i2=i2+1
    sigstepmin(l)=parmref(i2,1)
    sigstepmax(l)=parmref(i2,2)
    i2=i2+1
    if(bmax(l).ne.bmin(l)) then
        i1=i1+1
        b(l)=parms(i1)*(bmax(l)-bmin(l))+bmin(l)
    else
        b(l)=bmin(l)
    endif
    if(sigstepmax(l).ne.sigstepmin(l)) then
        i1=i1+1
        sigstep(l)=parms(i1)*(sigstepmax(l)-sigstepmin(l))+sigstepmin(l)
    else
        sigstep(l)=sigstepmin(l)
    endif
enddo

do j=1,dimen
    dcmin(j)=parmref(i2,1)
    dcmax(j)=parmref(i2,2)
    i2=i2+1
    if(dcmax(j).ne.dcmin(j)) then
        i1=i1+1
        dc(j)=parms(i1)*(dcmax(j)-dcmin(j))+dcmin(j)
    else
        dc(j)=dcmin(j)
    endif
enddo

end subroutine scaleparms

```

```

subroutine cal
!-----
-
! Routine to calculate either the thermodynamic or kinetic signals
! The thermodynamics are based on equilibrium probability densities and the
! signal functions. The kinetics propagates using the Smoluchowski equation

```

```

! with an SVD basis set.
!-----
-
      use set_kinds
      use masterdim
      use obscalc
      use rhopmfsig
      implicit none
      integer(ik) :: i1,i2,i3,i4,i5,i6,imin,imax,steps,errflag,test,i3end
      real(rk) :: aux(auxdim),delt,sig,aux_t0(auxdim)
      real(rk) :: rho(0:rhodim(1)+1,0:rhodim(2)+1), &
      pmf(0:rhodim(1)+1,0:rhodim(2)+1), rhocopy(0:rhodim(1)+1,0:rhodim(2)+1)
      real(rk) ::
t,c(ndim),sv(ndim),xscale(ndim),g(ndim,ndim),calcmax,calcmin,
scaleval,rhosum,rhonorm
      penaltyflag=0
      xscale(:)=1d-5
      errflag=0
      i2=0
      i3=1
      do i1=1,datablocks
! -----Thermodynamics-----
          if(datatype(i1) == 0) then
              do i2=i3,i3+onu(i1)-1
                  do i4=1,auxnum
                      aux(i4)=xaux(i2,i4)
                  enddo
                  call get_pmf(aux,pmf,0,0)
                  call get_rho(pmf,aux,rho)
                  call get_signal(sigtype(i1),rho,sig,aux)
                  calc(i2)=sig
              enddo
!              i3=i3+onu(i1)
! -----Kinetics-----
          else if(datatype(i1) == 1) then
              do i4=1,auxnum
                  aux_t0(i4)=xaux(i3,i4)
              enddo
! -----First point before propagation-----
              call get_pmf(aux_t0,pmf,0,0)
              call get_rho(pmf,aux_t0,rho)
              rhocopy(:,:)=rho(:,:)
              call norm_rho(rhocopy,rhosum)
              call get_signal(sigtype(i1),rhocopy,sig,aux_t0)
              calc(i3)=sig
              do i4=1,auxnum
                  aux(i4)=xaux(i3+1,i4)
              enddo
              t=0
! -----Initialize propagation (SVD, G matrix, c values)-----
              call propag_init(aux_t0,aux,c,sv,g)
! -----
              svsv(:)=sv(:)
              gs(:,:)=g(:,:)

              do i2=i3+1,i3+onu(i1)
                  call odesolve(nrho,c,xobs(i2-1),xobs(i2),0.01,errflag,xscale)
              enddo
          enddo
      enddo

```

```

        if(genflag==0) then
            print *,c(1),c(2),c(3)
        endif
!-----Convert rho back from basis expoansion c() to spatial form rho()--
        call convert_rho(c,sv,rho)
        rhocopy(:,:)=rho(:,:)
        call norm_rho(rhocopy,rhosum)
        call get_signal(sigtype(i1),rhocopy,sig,aux)
        calc(i2)=sig
    enddo
    rhonorm=abs(1-rhosum)

    if(genflag==0) then
        open(unit=80, file='test.out')
        do i2=1,nrho
            print *,"Final c value:",i2,c(i2)
        enddo
        do i2=0,mpts(1)+1
            write(80,*) ,rhocopy(i2,0)
        enddo
    endif

    if(genflag==0) print *,"Normalization Check:",rhosum
    if(rhonorm>0.05) penaltyflag=1 !If normalization far off, penalize
fitness
endif
!-----Scale values if scaling flag is on-----
    if(scaleflag(i1)==1) then
        calcmax=calc(i3)
        calcmin=calc(i3)
        do i2=i3,i3+onu(i1)-1 !Find max and min values
            if(calc(i2)>calcmax) calcmax=calc(i2)
            if(calc(i2)<calcmin) calcmin=calc(i2)
        enddo
        scaleval=(scalemax(i1)-scalemin(i1))/(calcmax-calcmin)
        do i2=i3,i3+onu(i1)-1 !Scale all values to scaling
range
            calc(i2)=calc(i2)*scaleval-scaleval*calcmin+scalemin(i1)
        enddo
    endif
    i3=i3+onu(i1)
enddo
end subroutine cal

subroutine convert_rho(c,sv,rho)
!-----
! Convert rho from basis to x,y form
!-----
    use set_kinds
    use masterdim
    use rhopmfsig
    implicit none
    integer(ik) :: i4,i3,i2,i1,i4start,i4end,imax
    real(rk) ::
c(ndim),sv(ndim),g(ndim,ndim),rho(0:rhodim(1)+1,0:rhodim(2)+1), &

```

```

    rhobas(0:rhodim(1)+1,0:rhodim(2)+1)

    if(dimen == 1) then
        i4start=0
        i4end=0
    else if (dimen == 2) then
        i4start=1
        i4end=mpts(2)
    endif
    do i3=1,mpts(1)
        do i4=i4start,i4end
            rho(i3,i4)=0
        enddo
    enddo
    do i2=1,nrho
        call get_rhobas(basis,rhobas,i2)
        do i3=1,mpts(1)
            do i4=i4start,i4end
                rho(i3,i4)=rho(i3,i4)+c(i2)*sv(i2)*rhobas(i3,i4)
            enddo
        enddo
    enddo
! Produce a zero border around rho
    if(dimen == 1) then
        rho(0,0)=0
        rho(mpts(1)+1,0)=0
    else if (dimen == 2) then
        imax=mpts(2)+1
        do i1=0,mpts(1)+1
            rho(i1,0)=0
            rho(i1,imax)=0
        enddo
        imax=mpts(1)+1
        do i2=0,mpts(2)
            rho(0,i2)=0
            rho(imax,i2)=0
        enddo
    endif

end subroutine convert_rho


subroutine norm_rho(rho,rhsum)
!-----
! Re-Normalize rho. Only used if rho is within 5% of 1 already. Otherwise,
! the population member is penalized.
!-----
    use set_kinds
    use masterdim
    use rhopmfsig
    implicit none
    integer(ik) :: i1,i2,imin,imax
    real(rk) :: rho(0:rhodim(1)+1,0:rhodim(2)+1),rhsum

    if(dimen == 1) then
        imin=0

```



```

    imax=0
    else if(dimen == 2) then
        imin=1
        imax=mpts(2)
    endif
    rhosum=0
    do i1=1,mpts(1)
        do i2=imin,imax
            rhosum=rhosum+rho(i1,i2) ! Sum for normalization
        enddo
    enddo

    do i1=1,mpts(1)
        do i2=imin,imax
            if(dimen==1) then
                rho(i1,i2)=rho(i1,i2)/(rhosum*delx(1))
            else if(dimen==2) then
                rho(i1,i2)=rho(i1,i2)/(rhosum*delx(1)*delx(2))
            endif
        enddo
    enddo

    if(dimen==1) then
        rhosum=rhosum*delx(1)
    else if(dimen==2) then
        rhosum=rhosum*delx(1)*delx(2)
    endif

end subroutine norm_rho

```

```

subroutine derivs(nv,x,y,dydx)
!-----
-
! Subroutine for propogation of population. This dif. eq. is the heart of
the
! Smoluchowski equation solution in the SVD basis.
! Called from RK4. Newton integrator was not adequate. Stiffness problems
! encountered when too many basis functions are used, but otherwise works
well.
!-----
-
    use set_kinds
    use masterdim
    use rhopmfsig
    implicit none
    integer(ik) :: nv,i1,i2
    real(rk) :: t,y(ndim),dydx(ndim),x, sums(ndim)

    sums(:)=0
    do i1=1,nrho
        do i2=1,nrho
            sums(i1)=sums(i1)+svs(i2)*gs(i1,i2)*y(i2)
        enddo
        dydx(i1)=1/svs(i1)*sums(i1)
    enddo

```

```

return
end subroutine derivs

subroutine get_pmf(aux,pmf,nx,ny)
!-----
! Determine the potential surface (when nx and ny = 0)
! Potential surface is a sum of Gaussian dimples.
!
! Can be used to get derivatives, although this is now deprecated and the
! subroutine get_dpmf is used for that purpose now because it minimizes
! overall subroutine calls to cut down on computational cost.
!-----

use set_kinds
use masterdim
use obscalc
use rhopmfsig
implicit none
integer(ik) :: i,k,i1,i2,i2end,imax,nx,ny
real(rk) :: c(xdim),aux(auxdim)
real(rk) :: pmf(0:rhodim(1)+1,0:rhodim(2)+1)
real(rk) :: x1,x2,x(statedim,xdim)
real(rk) :: w(statedim,xdim),d(statedim)

i2end=0
if(dimen==2) then
  i2end=mpts(2)+1
endif
do i1=0,mpts(1)+1
  do i2=0,i2end
    pmf(i1,i2)=0
  enddo
enddo

do k=1,statenum
  d(k)=d0(k,0)
  w(k,1)=w0(k,0,1)
  x(k,1)=x0(k,0,1)
  do i=1,auxnum
    d(k)=d(k)+d0(k,i)*(aux(i)-aux0(i))
!!-----Fix problem with potential going above 0-----
    if(d(k)<0) d(k)=0
!!-----
    w(k,1)=w(k,1)+w0(k,i,1)*(aux(i)-aux0(i))
    x(k,1)=x(k,1)+x0(k,i,1)*(aux(i)-aux0(i))
    x(k,2)=0
  enddo
  c(1)=1/w(k,1)**2
  c(2)=0
  if(dimen == 2) then
    w(k,2)=w0(k,0,2)
    x(k,2)=x0(k,0,2)
    do i=1,auxnum
      w(k,2)=w(k,2)+w0(k,i,2)*(aux(i)-aux0(i))

```

```

      x(k,2)=x(k,2)+x0(k,i,2)*(aux(i)-aux0(i))
    enddo
    c(2)=1/w(k,2)**2
  endif

  if(nx == 0 .and. ny==0) then !Give pmf
    do i1=0,mpts(1)+1
      do i2=0,i2end
        x1=i1*delx(1)
        x2=i2*delx(2)
        pmf(i1,i2)=pmf(i1,i2)-d(k)* &
          exp(-c(1)*(x1-x(k,1))**2-c(2)*(x2-x(k,2))**2)
      enddo
    enddo
  else if(nx==1 .and. ny==0) then !Give d/dx pmf
    do i1=0,mpts(1)+1
      do i2=0,i2end
        x1=i1*delx(1)
        x2=i2*delx(2)
        pmf(i1,i2)=pmf(i1,i2)+2*d(k)*c(1)*(x1-x(k,1))* &
          exp(-c(1)*(x1-x(k,1))**2-c(2)*(x2-x(k,2))**2)
      enddo
    enddo
  else if(nx==2 .and. ny==0) then !Give d2/dx**2 pmf
    do i1=0,mpts(1)+1
      do i2=0,i2end
        x1=i1*delx(1)
        x2=i2*delx(2)
        pmf(i1,i2)=pmf(i1,i2)+2*d(k)*c(1)* &
          exp(-c(1)*(x1-x(k,1))**2-c(2)*(x2-x(k,2))**2)- &
          d(k)*((c(1))**2)*(2*x1-2*x(k,1))**2* &
          exp(-c(1)*(x1-x(k,1))**2-c(2)*(x2-x(k,2))**2)
      enddo
    enddo
  else if(nx==0 .and. ny==1) then !Give d/dy pmf
    do i1=0,mpts(1)+1
      do i2=0,i2end
        x1=i1*delx(1)
        x2=i2*delx(2)
        pmf(i1,i2)=pmf(i1,i2)+2*d(k)*c(2)*(x2-x(k,2))* &
          exp(-c(1)*(x1-x(k,1))**2-c(2)*(x2-x(k,2))**2)
      enddo
    enddo
  else if(nx==0 .and. ny==2) then !Give d2/dy**2 pmf
    do i1=0,mpts(1)+1
      do i2=0,i2end
        x1=i1*delx(1)
        x2=i2*delx(2)
        pmf(i1,i2)=pmf(i1,i2)+2*d(k)*c(2)* &
          exp(-c(1)*(x1-x(k,1))**2-c(2)*(x2-x(k,2))**2)- &
          d(k)*((c(2))**2)*(2*x2-2*x(k,2))**2* &
          exp(-c(1)*(x1-x(k,1))**2-c(2)*(x2-x(k,2))**2)
      enddo
    enddo
  else
    print *, "Mixed and higher derivatives not currently supported."
    STOP
  end

```

```

        endif
    enddo
!   Produce a zero border around PMF
    if(dimen == 1) then
        pmf(0,0)=0
        pmf(mpts(1)+1,0)=0
    else if (dimen == 2) then
        imax=mpts(2)+1
        do i1=0,mpts(1)+1
            pmf(i1,0)=0
            pmf(i1,imax)=0
        enddo
        imax=mpts(1)+1
        do i2=0,mpts(2)
            pmf(0,i2)=0
            pmf(imax,i2)=0
        enddo
    endif

end subroutine get_pmf

subroutine get_dpmf(aux,pmf,dpmf,d2pmf)
!-----
! Gives analytical first and second derivatives for the potential surface
! with a single subroutine call
!-----
-
    use set_kinds
    use masterdim
    use obscalc
    use rhopmfsig
    implicit none
    integer(ik) :: i,k,i1,i2,i2end,imax
    real(rk) :: c(xdim),aux(auxdim)
    real(rk) ::
pmf(0:rhodim(1)+1,0:rhodim(2)+1),dpmf(2,0:rhodim(1)+1,0:rhodim(2)+1), &
d2pmf(2,0:rhodim(1)+1,0:rhodim(2)+1)
    real(rk) :: x1,x2,x(statedim,xdim)
    real(rk) :: w(statedim,xdim),d(statedim), evar

    i2end=0
    if(dimen==2) then
        i2end=mpts(2)+1
    endif
    do i1=0,mpts(1)+1
        do i2=0,i2end
            pmf(i1,i2)=0
            dpmf(:,i1,i2)=0
            d2pmf(:,i1,i2)=0
        enddo
    enddo

    do k=1,statenum
        d(k)=d0(k,0)
        w(k,1)=w0(k,0,1)
    enddo

```

```

x(k,1)=x0(k,0,1)
do i=1,auxnum
  d(k)=d(k)+d0(k,i)*(aux(i)-aux0(i))
  w(k,1)=w(k,1)+w0(k,i,1)*(aux(i)-aux0(i))
  x(k,1)=x(k,1)+x0(k,i,1)*(aux(i)-aux0(i))
  x(k,2)=0
enddo
c(1)=1/w(k,1)**2
c(2)=0
if(dimen == 2) then
  w(k,2)=w0(k,0,2)
  x(k,2)=x0(k,0,2)
  do i=1,auxnum
    w(k,2)=w(k,2)+w0(k,i,2)*(aux(i)-aux0(i))
    x(k,2)=x(k,2)+x0(k,i,2)*(aux(i)-aux0(i))
  enddo
  c(2)=1/w(k,2)**2
endif

!Give pmf
do i1=0,mpts(1)+1
  do i2=0,i2end
    x1=i1*delx(1)
    x2=i2*delx(2)
    evar=exp(-c(1)*(x1-x(k,1))**2-c(2)*(x2-x(k,2))**2) !Evaluate
exponential one time
    pmf(i1,i2)=pmf(i1,i2)-d(k)*evar
    dpmf(1,i1,i2)=dpmf(1,i1,i2)+2*d(k)*c(1)*(x1-x(k,1))*evar
    d2pmf(1,i1,i2)=d2pmf(1,i1,i2)+2*d(k)*c(1)* &
    evar-d(k)*((c(1))**2)*(2*x1-2*x(k,1))**2*evar
    dpmf(2,i1,i2)=dpmf(2,i1,i2)+2*d(k)*c(2)*(x2-x(k,2))*evar
    d2pmf(2,i1,i2)=d2pmf(2,i1,i2)+2*d(k)*c(2)* &
    evar-d(k)*((c(2))**2)*(2*x2-2*x(k,2))**2*evar
  enddo
enddo
enddo
! Produce a zero border around PMF
if(dimen == 1) then
  pmf(0,0)=0
  pmf(mpts(1)+1,0)=0
  dpmf(:,0,0)=0
  dpmf(:,mpts(1)+1,0)=0
  d2pmf(:,0,0)=0
  d2pmf(:,mpts(1)+1,0)=0
else if (dimen == 2) then
  imax=mpts(2)+1
  do i1=0,mpts(1)+1
    pmf(i1,0)=0
    pmf(i1,imax)=0
    dpmf(:,i1,0)=0
    dpmf(:,i1,imax)=0
    d2pmf(:,i1,0)=0
    d2pmf(:,i1,imax)=0
  enddo
  imax=mpts(1)+1
  do i2=0,mpts(2)
    pmf(0,i2)=0

```

```

        pmf(imax,i2)=0
        dpmf(:,0,i2)=0
        dpmf(:,imax,i2)=0
        d2pmf(:,0,i2)=0
        d2pmf(:,imax,i2)=0
    enddo
endif

end subroutine get_dpmf

subroutine get_rho(pmf,aux,rho)
!-----
!
! Get the equilibrium probability density for a potential surface
!-----
!
    use set_kinds
    use masterdim
    use obscalc
    use rhopmfsig
    use constants
    implicit none
    integer(ik) :: i1,i2,imin,imax
    real(rk) :: aux(auxdim),rho(0:rhodim(1)+1,0:rhodim(2)+1), &
    pmf(0:rhodim(1)+1,0:rhodim(2)+1),rhosum

    rhosum=0
    if(dimen == 1) then
        imin=0
        imax=0
    else if(dimen == 2) then
        imin=1
        imax=mpts(2)
    endif
    do i1=1,mpts(1)
        do i2=imin,imax
            rho(i1,i2)=exp(-pmf(i1,i2)/(kb*aux(1)))
            rhosum=rhosum+rho(i1,i2) ! Sum for normalization
        enddo
    enddo

!-----Test Block-----
!
    print *, "rhosum", rhosum
    rhox(:,:)=0
    do i1=1,mpts(1)
        do i2=imin,imax
            rhox(1,i1)=rhox(1,i2)+exp(-pmf(i1,i2)/(kb*aux(1)))
        enddo
    enddo

!-----End Test-----
!
    Normalization of rho
    do i1=1,mpts(1)
        do i2=imin,imax
            if(dimen==1) then
                rho(i1,i2)=rho(i1,i2)/(rhosum*delx(1))
            else if(dimen==2) then

```

```

        rho(i1,i2)=rho(i1,i2)/(rhosum*delx(1)*delx(2))
    endif
enddo
enddo

! Produce a zero border around rho
if(dimen == 1) then
    rho(0,0)=0
    rho(mpts(1)+1,0)=0
else if (dimen == 2) then
    imax=mpts(2)+1
    do i1=0,mpts(1)+1
        rho(i1,0)=0
        rho(i1,imax)=0
    enddo
    imax=mpts(1)+1
    do i2=0,mpts(2)+1
        rho(0,i2)=0
        rho(imax,i2)=0
    enddo
endif

end subroutine get_rho

subroutine get_signal(l,rho,sig,aux)
!-----
!
! This subroutine integrates the signal function s over the probability
! surface rho to obtain the weighted signal at the condition given by
aux().
! "l" is the signal type
!-----
-
    use set_kinds
    use masterdim
    use obscalc
    use rhopmfsig
    use constants
    implicit none
    integer(ik) :: i1,i2,i,j,l,i2start,i2end
    real(rk) :: rho(0:rhodim(1)+1,0:rhodim(2)+1),sig,aux(auxdim)
    real(rk) :: x(xdim),sigx

    if(dimen == 1) then
        i2start=0
        i2end=0
        a(1,2)=0
    else if (dimen == 2) then
        i2start=1
        i2end=mpts(2)
    endif
    sig=0
! Cycle through the coordinates x(i)
    do i1=1,mpts(1)
        x(1)=delx(1)*i1
        do i2=i2start,i2end

```

```

        x(2)=delx(2)*i2
!      Set signal at position x1,x2 to constant baseline
        sigx=s0(1,0)
!      Add linear auxiliary parameter (e.g. temperature) dependence to
baseline
        do i=1,auxnum
            sigx=sigx+s0(1,i)*(aux(i)-aux0(i))
        enddo

!-----Sigmoid-----

!      sigx=sigx+s1(1,1)*x(1)    !Slope
        sigx=sigx+s1(1,1)*(a(1,1)*x(1)+a(1,2)*x(2))    !Adds plane
        sigx=sigx+s1(1,2)*x(2) !Tilt plane
!      sigx=sigx+sigstep(1)/( 1 + exp( ( x(1)-b(1) )/s2(1,1)  ) ) ! 1-D
Sigmoid
        sigx=sigx+sigstep(1)/( 1 + exp( ( -1*(a(1,1)*x(1)+a(1,2)*x(2))-b(1)
)/s2(1,1)  ) ) ! 2-D Sigmoid

!-----End sigmoid-----

!-----Add quadrature-----
!      sigx=sigx+s2(1,1)*x(1)**2 !Add quadratic component to baseline
!-----

!-----0 check-----
        if(sigx.lt.0) sigx=0.0001 !Truncate at 0 (use value close to 0 to
avoid strange MPI errors)
!-----

!      Weight signal by probability density before going to next position x(i)
        sig=sig+sigx*rho(i1,i2)
        enddo
        enddo

        end subroutine get_signal

        subroutine get_sigx(l,rho,sigx,aux)
!-----
!
!      Like get_signal above, but instead of the integrated signal
!      returns signal values at each x-position
!-----
!
        use set_kinds
        use masterdim
        use obscalc
        use rhopmfsig
        use constants
        implicit none
        integer(ik) :: i1,i2,i,j,l,i2start,i2end
        real(rk) :: rho(0:rhodim(1)+1,0:rhodim(2)+1),aux(auxdim)
        real(rk) :: x(xdim),sigx(0:rhodim(1),0:rhodim(2))

```



```

        if(dimen == 1) then
            i2start=0
            i2end=0
            a(1,2)=0
        else if (dimen == 2) then
            i2start=0
            i2end=mpts(2)+1
        endif
        sigx(:,:)=0
!      Cycle through the coordinates x(i)
        do i1=0,mpts(1)+1
            x(1)=delx(1)*i1
            do i2=i2start,i2end
                x(2)=delx(2)*i2
!      Set signal at position x1,x2 to constant baseline
                sigx(i1,i2)=s0(1,0)
!      Add linear auxiliary parameter (e.g. temperature) dependence to
baseline
                do i=1,auxnum
                    sigx(i1,i2)=sigx(i1,i2)+s0(1,i)*(aux(i)-aux0(i))
                enddo

!-----Add quadrature-----
!      sigx(i1,i2)=sigx(i1,i2)+s2(1,1)*x(1)**2 !Add quadratic component
to baseline
!-----

!-----Sigmoid-----

!      sigx(i1,i2)=sigx(i1,i2)+s1(1,1)*x(1) !Slope
        sigx(i1,i2)=sigx(i1,i2)+s1(1,1)*(a(1,1)*x(1)+a(1,2)*x(2)) !Adds
plane
        sigx(i1,i2)=sigx(i1,i2)+s1(1,2)*x(2) !Tilt plane
!      sigx(i1,i2)=sigx(i1,i2)+sigstep(1)/( 1 + exp( ( x(1)-b(1)
)/s2(1,1) ) ) ! 1-D sigmoid
        sigx(i1,i2)=sigx(i1,i2)+sigstep(1)/( 1 + exp( -1*(
(a(1,1)*x(1)+a(1,2)*x(2))-b(1) )/s2(1,1) ) ) ! 2-D Sigmoid

!-----End sigmoid-----

!      Add step function to signal if one upper side of dividing surface
!      if(a(1,1)*x(1)+a(1,2)*x(2) > b(1)) then
!          sigx(i1,i2)=sigx(i1,i2)+sigstep(1)
!      endif

!-----0 check-----
        if(sigx(i1,i2).lt.0) sigx(i1,i2)=0.0001
!-----

!-----Step to 0 in y-----
!      if(x(2) > s2(1,2)) then
!          sigx(i1,i2)=0.0001
!          print *, "setting 0", x(2)
!      endif
!-----

        enddo

```

```

        enddo

        end subroutine get_sigx

!-----
!
! Initializes time propagation by computing the orthonormal SVD basis for rho
! and the g-matrix that is used in the differential equation (D is wrapped up
! in g).
!-----
!
        use masterdim
        use obscalc
        use rhopmfsig
        use constants
        implicit none
        integer(ik) :: i,i1,i2,i3,i4,imat,m,xpos(xdim),exitflag,i3end
        real(rk) :: aux_t0(auxdim),aux(auxdim),aux_after(auxdim),delaux(auxdim)
        real(rk) :: rho(0:rhodim(1)+1,0:rhodim(2)+1), &
        pmf(0:rhodim(1)+1,0:rhodim(2)+1),deriv,deriv_pmf!,xpos(xdim)
        real(rk) :: mat(dim,ndim), c(ndim), sv(ndim), g(ndim,ndim),
        gh(ndim,ndim),gah(ndim,ndim), &
        v(ndim,ndim),g12, dpmf(2,0:rhodim(1)+1,0:rhodim(2)+1), &
        d2pmf(2,0:rhodim(1)+1,0:rhodim(2)+1),drho(4),rhocopy(0:rhodim(1)+1,0:rhodim(2)
        )+1),dtest(4), gh12, gah12
        ! Check which auxiliary parameters are being 'jumped' at t=0, and figure
        ! out the stepsize for each to scan them for basis construction
        ! As elsewhere in the program aux(1) MUST be the temperature and MUST
        always
        ! be read in.
        ! call cpu_time(t1)
        do i=1,auxnum
            delaux(i)=(aux_after(i)-aux_t0(i))/float(nrho-1)
        enddo
        ! Loop through nrho values of aux(), compute PMF, then rho
        do i1=1,nrho
            do i=1,auxnum
                aux(i)=aux_t0(i)+float(i1-1)*delaux(i)
            enddo
            call get_pmf(aux,pmf,0,0)
            call get_rho(pmf,aux,rho)

        ! Save rho in matrix for singular value decomposition; imat positions
        both
        ! 1D and 2D rhos in the column dimension of matrix mat()
            if(dimen == 1) then
                m=mpts(1)
                do i2=1,mpts(1)
                    imat=i2
                    mat(imat,i1)=rho(i2,0)
                enddo
            else if(dimen == 2) then
                m=mpts(1)*mpts(2)
                do i2=1,mpts(1)

```

```

        do i3=1,mpts(2)
            imat=(i3-1)*mpts(2)+i2
            mat(imat,i1)=rho(i2,i3)
        enddo
    enddo
endif
enddo

!-----Test Block-----

    if(genflag==0) then
        rhocopy(:,:)=rho(:,:)
        !! Write pmf and rho to file
        open(unit=24,file='pmfrhotest1.out')
        i3end=0
        if(dimen==2) then
            i3end=mpts(2)+1
        endif

        write(24,*) "xpos ypos pmf rho"
        do i2=0,mpts(1)+1
            do i3=0,i3end
                write(24,'(2(f5.2,1x),f6.1,1x,f12.10)') delx(1)*i2, &
                    delx(2)*i3, pmf(i2,i3), rho(i2,i3)
            enddo
        enddo
    endif

!-----End Test Block-----

!      Singular value decompose mat() to obtain basis coefficient matrix v
!      (at least 2x2 if nrho=2) and basis function matrix basis()
!      call svdcmp(mat,basis,m,nrho,sv,v)
!Transpose v for sorting
v=transpose(v)

    call heapsort(nrho,m,sv,v,basis)

!Transpose back
v=transpose(v)

    exitflag=0
    do i1=2,nrho
        if(sv(i1)/sv(i1-1).LE.0.05.AND.genflag==0) then
            write(6,('("NRHO= ",i2," IS RECOMMENDED")')) i1-1
            exitflag=1
        else if(i1.EQ.nrho.AND.genflag==0) then
            write(6,('("NRHO SHOULD PROBABLY BE LARGER")'))
        endif
        if(exitflag == 1) exit
    enddo
!      c() is the orthogonal initial condition vector at aux_t0(), for use by
propag_rho
    do i1=1,nrho
        c(i1)=v(1,i1)
    enddo

!-----Test Block-----

```

```

if(genflag==0) then
    call convert_rho(c,sv,rho)
    rhocopy(:,:)=rho(:,:)
    !! Write pmf and rho to file
    open(unit=25,file='pmfrhotest2.out')
    i3end=0
    if(dimen==2) then
        i3end=mpts(2)+1
    endif

    write(25,*) "xpos ypos pmf rho"
    do i2=0,mpts(1)+1
        do i3=0,i3end
            write(25,'(2(f5.2,1x),f6.1,1x,f12.10)') delx(1)*i2, &
                delx(2)*i3, pmf(i2,i3), rho(i2,i3)
        enddo
    enddo
endif

!-----End Test Block-----

!-----Test-----
if(genflag==0) then
    open(unit=26,file='derivtest1.out')
    open(unit=27,file='derivtest2.out')
endif
!-----End Test-----

!      Get analytical derivatives for pmf
!      call get_dpmf(aux,pmf,dpmf,d2pmf)
!      Compute the propagator matrix g() for the Smoluchowski equation
!      drho/dt = SUM {i} OF Dii/kt
!      {d2V/dxi2*rho+dV/dxi*drho/dxi+kt*d2rho/dxi2}
!      by integrating the basis functions
!      Loop over basis indices
! call cpu_time(t1)
do i1=1,nrho
    do i2=1,nrho
        g(i1,i2)=0
        gh(i1,i2)=0
        gah(i1,i2)=0
        call get_rhobas(basis,rho,i2)
!      Loop over x,y coordinates by reconstructing them from mat index
        do i3=1,m
            xpos(2)=(i3-1)/mpts(1)+1
            xpos(1)=i3-mpts(1)*(xpos(2)-1)
            xpos(2)=(dimen-1)*xpos(2)
!      Loop over x,y derivatives
            g12=0
            gh12=0
            gah12=0
            call deriv2(rho,xpos,drho)
            call deriv2(pmf,xpos,dtest)
            do i4=1,dimen
!                g12=g12+dc(i4)*delx(i4)*(
d2pmf(i4,xpos(1),xpos(2))*basis(i3,i2)/(kb*aux(1))+ &
!                dpmf(i4,xpos(1),xpos(2))*deriv(i4,0,rho,xpos)/(kb*aux(1))+&

```

```

!      deriv(i4,i4,rho,xpos) )
      g12=g12+dc(i4)*delx(i4)*(
d2pmf(i4,xpos(1),xpos(2))*basis(i3,i2)/(kb*aux(1))+ &
      dpmf(i4,xpos(1),xpos(2))*drho(i4)/(kb*aux(1))+&
      drho(2+i4) )

!-----Hermitian and anti-hermitian division of operator-----
-
!      gh12=gh12+dc(i4)*delx(i4)*(
d2pmf(i4,xpos(1),xpos(2))*basis(i3,i2)/(kb*aux(1))+ &
!      drho(2+i4) )
!      gah12=gah12+dc(i4)*delx(i4)*(
dpmf(i4,xpos(1),xpos(2))*drho(i4)/(kb*aux(1)) )
!-----End H,A-----
--

!-----Test-----
!if(genflag.eq.0.and.i1.eq.1.and.i2.eq.1) then
! write(26,'(2(f5.2,1x),2(f12.10,1x))')
xpos(1)*delx(1),xpos(2)*delx(2),dpmf(i4,xpos(1),xpos(2)),d2pmf(i4,xpos(1),xpo
s(2))
! write(27,'(2(f5.2,1x),2(f12.10,1x))')
xpos(1)*delx(1),xpos(2)*delx(2),dtest(i4),dtest(2+i4)
!endif
!-----End Test-----
      if(i3==1) then
        g12=0
        gh12=0
        gah12=0
      endif
      if(i3==m) then
        g12=0
        gh12=0
        gah12=0
      endif
    enddo
  enddo
  enddo
  enddo

!-----Hermitian and anti-hermitian division of operator-----
-
!      if(genflag==0) then
!        do i1=1,nrho
!          print *, "gh1 ", (gh(i1,i2),i2=1,nrho)
!        enddo

!        do i1=1,nrho
!          print *, "gah1", (gah(i1,i2),i2=1,nrho)
!        enddo
!      endif
!      do i1=1,nrho
!        i2=1

```

```

!      do while(i2<i1)
!      gh(i1,i2)=(gh(i1,i2)+gh(i2,i1))/2
!      gh(i2,i1)=gh(i1,i2)
!      gah(i1,i2)=(gah(i1,i2)-gah(i2,i1))/2
!      gah(i2,i1)=-gah(i1,i2)
!      i2=i2+1
!      enddo
!      enddo
!      if(genflag==0) then
!      do i1=1,nrho
!      print *, "gh ", (gh(i1,i2),i2=1,nrho)
!      enddo

!      do i1=1,nrho
!      print *, "gah", (gah(i1,i2),i2=1,nrho)
!      enddo

!      do i1=1,nrho
!      print *, "sum", (gah(i1,i2)+gh(i1,i2),i2=1,nrho)
!      enddo

!      do i1=1,nrho
!      print *, "g  ", (g(i1,i2),i2=1,nrho)
!      enddo
!      endif

!-----End H,A-----
--

! call cpu_time(t2)
!print *, "time:", t2-t1
!      All of this is just for the nrho=3 test case
!      do i1=1,m
!      write(7,*) (mat(i1,i2),i2=1,3)
!      call convert_rho(c,sv,rho)
!      write(8,*) rho(i1,0)
!      enddo
!      write(6,*) "G:"
!      write(6,*) g(1,1),g(1,2),g(1,3)
!      write(6,*) g(2,1),g(2,2),g(2,3)
!      write(6,*) g(3,1),g(3,2),g(3,3)
!      write(6,*) "sv:",sv(1),sv(2),sv(3)
!      if(genflag==0) then
!      write(6,*) "sv:",sv(1),sv(2),sv(3)
!      do i1=1,nrho
!      print *, "sv:",i1,sv(i1)
!      write(6,*) "C(",i1,") at equilibrium (final PMF):",v(nrho,i1) !
Print final values
!      enddo

!      write(6,*) "w*G*Ceq matrix product:"
!      do i1=1,nrho
!      g12=0
!      gh12=0
!      do i2=1,nrho
!      g12=g12+g(i1,i2)*sv(i2)*v(nrho,i2)

```

```

        gh12=gh12+(gh(i1,i2)+gah(i1,i2))*sv(i2)*v(nrho,i2)
    enddo
    write(6,*) "Product for row",i1," of g (should be 0):",g12
    write(6,*) "Test:",gh12
enddo

!-----Test-----
!      do i1=1,nrho
!      do i2=1,nrho
!          g(i1,i2)=gh(i1,i2)+gah(i1,i2)
!      enddo
!      enddo
!-----End Test-----

    endif
!      STOP
! call cpu_time(t2)
!print *, "time:",t2-t1
end subroutine propag_init

!      Copy correct basis set column from mat() into rho and compute x position
!      from mat() position index m
    subroutine get_rhobas(mat,rhobas,basnum)
    use set_kinds
    use masterdim
    use rhopmfsig
    integer(ik) :: i1,i2,basnum
    real(rk) :: mat(dim,ndim), &
    rhobas(0:rhodim(1)+1,0:rhodim(2))

    if(dimen == 1) then
        do i1=1,mpts(1)
            rhobas(i1,0)=mat(i1,basnum)
        enddo
    else if(dimen == 2) then
        do i1=1,mpts(1)
            do i2=1,mpts(2)
                rhobas(i1,i2)=mat((i2-1)*mpts(1)+i1,basnum)
            enddo
        enddo
    endif

!      Produce a zero border around rhobas
    if(dimen == 1) then
        rhobas(0,0)=0
        rhobas(mpts(1)+1,0)=0
    else if(dimen == 2) then
        imax=mpts(2)+1
        do i1=0,mpts(1)+1
            rhobas(i1,0)=0
            rhobas(i1,imax)=0
        enddo
        imax=mpts(1)+1
        do i2=0,mpts(2)
            rhobas(0,i2)=0
            rhobas(imax,i2)=0
        enddo
    endif

end subroutine get_rhobas

```

```

! Function deriv() calculates 1st or 2nd derivatives by finite difference
! The first two arguments are the index of the variables (e.g. 1=x, 2=y
! so 1,1 = 2nd deriv w/r x, 2,0= 1st deriv w/r y); the next is a matrix
! containing the function (second index=0 for one dimension) the
! last is the x,y location in the column vector where the derivative
! is to be taken. deriv() assumes that location is bounded by 1..mpts, but
! func contains range 0...mpts+1 so edge derivatives can be taken
accurately.

```

```

function deriv(n1,n2,func,xpos)
use masterdim
use rhopmfsig
implicit none
real(rk) :: deriv
integer(ik) :: i1,j,n(2),order(xdim),n1,n2
integer(ik) :: xpos(xdim),ptend(xdim)
real(rk) :: func(0:rhodim(1)+1,0:rhodim(2)+1)

n(1)=n1
n(2)=n2
ptend(1)=mpts(1)-xpos(1)
ptend(2)=mpts(2)-xpos(2)
! Determine order of derivatives in each dimension
do j=1,dimen
  order(j)=0
enddo
do i1=1,2
  order(n(i1))=order(n(i1))+1
enddo
! Take requested derivative
if(order(1) == 1 .and. order(2) == 0) then
  if(xpos(1) .lt. 3 .or. ptend(1) .lt. 3) then ! 3-point deriv at edges
    deriv=(func(xpos(1)+1,xpos(2))-func(xpos(1)-1,xpos(2)))/(2*delx(1))
  else ! 5-point stencil derivative
    deriv=(-func(xpos(1)+2,xpos(2))+8*func(xpos(1)+1,xpos(2))- &
      8*func(xpos(1)-1,xpos(2))+func(xpos(1)-2,xpos(2)))/(12*delx(1))
  endif
else if(order(1) == 2 .and. order(2) == 0) then
  if(xpos(1) .lt. 3 .or. ptend(1) .lt. 3) then
    deriv=(func(xpos(1)+1,xpos(2))-2*func(xpos(1),xpos(2))+ &
      func(xpos(1)-1,xpos(2)))/delx(1)**2
  else
    deriv=(-func(xpos(1)+2,xpos(2))+16*func(xpos(1)+1,xpos(2))- &
      30*func(xpos(1),xpos(2))+16*func(xpos(1)-1,xpos(2))- &
      func(xpos(1)-2,xpos(2)))/(12*delx(1)**2)
  endif
else if(order(1) == 0 .and. order(2) == 1) then
  if(xpos(2) .lt. 3 .or. ptend(2) .lt. 3) then
    deriv=(func(xpos(1),xpos(2)+1)-func(xpos(1),xpos(2)-1))/(2*delx(2))
  else
    deriv=(-func(xpos(1),xpos(2)+2)+8*func(xpos(1),xpos(2)+1)- &
      8*func(xpos(1),xpos(2)-1)+func(xpos(1),xpos(2)-2))/(12*delx(2))
  endif
else if(order(1) == 0 .and. order(2) == 2) then
  if(xpos(2) .lt. 3 .or. ptend(2) .lt. 3) then
    deriv=(func(xpos(1),xpos(2)+1)-2*func(xpos(1),xpos(2))+ &

```



```

        func(xpos(1),xpos(2)-1))/delx(2)**2
    else
        deriv=(-func(xpos(1),xpos(2)+2)+16*func(xpos(1),xpos(2)+1)- &
        30*func(xpos(1),xpos(2))+16*func(xpos(1),xpos(2)-1)- &
        func(xpos(1),xpos(2)-2))/(12*delx(2)**2)
    endif
    else
        write(6,*) "Mixed and higher derivatives not currently supported."
        stop
    endif

end function deriv

subroutine deriv2(func,xpos,deriv)
use masterdim
use rhopmfsig
implicit none
real(rk) :: deriv(4)
integer(ik) :: i1,j,n(2),order(xdim),n1
integer(ik) :: xpos(xdim),ptend(xdim)
real(rk) :: func(0:rhodim(1)+1,0:rhodim(2)+1)

ptend(1)=mpts(1)-xpos(1)
ptend(2)=mpts(2)-xpos(2)

! Take requested derivative
if(xpos(1) .lt. 3 .or. ptend(1) .lt. 3) then ! 3-point deriv at edges
    deriv(1)=(func(xpos(1)+1,xpos(2))-func(xpos(1)-1,xpos(2)))/(2*delx(1))
    deriv(3)=(func(xpos(1)+1,xpos(2))-2*func(xpos(1),xpos(2))+ &
    func(xpos(1)-1,xpos(2)))/delx(1)**2
else ! 5-point stencil derivative
    deriv(1)=(-func(xpos(1)+2,xpos(2))+8*func(xpos(1)+1,xpos(2))- &
    8*func(xpos(1)-1,xpos(2))+func(xpos(1)-2,xpos(2)))/(12*delx(1))
    deriv(3)=(-func(xpos(1)+2,xpos(2))+16*func(xpos(1)+1,xpos(2))- &
    30*func(xpos(1),xpos(2))+16*func(xpos(1)-1,xpos(2))- &
    func(xpos(1)-2,xpos(2)))/(12*delx(1)**2)
endif
if(xpos(2) .lt. 3 .or. ptend(2) .lt. 3) then
    deriv(2)=(func(xpos(1),xpos(2)+1)-func(xpos(1),xpos(2)-1))/(2*delx(2))
    deriv(4)=(func(xpos(1),xpos(2)+1)-2*func(xpos(1),xpos(2))+ &
    func(xpos(1),xpos(2)-1))/delx(2)**2
else
    deriv(2)=(-func(xpos(1),xpos(2)+2)+8*func(xpos(1),xpos(2)+1)- &
    8*func(xpos(1),xpos(2)-1)+func(xpos(1),xpos(2)-2))/(12*delx(2))
    deriv(4)=(-func(xpos(1),xpos(2)+2)+16*func(xpos(1),xpos(2)+1)- &
    30*func(xpos(1),xpos(2))+16*func(xpos(1),xpos(2)-1)- &
    func(xpos(1),xpos(2)-2))/(12*delx(2)**2)
endif

end subroutine deriv2

! SVD subroutine
! mat is the m by n input matrix, w the singular value array, v is the
! matrix of eigenvectors containing the svd basis functions, and the m
! by n matrix a contains the linear combination coefficients for the basis
! functions in v. If m is smaller than n, n-m of the singular values

```

! will be returned as zero.

```

subroutine svdcmp(mat,a,m,n,w,v)
use set_kinds
use masterdim
implicit none
integer(ik) :: m,n
! The first dimension of a can be set > second for rect. matrices.
real(rk) :: a(dim,ndim),v(ndim,ndim),w(ndim),mat(dim,ndim)
integer(ik) :: i,its,j,jj,k,l,nm
real(rk) :: anorm,c,f,g,h,s,scale,x,y,z,rv1(ndim),pythag
do i=1,m
do j=1,n
a(i,j)=mat(i,j)
enddo
enddo
g=0.0
scale=0.0
anorm=0.0
do i=1,n
l=i+1
rv1(i)=scale*g
g=0.0
s=0.0
scale=0.0
if(i.le.m)then
do k=i,m
scale=scale+dabs(a(k,i))
enddo
if(scale.ne.0d0)then
do k=i,m
a(k,i)=a(k,i)/scale
s=s+a(k,i)*a(k,i)
enddo
f=a(i,i)
g=-sign(sqrt(s),f)
h=f*g-s
a(i,i)=f-g
do j=1,n
s=0.0
do k=i,m
s=s+a(k,i)*a(k,j)
enddo
f=s/h
do k=i,m
a(k,j)=a(k,j)+f*a(k,i)
enddo
enddo
do k=i,m
a(k,i)=scale*a(k,i)
enddo
endif
endif
w(i)=scale *g
g=0.0
s=0.0
scale=0.0

```

```

if((i.le.m).and.(i.ne.n))then
  do k=1,n
    scale=scale+dabs(a(i,k))
  enddo
  if(scale.ne.0.0)then
    do k=1,n
      a(i,k)=a(i,k)/scale
      s=s+a(i,k)*a(i,k)
    enddo
    f=a(i,1)
    g=-dsign(sqrt(s),f)
    h=f*g-s
    a(i,1)=f-g
    do k=1,n
      rv1(k)=a(i,k)/h
    enddo
    do j=1,m
      s=0.0
      do k=1,n
        s=s+a(j,k)*a(i,k)
      enddo
      do k=1,n
        a(j,k)=a(j,k)+s*rv1(k)
      enddo
    enddo
    do k=1,n
      a(i,k)=scale*a(i,k)
    enddo
  endif
endif
anorm=max(anorm,(dabs(w(i))+dabs(rv1(i))))
enddo
do i=n,1,-1
  if(i.lt.n)then
    if(g.ne.0d0) then
      do j=1,n
        v(j,i)=(a(i,j)/a(i,1))/g
      enddo
      do j=1,n
        s=0.0
        do k=1,n
          s=s+a(i,k)*v(k,j)
        enddo
        do k=1,n
          v(k,j)=v(k,j)+s*v(k,i)
        enddo
      enddo
    endif
    do j=1,n
      v(i,j)=0.0
      v(j,i)=0.0
    enddo
  endif
  v(i,i)=1.0
  g=rv1(i)
  l=i
enddo

```

```

do i=min(m,n),1,-1
  l=i+1
  g=w(i)
  do j=1,n
    a(i,j)=0.0
  enddo
  if(g.ne.0.0)then
    g=1.0/g
    do j=1,n
      s=0.0
      do k=1,m
        s=s+a(k,i)*a(k,j)
      enddo
      f=(s/a(i,i))*g
      do k=i,m
        a(k,j)=a(k,j)+f*a(k,i)
      enddo
    enddo
    do j=i,m
      a(j,i)=a(j,i)*g
    enddo
  else
    do j= i,m
      a(j,i)=0.0
    enddo
  endif
  a(i,i)=a(i,i)+1.0
enddo
do k=n,1,-1
  do its=1,30
    do l=k,1,-1
      nm=l-1
      if((dabs(rv1(l))+anorm).eq.anorm) exit
      if((dabs(w(nm))+anorm).eq.anorm) exit
    enddo
    if((dabs(rv1(l))+anorm).ne.anorm) then
      c=0.0
      s=1.0
      do i=1,k
        f=s*rv1(i)
        rv1(i)=c*rv1(i)
        if((dabs(f)+anorm).eq.anorm) exit
        g=w(i)
        h=pythag(f,g)
        w(i)=h
        h=1.0/h
        c= (g*h)
        s=-(f*h)
        do j=1,m
          y=a(j,nm)
          z=a(j,i)
          a(j,nm)=(y*c)+(z*s)
          a(j,i)=-(y*s)+(z*c)
        enddo
      enddo
    endif
  enddo
  z=w(k)

```

```

if(l.eq.k)then
  if(z.lt.0.0)then
    w(k)=-z
    do j=1,n
      v(j,k)=-v(j,k)
    enddo
  endif
endif
if(l.eq.k) exit
if(its.eq.30) pause 'no convergence in svdcmp'
x=w(l)
nm=k-1
y=w(nm)
g=rv1(nm)
h=rv1(k)
f=((y-z)*(y+z)+(g-h)*(g+h))/(2.0*h*y)
g=pythag(f,ld0)
f=((x-z)*(x+z)+h*((y/(f+sign(g,f)))-h))/x
c=1.0
s=1.0
do j=1,nm
  i=j+1
  g=rv1(i)
  y=w(i)
  h=s*g
  g=c*g
  z=pythag(f,h)
  rv1(j)=z
  c=f/z
  s=h/z
  f=(x*c)+(g*s)
  g=-(x*s)+(g*c)
  h=y*s
  y=y*c
  do jj=1,n
    x=v(jj,j)
    z=v(jj,i)
    v(jj,j)=(x*c)+(z*s)
    v(jj,i)=- (x*s)+(z*c)
  enddo
  z=pythag(f,h)
  w(j)=z
  if(z.ne.0.0)then
    z=1.0/z
    c=f*z
    s=h*z
  endif
  f=(c*g)+(s*y)
  x=-(s*g)+(c*y)
  do jj=1,m
    y=a(jj,j)
    z=a(jj,i)
    a(jj,j)=(y*c)+(z*s)
    a(jj,i)=-(y*s)+(z*c)
  enddo
enddo
rv1(l)=0.0

```

```

        rv1(k)=f
        w(k)=x
    enddo
enddo
return
END subroutine svdcmp

function pythag(a,b)
use set_kinds
implicit none
real(rk) :: pythag
real(rk) :: a,b
real(rk) :: absa,absb
absa=dabs(a)
absb=dabs(b)
if(absa.gt.absb)then
    pythag=absa*dsqrt(1d0+(absb/absa)**2)
else
    if(absb.eq.0.)then
        pythag=0d0
    else
        pythag=absb*dsqrt(1d0+(absa/absb)**2)
    endif
endif
return
END function pythag

!      Version of heapsort which coshuffles two matrices
subroutine heapsort(n,m,x,y,z)
use set_kinds
use masterdim
implicit none
integer(4) :: i,j,k,ir,n,l,m
real(8) :: x(ndim),temp,y(ndim,ndim),tempy(dim),z(dim,ndim),tempz(dim)

!
if(n.ge.2) then
    k=n/2+1
    ir=n
    do while(ir.ne.1)
        if(k.gt.1) then
            k=k-1
            temp=x(k)
            do l=1,n
                tempy(l)=y(k,l)
            enddo
            do l=1,m
                tempz(l)=z(l,k)
            enddo
        else
            temp=x(ir)
            do l=1,m
                tempz(l)=z(l,ir)
            enddo
            do l=1,n
                tempy(l)=y(ir,l)
            enddo
            x(ir)=x(1)

```

```

do l=1,m
  z(l,ir)=z(l,1)
enddo
do l=1,n
  y(ir,l)=y(1,l)
enddo
ir=ir-1
endif
if(ir.ne.1) then
  i=k
  j=2*k
  do while(j.le.ir)
    if(j.lt.ir.and.x(j).gt.x(j+1)) j=j+1
    if(temp.gt.x(j)) then
      x(i)=x(j)
      do l=1,m
        z(l,i)=z(l,j)
      enddo
      do l=1,n
        y(i,l)=y(j,l)
      enddo
      i=j
      j=2*j
    else
      j=ir+1
    endif
  enddo
  x(i)=temp
  do l=1,m
    z(l,i)=tempz(l)
  enddo
  do l=1,n
    y(i,l)=tempy(l)
  enddo
endif
enddo
x(1)=temp
do l=1,m
  z(l,1)=tempz(l)
enddo
do l=1,n
  y(1,l)=tempy(l)
enddo
endif
return
end

```

```

subroutine odesolve(n,y,xinit,xfinal,mindx,errflag,yscale)
integer(4), parameter :: nmax=20
integer(4) :: n,i,ierr,step,errflag
real(8) ::
xinit,y(nmax),xfinal,mindx,x,dx,yscale(nmax),yscal(nmax),nextdx

!      xinitinitial x
!      xfinalfinal x
!      mindx      minimum fractional stepsize allowed (e.g. 0.01

```

```

!           for 1% of computed dt
!   errflagerrflag contains error code for the step
!0=no problem;1=bulirsch stepsize had to be
!reduced;2=Runge-Kutta had to be used;3=failed
!   yscale   contains allowed relative error for each
!           variable (if zero, set to 10** -5 absol. in xscal)
!   see below for other variables

x=xinit
dx=xfinal-xinit
do i=1,n
    yscal(i)= dabs(y(i)*yscale(i))+1d-5
enddo

!   WHILE loop to step from tinit to tfinal; Bulirsch-Stoer is tried
!   initially, Runge-Kutta over the rest of the interval if that fails.

!   Modified to only do RK4 -GES

step=0
errflag=0
do while( errflag.lt.3.and.x.lt.xfinal.and.step.lt.50)
    step=step+1
    if(x+dx.gt.xfinal) then
        dx=xfinal-x
    endif
!   if(errflag.le.1) then
!       call odestep(n,x,y,dx,mindx,nextdx,yscal,ierr)
!       errflag=ierr
!       dx=nextdx
!   else if (errflag.eq.2) then
!       if(errflag.le.2) then
!           call rkstep(n,x,y,dx,mindx,nextdx,yscal,ierr)
!           errflag=ierr
!           if(errflag.ne.3) then
!               dx=nextdx
!           endif
!       endif
    endif
end do
if(step.gt.49) then
    errflag=3
endif
return
end

subroutine odestep(nv,x,y,htry,mindx,hnext,yscal,ierr)

integer(4) :: nv,ierr,i,j,errflag
integer(4), parameter :: nmax=20, imax=11, nuse=7
real(8), parameter :: one=1d0, shrink=.95d0, grow=1.2d0
integer(4) :: nseq(imax)
real(8) x,y(nmax),dydx(nmax),yscal(nmax),yerr(nmax),ysav(nmax), &
dysav(nmax),yseq(nmax),h,htry,hnext,mindx,xsav,xest

data nseq /2,4,6,8,12,16,24,32,48,64,96/
ierr=0
h=htry

```



```

xsav=x
call derivs(nv,x,y,dydx)
do i=1,nv
  ysav(i)=y(i)
  dysav(i)=dydx(i)
enddo
1 do i=1,imax
  call mmid(ysav,dysav,nv,xsav,h,nseq(i),yseq)
  xest=(h/nseq(i))**2
  call rzextr(i,xest,yseq,y,yerr,nv,nuse)
  errflag=0
  do j=1,nv
    if(dabs(yerr(j)).gt.yscal(j)) then
      errflag=1
    endif
  enddo
  if(errflag.eq.0) then
    x=x+h
    if(i.eq.nuse) then
      hnext=h*shrink
    else if(i.eq.nuse-1) then
      hnext=h*grow
    else
      hnext=(h*nseq(nuse-1))/nseq(i)
    endif
    return
  endif
enddo
h=0.25d0*h/2**((imax-nuse)/2)
ierr=1
if(h.lt.mindx*htry) then
  ierr=2
  do i=1,nv
    y(i)=ysav(i)
  enddo
  return
endif
go to 1
end

```

```

subroutine rzextr(iest,xest,yest,yz,dy,nv,nuse)

```

```

integer(4), parameter :: imax=11,nmax=20,ncol=7
integer(4) :: iest,nv,nuse,j,k
real(8) :: x(imax),yest(nmax),yz(nv),dy(nv),d(nmax,ncol),fx(ncol), &
yy,v,c,b1,b,ddy,xest,m1

```

```

x(iest)=xest
if(iest.eq.1) then
  do j=1,nv
    yz(j)=yest(j)
    d(j,1)=yest(j)
    dy(j)=yest(j)
  enddo
else

```

```

m1=min(iest,nuse)
do k=1,m1-1
  fx(k+1)=x(iest-k)/xest
enddo
do j=1,nv
  yy=yest(j)
  v=d(j,1)
  c=yy
  d(j,1)=yy
  do k=2,m1
    b1=fx(k)*v
    b=b1-c
    if(b.ne.0.) then
      b=(c-v)/b
      ddy=c*b
      c=b1*b
    else
      ddy=v
    endif
    if(k.ne.m1) then
      v=d(j,k)
    endif
    d(j,k)=ddy
    yy=yy+ddy
  enddo
  dy(j)=ddy
  yz(j)=yy
enddo
endif
return
end

```

```

subroutine mmid(y,dydx,nvar,xs,htot,nstep,yout)

```

```

integer(4), parameter :: nmax=20
integer(4) :: i,n,nvar,nstep
real(8) :: y(nmax),dydx(nmax),yout(nmax),ym(nmax),yn(nmax),xs, &
htot,x,h,h2,swap

```

```

h=htot/nstep
do i=1,nvar
  ym(i)=y(i)
  yn(i)=y(i)+h*dydx(i)
enddo
x=xs+h
call derivs(nvar,x,yn,yout)
h2=2d0*h
do n=2,nstep
  do i=1,nvar
    swap=ym(i)+h2*yout(i)
    ym(i)=yn(i)
    yn(i)=swap
  enddo
  x=x+h

```

```

    call derivs(nvar,x,yn,yout)
enddo
do i=1,nvar
    yout(i)=0.5*(ym(i)+yn(i)+h*yout(i))
enddo
return
end

subroutine rkstep(nv,x,y,htry,mindx,hnext,yscal,ierr)

integer(4) :: nv,ierr,i,j,errflag
integer(4), parameter :: nmax=20
real(8), parameter :: shrink=-0.25d0,grow=-0.2d0,fcor=1d0/15d0, &
safe=0.9,errcon=6d-4
real(8) x,y(nmax),dydx(nmax),yscal(nmax),ytemp(nmax),ysav(nmax), &
dysav(nmax),h,htry,hnext,mindx,xsav,errmax,hh,yerr(nmax)

h=htry
xsav=x
call derivs(nv,x,y,dydx)
do i=1,nv
    ysav(i)=y(i)
    dysav(i)=dydx(i)
enddo
do while(h.gt.htry*mindx*0.1d0)
    hh=0.5d0*h
    call rk4(ysav,dysav,nv,xsav,hh,ytemp)
    x=xsav+hh
    call derivs(nv,x,ytemp,dydx)
    call rk4(ytemp,dydx,nv,x,hh,y)
    x=xsav+h
    call rk4(ysav,dysav,nv,xsav,h,ytemp)
    errflag=0
    errmax=0d0
    do j=1,nv
        yerr(j)=y(j)-ytemp(j)
        errmax=dmax1(errmax,dabs(yerr(j)/yscal(j)))
        if(dabs(yerr(j)).gt.yscal(j)) then
            errflag=1
        endif
    enddo
    if(errflag.eq.0) then
        if(errmax.gt.errcon) then
            hnext=safe*h*(errmax**grow)
        else
            hnext=4d0*h
        endif
        ierr=2
        do i=1,nv
            y(i)=y(i)+yerr(i)*fcor
        enddo
        return
    else if(errflag.eq.1) then
        h=safe*h*(errmax**shrink)
    endif
end do
ierr=3

```

```

return
end

subroutine rk4(y,dydx,nv,x,h,yout)
integer(4), parameter :: nmax=20
integer(4) :: i,nv
real(8) :: y(nmax),dydx(nmax),yout(nmax),yt(nmax),dym(nmax),x, &
h,dym(nmax),hh,h6,xhh,xh
hh=h*0.5d0
h6=h/6d0
xh=x+h
xhh=x+hh
do i=1,nv
    yt(i)=y(i)+hh*dydx(i)
enddo
call derivs(nv,xhh,yt,dym)
do i=1,nv
    yt(i)=y(i)+hh*dym(i)
enddo
call derivs(nv,xhh,yt,dym)
do i=1,nv
    yt(i)=y(i)+h*dym(i)
    dym(i)=dydx(i)+dym(i)
enddo
call derivs(nv,xh,yt,dyt)
do i=1,nv
    yout(i)=y(i)+h6*(dydx(i)+dyt(i)+2d0*dym(i))
enddo
return
end

```

pik3.f90

```

MODULE Genetic_Algorithm
IMPLICIT NONE

```

```

!      Common block to make iseed visible to rninit (and to save
!      it between calls)
! COMMON /rnseed/ iseed
INTEGER, SAVE :: iseed

```

CONTAINS

```

SUBROUTINE pikaia(ff,n,ctrl,x,f,STATUS)
use masterdim

```

```

! Code converted using TO_F90 by Alan Miller
! Date: 2001-07-09 Time: 15:54:13

```

```

!=====
! Optimization (maximization) of user-supplied "fitness" function ff

```

```

! over n-dimensional parameter space x using a basic genetic algorithm
! method.

! Paul Charbonneau & Barry Knapp
! High Altitude Observatory
! National Center for Atmospheric Research
! Boulder CO 80307-3000
! USA
! <paulchar@hao.ucar.edu>
! <knapp@hao.ucar.edu>

! Web site:
! http://www.hao.ucar.edu/public/research/si/pikaia/pikaia.html

! Version 1.0 [ 1995 December 01 ]

! Genetic algorithms are heuristic search techniques that incorporate in a
! computational setting, the biological notion of evolution by means of
! natural selection. This subroutine implements the three basic operations
! of selection, crossover, and mutation, operating on "genotypes" encoded as
! strings.

! References:

! Charbonneau, Paul. "Genetic Algorithms in Astronomy and Astrophysics."
! Astrophysical J. (Supplement), vol 101, in press (December 1995).

! Goldberg, David E. Genetic Algorithms in Search, Optimization,
! & Machine Learning. Addison-Wesley, 1989.

! Davis, Lawrence, ed. Handbook of Genetic Algorithms.
! Van Nostrand Reinhold, 1991.
!=====
! USES: ff, urand, setctl, report, rnkpops, select, encode, decode,
! cross, mutate, genrep, stdrep, newpop, adjmut

INTEGER, INTENT(IN) :: n
real(8), INTENT(IN OUT) :: ctrl(13)
real(8), INTENT(OUT) :: x(n)
real(8), INTENT(OUT) :: f
INTEGER, INTENT(OUT) :: STATUS

INTERFACE
  FUNCTION ff(n, x) RESULT(fn_val)
    IMPLICIT NONE
    INTEGER, INTENT(IN) :: n
    real(8), INTENT(IN) :: x(:)
    real(8) :: fn_val
  END FUNCTION ff
END INTERFACE

! EXTERNAL ff

! Input:
! o Integer n is the parameter space dimension, i.e., the number
! of adjustable parameters.

```

```

! o Function ff is a user-supplied scalar function of n variables, which
! must have the calling sequence f = ff(n,x), where x is a real(8)
parameter
! array of length n. This function must be written so as to bound all
! parameters to the interval [0,1]; that is, the user must determine
! a priori bounds for the parameter space, and ff must use these bounds
! to perform the appropriate scalings to recover true parameter values in
! the a priori ranges.

! By convention, ff should return higher values for more optimal
! parameter values (i.e., individuals which are more "fit").
! For example, in fitting a function through data points, ff
! could return the inverse of chi**2.

! In most cases initialization code will have to be written
! (either in a driver or in a separate subroutine) which loads
! in data values and communicates with ff via one or more labeled
! common blocks. An example exercise driver and fitness function
! are provided in the accompanying file, xpkai.f.

! Input/Output:

! o Array ctrl is an array of control flags and parameters, to
! control the genetic behavior of the algorithm, and also printed
! output. A default value will be used for any control variable
! which is supplied with a value less than zero. On exit, ctrl
! contains the actual values used as control variables. The
! elements of ctrl and their defaults are:

! ctrl( 1) - number of individuals in a population (default
! is 100)
! ctrl( 2) - number of generations over which solution is
! to evolve (default is 500)
! ctrl( 3) - number of significant digits (i.e., number of
! genes) retained in chromosomal encoding (default
! is 6) (Note: This number is limited by the
! machine floating point precision. Most 32-bit
! floating point representations have only 6 full
! digits of precision. To achieve greater preci-
! sion this routine could be converted to double
! precision, but note that this would also require
! a double precision random number generator, which
! likely would not have more than 9 digits of
! precision if it used 4-byte integers internally.)
! ctrl( 4) - crossover probability; must be <= 1.0 (default is 0.85)
! ctrl( 5) - mutation mode; 1/2=steady/variable (default is 2)
! ctrl( 6) - initial mutation rate; should be small (default is 0.005)
! (Note: the mutation rate is the probability that any one
! gene locus will mutate in any one generation.)
! ctrl( 7) - minimum mutation rate; must be >= 0.0 (default is 0.0005)
! ctrl( 8) - maximum mutation rate; must be <= 1.0 (default is 0.25)
! ctrl( 9) - relative fitness differential; range from 0
! (none) to 1 (maximum). (default is 1.)
! ctrl(10) - reproduction plan; 1/2/3=Full generational
! replacement/Steady-state-replace-random/Steady-

```

```

!           state-replace-worst (default is 3)
!   ctrl(11) - elitism flag; 0/1=off/on (default is 0)
!           (Applies only to reproduction plans 1 and 2)
!   ctrl(12) - printed output 0/1/2=None/Minimal/Verbose (default is 0)

```

! Output:

```

!   o Array  x(1:n)  is the "fittest" (optimal) solution found,
!       i.e., the solution which maximizes fitness function ff

!   o Scalar  f  is the value of the fitness function at x

!   o Integer  status  is an indicator of the success or failure
!       of the call to pikaia (0=success; non-zero=failure)

```

! Constants

```

INTEGER, PARAMETER :: nmax = parmdim, pmax = 128, dmax = 6, convgens = 25
!Review 25 past generations for convergence -GES
real, parameter :: convcrit = 0.0001 !Convergence criteria -GES

```

! o NMAX is the maximum number of adjustable parameters (n <= NMAX)

! o PMAX is the maximum population (ctrl(1) <= PMAX)

! o DMAX is the maximum number of Genes (digits) per Chromosome
! segment (parameter) (ctrl(3) <= DMAX)

! Local variables

```

INTEGER :: np, nd, ngen, imut, irep, ielite, ivrb, k, ip, ig, ip1, &
           ip2, NEW, newtot, inrange, keepnum ! -GES
real(8) :: pcross, pmut, pmutmn, pmutmx, fdif, conv, tgen, t1, t2 ! -GES

real(8) :: ph(nmax,2), oldph(nmax,pmax), newph(nmax,pmax),
recentfit(convgens), & ! -GES
           maxran, minran, scalefac ! -GES

```

```

INTEGER :: gn1(nmax*dmax), gn2(nmax*dmax)
INTEGER :: ifit(pmax), jfit(pmax)
real(8) :: fitns(pmax)

```

```

!   User-supplied uniform random number generator
! real(8) :: urand
! EXTERNAL urand

```

! Function urand should not take any arguments. If the user wishes to be able
! to initialize urand, so that the same sequence of random numbers can be
! repeated, this capability could be implemented with a separate subroutine,
! and called from the user's driver program. An example urand function
! (and initialization subroutine) which uses the function ran0 (the "minimal
! standard" random number generator of Park and Miller [Comm. ACM 31, 1192-
! 1201, Oct 1988; Comm. ACM 36 No. 7, 105-110, July 1993]) is provided.

```

!      Set control variables from input and defaults
CALL setctl(ctrl, n, np, ngen, nd, pcross, pmutmn, pmutmx, pmut, imut, fdif,
&
!      irep, ielite, ivrb, keepnum, STATUS)
IF (STATUS /= 0) THEN
  WRITE (*, *) ' Control vector (ctrl) argument(s) invalid'
  RETURN
END IF

!      Make sure locally-dimensioned arrays are big enough
IF (n > nmax .OR. np > pmax .OR. nd > dmax) THEN
  WRITE (*, *) ' Number of parameters, population, or genes too large'
  STATUS = -1
  RETURN
END IF

!      Compute initial (random but bounded) phenotypes
!DO ip = 1, np
!  DO k = 1, n
!    oldph(k,ip) = urand()
!  END DO
!  fitns(ip) = ff(n, oldph(:,ip))
!END DO

!      Compute initial phenotypes: Gaussian distribution around initial guess
-GES
do k=1,n
  minran=0
  maxran=0
  do ip=1,np
    oldph(k,ip)=getgausran()
    if(oldph(k,ip)<minran) minran=oldph(k,ip)
    if(oldph(k,ip)>maxran) maxran=oldph(k,ip)
  enddo
  scalefac=maxran-minran
  do ip=1,np
    inrange=0
    do while (inrange==0)
      oldph(k,ip)=oldph(k,ip)/scalefac*0.5+x(k)
      if(oldph(k,ip)<0 .OR. oldph(k,ip)>1) then
        oldph(k,ip)=getgausran()
!      print *, "Finding new"
      else
        inrange=1
      endif
    enddo
  enddo
enddo

!mpi Do loop eliminated for parallel version -GES
!do ip=1,np
!  fitns(ip) = ff(n, oldph(:,ip))
!enddo

call cpu_time(t1)
call mpi_fitness(np, n, oldph, fitns)

```



```

call cpu_time(t2)
tgen=t2-t1

!      Rank initial population by fitness order
CALL rnkpop(np,fitns,ifit,jfit)

conv = 1  ! Set initial convergence value to larger than threshold -GES
ig = 1    ! Set initial generation to 1 - GES
!      Main Generation Loop
!DO  ig = 1, ngen
do while(conv > convcrit) ! Run GA until convergence criterion is met or
maximum generations is reached -GES
!      Main Population Loop
    newtot = 0
    DO  ip = 1, np / 2

!          1. pick two parents
        CALL select(np,jfit,fdif,ip1)
        30 CALL select(np,jfit,fdif,ip2)
        IF (ip1 == ip2) GO TO 30

!          2. encode parent phenotypes
        CALL encode(n,nd,oldph(1,ip1),gn1)
        CALL encode(n,nd,oldph(1,ip2),gn2)

!          3. breed
        CALL cross(n,nd,pcross,gn1,gn2)
        CALL mutate(n,nd,pmut,gn1)
        CALL mutate(n,nd,pmut,gn2)

!          4. decode offspring genotypes
        CALL decode(n,nd,gn1,ph(1,1))
        CALL decode(n,nd,gn2,ph(1,2))

!          5. insert into population
        IF (irep == 1) THEN
            CALL genrep(nmax,n,np,ip,ph,newph)
        ELSE
            CALL stdrep(ff,nmax,n,np,irep,ielite,ph,oldph,fitns,ifit, jfit,NEW)
            newtot = newtot + NEW
        END IF

!      End of Main Population Loop
    END DO

!      if running full generational replacement: swap populations
    IF (irep == 1) CALL newpop(ff,ielite,nmax,n,np,oldph,newph,ifit, &
        jfit,fitns,newtot,keepnum)

!      adjust mutation rate?
    IF (imut == 2) CALL adjmut(np,fitns,ifit,pmutmn,pmutmx,pmut)

!      print generation report to standard output?
    IF (ivrb > 0) CALL
report(ivrb,nmax,n,np,nd,oldph,fitns,ifit,pmut,ig,newtot,tgen)

!      End of Main Generation Loop

```

```

    ig = ig+1
    call checkconv(fitns, ifit, np, recentfit, ig, conv, convgens) !Check for
convergence
    if(ig > ngen) conv=0 !End execution if maximum generations has been reached
END DO

!      Return best phenotype and its fitness
DO k = 1, n
    x(k) = oldph(k,ifit(np))
END DO
f = fitns(ifit(np))

RETURN
END SUBROUTINE pikaia

!*****

subroutine checkconv(fitns, ifit, np, recentfit, ig, conv, convgens)
!=====
!      Check to see if convergence criteria met -GES
!=====
    INTEGER, INTENT(IN)      :: np, convgens
    real(8), INTENT(IN)      :: fitns(np)
    INTEGER, INTENT(IN)      :: ifit(np)
    real(8), INTENT(IN OUT)  :: recentfit(convgens)
    real(8), INTENT(IN OUT)  :: conv
    INTEGER, INTENT(IN)      :: ig
    integer :: il

    if(ig < convgens+1) then
        recentfit(ig) = fitns(ifit(np)) !Add best fitness of generation to stack
        ! Don't change conv from it's default
    else
        do il=1,convgens-1 !Shuffle oldest fitness off the stack
            recentfit(il)=recentfit(il+1)
        enddo
        recentfit(convgens)=fitns(ifit(np)) !Put the new generation's best
fitness on the end of the stack
        conv = recentfit(convgens)-recentfit(1) ! Set conv to difference between
oldest and newest maxfits in the stack
    endif

end subroutine checkconv

!*****

SUBROUTINE setctl(ctrl,n,np,ngen,nd,pcross,pmutmn,pmutmx,pmut, &
                imut,fdif,irep,ielite,ivrb,keepnum,STATUS)
!=====
!      Set control variables and flags from input and defaults
!=====

!      Input
!      Input/Output
real(8), INTENT(IN OUT)  :: ctrl(13)
INTEGER, INTENT(IN)      :: n

```

```

!      Output
INTEGER, INTENT(OUT)  :: np
INTEGER, INTENT(OUT)  :: ngen
INTEGER, INTENT(OUT)  :: nd
real(8), INTENT(OUT)  :: pcross
real(8), INTENT(OUT)  :: pmutmn
real(8), INTENT(OUT)  :: pmutmx
real(8), INTENT(OUT)  :: pmut
INTEGER, INTENT(OUT)  :: imut
real(8), INTENT(OUT)  :: fdif
INTEGER, INTENT(OUT)  :: irep
INTEGER, INTENT(OUT)  :: ielite
INTEGER, INTENT(OUT)  :: ivrb
integer, intent(out)  :: keepnum
INTEGER, INTENT(OUT)  :: STATUS

!      Local
INTEGER :: i
real(8), SAVE  :: dfault(13) = (/ 100., 500., 5., .85, 2., .005, .0005, .25,
&
                                1., 1., 1., 0.,0 /)

DO  i = 1, 13
  IF (ctrl(i) < 0.) ctrl(i) = dfault(i)
END DO

np = ctrl(1)
ngen = ctrl(2)
nd = ctrl(3)
pcross = ctrl(4)
imut = ctrl(5)
pmut = ctrl(6)
pmutmn = ctrl(7)
pmutmx = ctrl(8)
fdif = ctrl(9)
irep = ctrl(10)
ielite = ctrl(11)
ivrb = ctrl(12)
keepnum = ctrl(13)
STATUS = 0

!      Print a header
IF (ivrb > 0) THEN

  WRITE (*,5000) ngen, np, n, nd, pcross, pmut, pmutmn, pmutmx, fdif
  IF (imut == 1) WRITE (*,5100) 'Constant'
  IF (imut == 2) WRITE (*,5100) 'Variable'
  IF (irep == 1) WRITE (*,5200) 'Full generational replacement'
  IF (irep == 2) WRITE (*,5200) 'Steady-state-replace-random'
  IF (irep == 3) WRITE (*,5200) 'Steady-state-replace-worst'
  write (*,*) 'Gen  MaxFit      MinFit   MeanFit   MedianFit   Time' !
Statistics header -GES
END IF

!      Check some control values

```

```

IF (imut /= 1 .AND. imut /= 2) THEN
    WRITE (*,5300)
    STATUS = 5
END IF

IF (fdif > 1.) THEN
    WRITE (*,5400)
    STATUS = 9
END IF

IF (irep /= 1 .AND. irep /= 2 .AND. irep /= 3) THEN
    WRITE (*,5500)
    STATUS = 10
END IF

IF (pcross > 1.0 .OR. pcross < 0.) THEN
    WRITE (*,5600)
    STATUS = 4
END IF

IF (ielite /= 0 .AND. ielite /= 1) THEN
    WRITE (*,5700)
    STATUS = 11
END IF

IF (irep == 1 .AND. imut == 1 .AND. pmut > 0.5 .AND. ielite == 0) THEN
    WRITE (*,5800)
END IF

IF (irep == 1 .AND. imut == 2 .AND. pmutmx > 0.5 .AND. ielite == 0) THEN
    WRITE (*,5900)
END IF

IF (fdif < 0.33 .AND. irep /= 3) THEN
    WRITE (*,6000)
END IF

IF (MOD(np,2) > 0) THEN
    np = np - 1
    WRITE (*,6100) np
END IF

RETURN
5000 FORMAT (' ', 60('*') / &
    ' *', t16, 'PIKAIA Genetic Algorithm Report ', t60, '*' / &
    ' ', 60('*') // &
    '    Number of Generations evolving: ', i4 / &
    '    Individuals per generation: ', i4 / &
    '    Number of Chromosome segments: ', i4 / &
    '    Length of Chromosome segments: ', i4 / &
    '    Crossover probability: ', f9.4 / &
    '    Initial mutation rate: ', f9.4 / &
    '    Minimum mutation rate: ', f9.4 / &
    '    Maximum mutation rate: ', f9.4 / &
    '    Relative fitness differential: ', f9.4)
5100 FORMAT ('                      Mutation Mode: '/ a)
5200 FORMAT ('                      Reproduction Plan: '/ a)

```

```

5300 FORMAT (' ERROR: illegal value for imut (ctrl(5))')
5400 FORMAT (' ERROR: illegal value for fdif (ctrl(9))')
5500 FORMAT (' ERROR: illegal value for irep (ctrl(10))')
5600 FORMAT (' ERROR: illegal value for pcross (ctrl(4))')
5700 FORMAT (' ERROR: illegal value for ielite (ctrl(11))')
5800 FORMAT (' WARNING: dangerously high value for pmut (ctrl(6));' / &
' (Should enforce elitism with ctrl(11)=1.)')
5900 FORMAT (' WARNING: dangerously high value for pmutmx (ctrl(8));' / &
' (Should enforce elitism with ctrl(11)=1.)')
6000 FORMAT (' WARNING: dangerously low value of fdif (ctrl(9))')
6100 FORMAT (' WARNING: decreasing population size (ctrl(1)) to np=' / i4 )
END SUBROUTINE setctl

```

```

!*****

```

```

SUBROUTINE report(ivrb, ndim, n, np, nd, oldph, fitns, ifit, pmut, ig,
nnew,tgen)

```

```

!      Write generation report to standard output

```

```

!      Input:

```

```

INTEGER, INTENT(IN)  :: ivrb
INTEGER, INTENT(IN)  :: ndim
INTEGER, INTENT(IN)  :: n
INTEGER, INTENT(IN)  :: np
INTEGER, INTENT(IN)  :: nd
real(8), INTENT(IN)  :: oldph(ndim, np)
real(8), INTENT(IN)  :: fitns(np)
INTEGER, INTENT(IN)  :: ifit(np)
real(8), INTENT(IN)  :: pmut,tgen
INTEGER, INTENT(IN)  :: ig
INTEGER, INTENT(IN)  :: nnew

```

```

!      Output: none

```

```

!      Local

```

```

real(8), SAVE  :: bestft = 0.0, pmutpv = 0.0
real(8) :: sum
INTEGER  :: ndpwr, k, i1
LOGICAL  :: rpt

```

```

rpt = .false.

```

```

IF (pmut /= pmutpv) THEN
  pmutpv = pmut
  rpt = .true.
END IF

```

```

IF (fitns(ifit(np)) /= bestft) THEN
  bestft = fitns(ifit(np))
  rpt = .true.
END IF

```

```

IF (rpt .OR. ivrb >= 2) THEN

```

```

!      Power of 10 to make integer genotypes for display
  ndpwr = nint(10.**nd)

```

```

!  WRITE (*, '(/i6, i6, f10.6, 4f10.6)') ig, nnew, pmut, &
!      fitns(ifu(n)), fitns(ifu(n-1)), fitns(ifu(n/2))

!! Get the sum fitness of the generation -GES
sum=0
do i1=1, np
    sum=sum+fitns(ifu(i1))
enddo

WRITE (*, '(i4, 5f10.4)') ig, & !ig, nnew, pmut, &
    fitns(ifu(n)), fitns(ifu(1)), sum/np, fitns(ifu(n/2)), tgen !Print
fitness of best, worst, mean, and median in population -GES and time for
generation

!! Phenotype printing disabled -GES
!  DO  k = 1, n
!      WRITE (*, '(22x, 3i10)') nint(ndpwr*oldph(k, ifu(n))), &
!          nint(ndpwr*oldph(k, ifu(n-1))), nint(ndpwr*oldph(k, ifu(n/2)))
!  END DO

END IF
RETURN
END SUBROUTINE report

!*****
!                               GENETICS MODULE
!*****

!      ENCODE:    encodes phenotype into genotype
!                  called by: PIKAIA

!      DECODE:    decodes genotype into phenotype
!                  called by: PIKAIA

!      CROSS:     Breeds two offspring from two parents
!                  called by: PIKAIA

!      MUTATE:    Introduces random mutation in a genotype
!                  called by: PIKAIA

!      ADJMUT:    Implements variable mutation rate
!                  called by: PIKAIA

!*****

SUBROUTINE encode(n, nd, ph, gn)
!=====
!      encode phenotype parameters into integer genotype
!      ph(k) are x, y coordinates [ 0 < x, y < 1 ]
!=====

INTEGER, INTENT(IN)    :: n
INTEGER, INTENT(IN)    :: nd
real(8), INTENT(IN OUT) :: ph(n)

```

```

INTEGER, INTENT(OUT)    :: gn(n*nd)

!      Inputs:

!      Output:

!      Local:
INTEGER :: ip, i, j, ii
real(8) :: z

z = 10. ** nd
ii = 0
DO i = 1, n
    ip = INT(ph(i)*z)
    DO j = nd, 1, -1
        gn(ii+j) = MOD(ip, 10)
        ip = ip / 10
    END DO
    ii = ii + nd
END DO

RETURN
END SUBROUTINE encode

!*****

SUBROUTINE decode(n, nd, gn, ph)
!=====
!      decode genotype into phenotype parameters
!      ph(k) are x, y coordinates [ 0 < x, y < 1 ]
!=====

INTEGER, INTENT(IN)    :: n
INTEGER, INTENT(IN)    :: nd
INTEGER, INTENT(IN)    :: gn(n*nd)
real(8), INTENT(OUT)    :: ph(n)

!      Inputs:

!      Output:

!      Local:
INTEGER :: ip, i, j, ii
real(8) :: z

z = 10. ** (-nd)
ii = 0
DO i = 1, n
    ip = 0
    DO j = 1, nd
        ip = 10 * ip + gn(ii+j)
    END DO
    ph(i) = ip / z
END DO

```

```

        END DO
        ph(i) = ip * z
        ii = ii + nd
    END DO

RETURN
END SUBROUTINE decode

!*****

SUBROUTINE cross(n, nd, pcross, gn1, gn2)
!=====
!     breeds two parent chromosomes into two offspring chromosomes
!     breeding occurs through crossover starting at position ispl
!=====
!     USES: urand

!     Inputs:
INTEGER, INTENT(IN)      :: n
INTEGER, INTENT(IN)      :: nd
real(8), INTENT(IN)      :: pcross

!     Input/Output:
INTEGER, INTENT(IN OUT)  :: gn1(n*nd)
INTEGER, INTENT(IN OUT)  :: gn2(n*nd)

!     Local:
INTEGER :: i, ispl, t

!     Function
! real(8) :: urand
! EXTERNAL urand

!     Use crossover probability to decide whether a crossover occurs
IF (urand() < pcross) THEN

!         Compute crossover point
ispl = INT(urand()*n*nd) + 1

!         Swap genes at ispl and above
DO i = ispl, n * nd
    t = gn2(i)
    gn2(i) = gn1(i)
    gn1(i) = t
END DO
END IF

RETURN
END SUBROUTINE cross

!*****

SUBROUTINE mutate(n, nd, pmut, gn)
!=====
!     Mutations occur at rate pmut at all gene loci

```



```

!=====
!      USES: urand

!      Input:
INTEGER, INTENT(IN)      :: n
INTEGER, INTENT(IN)      :: nd
real(8), INTENT(IN)      :: pmut

!      Input/Output:
INTEGER, INTENT(IN OUT)  :: gn(n*nd)

!      Local:
INTEGER :: i

!      Function:
! real(8) :: urand
! EXTERNAL urand

!      Subject each locus to mutation at the rate pmut
DO i = 1, n * nd
  IF (urand() < pmut) THEN
    gn(i) = INT(urand()*10.)
  END IF
END DO

RETURN
END SUBROUTINE mutate

!*****

SUBROUTINE adjmut(np, fitns, ifit, pmutmn, pmutmx, pmut)
!=====
!      dynamical adjustment of mutation rate; criterion is relative
!      difference in absolute fitnesses of best and median individuals
!=====

!      Input:
INTEGER, INTENT(IN)      :: np
real(8), INTENT(IN)      :: fitns(:)
INTEGER, INTENT(IN)      :: ifit(:)
real(8), INTENT(IN)      :: pmutmn
real(8), INTENT(IN)      :: pmutmx

!      Input/Output:
real(8), INTENT(IN OUT)  :: pmut

!      Local:
real(8) :: rdif
real(8), PARAMETER :: rdiflo = 0.05, rdifhi = 0.25, delta = 1.5

rdif = ABS(fitns(ifit(np)) - fitns(ifit(np/2))) / (fitns(ifit(np)) + &
  fitns(ifit(np/2)))
IF (rdif <= rdiflo) THEN
  pmut = MIN(pmutmx, pmut*delta)
ELSE IF (rdif >= rdifhi) THEN
  pmut = MAX(pmutmn, pmut/delta)

```

END IF

RETURN

END SUBROUTINE adjmut

```
!*****
!                                REPRODUCTION MODULE
!*****
```

```
!  SELECT:   Parent selection by roulette wheel algorithm
!            called by: PIKAIA
```

```
!  RNKPOP:   Ranks initial population
!            called by: PIKAIA, NEWPOP
```

```
!  GENREP:   Inserts offspring into population, for full
!            generational replacement
!            called by: PIKAIA
```

```
!  STDREP:   Inserts offspring into population, for steady-state
!            reproduction
!            called by: PIKAIA
!            calls:      FF
```

```
!  NEWPOP:   Replaces old generation with new generation
!            called by: PIKAIA
!            calls:      FF, RNKPOP
```

```
!*****
```

SUBROUTINE select(np, jfit, fdif, idad)

```
!=====
!   Selects a parent from the population, using roulette wheel
!   algorithm with the relative fitnesses of the phenotypes as
!   the "hit" probabilities [see Davis 1991, chap. 1].
!=====
!   USES: urand
```

```
!   Input:
INTEGER, INTENT(IN)   :: np
INTEGER, INTENT(IN)   :: jfit(np)
real(8), INTENT(IN)   :: fdif
```

```
!   Output:
INTEGER, INTENT(OUT)  :: idad
```

```
!   Local:
INTEGER :: np1, i
real(8) :: dice, rtfit
```

```
!   Function:
! real(8) :: urand
! EXTERNAL urand
```

```
np1 = np + 1
dice = urand() * np * np1
```

```

rtfit = 0.
DO i = 1, np
  rtfit = rtfit + np1 + fdif * (np1-2*jfit(i))
  IF (rtfit >= dice) THEN
    idad = i
    GO TO 20
  END IF
END DO
!      Assert: loop will never exit by falling through

20 RETURN
END SUBROUTINE select

!*****

SUBROUTINE rnkpop(n, arrin, indx, rank)
!=====
!      Calls external sort routine to produce key index and rank order
!      of input array arrin (which is not altered).
!=====
!      USES: rqsort

!      Input
INTEGER, INTENT(IN)      :: n
real(8), INTENT(IN)      :: arrin(:)

!      Output
INTEGER, INTENT(OUT)     :: indx(:)
INTEGER, INTENT(OUT)     :: rank(:)

!      Local
INTEGER :: i

!      External sort subroutine
! EXTERNAL rqsort

!      Compute the key index
CALL rqsort(n, arrin, indx)

!      ...and the rank order
DO i = 1, n
  rank(indx(i)) = n - i + 1
END DO
RETURN
END SUBROUTINE rnkpop

!*****

SUBROUTINE genrep(ndim, n, np, ip, ph, newph)
!=====
!      full generational replacement: accumulate offspring into new
!      population array
!=====

!      Input:

```

```

INTEGER, INTENT(IN)    :: ndim
INTEGER, INTENT(IN)    :: n
INTEGER, INTENT(IN)    :: np
INTEGER, INTENT(IN)    :: ip
real(8), INTENT(IN)    :: ph(ndim, 2)

!      Output:
real(8), INTENT(OUT)    :: newph(ndim, np)

!      Local:
INTEGER :: i1, i2, k

!      Insert one offspring pair into new population
i1 = 2 * ip - 1
i2 = i1 + 1
DO  k = 1, n
    newph(k, i1) = ph(k, 1)
    newph(k, i2) = ph(k, 2)
END DO

RETURN
END SUBROUTINE genrep

!*****

SUBROUTINE stdrep(ff, ndim, n, np, irep, ielite, ph, oldph, fitns, ifit,
jfit, nnew)
=====
!      steady-state reproduction: insert offspring pair into population
!      only if they are fit enough (replace-random if irep=2 or
!      replace-worst if irep=3).
=====
!      USES: ff, urand

!      Input:
INTEGER, INTENT(IN)    :: ndim
INTEGER, INTENT(IN)    :: n
INTEGER, INTENT(IN)    :: np
INTEGER, INTENT(IN)    :: irep
INTEGER, INTENT(IN)    :: ielite
real(8), INTENT(IN)    :: ph(ndim, 2)

!      Input/Output:
real(8), INTENT(IN OUT) :: oldph(ndim, np)
real(8), INTENT(IN OUT) :: fitns(np)
INTEGER, INTENT(IN OUT) :: ifit(np)
INTEGER, INTENT(IN OUT) :: jfit(np)

!      Output:
INTEGER, INTENT(OUT)    :: nnew

INTERFACE
    FUNCTION ff(n, x) RESULT(fn_val)
        IMPLICIT NONE
        INTEGER, INTENT(IN) :: n

```

```

        real(8), INTENT(IN)      :: x(:)
        real(8)                  :: fn_val
    END FUNCTION ff
END INTERFACE

! EXTERNAL ff

!      Local:
INTEGER :: i, j, k, il, ifl
real(8) :: fit

!      External function
! real(8) :: urand
! EXTERNAL urand

nnew = 0
loop70: DO j = 1, 2

!      1. compute offspring fitness (with caller's fitness function)
    fit = ff(n, ph(:, j))

!      2. if fit enough, insert in population
    DO i = np, 1, -1
        IF (fit > fitns(ifit(i))) THEN

!              make sure the phenotype is not already in the population
            IF (i < np) THEN
                DO k = 1, n
                    IF (oldph(k, ifit(i+1)) /= ph(k, j)) GO TO 20
                END DO
                CYCLE loop70
            END IF

!              offspring is fit enough for insertion, and is unique

!              (i) insert phenotype at appropriate place in population
20 IF (irep == 3) THEN
                il = 1
            ELSE IF (ielite == 0 .OR. i == np) THEN
                il = INT(urand()*np) + 1
            ELSE
                il = INT(urand()*(np-1)) + 1
            END IF
            ifl = ifit(il)
            fitns(ifl) = fit
            DO k = 1, n
                oldph(k, ifl) = ph(k, j)
            END DO

!              (ii) shift and update ranking arrays
            IF (i < il) THEN

!                  shift up
                jfit(ifl) = np - i
                DO k = il - 1, i + 1, -1
                    jfit(ifit(k)) = jfit(ifit(k)) - 1

```

```

        ifit(k+1) = ifit(k)
    END DO
    ifit(i+1) = if1
ELSE
!
        shift down
    jfit(if1) = np - i + 1
    DO k = i1 + 1, i
        jfit(ifit(k)) = jfit(ifit(k)) + 1
        ifit(k-1) = ifit(k)
    END DO
    ifit(i) = if1
END IF
    nnew = nnew + 1
    CYCLE loop70
END IF
END DO

END DO loop70

RETURN
END SUBROUTINE stdrep

!*****

SUBROUTINE newpop(ff, ielite, ndim, n, np, oldph, newph, ifit, jfit, fitns,
nnew, keepnum)
!=====
!      replaces old population by new; recomputes fitnesses & ranks
!=====
!      USES: ff, rnkpob

!      Input:
INTEGER, INTENT(IN)    :: ielite
INTEGER, INTENT(IN)    :: ndim
INTEGER, INTENT(IN)    :: n
INTEGER, INTENT(IN)    :: np
integer, intent(in)    :: keepnum

!      Input/Output:
real(8), INTENT(IN OUT) :: oldph(ndim, np)
real(8), INTENT(IN OUT) :: newph(ndim, np)

!      Output:
INTEGER, INTENT(OUT)    :: ifit(np)
INTEGER, INTENT(OUT)    :: jfit(np)
real(8), INTENT(OUT)    :: fitns(np)
INTEGER, INTENT(OUT)    :: nnew

INTERFACE
    FUNCTION ff(n, x) RESULT(fn_val)
        IMPLICIT NONE
        INTEGER, INTENT(IN)    :: n
        real(8), INTENT(IN)    :: x(:)
        real(8)                :: fn_val
    END FUNCTION ff
END INTERFACE

```

```

! EXTERNAL ff

!      Local:
INTEGER :: i, k, il

nnew = np

!      if using elitism, introduce in new population fittest of old
!      population (if greater than fitness of the individual it is
!      to replace)

      IF (ielite == 1 .AND. ff(n, newph(:, 1)) < fitns(ifit(np))) THEN !May need
to change this line after .and.
!      do il = keepnum,np    !-GES  Keep the most fit number as specified in
fort.1, not just the single most fit
      DO  k = 1, n
        newph(k, 1) = oldph(k, ifit(np))
!      newph(k, il-keepnum+1) = oldph(k,ifit(il)) !-GES
      END DO
      nnew = nnew - 1
!      enddo          !-GES
    END IF

!      replace population
DO  i = 1, np
  DO  k = 1, n
    oldph(k, i) = newph(k, i)
  END DO

!      get fitness using caller's fitness function
!mpi Moving parallel fitness call out of do loop
!  fitns(i) = ff(n, oldph(:, i))
END DO

  call mpi_fitness(np, n, oldph, fitns)

!      compute new population fitness rank order
CALL rnkpop(np, fitns, ifit, jfit)

RETURN
END SUBROUTINE newpop

!=====
!  Return a random number in a Guassian distribution -GES
!=====
function getgausran() RESULT(fn_val)
  implicit none
  real(8) w,x1,x2,fn_val,iseed
  w=2
  do while ( w >= 1.0 )  !Polar Box-Muller transform to get Gaussian
distribution of random numbers
    x1 = 2.0 * ran0() - 1.0 !Transform range [0,1] from ran0 to [-1,1] for
polar form of Box-Muller
    x2 = 2.0 * ran0() - 1.0
    w = x1**2 + x2**2
  enddo

```

```

w = sqrt( (-2.0 * log( w ) ) / w )
fn_val = x1 * w !Resulting distribution has mean of zero and variance of 1
end function getgausran

```

```

!*****

```

```

FUNCTION urand() RESULT(fn_val)

```

```

!=====

```

```

! Return the next pseudo-random deviate from a sequence which is
! uniformly distributed in the interval [0, 1]

```

```

! Uses the function ran0, the "minimal standard" random number
! generator of Park and Miller (Comm. ACM 31, 1192-1201, Oct 1988;
! Comm. ACM 36 No. 7, 105-110, July 1993).

```

```

!=====

```

```

!      Input - none

```

```

!      Output
real(8)  :: fn_val

```

```

!      Local
! INTEGER :: iseed
! real(8) :: ran0
! EXTERNAL ran0

```

```

!      Common block to make iseed visible to rninit (and to save
!      it between calls)
! COMMON /rnseed/ iseed

```

```

fn_val = ran0()
RETURN
END FUNCTION urand

```

```

!*****

```

```

SUBROUTINE rninit(seed)

```

```

!=====

```

```

!      Initialize random number generator urand with given seed

```

```

!=====

```

```

!      Input
INTEGER, INTENT(IN)  :: seed

```

```

!      Output - none

```

```

!      Local
! INTEGER :: iseed

```

```

!      Common block to communicate with urand
! COMMON /rnseed/ iseed

```

```

!      Set the seed value
iseed = seed
IF (iseed <= 0) iseed = 123456
RETURN
END SUBROUTINE rninit

```



```

!*****

FUNCTION ran0() RESULT(fn_val)
!=====
!  "Minimal standard" pseudo-random number generator of Park and Miller.
!  Returns a uniform random deviate r s.t.  $0 < r < 1.0$ .
!  Set seed to any non-zero integer value to initialize a sequence, then do
!  not change seed between calls for successive deviates in the sequence.

!  References:
!    Park, S. and Miller, K., "Random Number Generators: Good Ones
!      are Hard to Find", Comm. ACM 31, 1192-1201 (Oct. 1988)
!    Park, S. and Miller, K., in "Remarks on Choosing and Implementing
!      Random Number Generators", Comm. ACM 36 No. 7, 105-110 (July 1993)
!=====
! *** Declaration section ***

!      Output:
real(8)  :: fn_val

!      Constants:

INTEGER, PARAMETER  :: a = 48271, m = 2147483647, q = 44488, r = 3399

real(8), PARAMETER :: scale = 1./m, eps = 1.2E-7, rnmx = 1. - eps

!      Local:
INTEGER  :: j

! *** Executable section ***

j = iseed / q
iseed = a * (iseed - j*q) - r * j
IF (iseed < 0) iseed = iseed + m
fn_val = MIN(iseed*scale, rnmx)

RETURN
END FUNCTION ran0

!*****

SUBROUTINE rqsort(n, a, p)
  use masterdim
!=====
!  Return integer array p which indexes array a in increasing order.
!  Array a is not disturbed.  The Quicksort algorithm is used.

!  B. G. Knapp, 86/12/23

!  Reference: N. Wirth, Algorithms and Data Structures/
!  Prentice-Hall, 1986
!=====

INTEGER, INTENT(IN)  :: n
real(8), INTENT(IN)  :: a(:)
INTEGER, INTENT(OUT) :: p(:)

```

```

!      Constants

INTEGER, PARAMETER :: lgn = parmdim, q = 11
!      (LGN = log base 2 of maximum n;
!      Q = smallest subfile to use quicksort on)

!      Local:
real(8) :: x
INTEGER :: stackl(lgn), stackr(lgn), s, t, l, m, r, i, j

!      Initialize the stack
stackl(1) = 1
stackr(1) = n
s = 1

!      Initialize the pointer array
DO i = 1, n
    p(i) = i
END DO

20 IF (s > 0) THEN
    l = stackl(s)
    r = stackr(s)
    s = s - 1

    30 IF ((r-l) < q) THEN

!          Use straight insertion
        DO i = l + 1, r
            t = p(i)
            x = a(t)
            DO j = i - 1, l, -1
                IF (a(p(j)) <= x) GO TO 50
                p(j+1) = p(j)
            END DO
            j = l - 1
            50 p(j+1) = t
        END DO
    ELSE

!          Use quicksort, with pivot as median of a(l), a(m), a(r)
        m = (l+r) / 2
        t = p(m)
        IF (a(t) < a(p(l))) THEN
            p(m) = p(l)
            p(l) = t
            t = p(m)
        END IF
        IF (a(t) > a(p(r))) THEN
            p(m) = p(r)
            p(r) = t
            t = p(m)
        END IF
        IF (a(t) < a(p(l))) THEN
            p(m) = p(l)
            p(l) = t
            t = p(m)
        END IF
    END IF
END IF

```

```

        END IF
    END IF

!           Partition
    x = a(t)
    i = l + 1
    j = r - 1
70 IF (i <= j) THEN
    80 IF (a(p(i)) < x) THEN
        i = i + 1
        GO TO 80
    END IF
    90 IF (x < a(p(j))) THEN
        j = j - 1
        GO TO 90
    END IF
    IF (i <= j) THEN
        t = p(i)
        p(i) = p(j)
        p(j) = t
        i = i + 1
        j = j - 1
    END IF
    GO TO 70
END IF

!           Stack the larger subfile
    s = s + 1
    IF (j-l > r-i) THEN
        stackl(s) = l
        stackr(s) = j
        l = i
    ELSE
        stackl(s) = i
        stackr(s) = r
        r = j
    END IF
    GO TO 30
END IF
GO TO 20
END IF
RETURN
END SUBROUTINE rqsor

END MODULE Genetic_Algorithm

```

mpi_pikaia.f90

```

    program mpi_pikaia
! -----
! Front end for parallel PIKAIA to work with MPI
! -----
    implicit none

    include 'mpif.h'

    integer ierr,myid,nproc,nslaves,rc

```

```

integer trial,slave,msgtype

! -----
!   Initialize MPI
! -----
call mpi_init( ierr )
call mpi_comm_rank( MPI_COMM_WORLD, myid, ierr )
call mpi_comm_size( MPI_COMM_WORLD, nproc, ierr )
nslaves=nproc-1

! -----
!   Master program (parallel PIKAIA)
! -----
if (myid.EQ. 0) then
  call se
! -----
!   Finish with shutdown signal to slaves
! -----
  trial = -1
  msgtype = 1
  do slave=1,nslaves
    call mpi_send( trial, 1, MPI_INTEGER, slave, &
                  msgtype, MPI_COMM_WORLD, ierr )
  enddo

! -----
!   Slave tasks (fitness evaluation)
! -----
elseif (myid.GT. 0) then
  call ff_slave
endif

call mpi_finalize(rc)
stop
end

```

mpi_fitness.f90

```

subroutine mpi_fitness (num_jobs, npar, oldph, fitness)
  use masterdim
! -----
!   parallel fitness evaluation using MPI
! -----
  implicit none

  include 'mpif.h'

  integer ndone, nproc, ierr, nspawn
  integer msgtype, job, trial, slave
  integer par, npar, status(MPI_STATUS_SIZE), num_jobs
!   double precision data(32), result
  real(8) data(parmdim),result
  real(8) oldph(parmdim,parmdim**2), fitness(parmdim**2)
  logical receiving

! -----
!   initialize counter
! -----

```

```

        ndone = 0
! -----
!     determine number of processors
! -----
        call mpi_comm_size( MPI_COMM_WORLD, nproc, ierr )

! -----
!     run jobs on slave nodes only
! -----
        nspawn = nproc-1

! -----
!     send an initial job to each node
! -----
        do job=1,nspawn
            trial = job
            slave = job
            call sendjob(trial,slave,npar,oldph)
        enddo

        do job=1,num_jobs
! -----
!     listen for responses
! -----
25         msgtype = 2
            call mpi_iprobe( MPI_ANY_SOURCE, msgtype, MPI_COMM_WORLD, &
                           receiving, status, ierr )

            if (receiving) then
! -----
!     get data from responding node
! -----
                call mpi_recv( slave, 1, MPI_INTEGER, MPI_ANY_SOURCE, &
                              msgtype, MPI_COMM_WORLD, status, ierr )
                call mpi_recv( trial, 1, MPI_INTEGER, slave, &
                              msgtype, MPI_COMM_WORLD, status, ierr )
                call mpi_recv( result, 1, MPI_DOUBLE_PRECISION, slave, &
                              msgtype, MPI_COMM_WORLD, status, ierr )

                fitness(trial) = result
                ndone = ndone + 1

! -----
!     send new job to responding node
! -----
140         if (ndone .LE. (num_jobs-nspawn)) then
            trial = job + nspawn
            call sendjob(trial,slave,npar,oldph)
        endif
        goto 100
    endif

! -----
!     return to listen again or move on
! -----
        if (.NOT. receiving) goto 25

```

```

        goto 199
100    continue
    enddo

! -----
!    ready for next generation of jobs
! -----

199    return
    end

!*****
    subroutine sendjob(trial,slave,npar,oldph)
    use masterdim
    use rhopmfsig
    use obscalc
    implicit none

    include 'mpif.h'

    integer trial, slave, par, npar, ierr, msgtype,il
!    double precision data(32)
    real(8) oldph(paramdim,paramdim**2), data(paramdim), parmmax(refdim)

    do par=1,npar
        data(par) = oldph(par,trial)
    enddo

    msgtype = 1
    call mpi_send( trial, 1, MPI_INTEGER, slave,&
                   msgtype, MPI_COMM_WORLD, ierr )
    call mpi_send( npar, 1, MPI_INTEGER, slave,&
                   msgtype, MPI_COMM_WORLD, ierr )
    call mpi_send( data, npar*2, MPI_REAL, slave,&
                   msgtype, MPI_COMM_WORLD, ierr )
    call mpi_send( nums, numdim*2, MPI_INTEGER, slave,&
                   msgtype, MPI_COMM_WORLD, ierr )
    do il=1,2
        call mpi_send( parmref(:,il), refdim*2, MPI_REAL,slave,&
                       msgtype, MPI_COMM_WORLD, ierr )
    enddo
    call mpi_send( xobs, odim*2, MPI_REAL, slave,&
                   msgtype, MPI_COMM_WORLD, ierr )
    call mpi_send( obs, odim*2, MPI_REAL, slave,&
                   msgtype, MPI_COMM_WORLD, ierr )
    call mpi_send( osig, odim*2, MPI_REAL, slave,&
                   msgtype, MPI_COMM_WORLD, ierr )
    do il=1,auxnum
        call mpi_send( xaux(:,il), odim*2, MPI_REAL, slave,&
                       msgtype, MPI_COMM_WORLD, ierr )
    enddo

    return
    end

```

ff_slave.f90

```
      subroutine ff_slave
      use rhopmfsig
      use obscalc
! -----
! fitness function slave program
! -----
      implicit none

      include 'mpif.h'

INTERFACE
  FUNCTION get_fitness(n, x) RESULT(result)
    IMPLICIT NONE
    INTEGER, INTENT(IN)    :: n
    real(8), INTENT(IN)    :: x(:)
    real(8)                :: result
  END FUNCTION get_fitness
END INTERFACE

      integer myid, ierr, status(MPI_STATUS_SIZE)
      integer master, msgtype, trial, n, il

!      double precision data(32), fn_val
      real(8) data(parmdim), result, parmtest(refdim), xauxtemp(odim)
!      real(8) fitness
!      real userff
!      external userff

! -----
! identify this slave task
! -----
      call mpi_comm_rank( MPI_COMM_WORLD, myid, ierr )

! -----
! listen for a new job
! -----
      master = 0
25    msgtype = 1

! -----
! receive data from master host
! -----
      call mpi_recv( trial, 1, MPI_INTEGER, master, &
                     msgtype, MPI_COMM_WORLD, status, ierr )
      if (trial .EQ. -1) goto 99
      call mpi_recv( n, 1, MPI_INTEGER, master, &
                     msgtype, MPI_COMM_WORLD, status, ierr )
      call mpi_recv( data, n*2, MPI_REAL, master, &
                     msgtype, MPI_COMM_WORLD, status, ierr )
      call mpi_recv( nums, numdim*2, MPI_INTEGER, master, &
                     msgtype, MPI_COMM_WORLD, status, ierr )
      do il=1,2
        call mpi_recv( parmtest, refdim*2, MPI_REAL, master,
msgtype,MPI_COMM_WORLD,status,ierr)
        parmref(:,il)=parmtest(:)

```

```

        enddo
        call mpi_recv( xobs, odim*2, MPI_REAL, master,&
                       msgtype, MPI_COMM_WORLD, status, ierr )
        call mpi_recv( obs, odim*2, MPI_REAL, master,&
                       msgtype, MPI_COMM_WORLD, status, ierr )
        call mpi_recv( osig, odim*2, MPI_REAL, master,&
                       msgtype, MPI_COMM_WORLD, status, ierr )
        do il=1,nums(4)
            call mpi_recv( xauxtemp, odim*2, MPI_REAL, master,&
                           msgtype, MPI_COMM_WORLD, status, ierr )
            xaux(:,il)=xauxtemp(:)
        enddo

! -----
! perform calculations with data
! -----

        result = get_fitness( n, data )

! -----
! send result to master host
! -----

        msgtype = 2
        call mpi_send( myid, 1, MPI_INTEGER, master, &
                       msgtype, MPI_COMM_WORLD, ierr )
        call mpi_send( trial, 1, MPI_INTEGER, master, &
                       msgtype, MPI_COMM_WORLD, ierr )
        call mpi_send( result, 1, MPI_DOUBLE_PRECISION, &
                       master, msgtype, MPI_COMM_WORLD, ierr )

! -----
! go back for more work
! -----

        goto 25

99    return
    end

```


Appendix F: Fortran Code for Thermodynamics from Kinetics Fitting

Sample Input File fort.1

```
0.01,1,0.001,0,7,1
8,11
4296.15000.001640.0051
4298.15000.005020.0051
4303.15000.010390.0051
4307.15000.022270.0051
4312.15000.024510.0051
4313.15000.025990.0051
4315.15000.022720.0051
4317.15000.023810.0051
4318.15000.021430.0051
4320.15000.01810.0051
4323.15000.014560.0051
```

Sample Input File fort.4

```
8,20
00 (0.00E+00) 1
00 (0.00E+00) 2
00 (0.00E+00) 3
00 (0.00E+00) 4
319.553181 (0.11E+00) 5 Tm
-0.079791 (0.14E-01) 6 g(1)
15.897611 (0.22E-02) 7 A0
00 (0.27E-03) 8 mA
00 (0.00E+00) 1
00 (0.00E+00) 2
00 (0.00E+00) 3
00 (0.00E+00) 4
320.669891 (0.11E+00) 5
-0.307551 (0.14E-01) 6
15.897611 (0.22E-02) 7
00 (0.27E-03) 8
00 (0.00E+00) 1
00 (0.00E+00) 2
00 (0.00E+00) 3
00 (0.00E+00) 4
329.703231 (0.11E+00) 5
-0.259211 (0.14E-01) 6
15.897611 (0.22E-02) 7
00 (0.27E-03) 8
00 (0.00E+00) 1
00 (0.00E+00) 2
00 (0.00E+00) 3
00 (0.00E+00) 4
327.01241 (0.11E+00) 5
-0.169321 (0.14E-01) 6
15.897611 (0.22E-02) 7
00 (0.27E-03) 8
00 (0.00E+00) 1
00 (0.00E+00) 2
00 (0.00E+00) 3
```

```

00 (0.00E+00) 4
312.798481 (0.11E+00) 5
-0.185261 (0.14E-01) 6
15.897611 (0.22E-02) 7
00 (0.27E-03) 8
00 (0.00E+00) 1
00 (0.00E+00) 2
00 (0.00E+00) 3
00 (0.00E+00) 4
325.087871 (0.11E+00) 5
-0.306131 (0.14E-01) 6
15.897611 (0.22E-02) 7
00 (0.27E-03) 8
00 (0.00E+00) 1
00 (0.00E+00) 2
00 (0.00E+00) 3
00 (0.00E+00) 4
340.89551 (0.11E+00) 5
-0.201291 (0.14E-01) 6
15.897611 (0.22E-02) 7
00 (0.27E-03) 8
00 (0.00E+00) 1
00 (0.00E+00) 2
00 (0.00E+00) 3
00 (0.00E+00) 4
326.752191 (0.11E+00) 5
-0.326411 (0.14E-01) 6
15.897611 (0.22E-02) 7
00 (0.27E-03) 8
00 (0.00E+00) 1
00 (0.00E+00) 2
00 (0.00E+00) 3
00 (0.00E+00) 4
318.214811 (0.11E+00) 5
-0.080891 (0.14E-01) 6
15.897611 (0.22E-02) 7
00 (0.27E-03) 8
00 (0.00E+00) 1
00 (0.00E+00) 2
00 (0.00E+00) 3
00 (0.00E+00) 4
314.955921 (0.11E+00) 5
-0.309341 (0.14E-01) 6
15.897611 (0.22E-02) 7
00 (0.27E-03) 8
00 (0.00E+00) 1
00 (0.00E+00) 2
00 (0.00E+00) 3
00 (0.00E+00) 4
332.348611 (0.11E+00) 5
-0.331441 (0.14E-01) 6
15.897611 (0.22E-02) 7
00 (0.27E-03) 8
00 (0.00E+00) 1
00 (0.00E+00) 2
00 (0.00E+00) 3
00 (0.00E+00) 4

```

306.613861 (0.11E+00) 5
 -0.151081 (0.14E-01) 6
 15.897611 (0.22E-02) 7
 00 (0.27E-03) 8
 00 (0.00E+00) 1
 00 (0.00E+00) 2
 00 (0.00E+00) 3
 00 (0.00E+00) 4
 320.860861 (0.11E+00) 5
 -0.269791 (0.14E-01) 6
 15.897611 (0.22E-02) 7
 00 (0.27E-03) 8
 00 (0.00E+00) 1
 00 (0.00E+00) 2
 00 (0.00E+00) 3
 00 (0.00E+00) 4
 312.406711 (0.11E+00) 5
 -0.082981 (0.14E-01) 6
 15.897611 (0.22E-02) 7
 00 (0.27E-03) 8
 00 (0.00E+00) 1
 00 (0.00E+00) 2
 00 (0.00E+00) 3
 00 (0.00E+00) 4
 340.783041 (0.11E+00) 5
 -0.166841 (0.14E-01) 6
 15.897611 (0.22E-02) 7
 00 (0.27E-03) 8
 00 (0.00E+00) 1
 00 (0.00E+00) 2
 00 (0.00E+00) 3
 00 (0.00E+00) 4
 333.022051 (0.11E+00) 5
 -0.029961 (0.14E-01) 6
 15.897611 (0.22E-02) 7
 00 (0.27E-03) 8
 00 (0.00E+00) 1
 00 (0.00E+00) 2
 00 (0.00E+00) 3
 00 (0.00E+00) 4
 329.047441 (0.11E+00) 5
 -0.208771 (0.14E-01) 6
 15.897611 (0.22E-02) 7
 00 (0.27E-03) 8
 00 (0.00E+00) 1
 00 (0.00E+00) 2
 00 (0.00E+00) 3
 00 (0.00E+00) 4
 330.251751 (0.11E+00) 5
 -0.115471 (0.14E-01) 6
 15.897611 (0.22E-02) 7
 00 (0.27E-03) 8
 00 (0.00E+00) 1
 00 (0.00E+00) 2
 00 (0.00E+00) 3
 00 (0.00E+00) 4
 302.731931 (0.11E+00) 5

```

-0.163321(0.14E-01)6
15.897611(0.22E-02)7
00(0.27E-03)8
00(0.00E+00)1
00(0.00E+00)2
00(0.00E+00)3
00(0.00E+00)4
309.472771(0.11E+00)5
-0.081871(0.14E-01)6
15.858011(0.22E-02)7
00(0.27E-03)8

```

titrfit.f

!Models 6 and 7 are the derivative and full method added to existing code
!For these, the first value in the datasets are the size of the temperature
!jump instead of the denaturant concentration as used in other models.

```

!      PROGRAM TITRFIT is an upgraded F95 version of CDFIT.  It
!      fits cd and fluorescence T or denaturant titrations to
!      various thermodynamic models

!      VARIABLE DECLARATION

      module masterdim
        implicit none
        integer(4), parameter :: odim=1000, padim=49
      end module masterdim

      module obscalc
        use masterdim
        implicit none
        real(8) :: obs(odim),osig(odim)
        real(8) :: calc(odim)
        real(8) :: pa(padim),pasig(padim),chsqcopy
        integer(4) :: onum,panum,paf(padim),model,meas(odim),mnum,
1 lamflag(odim),maxlflag
!      The following are independent variables or other
!      information required by cal to evaluate calc():
        real(8) :: den(odim),dg(odim),k(odim),temp(odim),lambda(odim),
2 lamflmax,lamflmin,mintemp,maxtemp
      end module obscalc

!      Finds the inverse of a matrix by Gauss-Jordan elimination,
!      n is the actual matrix size, np the storage size (see
!      numerical recipes gaussj)
      module invert
        implicit none
        integer(4),parameter :: nmax=100 !max dimension of matrix

      contains

        subroutine matinv(a,np,n,err)
          implicit none
          real(8) :: a(np,np),big,dum,pivinv

```

```

integer(4) :: ipiv(nmax),indxr(nmax),indxc(nmax),i,icol,irow,
1 j,k,l,ll,n,np,err

err=0
if(n > np .or. n > nmax) then
  write(6,*) "Dimensions exceeded in matinv."
  stop
endif
do j=1,n
  ipiv(j)=0
enddo
do i=1,n
  big=0
  do j=1,n
    if(ipiv(j) /= 1) then
      do k=1,n
        if (ipiv(k) == 0) then
          if (abs(a(j,k)) >= big) then
            big=abs(a(j,k))
            irow=j
            icol=k
          endif
        else if (ipiv(k) > 1) then
          err=4
          return
        endif
      enddo
    endif
  enddo
  ipiv(icol)=ipiv(icol)+1
  if (irow /= icol) then
    do l=1,n
      dum=a(irow,l)
      a(irow,l)=a(icol,l)
      a(icol,l)=dum
    enddo
  endif
  indxr(i)=irow
  indxc(i)=icol
  if (a(icol,icol) == 0) then
    err=4
    return
  endif
  pivinv=1./a(icol,icol)
  a(icol,icol)=1
  do l=1,n
    a(icol,l)=a(icol,l)*pivinv
  enddo
  do ll=1,n
    if(ll /= icol) then
      dum=a(ll,icol)
      a(ll,icol)=0
      do l=1,n
        a(ll,l)=a(ll,l)-a(icol,l)*dum
      enddo
    endif
  enddo
enddo

```

```

        enddo
        do l=n,1,-1
            if(indxr(l) /= indxc(l)) then
                do k=1,n
                    dum=a(k,indxr(l))
                    a(k,indxr(l))=a(k,indxc(l))
                    a(k,indxc(l))=dum
                enddo
            endif
        enddo
    end subroutine matinv

end module invert

! Non-linear least squares fitting module
module nllsqfit
    use masterdim !From this, needs padim and odim
    use obscalc   !From this, needs obs,osig,calc,pa,paf,
                  !pasig,panum,onum
    use invert     !Needs this for matrix inversion calls
    implicit none
    integer(4) :: xpos(padim),xnum
    real(8) :: ocalc(odim),weight(odim),
2 beta(padim),alpha(padim,padim),alphin(padim,padim),
3 deriv(padim,odim)

    contains

        subroutine nllsq(debug,marq,chsq,delchi,delgrad,err,grad,
1            maxiter,icount)
            implicit none
            integer(4) :: fnum,err,debug,maxiter,icount,ifail,i1,i2,i3
            real(8) :: marq,delchi,grad,delgrad,ograd,chsq,chole,
1 x(padim),nextx(padim)

! Variables used in subroutines of module:

c OBS      ARRAY OF OBSERVED FUNCTION VALUES
c OSIG     UNCERTAINTIES OF OBSERVABLES
c CALC     ARRAY OF CALCULATED FUNCT. VALUES
c ONUM     NUMBER OF OBSERVED PARAMETERS
c XNUM     NUMBER OF ACTUALLY FITTED PARAMETERS
c PANUM    NUMBER OF FITTING PARAMETERS.
c PA       ARRAY OF FITTING PARAMETERS
c PAF      FITTING FLAGS;=0 FOR PARAMETERS HELD CONSTANT,
c          =1 FOR FITTED PARAMETERS
c PASIG    ARRAY THAT RETURNS UNCERTAINTIES IN PARAMETERS
c MARQ     MARQUARD PARAMETER; LARGE VALUE INDICATES
c          STEEPEST DESCENT STEP, SMALL VALUE NEWTON
c          (LINEARIZED CHISQ) STEP. SHOULD BE SET TO 0.001
c          INITIALLY
c CHSQ     CHI**2 OF FIT
c DELCHI   IF TWO SUCCESSIVE CHSQ AGREE WITHIN DELCHI, THE
c          FIT IS TERMINATED
c DELGRAD  IF THE GRADIENT OF CHSQ FALLS BELOW DELGRAD, THE
c          FIT IS TERMINATED
c ERR      ERROR CODE;SHOULD BE SET TO ZERO INITIALLY.

```

```

C          ERR=1: NO PARAMETERS FITTED;ONLY CHSQ IS RETURNED
C          ERR=2: MORE PARAMETERS THAN OBSERVABLES FITTED
C          ERR=3: MATRIX INVERSION FAILED;JACOBIAN SINGULAR
C          ERR=4: RECOVERY FROM SINGULAR JACOBIAN FAILED
C          ERR=5: NUMBER OF ITERATIONS IN ITER EXCEEDED
C          ERR=6: MARQ EXCEEDED 10**10; SSQ CANNOT BE MINI
C                  MIZED BECAUSE GRADIENTS TO STEEP OR DELCHI
C                  SET UNREALISTICALLY SMALL
C  ITER          MAXIMUM NUMBER OF ITERATIONS(CALLS OF DERIVATIVE)
C
C  THE FOLLOWING PARAMETERS MUST NOT BE SET TO ANYTHING INITIALLY,
C  BUT ARE USEFUL FOR DEBUGGING OR ADDITIONAL INFORMATION ABOUT
C  THE FIT; DIMENSIONING IS AS FOR OBS AND PA
C
C  X             ARRAY OF THOSE PA WHICH ARE FITTED
C  GRAD          NORM OF THE GRADIENT OF CHSQ;SHOULD BE CLOSE TO
C                ZERO NEAR THE MINIMUM
C  NEXTX         ARRAY OF FITTING PARAMETERS BEFORE TESTING FOR
C                ITS VIABILITY IN DECREASING CHSQ
C  ALPHA         MATRIX THAT CONTAINS THE JACOBIAN TRANSPOSE TIMES
C                THE JACOBIAN
C  BETA          GRADIENT OF SSQ
C  DERIV         MATRIX OF DERIVATIVES OF ALL OBS W/R TO ALL PARA-
C                METERS
C  ALPHIN        ON OUTPUT, CONTAINS PARAMETER CORRELATIONS
C
C  DETERMINE CONSTANTS TO BE FIT AND THEIR NUMBER
C
C      icoount=1
C      ograd=0d0
C      xnum=0
C      do il=1,panum
C        if(paf(il) /= 0) then
C          xnum=xnum+1
C          xpos(xnum)=il
C          x(xnum)=pa(il)
C        endif
C      enddo
C      if(xnum == 0) then
C        call chisq(chsq,x,icoount,ifail)
C        err=1
C        return
C      endif
C
C  !  EVALUATE DEGREES OF FREEDOM
C
C      fnum=onum-xnum
C      if (fnum < 1) then
C        err=2
C        return
C      endif
C
C  !  CALCULATE WEIGHTS
C
C      do il=1,onum
C        weight(il)=1d0/(osig(il)*osig(il))
C      enddo

```

```

!      EVALUATE INITIAL CHSQ; NOTE THAT THIS ALSO CALCULATES
!      CALC FOR THE PARAMETER SET X

      call chisq(chold,x,icount,ifail)

!      CALCULATE INITIAL GRADIENT OF CHISQ
!
      do i1=1,xnum
        beta(i1)=0d0
        do i2=1,i1
          alpha(i1,i2)=0d0
        enddo
      enddo

      icount=icount+1
      call der(icount,ifail)
      do i1=1,onum
        do i2=1,xnum
          beta(i2)=beta(i2)+weight(i1)*(obs(i1)-calc(i1))*
1          deriv(i2,i1)
          do i3=1,i2
            alpha(i2,i3)=alpha(i2,i3)+weight(i1)*deriv(i2,i1)
1            *deriv(i3,i1)
          enddo
        enddo
      enddo
      do i1=1,xnum
        do i2=1,i1
          alpha(i2,i1)=alpha(i1,i2)
        enddo
      enddo

!      CALCULATE PARAMETER INCREMENTS AS DELX=BETA*(MARQ*DIAGONAL(
!      ALPHA)+ALPHA)**-1 AND ADD TO X TO GIVE NEXTX, THE NEW TRIAL
!      SET OF PARAMETERS. NOTE THAT A SCALED ALPHA IS INVERTED, TO
!      IMPROVE ACCURACY, AND THEN RESCALED

      DO !Start of main fitting loop
      do i1=1,xnum
        do i2=1,xnum
          alphin(i1,i2)=alpha(i1,i2)/sqrt(alpha(i1,i1)*alpha(i2,i2))
        enddo
        alphin(i1,i1)=1d0+marq
      enddo
      call matinv(alphin,padim,xnum,err)
      if(err == 0) then
        do i1=1,xnum
          nextx(i1)=x(i1)
          do i2=1,xnum
            nextx(i1)=nextx(i1)+beta(i2)*alphin(i1,i2)/sqrt(
1            alpha(i1,i1)*alpha(i2,i2))
          enddo
        enddo
        call chisq(chsq,nextx,icount,ifail)
      else
        return
      enddo

```



```

endif

!   CALCULATE NEW TRIAL CHSQ AND CHECK IF IT INCREASED OR DE-
!   CREASED. IF IT DECREASED, NEXTX BECOMES X. SINCE CHSQ HAS
!   ALREADY EVALUATED CALC(NEXTX), THE NEXT ITERATION CAN BE
!   CONTINUED BY CALCULATING A NEW ALPHA AND BETA.

      if(chold-chsq > 0d0.and.ifail == 0) then
        grad=0d0
        do i1=1,xnum
          x(i1)=nextx(i1)
          grad=grad+beta(i1)*beta(i1)
        enddo
        grad=sqrt(grad)
        if(dabs(chold-chsq) < delchi.or.dabs(ograd-grad)
1      < delgrad) then
          do i1=1,xnum
            do i2=1,xnum
              alphin(i1,i2)=alpha(i1,i2)/dsqrt(alpha(i1,i1)*alpha(i2,i2))
            enddo
          enddo
          call matinv(alphin,padim,xnum,err)
          if(err /= 0) then
            err=8
          endif
          do i1=1,xnum
            pasig(xpos(i1))=dsqrt(alphin(i1,i1)/alpha(i1,i1))
          enddo
          do i1=1,xnum
            do i2=1,xnum
              alphin(i1,i2)=alphin(i1,i2)/sqrt(alpha(i1,i1)*
1          alpha(i2,i2))/(pasig(xpos(i1))*pasig(xpos(i2)))
            enddo
          enddo
          do i1=1,xnum
            pasig(xpos(i1))=sqrt(alphin(i1,i1)/alpha(i1,i1))
          enddo
          return
        endif
        marq=marq/10d0
        ograd=grad
        chold=chsq
        if(debug == 1) then
          write(6,fmt=' (" ****"/"CHI**2= ",e15.7/" PREV.GRAD= ",
1          e15.7/"MARQ= ",e10.2) ') chsq,grad,marq
          do i1=1,xnum
            write(6,fmt=' (" #",i2," X= ",e15.8," PREV.GRAD= ",
1          e15.7) ') i1,x(i1),beta(i1)
          enddo
        endif

!   CALCULATE NEW ~(J)*F*dF/dX , NEW GRADIENT OF CHSQ AND THE
!   ~J*J MATRIX, WHERE F=(O-C)/OSIG AND ~ MEANS TRANSPOSE
      do i1=1,xnum
        beta(i1)=0d0
        do i2=1,i1
          alpha(i1,i2)=0d0

```

```

        enddo
    enddo

    icount=icount+1
    call der(icount,ifail)
    do i1=1,onum
        do i2=1,xnum
            beta(i2)=beta(i2)+weight(i1)*(obs(i1)-calc(i1))*
1          deriv(i2,i1)
            do i3=1,i2
                alpha(i2,i3)=alpha(i2,i3)+weight(i1)*deriv(i2,i1)
1          *deriv(i3,i1)
            enddo
        enddo
    enddo
    do i1=1,xnum
        do i2=1,i1
            alpha(i2,i1)=alpha(i1,i2)
        enddo
    enddo

!      IF CHSQ INCREASED, THE MARQUARDT PARAMETER MUST BE INCREA-
!      SED TO FORCE DESCENT IN CHSQ. NEXTX IS DISCARDED AND A
!      SMALLER STEP AWAY FROM THE ORIGINAL X IS TRIED

    else
        if(maxiter < icount) then
            err=5
            return
        endif
        marq=max(marq*10d0,0.001d0)
        if(marq.gt.1d10) then
            err=6
            return
        endif
        if(debug == 1) then
            write(6,fmt='(" ****"/"CHI**2= ",e15.7/" GRAD= ",
1          e15.7/"MARQ= ",e10.2/" ITERATION FAILED")') chsq,grad,marq
            do i1=1,xnum
                write(6,fmt='(" #",i2," NEXTX= ",e15.8," GRAD= ",
1          e15.7)') i1,nextx(i1),beta(i1)
            enddo
        endif
        do i1=1,onum
            calc(i1)=ocalc(i1)
        enddo
    endif
    ENDDO !End of main fitting loop

end subroutine nllsq

!      CHISQ RETURNS THE REDUCED CHI**2 AFTER CALLING THE ROUTINE
!      OBSERVED WHICH SHOULD RETURN THE OBSERVED VALUES

    subroutine chisq(chsq,x,icount,ifail)
        use masterdim
use obscalc

```

```

        implicit none
        real(8) :: chsq,x(padim)
        integer(4) :: il,ifail,icount
        do il=1,xnum
            pa(xpos(il))=x(il)
        enddo
        call cal(icount,ifail)
        if(ifail /= 0) then
            write(6,*) "Warning; subroutine cal() has ifail= ",ifail
        endif
        chsq=0d0
        do il=1,onum
            chsq=chsq+(obs(il)-calc(il))*(obs(il)-calc(il))*weight(il)
        enddo
        chsq=chsq/(onum-xnum)
    end subroutine chsq

!      DER CALCULATES THE DERIVATIVES OF ALL OBS W/R TO ALL X
!      IT ALSO SAVES CALC FOR RECOVERY SHOULD SSQ NOT DECREASE

    subroutine der(icount,ifail)
        use masterdim
use obscalc
        implicit none
        real(8) :: save
        integer(4) :: ifail,il,i2,icount
        do il=1,onum
            ocalc(il)=calc(il)
        enddo
        do il=1,xnum
            save=pa(xpos(il))
            pa(xpos(il))=pa(xpos(il))*1.0000001d0
            if(pa(xpos(il)).eq.0) then
                pa(xpos(il))=1d-7
            endif
            call cal(icount,ifail)
            if(ifail /= 0) then
                write(6,*) "Warning; subroutine cal() has ifail= ",ifail
            endif
            do i2=1,onum
                if(save.ne.0) then
                    deriv(il,i2)=(calc(i2)-ocalc(i2))*1d7/save
                else
                    deriv(il,i2)=(calc(i2)-ocalc(i2))*1d7
                endif
            enddo
            pa(xpos(il))=save
        enddo
    end subroutine der

end module nllsqfit

program main
    use masterdim
    use obscalc
    integer(4) :: il,i2,tnum
    real(8) :: tmbest,tmsigbest,glbest,glsigbest,chsqbset

```

```

        open(unit=20,file="temps.out",access='APPEND') !Test
        open(unit=30,file="best.out",access='APPEND')
        open(unit=40,file="test.out")
chsqbest=1000

read(4,*) panum,tnum
do i2=1,tnum
do i1=1,panum
    read(4,*) pa(i1),paf(i1)
enddo
    call fitter
close(1)
    write (20,'(f10.5,1x,e15.8)') pa(i1),chsqcopy      !Test
write(9,'(6(e12.6,1x))'),pa(1),pa(2),pa(3),pa(4),pa(5),pa(7)
    if(chsqcopy<chsqbest) then
        chsqbest=chsqcopy
tmbest=pa(5)
tmsigbest=pasig(5)
glbest=pa(7)
glsigbest=pasig(7)
write (40,*) ,i2
    endif
enddo
write(30,'(4(f10.5,1x))')tmbest,tmsigbest,glbest,glsigbest!,chsqbest ,e15.8
print *,glsigbest
end program main

subroutine fitter
use masterdim
use obscalc

    use nllsqfit
    implicit none
    integer(4) :: i1,i2,err,debug,maxiter,icount
    real(8) :: marq,chsq,delchi,delgrad,grad

!      Input of Marquard parameter (typically 0.01), debug flag (=1
!      means detailed output in unit 6 at each iteration, =0 means
!      no debugging output), minimum delchi difference (since chi**2
!      ideally 1 at the end of the fit, delchi ~ 0.000001) and
!      minimum gradient difference (usually 0); model is the model
!      to be used (see cal), and mnum the number of measurement types
!      (1 or 2, for CD and/or fluorescence); panum = number of
!      parameters to be fit, onum = number of observed points, pa =
!      the parameters, paf = fitting flag (pa(i) is fit if paf(i) =
!      1, held constant if paf(i)=0)

    read(1,*) marq,debug,delchi,delgrad,model,mnum
    read(1,*) panum,onum
!print *, "Test2",pa(7),panum
!do i1=1,panum
!    read(1,*) pa(i1),paf(i1)
!enddo

```

```

!      Read in observed data obs()
!      den(): denaturant concentration
!      temp(): temperature
!      lambda(): wavelength; lamflag() = 1,2,3... labels the
!      different wavelengths in INCREASING order with consecutive integers
!      obs(): signal to be fitted
!      osig(): estimated uncertainty in signal to be fitted
!      meas(): =1 is CD, =2 is fluorescence (if lambda=0, it will be
!      assumed that an average/integrated intensity is reported)

      maxlflag=0
      mintemp=100000.
      maxtemp=0
      do i1=1,onum
        read(1,*) den(i1),temp(i1),lambda(i1),lamflag(i1),obs(i1),
1      osig(i1),meas(i1)
        maxlflag=max(maxlflag,lamflag(i1))
        mintemp=min(mintemp,temp(i1))
        maxtemp=max(maxtemp,temp(i1))
        if(lamflag(i1) == 1) lamflmin=lambda(i1)
        if(lamflag(i1) == maxlflag) lamflmax=lambda(i1)
      enddo

      err=0
      maxiter=200
!      Perform nonlinear least squares fit

      call nllsq(debug,marq,chs,delchi,delgrad,err,grad,
1      maxiter,icount)
! call nllsq(debug,marq,chs,delchi,delgrad,err,grad,
!      1      maxiter,icount)

      if(err /= 0) then
        write(2,*) 'Fit has not converged;err= ',err
      endif

!      Output observed and calculated data

      do i1=1,onum
        write(2,160) den(i1),temp(i1),lambda(i1),obs(i1),calc(i1),
1      obs(i1)-calc(i1),dg(i1)
160      format(' ',3f9.2,3f12.4,1x,f9.2)
      enddo

!      Output fitted parameters

      do i1=1,panum
        write (2,170) pa(i1),paf(i1),pasig(i1),i1
170      format(e15.8,1x,i1,1x,'(',e8.2,')', 1x,i2)
      enddo

!Test----

!      read(4,*) tnum
!      do i2=1,tnum
!      do i1=1,panum

```

```

!      read(4,*) pa(i1),paf(i1)
!      enddo
!      call nllsq(debug,marq,chs,delchi,delgrad,err,grad,
!      1          maxiter,icount)

!      i1=5                                !Test
!      write (20,170) pa(i1),paf(i1),pasig(i1),i1    !Test
!      enddo
!      !----End Test----
!      Output correlation matrix with scaled diagonal

      do i1=1,xnum
        write(2,185) (alpin(i1,i2), i2=1,xnum)
185      format(100(f9.5))
      enddo
      write(2,*) 'chs=' ,chs,'grad=' ,grad,'icount=' ,icount
      chscopy=chs
      end subroutine fitter

!      SUBROUTINE CAL RETURNS CALC TITRATIONS TO NLLSQ
!      This needs to be modified by the user to contain the desired
!      functions; calc(i) is the calculated point of the function
!      corresponding to the observed point obs(i)
!      CAL obtains dimensioning parameters and independent
!      variable information from modules masterdim and obscalc.
!      CAL receives only the iteration count as a parameter, and
!      should return ifail=0 if the call was successful.

      subroutine cal(icount,ifail)
      use masterdim
      use obscalc
      implicit none
      real(8) :: t0,dh0,ds0,dc, dg0, dg1, dg2, dg1m, dg1(20), tm(20), tstart
      real(8) :: dh,ds,sigf,sigu,cm,m,rhot1,rhot2
      real(8) :: f0(10),u0(10),fslope(10),uslope(10)
      real(8) :: f0low,fs1low,fs2low,f0hi,fs1hi,fs2hi,
1      u0low,us1low,us2low,u0hi,us1hi,us2hi,
2      frac
      real(8) :: A0, Aslope, expo, amp, pre
      integer(4) :: i,icount,ifail,start,j

!      Use 1 or 2 sets of baselines, depending on whether
!      1 (e.g. CD) or 2 (e.g. CD and fluorescence) data
!      sets are fitted
      do j=1,mnum
        f0(j)=pa(4*(j-1)+1)
        fslope(j)=pa(4*(j-1)+2)
        u0(j)=pa(4*(j-1)+3)
        uslope(j)=pa(4*(j-1)+4)
      enddo

!      SPECIAL CONSTRAINT; delete if not desired
!      Holds slopes of measurement 3 to same as measurement 1
!      fslope(3)=fslope(1)
!      uslope(3)=uslope(1)
!      END SPECIAL CONSTRAINT

```

```

start=4*mnum+1

if(model == 1) then
c
c      Two state model U to F; t0 is the reference temperature in K,
c      dh0,ds0,dcp are the reference enthalpy, entropy and heat
c      capacity for the U to F reaction; for temperature titrations
c      xobs() is the temperature
c
      t0=pa(start)
      dh0=pa(start+1)
      ds0=pa(start+2)
      dcp=pa(start+3)
c
      do i=1,onum
        dh=dh0+dcp*(temp(i)-t0)
        ds=ds0+dcp*dlog(temp(i)/t0)
        dg(i)=dh-temp(i)*ds
        k(i)=dexp(-dg(i)/(8.31d-3*temp(i)))
        sigu=u0(meas(i))+uslope(meas(i))*(temp(i)-t0)
        sigf=f0(meas(i))+fslope(meas(i))*(temp(i)-t0)
        calc(i)=(sigf*k(i)+sigu)/(1d0+k(i))
      enddo

else if(model == 2) then
c
c      Two state model U to F; Cm is the midpoint denaturant conc.
c      m is the m value; for denaturant titrations; x() is the
c      denaturant concentration; temp() is the temperature
c
      cm=pa(start)
      m=pa(start+1)
c
      do i=1,onum
        dg(i)=m*(den(i)-cm)
        k(i)=dexp(-dg(i)/(8.31d-3*temp(i)))
        sigu=u0(meas(i))+uslope(meas(i))*den(i)
        sigf=f0(meas(i))+fslope(meas(i))*den(i)
        calc(i)=(sigf*k(i)+sigu)/(1d0+k(i))
      enddo

else if(model == 3) then
c
c      Temperature denaturation for two state system, assuming
c      quadratic free energy
c
      t0=pa(start)
      dg0=pa(start+1)
      dg11=pa(start+2)
      dg2=pa(start+3)
c
      do i=1,onum
        dg(i)=dg0+dg11*(temp(i)-t0)+dg2*(temp(i)-t0)**2
        k(i)=dexp(-dg(i)/(8.31d-3*temp(i)))
        sigu=u0(meas(i))+uslope(meas(i))*(temp(i)-t0)
        sigf=f0(meas(i))+fslope(meas(i))*(temp(i)-t0)

```

```

        calc(i)=(sigf*k(i)+sigu)/(1d0+k(i))
    enddo

else if(model == 4) then
c
c   Combined temperature and denaturant titration fit
c
    t0=pa(start)
    dg0=pa(start+1)
    dg2=pa(start+2)
    m=pa(start+3)
    dg1m=pa(start+4)
    do i=1,onum
        dg(i)=dg0+dg2*(temp(i)-t0)**2+m*den(i)+dg1m*den(i)*
1      (temp(i)-t0)
        k(i)=dexp(-dg(i)/(8.31d-3*temp(i)))
        sigu=u0(meas(i))+uslope(meas(i))*(temp(i)-t0)
        sigf=f0(meas(i))+fslope(meas(i))*(temp(i)-t0)
        calc(i)=(sigf*k(i)+sigu)/(1d0+k(i))
    enddo
else if(model == 5) then
c
c   Fits fluorescence data at different wavelengths such that the
c   quadratic baseline is linearly interpolated with wavelength, but
c   each two state transition has its own dg1 and Tm; assumes the
c   data are normalized to 1 and 0 at the min. and max. temperatures.

    if(maxlflag > 20) then
        write(6,*) 'Too many fluorescence channels for dimension'
        stop
    endif
    do i=1,maxlflag
        tm(i)=pa(2*i-1)
        dg1(i)=pa(2*i)
    enddo
    start=2*maxlflag+1
    f0low=pa(start)
    fs11low=pa(start+1)
    fs12low=pa(start+2)
!   Some of the baseline parameters are fixed equal to others
    f0hi=pa(start)
    fs11hi=pa(start+8)
    fs12hi=pa(start+2)
    u0low=pa(start+3)
    us11low=pa(start+4)
    us12low=pa(start+5)
    u0hi=pa(start+3)
    us11hi=pa(start+6)
    us12hi=pa(start+7)
    do i=1,onum
        dg(i)=dg1(lamflag(i))*(temp(i)-tm(lamflag(i)))
        k(i)=dexp(-dg(i)/(8.31d-3*temp(i)))
        frac=(lambda(i)-lamflmin)/(lamflmax-lamflmin)
        sigu=u0low*(1-frac)+u0hi*frac +
1      (us11low*(1-frac)+us11hi*frac)*(temp(i)-maxtemp) +
2      (us12low*(1-frac)+us12hi*frac)*(temp(i)-maxtemp)**2
        sigf=f0low*(1-frac)+f0hi*frac +

```



```

1  (fsl1low*(1-frac)+fsl1hi*frac)*(temp(i)-mintemp) +
2  (fsl2low*(1-frac)+fsl2hi*frac)*(temp(i)-mintemp)**2
   calc(i)=(sigf*k(i)+sigu)/(1d0+k(i))
   enddo
elseif(model==6) then
!
!   Fits thermodynamic parameters for two-state based on kinetic data,
derivative version
   t0=pa(start)
   dg11=pa(start+1)
   A0=pa(start+2)
   Aslope=pa(start+3)

   do i=1, onum
      tstart=temp(i)-den(i)/2d0 ! T+dT/2-dT/2 (T at start of jump using input
as midpoint)
      !expo=dexp(-dg11*(temp(i)-t0)/(8.31d-3*temp(i)))
expo=dexp(-dg11*(tstart-t0)/(8.31d-3*tstart))
      !amp=(A0+Aslope*(temp(i)+den(i)/2d0-t0))
amp=(A0+Aslope*(temp(i)-t0))
      !pre=(-dg11*den(i)*t0)/(8.31d-3*temp(i)*temp(i))
pre=(-dg11*den(i)*t0)/(8.31d-3*tstart*tstart)
      calc(i)=pre*amp*expo/((1d0+expo)*(1+expo))
   enddo

elseif(model==7) then
!
!   Fits thermodynamic parameters for two-state based on kinetic data, full
version
   t0=pa(start)
   dg11=pa(start+1)
   A0=pa(start+2)
   Aslope=pa(start+3)

   do i=1, onum
      tstart=temp(i)-den(i) ! T + dT - dT (T at start of jump using input as
final T)
      expo=dexp(-dg11*(temp(i)-t0)/(8.31d-3*temp(i)))
rhot2=expo/(1+expo)
      expo=dexp(-dg11*(tstart-t0)/(8.31d-3*tstart))
rhot1=expo/(1+expo)
      amp=(A0+Aslope*(temp(i)-t0))
calc(i)=amp*(rhot2-rhot1)
   enddo

endif
end subroutine cal

```

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